

TRAVEO™ T2G 32-bit Automotive MCU

Based on Arm® Cortex®-M7 single

General description

CYT3DL is a family of TRAVEO™ T2G microcontrollers targeted at automotive systems such as instrument clusters and Head-Up Displays (HUD). CYT3DL has a 2D Graphics engine, sound processing, an Arm® Cortex®-M7 CPU for primary processing, and an Arm® Cortex®-M0+ CPU for peripheral and security processing. These devices contain embedded peripherals supporting Controller Area Network with Flexible Data rate (CAN FD), Local Interconnect Network (LIN), Clock Extension Peripheral Interface (CXPI), and Ethernet. TRAVEO™ T2G devices are manufactured on an advanced 40-nm process. CYT3DL incorporates Infineon' low-power flash memory, multiple high-performance analog and digital peripherals, and enables the creation of a secure computing platform.

Features

• Graphics subsystem

- Supports 2D and 2.5D (perspective warping, 3D effects) graphics rendering
- Internal color resolution
 - 40-bit for RGBA (4 × 10-bit)
 - 24-bit for RGB (3 × 8-bit)
- 2048 KB of embedded video RAM memory (VRAM)
- Two video output interfaces supporting a display from
 - Parallel RGB (max display size: 800 × 600 at 40 MHz)
 - FPD-link single (max display size: 1920 × 720 at 110 MHz)
- One Capture engine for video input processing for ITU 656 or parallel RGB/YUV or MIPI CSI-2 input
 - ITU656 (standard camera capture: up to 800 × 480), multiplexed with RGB interface
 - RGB (max capture size 1600 × 600 at 80 MHz) or
 - Two-/four-lane MIPI CSI-2 interface (max capture size: 1920 × 720 for two lanes at 110 MHz, 2880 × 1080 for four lanes at 220 MHz)
- Display warping on-the-fly for HUD applications
- Direct video feed through from capture to display interface with graphics overlay
- Composition engine for scene composition from display layers
- Display engine for video timing generation and display functions
- Drawing engine for acceleration of vector graphics rendering
- Command sequencer for setup and control of the rendering process
- Supports graphics rendering without frame buffers (on-the-fly)
- Single-channel FPD-Link/LVDS interface for up to HD resolution video output

• Sound subsystem

- Four time-division multiplexing (TDM) interfaces
- Two pulse-code modulation-pulse width modulation (PCM-PWM) interfaces
- Up to five sound generator (SG) interfaces
- Two PCM Audio stream mixers with five input streams
- One audio digital-to-analog converter (DAC)

• CPU subsystem

- 240-MHz (max) 32-bit Arm® Cortex®-M7 CPU, with
 - Single-cycle multiply
 - Single/double-precision floating point unit (FPU)
 - 16-KB data cache, 16-KB instruction cache
 - Memory protection unit (MPU)
 - 64-KB instruction and 64-KB data Tightly-Coupled Memories (TCM)

Features

- 100-MHz 32-bit Arm® Cortex®-M0+ CPU with
 - Single-cycle multiply
 - Memory protection unit
- Inter-processor communication in hardware
- Four DMA controllers
 - Peripheral DMA controller #0 (P-DMA0) with 76 channels
 - Peripheral DMA controller #1 (P-DMA1) with 84 channels
 - Memory DMA (AHB) controller (M-DMA0) with 8 channels
 - Memory DMA (AXI) controller (M-DMA1) with 4 channels
- **Integrated memories**
 - 4160-KB code-flash with an additional 128-KB of work-flash
 - Read-While-Write (RWW) allows updating the code-flash/work-flash while executing from it
 - Single- and dual-bank modes (specifically for Firmware update Over The Air [FOTA])
 - Flash programming through SWD/JTAG interface
 - 384-KB SRAM with selectable retention granularity
- **Crypto engine**^[1]
 - Supports Enhanced Secure Hardware Extension (eSHE) and Hardware Security Module (HSM)
 - Secure boot and authentication
 - Using digital signature verification^[1]
 - Using fast secure boot
 - AES: 128-bit blocks, 128-/192-/256-bit keys
 - 3DES^[1]: 64-bit blocks, 64-bit key
 - Vector unit^[1] supporting asymmetric key cryptography such as Rivest-Shamir-Adleman (RSA) and Elliptic Curve (ECC)
 - SHA-1/2/3^[1]: SHA-512, SHA-256, SHA-160 with variable length input data
 - CRC^[1]: supports CCITT CRC16 and IEEE-802.3 CRC32
 - True random number generator (TRNG) and pseudo random number generator (PRNG)
 - Galois/Counter Mode (GCM)
- **Functional safety for ASIL-B**
 - Memory protection unit (MPU)
 - Shared memory protection unit (SMPU)
 - Peripheral protection unit (PPU)
 - Watchdog timer (WDT)
 - Multi-counter watchdog timer (MCWDT)
 - Low-voltage detector (LVD)
 - Brown-out detection (BOD)
 - Overvoltage detection (OVD)
 - Overcurrent detection (OCD)
 - Clock supervisor (CSV)
 - Supported in all power modes except Hibernate mode
 - Hardware error correction (SECDED ECC) on all safety-critical memories (SRAM, flash, TCM)
- **Low-power 2.7-V to 5.5-V operation**
 - Low-power Active, Sleep, Low-power Sleep, DeepSleep, and Hibernate modes for fine-grained power management
 - Configurable options for robust BOD
 - Two threshold levels (2.7 V and 3.0 V) for BOD on V_{DD} and V_{DDA_ADC}
 - One threshold level (1.1 V) for BOD on V_{CCD}
- **Wakeup support**
 - Up to four pins to wakeup from Hibernate mode
 - Up to 61 GPIO pins to wakeup from DeepSleep mode
 - Event Generator, SCB, Watchdog Timer, RTC alarms to wake from DeepSleep modes

Note

1. The Crypto engine features are available on select MPNs.

Features**• Clocks**

- Internal main oscillator (IMO)
- Internal low-speed oscillator (ILO)
- External crystal oscillator (ECO)
- Watch crystal oscillator (WCO)
- Phase-locked loop (PLL)
- Frequency-locked loop (FLL)
- Low-power external crystal oscillator (LPECO)

• Communication interfaces

- Up to four CAN FD channels
 - Increased data rate (up to 8 Mbps) compared to classic CAN, limited by physical layer topology and transceivers
 - Compliant to ISO 11898-1:2015
 - Supports all the requirements of Bosch CAN FD Specification V1.0 non-ISO CAN FD
 - ISO 16845:2015 certificate available
- Up to 12 runtime-reconfigurable serial communication block (SCB) channels, each configurable as I²C, SPI, or UART
- Up to two independent LIN channels
 - LIN protocol compliant with ISO 17987
- Up to two CXPI channels with data rate up to 20 kbps
- 10/100 Mbps Ethernet MAC interface conforming to IEEE-802.3bw
 - Supports the following PHY interfaces:
 - Media-independent interface (MII)
 - Reduced media-independent interface (RMII)
 - Compliant with IEEE-802.1BA for audio video bridging (AVB)
 - Compliant with IEEE-1588 precision time protocol (PTP)

• Serial memory interface (SMIF)

- Two SPIs (single, dual, quad, or octal), xSPI interface
- On-the-fly encryption and decryption
- Execute-In-Place (XIP) from external memory

• Timers

- Up to 50 16-bit and 32 32-bit Timer/Counter Pulse-Width modulator (TCPWM) blocks for regular operations
 - Up to 12 16-bit counters optimized for motor-control operations (Equivalent to 6 stepper motor-control [SMC] channels with ZPD and slew rate control capability)
 - Supports timer, capture, quadrature decoding, pulse-width modulation (PWM), PWM with dead time (PWM_DT), pseudo-random PWM (PWM_PR), and shift-register (SR) modes
- Up to 16 Event Generation (EVTGEN) timers supporting cyclic wakeup from DeepSleep
 - Events trigger a specific device operation (such as execution of an interrupt handler, a SAR ADC conversion, and so on)

• Real time clock (RTC)

- Year/Month/Date, Day-of-week, Hour:Minute:Second fields
- 12- and 24-hour formats
- Automatic leap-year correction

• I/O

- Up to 135 programmable I/Os
- Four I/O types
 - GPIO Standard (GPIO_STD)
 - GPIO Enhanced (GPIO_ENH)
 - GPIO Stepper Motor Control (GPIO_SMC)
 - High-Speed I/O Standard with Low Noise (HSIO_STDLN)

Features

- **Power**
 - Regulators
 - Generates 1.1-V nominal core supply from a 2.7-V to 5.5-V input supply
 - Two regulators: DeepSleep and Core internal
 - PMIC control module
- **Programmable analog**
 - One SAR A/D converter
 - Each ADC supports 32 logical channels, with 48 external channels. Any external channel can be connected to any logical channel in the SAR.
 - 12-bit resolution and sampling rates up to 1 Msps
 - The ADC also supports six internal analog inputs like
 - Bandgap reference to establish absolute voltage levels
 - Calibrated diode for junction temperature calculations
 - Two AMUXBUS inputs and two direct connections to monitor supply levels
 - ADC supports addressing of external multiplexers
 - ADC has a sequencer supporting autonomous scanning of configured channels
- **Smart I/O**
 - One smart I/O block, which can perform Boolean operations on signals going to and from I/Os
 - Up to eight I/Os (GPIO_STD) supported
- **Debug interface**
 - JTAG controller and interface compliant to IEEE-1149.1-2001
 - Arm® SWD (serial wire debug) port
 - Supports Arm® Embedded Trace Macrocell (ETM) Trace
 - Data trace using SWD
 - Instruction and data trace using JTAG
- **Compatible with industry-standard tools**
 - GHS MULTI or IAR EWARM for code development and debugging
- **Packages**
 - 272-BGA, 16 × 16 × 1.7 mm (max), 0.8-mm ball pitch
 - 216-TEQFP, 24 × 24 × 1.6 mm (max), 0.4-mm ball pitch

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1 Features list

Table 1-1 CYT3DL feature list

Features	Packages	
	216-TEQFP	272-BGA
CPU		
Core	32-bit Arm® Cortex®-M7 CPU and 32-bit Arm® Cortex®-M0+ CPU	
Functional safety	ASIL-B	
Operation voltage for GPIO_STD	2.7 V to 5.5 V	
Operation voltage for GPIO_ENH	2.7 V to 5.5 V	
Operation voltage for GPIO_SMC	2.7 V to 5.5 V	
Operation voltage for HSIO_STDLN	3.0 V to 3.6 V	
Core voltage VCCD	1.09 V to 1.21 V	
Operation frequency	Arm® Cortex®-M7 240 MHz (max) and Arm® Cortex®-M0+ 100 MHz (max)	
MPU, PPU	Supported	
FPU	Supports both single (32-bit) and double (64-bit) precision	
DSP-MUL/DIV/MAC	Supported by Arm® Cortex®-M7 CPU	
TCM	64-KB instruction and 64-KB data for Cortex®-M7 CPU	
Memory		
Code-flash	4160 KB (4032 KB + 128 KB)	
Work-flash	128 KB (96 KB + 32 KB)	
SRAM (configurable for retention)	384 KB	
ROM	64 KB	
Communication Interfaces		
CAN0 (CAN-FD: Up to 8 Mbps)	2 ch	
CAN1 (CAN-FD: Up to 8 Mbps)	2 ch	
CAN RAM	16 KB per instance (2 ch), 32 KB in total	
Serial Communication Block (SCB/UART)	9 ch	12 ch
Serial Communication Block (SCB/I²C)	9 ch	11 ch
Serial Communication Block (SCB/SPI)	8 ch	11 ch
LINO	2 ch	
CXPI controller	2 ch	
Ethernet MAC	1 ch × 10/100	
Memory Interfaces		
SMIF (Single SPI / Dual SPI / Quad SPI / Octal SPI / xSPI)	2 ch (HSIO_STDLN at 100 MHz)	2 ch (HSIO_STDLN at 133 MHz)
Timers		
RTC	1 ch	
TCPWM (16-bit)	38 ch	
TCPWM (16-bit) SMC	12 ch (Equivalent to 6 ch SMC with ZPD and slew rate control)	
TCPWM (32-bit)	32 ch	
External Interrupts	108	135
Analog		
12-bit, 1 Msps SAR ADC	1 Unit (SAR#0, 32 logical channels)	
	48 external channels	
	6 ch for Internal sampling	
Security		
Flash Security (program/work read protection)	Supported	
Flash Chip erase enable	Configurable	

Features list

Table 1-1 **CYT3DL feature list** (continued)

Features	Packages	
	216-TEQFP	272-BGA
eSHE / HSM	By separate firmware ^[2]	
Sound		
Mixer	2 ch (5 mixer sources)	
PCM-PWM	2 ch	
TDM/I ² S	4 TDM structures (each support 32 channels)	
TDM/RX	3 ch	4 ch
TDM/TX	2 ch	4 ch
Audio DAC	1 ch	
Sound Generator (SG)	5 ch	
Graphics		
2/2.5 D Engine	Supported	
Embedded Video RAM	2048 KB (with protection)	
Vector Drawing	Supported	
Warping	Supported (on the fly)	
Scale/Rotate/Blend	Supported (on the fly)	
Graphics Engine Clock	200 MHz (max)	
Timing Control	One output	
Video Capture	One Capture (1× MIPI CSI-2, up to 4 lanes)	One Capture (1× RGB or 1× MIPI CSI-2, up to 4 lanes)
Video Capture Formats	TTL - ITU656 (8-/10-bit, RGB/YUV interlaced or progressive), Parallel RGB (1 to 24 bpp), YUV444, YUV422 MIPI CSI-2 - Table 29-3	
Number of Displays	Up to two (1× LVDS single and/or 1× RGB)	
RGB888/TTL Output	1 ch at 40 MHz (max)	
FPD-link/LVDS Output	Single channel LVDS at 80 MHz pixel clock (max)	Single channel LVDS at 110 MHz pixel clock (max)
MIPI CSI-2 Input	4 or 2 lane MIPI CSI-2 at 80 MHz pixel clock (max)	4 or 2 lane MIPI CSI-2 at 110 MHz pixel clock (max)
System		
DMA Controller	P-DMA0 with 76 channels (32 general purpose), P-DMA1 with 84 channels (16 general purpose), M-DMA0 with 8 channels, and AXI M-DMA1 with 4 channels	
Internal Main Oscillator	8 MHz	
Internal Low speed Oscillator	32.768 kHz (nominal)	
PLL	Input frequency: 3.988 to 33.34 MHz, PLL output frequency: up to 240 MHz	
FLL	Input frequency: 0.25 to 100 MHz, FLL output frequency: up to 100 MHz	
Watchdog timer and multi-counter watchdog timer	Supported (WDT + 2× MCWDT) MCWDT#0 tied to CM0+, MCWDT#1 to CM7_0	
Clock supervisor	Supported	
Cyclic wakeup from DeepSleep	Supported	
GPIO Standard (GPIO_STD)	20	29
GPIO Enhanced (GPIO_ENH)	8	
GPIO SMC (GPIO_SMC) ^[3]	24	
HSIO Standard Low Noise (HSIO_STDLN)	55	74
Notes		
2. Enhanced Secure Hardware Extension (eSHE) and Hardware Security Module (HSM) support are enabled by third-party firmware.		
3. High current SMC I/O for direct connections to stepper motor coils for pointer instruments.		
Smart I/O (Blocks)	1 block, mapped through 8 I/Os	
Low-voltage detect	Two, 26 selectable levels	

Features list

Table 1-1 **CYT3DL feature list** *(continued)*

Features	Packages	
	216-TEQFP	272-BGA
Maximum ambient temperature	105°C for S-grade, 125°C for E-grade	
Debug interface	SWD/JTAG	
Debug Trace	Arm® Cortex®-M7 ETB size of 8 KB, Arm® Cortex®-M0+ MTB size of 4 KB	

Features list

1.1 Peripheral instance list

The following table lists the instances supported under each package for communication peripherals, based on the minimum, and full pins needed for the functionality.

Table 1-2 Minimum peripheral instance list

Module	216-TEQFP	272-BGA	Minimum pin functions
CAN0	0-1	0-1	TX, RX
CAN1	0-1	0-1	TX, RX
LIN0	0-1	0-1	TX, RX
CXPI	0-1	0-1	TX, RX
SCB/UART	0-4, 8-11	0-11	TX, RX
SCB/I2C	1-4, 7-11	1-11	SCL, SDA
SCB/SPI	1-4, 8-11	1-11	MISO, MOSI, SCK, SELECT0
TDM/RX	0-2	0-3	MCK, FSYNC, SCK, SD
TDM/TX	2-3	0-3	MCK, FSYNC, SCK, SD
SG	0-4	0-4	TONE, AMPL
ETHERNET	0	0	RMII
SMIF	0-1	0-1	DATA, CLK, RWDS, SELECT0-1
PWM	0-1	0-1	LINE1_P/N, LINE2_P/N
TCPWM (32-bit)	0-31	0-31	PWM, PWM_N
TCPWM (16-bit) ^[4]	32-35, 256-267, 520-533, 536-543	32-37, 256-267, 512-543	PWM, PWM_N

Table 1-3 Full peripheral instance list

Module	216-TEQFP	272-BGA	Full pin functions
CAN0	0-1	0-1	TX, RX
CAN1	0-1	0-1	TX, RX
LIN0	0-1	0-1	TX, RX, EN
CXPI	0-1	0-1	TX, RX, EN
SCB/UART	0-4, 8-11	0-11	TX, RX, RTS, CTS
SCB/I2C	1-4, 7-11	1-11	SCL, SDA
SCB/SPI	1-4, 8	1-11	MISO, MOSI, SCK, SELECT0-1
TDM/RX	0-2	0-3	MCK, FSYNC, SCK, SD
TDM/TX	2-3	0-3	MCK, FSYNC, SCK, SD
SG	4	0-4	TONE, AMPL, MCK
ETHERNET	–	0	MII
SMIF	0-1	0-1	DATA, CLK, RWDS, SELECT0-1
PWM	0-1	0-1	LINE1_P/N, LINE2_P/N, MCK
TCPWM (32-bit)	0-31	0-31	PWM, PWM_N, TC_TR
TCPWM (16-bit) ^[4]	32-33, 36-37, 518-519, 522-541	32-37, 512-543	PWM, PWM_N, TC_TR

Note

4. Channels 522-524 pin functions shared on same pin.

Block diagram

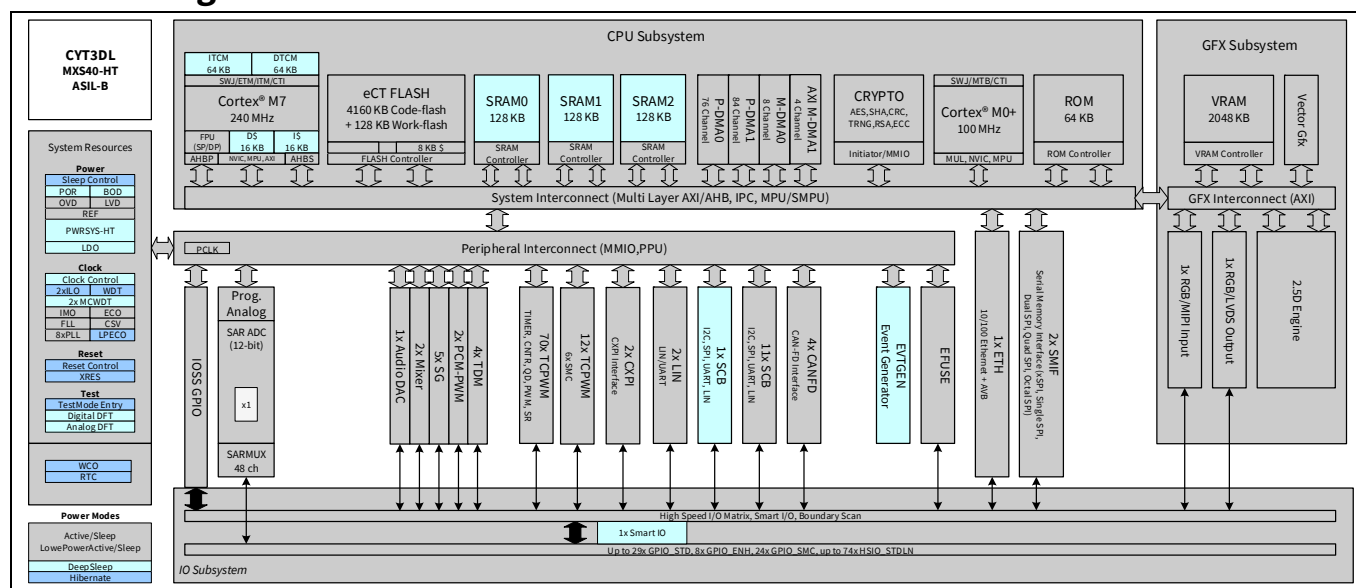


Figure 2-1 Architecture block diagram

CYT3DL provides extensive support for programming, testing, debugging, and tracing of both hardware and firmware.

Debug-on-chip functionality enables in-system debugging using the production device. It does not require special interfaces, debugging pods, simulators, or emulators.

The JTAG interface is fully compatible with industry-standard third-party probes such as I-jet, J-Link, and GHS.

The debug circuits are enabled by default.

CYT3DL provides a high level of security with robust flash protection and the ability to disable features such as debug.

Additionally, each device interface can be permanently disabled for applications concerned with phishing attacks due to a maliciously reprogrammed device or attempts to defeat security by starting and interrupting flash programming sequences. All programming, debug, and test interfaces are disabled when maximum device security is enabled.

- GPIO_STD supports 2.7 V to 5.5 V V_{DDIO_GPIO} range.
- GPIO_ENH supports 2.7 V to 5.5 V V_{DDIO_GPIO} range with higher currents at lower voltages.
- GPIO_SMC supports 2.7 V to 5.5 V V_{DDIO_SMC} range with currents higher than GPIO_ENH.
- HSIO_STDLN supports 3.0 V to 3.6 V V_{DDIO_HSIO} range with high-speed signaling and programmable drive strength.

3 Functional description

3.1 CPU subsystem

3.1.1 CPU

The CYT3DL CPU subsystem contains a 32-bit Arm® Cortex®-M0+ CPU with MPU, and a 32-bit Arm® Cortex®-M7 CPU, with MPU, single/double-precision FPU, and 16-KB data and instruction caches. This subsystem also includes P-/M-DMA controllers, a cryptographic accelerator, 4160 KB of code-flash, 128 KB of work-flash, 384 KB of SRAM, and 64 KB of ROM.

The Cortex®-M0+ CPU provides a secure, un-interruptible boot function. This guarantees that, following completion of the boot function, system integrity is valid and privileges are enforced. Shared resources (flash, SRAM, peripherals, and so on) can be accessed through bus arbitration, and exclusive accesses are supported by an inter-processor communication (IPC) mechanism using hardware semaphores.

Each Cortex®-M7 CPU has 64 KB of instruction and 64 KB of data TCM with programmable read wait states. Each TCM is clocked by the associated Cortex®-M7 CPU clock.

3.1.2 DMA controllers

CYT3DL has four DMA controllers: P-DMA0 with 32 general purpose and 44 dedicated channels, P-DMA1 with 16 general purpose and 68 dedicated channels, M-DMA0 with eight channels, and AXI M-DMA1 with four channels. P-DMA is used for peripheral-to-memory and memory-to-peripheral data transfers and provides low latency for a large number of channels. Each P-DMA controller uses a single data-transfer engine that is shared by the associated channels. General purpose channels have a rich interconnect matrix including P-DMA cross triggering which enables demanding data-transfer scenarios. Dedicated channels have a single triggering input (such as an ADC channel) to handle common transfer needs. M-DMA is used for memory-to-memory data transfers and provides high memory bandwidth for a small number of channels. M-DMA uses a dedicated data-transfer engine for each channel. They support independent accesses to peripherals using the AHB multi-layer bus. AXI M-DMA is used to provide access to AXI slaves like VRAM.

3.1.3 Flash

CYT3DL has 4160 KB (4032 KB with a 32-KB sector size, and 128 KB with an 8-KB sector size) of code-flash with an additional work-flash of 128 KB (96 KB with a 2-KB sector size, and 32 KB with a 128-B sector size). Work-flash is optimized for reprogramming many more times than code-flash. Code-flash supports Read-While-Write (RWW) operation so that flash may be updated while the CPU is active. Both the code-flash and work-flash areas support dual-bank operation for over-the-air (OTA) programming.

3.1.4 SRAM

CYT3DL has 384 KB of SRAM with two independent controllers. SRAM0 provides DeepSleep retention in 32-KB increments while SRAM1/2 is selectable between fully retained and not retained.

3.1.5 ROM

CYT3DL has 64 KB of ROM that contains boot and configuration routines. This ROM enables secure boot and authentication of user flash to guarantee a secure system.

3.1.6 Cryptography accelerator for security

The cryptography accelerator implements (3)DES block cipher, AES block cipher, SHA hash, cyclic redundancy check, pseudo random number generation, true random number generation, galois/counter mode, and a vector unit to support asymmetric key cryptography such as RSA and ECC.

Depending on the part number, this block is either completely or partially available or not available at all. See [“Ordering information”](#) on page 193 for more details.

3.2 System resources

3.2.1 Power system

The power system ensures that the supply voltage levels meet the requirements of each power mode, and provides a full-system reset when these levels are not valid. Internal power-on reset (POR) guarantees full-chip reset during the initial power ramp.

Three BOD circuits monitor the external supply voltages (V_{DD} , V_{DDA_ADC} , V_{CCD}). The BOD on V_{DD} and V_{CCD} is initially enabled and cannot be disabled. The BOD on V_{DDA_ADC} is initially disabled and can be enabled by the user. For the external supplies V_{DD} and V_{DDA_ADC} , BOD circuits are software-configurable with two settings; a 2.7-V minimum voltage that is robust for all internal signaling, and a 3.0-V minimum voltage, which is also robust for all I/O specifications (which are guaranteed at 2.7 V). The BOD on V_{CCD} is provided as a safety measure and is not a robust detector.

Three overvoltage detection (OVD) circuits are provided for monitoring external supplies (V_{DD} , V_{DDA_ADC} , V_{CCD}), and overcurrent detection circuits (OCD) for monitoring internal and external regulators. OVD thresholds on V_{DD} and V_{DDA_ADC} are configurable with two settings; a 5.0-V and 5.5-V maximum voltage.

Two voltage detection circuits are provided to monitor the external supply voltage (V_{DD}) for falling and rising levels, each configurable for one of the 26 selectable levels.

All BOD, OVD, and OCD circuits on V_{DD} and V_{CCD} generate a reset, because these protect the CPUs and fault logic. The BOD and OVD circuits on V_{DDA_ADC} can be configured to generate either a reset, or a fault.

3.2.2 Regulators

CYT3DL contains two regulators that provide power to the low-voltage core transistors: DeepSleep and core internal. These regulators accept a 2.7-V to 5.5-V V_{DD} supply and provide a low-noise 1.1-V supply to various parts of the device. These regulators are automatically enabled and disabled by hardware and firmware when switching between power modes. The core internal regulator operates in Active mode and provides power to the CPU subsystem and associated peripherals.

3.2.2.1 DeepSleep

The DeepSleep regulator is used to maintain power in a small number of blocks when in DeepSleep mode. These blocks include the ILO and WDT timers, BOD detector, SCB0, SRAM memories, Smart I/O, and other configuration memories. The DeepSleep regulator is enabled when in DeepSleep mode, and the core internal regulator is disabled. It is disabled when XRES_L is asserted (LOW) and when the core internal regulator is disabled.

3.2.2.2 Core internal

The core internal regulator supports load currents up to 300 mA, and is operational during device start-up (boot process), and in Active/Sleep modes. (Graphics subsystem is not supported)

3.2.3 PMIC control module

An internal PMIC module is available to control an external PMIC. The PMIC control module manages the handoff between the internal active regulator, used only for boot, and the external PMIC.

Both the core internal and external PMIC require an external bulk storage capacitor connected to the V_{CCD} pin. This capacitor provides charge under the dynamic loads of the low-voltage core transistors.

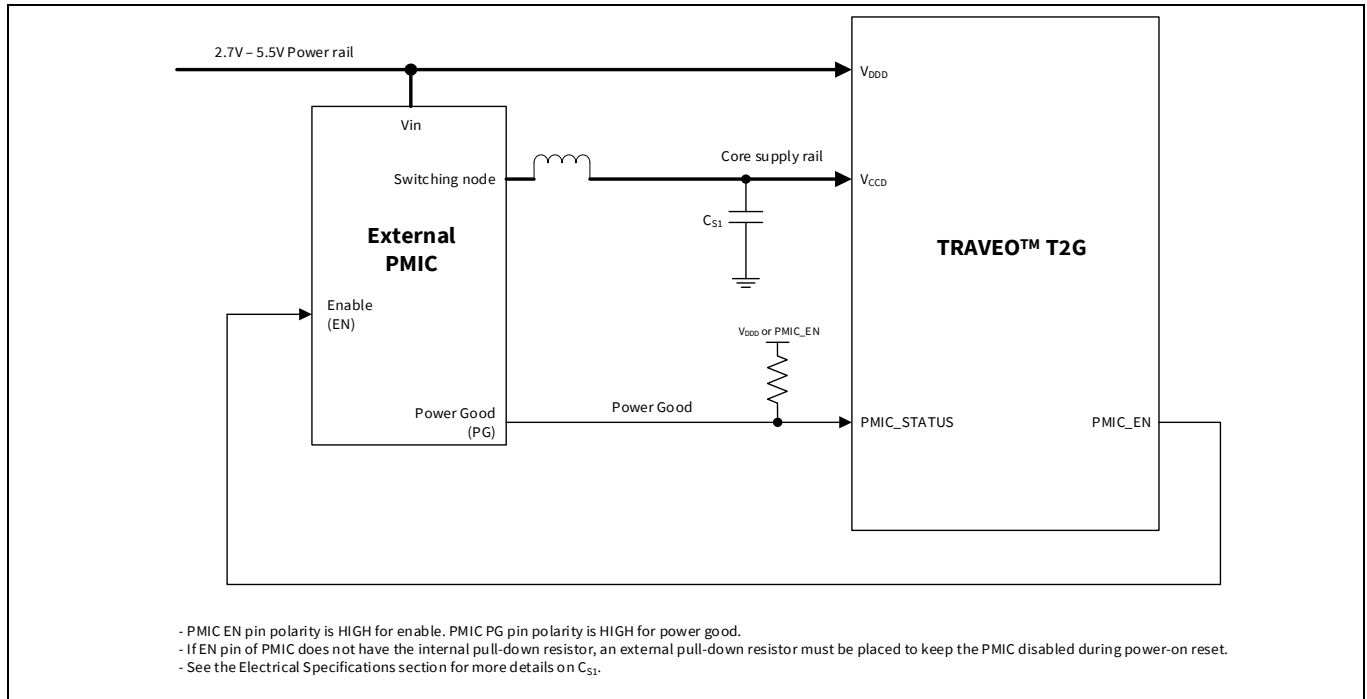


Figure 3-1 Sample PMIC control interface

3.2.4 Clock system

The CYT3DL clock system provides clocks to all subsystems that require them, and glitch-free switching between different clock sources. In addition, the clock system ensures that no metastable conditions occur.

The clock system for CYT3DL consists of the 8-MHz IMO, two ILOs, four watchdog timers, eight PLLs, an FLL, five clock supervisors (CSV), a 7.2- to 33.34-MHz ECO, a 3.99- to 8.01-MHz LPECO, and a 32.768-kHz WCO.

The clock system supports three main clock domains: CLK_HF, CLK_SLOW, and CLK_LF.

- CLK_HFx are the Active mode clocks. Each can use any of the high frequency clock sources including IMO, EXT_CLK, ECO, LPECO, FLL, or PLL
- CLK_SLOW provides a reference clock for the Cortex®-CM0+ CPU, Crypto, P-/M-DMA, and other slow infrastructure blocks of CPU subsystem
- CLK_LF is a DeepSleep domain clock and provides a reference clock for the MCWDT or RTC modules. The reference clock for the CLK_LF domain is either disabled or selectable from ILO0, ILO1, or WCO.

Table 3-1 CLK_HF destinations

Name	Description
CLK_HF0	CPUSS (Memories, CLK_SLOW, Peripherals)
CLK_HF1	CPUSS (Cortex®-M7 CPU)
CLK_HF2	CAN FD, CXPI, LIN, SCB, SAR
CLK_HF3	Event Generator, Clock output (CLK_EXT)

Table 3-1 CLK_HF destinations *(continued)*

Name	Description
CLK_HF4	Ethernet Internal Clock
CLK_HF5	Sound Subsystem #0 (TDM, SG, PWM, MIXER, DAC), Ethernet TSU
CLK_HF6	Sound Subsystem #1 (TDM, SG, PWM, MIXER)
CLK_HF7	Sound Subsystem #2 (TDM, SG, PWM)
CLK_HF8	SMIF #0
CLK_HF9	SMIF #1
CLK_HF10	Video Subsystem
CLK_HF11	Video Display #0
CLK_HF12	Video Display #1

3.2.4.1 IMO clock source

The IMO is the frequency reference in CYT3DL when no external reference is available or enabled. The IMO operates at a frequency of around 8 MHz.

3.2.4.2 ILO clock source

An ILO is a low-power oscillator, nominally 32.768 kHz, which generates clocks for a watchdog timer when in DeepSleep mode. There are two ILOs to ensure clock supervisor (CSV) capability in DeepSleep mode. ILO-driven counters can be calibrated to the IMO, WCO, or ECO to improve their accuracy. ILO1 is also used for clock supervision.

3.2.4.3 PLL and FLL

A PLL (three 200 MHz and five 400 MHz) or FLL may be used to generate high-speed clocks from the IMO, ECO, or an EXT_CLK. The FLL provides a much faster lock than the PLL (5 μ s instead of 35 μ s) in exchange for a small amount ($\pm 1\%$) of frequency error^[9] and a lower max output frequency (100 MHz instead of up to 400 MHz). The 400-MHz PLL supports spread spectrum clock generation (SSCG) with down spreading.

3.2.4.4 Clock supervisor

Each clock supervisor (CSV) allows one clock (reference) to supervise the behavior of another clock (monitored). Each CSV has counters for both the monitored and reference clocks. Parameters for each counter determine the frequency of the reference clock as well as the upper and lower frequency limits of the monitored clock. If the frequency range comparator detects a stopped clock or a clock outside the specified frequency range, an abnormal state is signaled and either a reset or an interrupt is generated.

3.2.4.5 EXT_CLK

One of three GPIO_STD I/Os can be used to provide an external clock input of up to 100 MHz. This clock can be used as the source clock for either the PLL or FLL, or can be used directly by the CLK_HF domain.

3.2.4.6 ECO

The ECO provides high-frequency clocking using an external crystal connected to the ECO_IN and ECO_OUT pins. It supports fundamental mode (non-overtone) quartz crystals, in the range of 7.2 to 33.34 MHz. When used in conjunction with the PLL, it generates CPU and peripheral clocks up to device's maximum frequency. ECO accuracy depends on the selected crystal. If the ECO is disabled, the associated pins can be used for any of the available I/O functions.

Note

9. Operation of reference-timed peripherals (such as a UART) with an FLL-based reference is not recommended due to the allowed frequency error.

3.2.4.7 LPECO

The LPECO provides high-frequency clocking using an external crystal connected to the LPECO_IN and LPECO_OUT pins. It supports fundamental mode (non-overtone) quartz crystals, in the range of 3.99 to 8.01 MHz. LPECO can operate during DeepSleep, and Hibernate modes with significant lower current consumptions. It can also be used for real-time-clock applications. When used in conjunction with the PLL, it generates CPU and peripheral clocks up to device's maximum frequency.

3.2.4.8 WCO

The WCO is a low-power, watch-crystal oscillator intended for real-time-clock applications. It requires an external 32.768-kHz crystal connected to the WCO_IN and WCO_OUT pins. The WCO can also be configured as a clock reference for CLK_LF, which is the clock source for the MCWDT and RTC.

3.2.5 Reset

CYT3DL can be reset from a variety of sources, including software. Most reset events are asynchronous and guarantee reversion to a known state. The reset cause (POR, BOD, OVD, overcurrent, XRES_L, WDT, MCWDT, software reset, fault, CSV, Hibernate wakeup, debug) is recorded in a register, which is sticky through reset and allows software to determine the cause of the reset. An XRES_L pin is available for external reset.

3.2.6 Watchdog timer

CYT3DL has one watchdog timer (WDT) and two multi-counter watchdog timers (MCWDT).

The WDT is a free-running counter clocked only by ILO0, which allows it to be used as a wakeup source from Hibernate. Watchdog operation is possible during all power modes. To prevent a device reset from a WDT timeout, the WDT must be serviced during a configured window. A watchdog reset is recorded in the reset cause register.

An MCWDT is available for each of the CPU cores. These timers provide more capabilities than the WDT, and are only available in Active, Sleep, and DeepSleep modes. These timers have multiple counters that can be used separately or cascaded to trigger interrupts and/or resets. They are clocked from ILO0 or the WCO.

3.2.7 Power modes

CYT3DL has six power modes that apply to the core functions, CM0+ core, and peripherals without power switches. Power modes for the CM7 cores and VIDEOSS are controlled separately.

- Active – all peripherals are available
- Low-Power Active (LPACTIVE) – Low-power profile of Active mode where all peripherals and the CPUs are available, but with limited capability
- Sleep – all peripherals except the CPUs are available
- Low-Power Sleep (LPSLEEP) – Low-power profile of Sleep mode where all peripherals except the CPUs are available, but with limited capability
- DeepSleep – only peripherals which work with CLK_LF are available
- Hibernate – the device and I/O states are frozen, the device resets on wakeup

3.3 Peripherals

3.3.1 Peripheral clock dividers

Integer and fractional clock dividers are provided for peripheral and timing purposes.

Table 3-2 Clock dividers - CPUSS Group (Number 0)

Divider type	Instances	Description
div_8	9	Integer divider, 8 bits
div_16	16	Integer divider, 16 bits
div_16_5	7	Fractional divider, 16.5 bits (16 integer bits, 5 fractional bits)
div_24_5	3	Fractional divider, 24.5 bits (24 integer bits, 5 fractional bits)

Table 3-3 Clock dividers - CPUSS Group (Number 1)

Divider type	Instances	Description
div_8	3	Integer divider, 8 bits
div_16	4	Integer divider, 16 bits
div_24_5	7	Fractional divider, 24.5 bits (24 integer bits, 5 fractional bits)

3.3.2 Peripheral protection unit

The peripheral protection unit (PPU) controls and monitors unauthorized access from all masters (CPU, P-/M-DMA, Crypto, and any enabled debug interface) to the peripherals. It allows or restricts data transfers on the bus infrastructure. The access rules are enforced based on specific properties of a transfer, such as an address range for the transfer and access attributes (such as read/write, user/privilege, and secure/non-secure).

3.3.3 12-bit SAR ADC

CYT3DL contains one 1-Msps SAR ADC. This ADC can be clocked at up to 26.67 MHz and provide a 12-bit result in 26 clock cycles.

The references for the SAR ADC comes from a dedicated pair of inputs: VREFH and VREFL^[10].

CYT3DL supports 32 logical ADC channels which can select one of 54 input sources. Sources include 48 external inputs from I/Os, and six internal connections for diagnostic and monitoring purposes.

The number of ADC channels (per ADC and package type) are listed in [Table 1-1](#).

SAR ADC has a sequencer, which autonomously cycles through the configured channels (sequencer scan) with zero-switching overhead (that is, the aggregate sampling bandwidth, when clocked at 26.67 MHz, is equal to 1 Msps whether it is for a single channel or distributed over several channels). The sequencer switching is controlled through a state machine or firmware. The sequencer prioritizes trigger requests, enables the appropriate analog channel, controls ADC sampling, initiates ADC data conversion, manages results, and initiates subsequent conversions for repetitive or group conversions without CPU intervention.

SAR ADC has two analog multiplexers used to connect the signals to be measured to the ADC. One is SARMUX0 which has 24 GPIO_STD inputs (ADC[0]_0 to ADC[0]_23), and six additional inputs to measure internal signals such as a band-gap reference, a temperature sensor, V_{CCD}, V_{DDA_ADC} power supplies and AMUXBUSA/B signals. The other multiplexer is SARMUX1 which has 24 GPIO_SMC inputs (ADC[1]_0 to ADC[1]_23).

CYT3DL has a temperature sensor. Software post processing is required to convert the temperature sensor reading into kelvin or Celsius values.

To accommodate signals with varying source impedances and frequencies, it is possible to have different sample times programmed for each channel. ADC also supports range comparison, which allows fast detection of out-of-range values without having to wait for a sequencer scan to complete and for the CPU firmware to evaluate the measurement for out-of-range values.

The ADC cannot be used in DeepSleep and Hibernate modes as these modes require a high-speed clock. The ADC input reference voltage (V_{REFH}) range is 2.7 V to V_{DDA_ADC}, and V_{REFL} is V_{SSA_ADC}.

Note

10.VREF_L prevents IR drops in the VSSIO and VSSA_ADC paths from impacting the measurements. VREF_L, when properly connected, reduces or removes the impact of IR drops in the VSSIO and VSSA_ADC paths from measurements.

3.3.4 Timer/Counter/PWM block (TCPWM)

The TCPWM block consists of 16-bit (50 channels) and 32-bit (32 channels) counters with user-programmable period.

Each TCPWM counter contains a capture register to record the count at the time of an event, a period register (used to either stop or auto-reload the counter when its count is equal to the period register), and compare registers to generate signals that are used as PWM duty-cycle outputs.

Each counter within the TCPWM block supports several functional modes such as timer, capture, quadrature, PWM, PWM with dead-time insertion (PWM_DT, 8-bit), pseudo-random PWM (PWM_PR), and shift-register.

The TCPWM block also provides true and complement outputs, with programmable offset between them, to allow their use as deadband complementary PWM outputs. The TCPWM block also has a kill input (only for the PWM mode) to force outputs to a predetermined state; for example, this may be used in motor-drive systems when an overcurrent state is detected and the PWMs driving the FETs need to be shut off immediately (no time for software intervention).

Twelve of the 16-bit counters are optimized for DC and stepper motor-control operations, these also have ZPD (Zero Point detection) and slew rate control capabilities. Two of these TCPWM channels constitute one SMC channel.

3.3.5 Serial Communication Blocks (SCB)

CYT3DL contains up to 12 serial communication blocks, each configurable to support I²C, UART, or SPI.

3.3.5.1 I²C interface

An SCB can be configured to implement a full I²C master (capable of multi-master arbitration) or slave interface. Each SCB configured for I²C can operate at speeds of up to 1 Mbps (Fast-mode Plus) and has flexible buffering options to reduce the interrupt overhead and latency of the CPU. In addition, each SCB supports FIFO buffering for receive and transmit data, which, by increasing the time for the CPU to read the data, reduces the need for clock stretching. The I²C interface is compatible with Standard, Fast-mode, and Fast-mode Plus devices as specified in the NXP I²C-bus specification and user manual (UM10204). The I²C-bus I/O is implemented with GPIO in open-drain modes^[11, 12].

3.3.5.2 UART interface

When configured as a UART, each SCB provides a full-featured UART with maximum signaling rate determined by the configured peripheral-clock frequency and over-sampling rate. It supports infrared interface (IrDA) and SmartCard (ISO 7816) protocols, which are minor variants of the UART protocol. It also supports the 9-bit multi-processor mode that allows the addressing of peripherals connected over common Rx and Tx lines. Common UART functions such as parity, number of stop bits, break detect, and frame error are supported. FIFO buffering of transmit and receive data allows greater CPU service latencies to be tolerated.

The LIN protocol is supported by the UART. LIN is based on a single-master multi-slave topology. There is one master node and multiple slave nodes on the LIN bus. The SCB UART supports only LIN slave functionality. Compared to the dedicated LIN blocks, an SCB/UART used for LIN requires a higher level of software interaction and increased CPU load.

Notes

11. This is not 100% compliant with the I²C-bus specification; I/Os are not overvoltage tolerant, do not support the 20-mA sink requirement of Fast-mode Plus, and violate the leakage specification when no power is applied.

12. See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

3.3.5.3 SPI interface

The SPI configuration supports full Motorola SPI, TI Synchronous Serial Protocol (SSP, essentially adds a start pulse that is used to synchronize SPI-based codecs), and National Microwire (a half-duplex form of SPI). The SPI interface can use the FIFO. The SPI interface operates with up to a 12.5-MHz SPI Clock. SCB also supports EZSPI^[13] mode.

SCB0 supports the following additional features:

- Operable as a slave in DeepSleep mode
- I²C slave EZ (EZI2C^[14]) mode with up to 256-B data buffer for multi-byte communication without CPU intervention
- I²C slave externally-clocked operations
- Command/response mode with a 512-B data buffer for multi-byte communication without CPU intervention

3.3.6 Controller area network flexible data-rate (CAN FD)

CYT3DL supports two CAN FD controller blocks, each supporting two CAN FD channel. All CAN FD controllers are compliant with the ISO 11898-1:2015 standard; an ISO 16845:2015 certificate is available. It also implements the time-triggered CAN (TTCAN) protocol specified in ISO 11898-4 (TTCAN protocol levels 1 and 2) completely in hardware. All functions concerning the handling of messages are implemented by the Rx and Tx handlers. The Rx handler manages message acceptance filtering, transfer of received messages from the CAN core to a message RAM, and provides receive-message status. The Tx handler is responsible for the transfer of transmit messages from the message RAM to the CAN core, and provides transmit-message status.

3.3.7 Local interconnect network (LIN)

CYT3DL contains up to two LIN channels. Each channel supports transmission/reception of data following the LIN protocol according to ISO standard 17987. Each LIN channel connects to an external transceiver through a 3-pin interface (including an enable function) and supports master and slave functionality. Each block also supports classic and enhanced checksum, along with break detection during message reception and wake-up signaling. Break detection, sync field, checksum calculations, and error interrupts are handled in hardware.

3.3.8 Clock extension peripheral interface (CXPI)

CYT3DL contains up to four CXPI channels compliant with JASO D015 and ISO standard 20794 including the controller specification.

Each channel supports:

- Master and slave functionality
- Polling and event trigger method for both normal and long frames
- Non-return to zero (NRZ) and PWM signaling modes
- Collision resolution and carries sense multiple access
- Wakeup pulse generation and detection
- CRC8 and CRC16 for both normal and long frames
- Error detection
- Dedicated FIFO (16 B) for transmit and receive

3.3.9 Ethernet MAC

CYT3DL supports one Ethernet channel with transfer rates of 10, or 100 Mbps. It is compatible with IEEE 802.3 standard. It supports IEEE 802AS and 1588 precision clock synchronization protocol. It supports MII and RMII PHY interfaces. It supports full-duplex data transport using external PHY devices. It supports half-duplex data transport in RMII mode only using external PHY devices. The device also supports Audio-Video Bridging (AVB). The MAC supports standard 6-byte programmable addresses. Module uses AXI interface for DMA access.

Notes

13. The Easy SPI (EZSPI) protocol is based on the Motorola SPI protocol operating in any mode (0, 1, 2, or 3). It allows communication between master and slave while reducing the need for CPU intervention.

14. The Easy I²C (EZI2C) protocol is a unique communication scheme built on top of the I²C protocol by Infineon. It uses a meta protocol around the standard I²C protocol to communicate to an I²C slave using indexed memory transfers. This reduces the need for CPU intervention.

3.3.10 Serial memory interface (SMIF)

In addition to the internal flash memory, CYT3DL supports direct connection to two units of 512 MB of external flash or RAM memory. This connection is made through either a xSPI or serial peripheral interface (SPI). xSPI allows connection to HyperFlash and HyperRAM devices, while SPI (single, dual, quad, or octal SPI) can connect with serial flash memory. Code stored in memory connected through this interface allows execute-in-place (XIP) operation, which does not require the instructions to be first copied to internal memory, and on-the-fly encryption and decryption for environments requiring secure external data and code.

3.3.11 Sound subsystem

CYT3DL supports the following,

- Up to four time-division multiplexing (TDM) interfaces
 - Full-duplex transmitter and receiver operation
 - Independent transmitter or receiver operation, each in master or slave mode
 - Up to 32 channels, each channel can be individually enabled or disabled
- Up to two pulse code modulation-pulse width modulation (PCM-PWM) interface
 - Conversion of PCM audio streaming to PWM signals
 - Up to 32-bit output sample resolution
 - Supports E- and H-bridge formats
 - Dead time insertion
- Up to five sound generator (SG) interfaces
 - PWM modulated (amplitude, tone) sound generation
 - Separate volume and frequency control (two signals) and combined volume-frequency control (one signal) formats
- Up to five mixers
 - Combines multiple PCM source streams into a single PCM destination stream
 - PCM source stream can be gain/volume controlled
 - Fixed PCM sample formatting (16-bit pairs)
 - LPF support by FIR filter
 - Fade-in and Fade-out control for both source and destination PCM streams
- One audio digital-to-analog converter (DAC)
 - Programmable sampling rate and frequency control
 - Supports stereo (Left and Right)
 - Supports CIC filter, FIR filter, Interpolation filter, and Delta-Sigma modulator
 - Multi-level DAC

3.3.12 One-time-programmable (OTP) eFuse

CYT3DL contains a 1024-bit OTP eFuse memory that can be used to store and access a unique and unalterable identifier or serial number for each device. eFuses are also used to control the device life-cycle (manufacturing, programming, normal operation, end-of-life, and so on) and the security state. Of the 1024 bits, 192 are available for user purposes.

3.3.13 Event generator

The event generator supports generation of interrupts and triggers in Active mode and interrupts in DeepSleep mode. The event generators are used to trigger a specific device operation (execution of an interrupt handler, a SARADC conversion, and so on) and to provide a cyclic wakeup mechanism from DeepSleep mode. They provide CPU-free triggers for device functions, and reduce CPU involvement in triggering device functions, thus reducing overall power consumption and processing overhead.

3.3.14 Trigger multiplexer

CYT3DL supports connecting various peripherals using trigger signals. Triggers are used to inform a peripheral of the occurrence of an event or change of state. These triggers are used to affect or initiate some action in other peripherals. The trigger multiplexer is used to route triggers from a source peripheral to a destination. Triggers provide active logic functionality and are typically supported in Active mode.

3.4 Graphics

CYT3DL supports one instance of the graphics subsystem which includes 2048 KB of embedded Video RAM, a 2D graphics core and interfaces for video input and output processing.

CYT3DL supports 4-lane MIPI CSI-2 interface for up to HD (1920 × 720) resolution video inputs and single channel FPD-link interface for up to HD (1920 × 720) resolution video output. The 2D graphics core supports a BLock Image Transfer (BLIT) engine for faster graphics rendering to memory or on-the-fly to display, a drawing engine for acceleration of vector graphics rendering and a command sequencer for setup and control of the rendering process. The video I/O supports a composition engine for scene composition from display layers, a display engine for video timing generation, and display functions and a capture engine for video input processing. The device also supports perspective correction for 3D effects ("2.5D"). One layer, such as head-up displays, can be warped on-the-fly.

3.5 I/Os

CYT3DL has up to 135 programmable I/Os.

The I/Os are organized as logical entities called ports, which are a maximum of 8 bits wide. During power-on and reset, the I/Os are forced to the High-Z state. During the Hibernate mode, the I/Os are frozen.

Every I/O can generate an interrupt (if enabled) and each port has an interrupt request (IRQ) and interrupt service routine (ISR) associated with it.

I/O port power source mapping is listed in [Table 3-4](#). The associated supply determines the V_{OH} , V_{OL} , V_{IH} , and V_{IL} levels when configured for CMOS and Automotive thresholds.

Table 3-4 I/O port power source

Supply pins	Ports
VDDD ^[15]	P0
VDDIO_GPIO_1 ^[15]	P1, P2, P3
VDDIO_GPIO_2 ^[15]	P4, P5, P6
VDDIO_SMC ^[15]	P7, P8, P9
VDDIO_HSIO	P11, P12, P13, P14, P15, P16, P17, P18, P19, P20, P21

All I/Os support the following programmable drive modes:

- High impedance
- Resistive pull-up
- Resistive pull-down
- Open drain with strong pull-down
- Open drain with strong pull-up
- Strong pull-up or pull-down
- Weak pull-up or pull-down

CYT3DL has four types of programmable GPIOs: GPIO Standard, GPIO Enhanced, GPIO SMC, and HSIO Standard with Low noise. Only GPIO_STD, GPIO_ENH, and GPIO_SMC have the capability to wakeup the device from DeepSleep mode. All these I/Os have GPIO input/output functionality, some of these might need special configuration^[16].

Notes

15. Ensure that $V_{DDD} \geq (V_{DDIO_GPIO_1} - 0.3\text{ V}) \geq (V_{DDIO_GPIO_2} - 0.3\text{ V})$.

16. Refer to the family-specific Architecture TRM for more information on the I/O configurations (002-25800, TRAVEO™ T2G Automotive MCU cluster 2D architecture technical reference manual).

3.5.1 GPIO

Three types of GPIOs are supported:

- GPIO_STD, GPIO_ENH, and GPIO_SMC

These implement the following:

- Configurable input threshold (CMOS, TTL, or Automotive)
- Hold mode for latching previous state (used for retaining the I/O state in DeepSleep mode)
- Analog input mode (input and output buffers disabled)
- Edge-triggered interrupts on rising edge, falling edge, or on both the edges, on pin basis

3.5.1.1 GPIO Standard (GPIO_STD)

This GPIO supports standard automotive signaling across the 2.7-V to 5.5-V V_{DDIO} range. GPIO_STD I/Os have multiple configurable drive levels, drive modes, and selectable input levels.

3.5.1.2 GPIO Enhanced (GPIO_ENH)

This GPIO supports extended functionality automotive signaling across the 2.7-V to 5.5-V V_{DDIO} range with higher currents at lower voltages (full I2C timing support, slew-rate control).

3.5.1.3 GPIO SMC (GPIO_SMC)

This GPIO provides significant drive strength than GPIO_STD and GPIO_ENH (Supports 30-mA drive).

3.5.2 HSIO

These I/Os are optimized exclusively for high-speed signaling and do not support slew-rate control, DeepSleep operation, POR mode control, analog connections, or non-CMOS signaling levels. HSIO support programmable drive strength. They are available only in Active mode.

3.5.2.1 HSIO standard low noise (HSIO_STDLN)

This I/O supports clocking and signaling up to 133 MHz for BGA packages and 100 MHz for TEQFP packages. Supports high-speed peripherals such as Graphics input/output, and Ethernet. Also supports holding state during DeepSleep mode. Low noise version optimizes the noise generated by having specific modes for each interface support.

3.5.3 Port nomenclature

Px.y describes a particular bit “y” available within an I/O port “x.”

For example, P4.2 reads “port 4, bit 2”.

3.5.4 Smart I/O

Smart I/O allows Boolean operations on signals going to the I/O from the subsystems of the chip or on signals coming into the chip. CYT3DL has one Smart I/O block. Operation can be synchronous or asynchronous and the blocks operate in all device power modes except for the Hibernate mode.

4 CYT3DL address map

The CYT3DL microcontroller supports the memory spaces shown in [Figure 4-1](#).

- 4160 KB (4032 KB + 128 KB) of code-flash, used in the single- or dual-bank mode based on the associated bit in the flash control register
 - Single-bank mode: 4160 KB
 - Dual-bank mode: 2080 KB per bank
- 128 KB (92 KB + 32 KB) of work-flash, used in the single- or dual-bank mode based on the associated bit in the flash control register
 - Single-bank mode: 128 KB
 - Dual-bank mode: 64 KB per bank
- 64 KB of secure ROM
- 384 KB of SRAM (First 2 KB is reserved for internal usage)
- 64 KB of Instruction TCM for each Cortex®-M7 CPU
- 64 KB of Data TCM for each Cortex®-M7 CPU
- 512 MB SMIF XIP1
- 512 MB SMIF XIP2
- 2048 KB of VRAM

CYT3DL address map

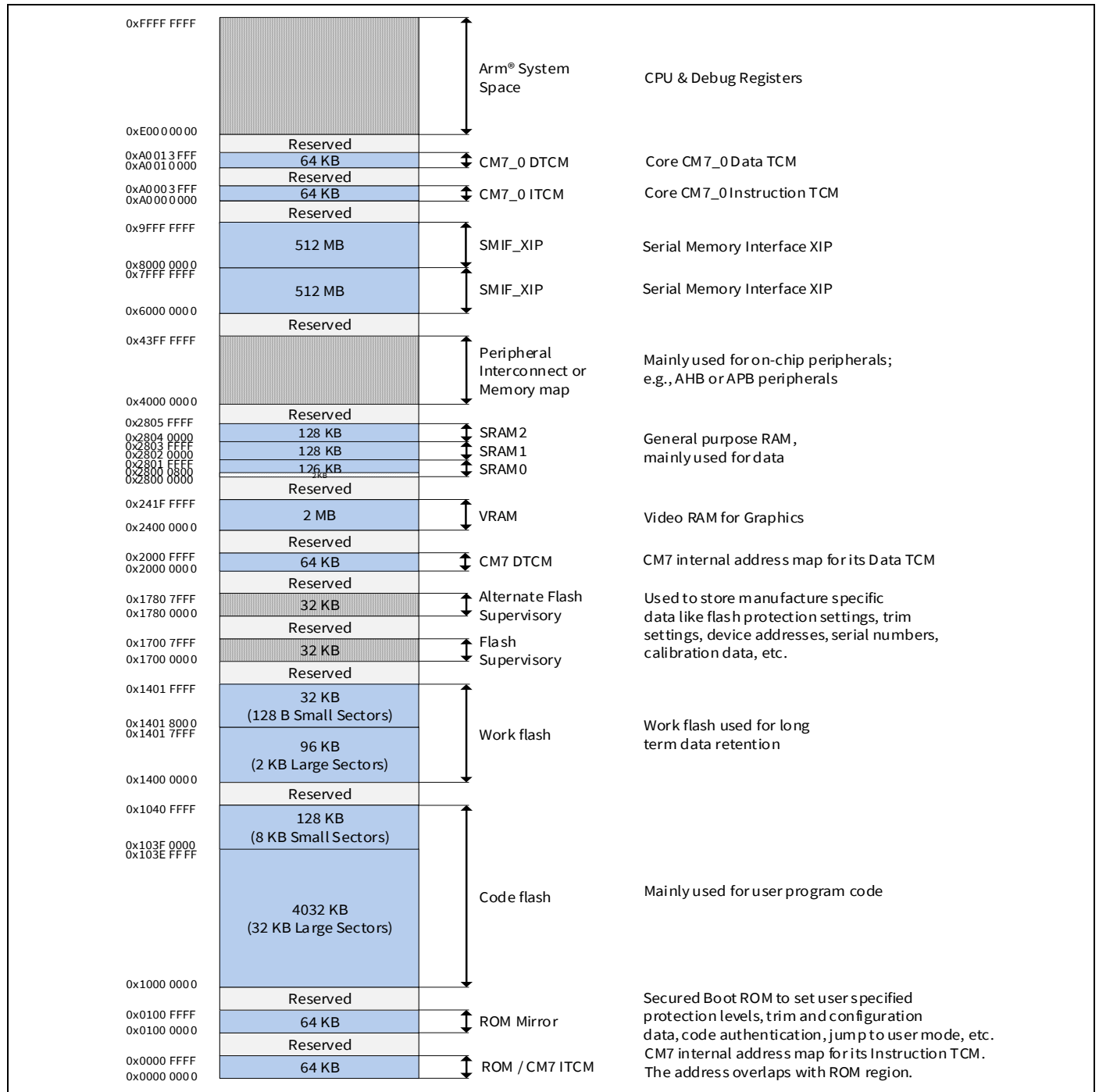


Figure 4-1 CYT3DL address map^[17, 18]

Notes

17. The size representation is not up to scale.

18. First 2KB of SRAM is reserved, not available for users. User must keep the power of first 32KB block of SRAM0 in enabled or retained in all Active, LP Active, Sleep, LP Sleep, DeepSleep modes.

5 Flash base address map

Table 5-1 through **Table 5-6** give information about the sector mapping of the code- and work-flash regions along with their respective base addresses.

Table 5-1 Code-flash address mapping in single bank mode

Code-flash Size (KB)	Large Sectors (LS)	Small Sectors (SS)	Large Sector Base Address	Small Sector Base Address
4160	32 KB × 126	8 KB × 16	0x1000 0000	0x103F 0000

Table 5-2 Work-flash Address Mapping in Single Bank Mode

Work-flash Size (KB)	Large Sectors	Small Sectors	Large Sector Base Address	Small Sector Base Address
128	2 KB × 48	128 B × 256	0x1400 0000	0x1401 8000

Table 5-3 Code-flash Address Mapping in Dual Bank Mode (Mapping A)

Code-flash Size (KB)	First Half LS	First Half SS	Second Half LS	Second Half SS	First Half LS Base Address	First Half SS Base Address	Second Half LS Base Address	Second Half SS Base Address
4160	32 KB × 63	8 KB × 8	32 KB × 63	8 KB × 8	0x1000 0000	0x101F 8000	0x1200 0000	0x121F 8000

Table 5-4 Code-flash Address Mapping in Dual Bank Mode (Mapping B)

Code-flash Size (KB)	First Half LS	First Half SS	Second Half LS	Second Half SS	First Half LS Base Address	First Half SS Base Address	Second Half LS Base Address	Second Half SS Base Address
4160	32 KB × 63	8 KB × 8	32 KB × 63	8 KB × 8	0x1200 0000	0x121F 8000	0x1000 0000	0x101F 8000

Table 5-5 Work-flash Address Mapping in Dual Bank Mode (Mapping A)

Work-flash Size (KB)	First Half LS	First Half SS	Second Half LS	Second Half SS	First Half LS Base Address	First Half SS Base Address	Second Half LS Base Address	Second Half SS Base Address
128	2 KB × 24	128 B × 128	2 KB × 24	128 B × 128	0x1400 0000	0x1400 C000	0x1500 0000	0x1500 C000

Table 5-6 Work-flash Address Mapping in Dual Bank Mode (Mapping B)

Work-flash Size (KB)	First Half LS	First Half SS	Second Half LS	Second Half SS	First Half LS Base Address	First Half SS Base Address	Second Half LS Base Address	Second Half SS Base Address
128	2 KB × 24	128 B × 128	2 KB × 24	128 B × 128	0x1500 0000	0x1500 C000	0x1400 0000	0x1401 8000

6 Peripheral I/O map

Table 6-1 CYT3DL peripheral I/O map

Section	Description	Base address	Instances	Instance size	Group	Slave
PERI	Peripheral interconnect	0x4000 0000			0	0
	Peripheral group (0, 1, 2, 3, 4, 5, 6, 8, 9, 10)	0x4000 4000	10	0x40		
	Peripheral trigger group	0x4000 8000	13	0x400		
	Peripheral 1:1 trigger group	0x4000 C000	8	0x400		
PERI_MS	Peripheral interconnect, master interface	0x4002 0000			0	1
	PERI Programmable PPU	0x4002 0000	10 ^[19]	0x40		
	PERI Fixed PPU	0x4002 0800	582	0x40		
PERI_PCLK	Peripheral Clock Groups	0x4004 0000	2	0x2000	0	2
Crypto	Cryptography component	0x4010 0000			1	0
CPUSS	CPU subsystem (CPUSS)	0x4020 0000			2	0
FAULT	Fault structure subsystem	0x4021 0000			2	1
	Fault structures	0x4021 0000	4	0x100		
IPC	Inter process communication	0x4022 0000			2	2
	IPC structures	0x4022 0000	8	0x20		
	IPC interrupt structures	0x4022 1000	8	0x20		
PROT	Protection	0x4023 0000			2	3
	Shared memory protection unit structures	0x4023 2000	16	0x40		
	Memory protection unit structures	0x4023 4000	16	0x400		
FLASHC	Flash controller	0x4024 0000			2	4
SRSS	System Resources Subsystem Core Registers	0x4026 0000			2	5
	Clock Supervision High Frequency	0x4026 1400	14	0x10		
	Clock Supervision Reference Frequency	0x4026 1710	1			
	Clock Supervision Low Frequency	0x4026 1720	1			
	Clock Supervision Internal Low Frequency	0x4026 1730	1			
	Clock PLL 400 MHz	0x4026 1900	5	0x10		
	Multi Counter WDT	0x4026 8000	2	0x100		
	Free Running WDT	0x4026 C000	1			
BACKUP	SRSS Backup Domain/RTC	0x4027 0000			2	6
	Backup Register	0x4027 1000	4	0x04		
P-DMA	P-DMA 0 Controller	0x4028 0000			2	7
	P-DMA 0 channel structures	0x4028 8000	76	0x40		
	P-DMA 1 Controller	0x4029 0000			2	8
	P-DMA 1 channel structures	0x4029 8000	84	0x40		

Note

19. These programmable PPUs are configured by the Boot ROM and are available for the user based on the access rights. Refer to the device-specific TRM to know more about the configuration of these programmable PPUs.

Table 6-1 **CYT3DL peripheral I/O map** *(continued)*

Section	Description	Base address	Instances	Instance size	Group	Slave
M-DMA	M-DMA0 Controller (AHB Bus)	0x402A 0000			2	9
	M-DMA0 channels	0x402A 1000	8	0x100		
	M-DMA1 Controller (AXI Bus)	0x402B 0000			2	10
	M-DMA1 channels	0x402B 1000	8	0x100		
eFUSE	eFUSE Customer Data (192 bits)	0x402C 0868	6	0x04	2	11
HSIOM	High-Speed I/O Matrix (HSIOM)	0x4030 0000	21	0x10	3	0
GPIO	GPIO port control/configuration	0x4031 0000	21	0x80	3	1
SMARTIO	Programmable I/O configuration	0x4032 0000			3	2
	SMARTIO port configuration	0x4032 0C00	1	0x100		
TCPWM	Timer/Counter/PWM 0 (TCPWM0)	0x4038 0000			3	3
	TCPWM0 Group #0 (16-bit)	0x4038 0000	38	0x80		
	TCPWM0 Group #1 (16-bit, Motor control)	0x4038 8000	12	0x80		
	TCPWM0 Group #2 (32-bit)	0x4039 0000	32	0x80		
EVTGEN	Event generator 0 (EVTGEN0)	0x403F 0000			3	4
	Event generator 0 comparator structures	0x403F 0800	16	0x20		
SMIF	Serial Memory Interface 0 (SMIF0)	0x4042 0000			4	0
	SMIF0 Devices	0x4042 0800	2	0x80		
	Serial Memory Interface 1 (SMIF1)	0x4043 0000			4	1
	SMIF1 Devices	0x4043 0800	2	0x80		
ETH	Ethernet 0 (ETH0)	0x4048 0000	1		4	2
LIN	Local Interconnect Network 0 (LIN0)	0x4050 0000			5	0
	LIN0 Channels	0x4050 8000	2	0x100		
CXPI	Clock Extension Peripheral Interface 0 (CXPI0)	0x4051 0000			5	1
	CXPI0 Channels	0x4051 8000	2	0x100		
CAN	CAN0 controller	0x4052 0000	2	0x200	5	2
	Message RAM CAN0	0x4053 0000		0x4000		
	CAN1 controller	0x4054 0000	2	0x200	5	3
	Message RAM CAN1	0x4055 0000		0x4000		
SCB	Serial Communications Block (SPI/UART/I ² C)	0x4060 0000	12	0x10000	6	0-11

Table 6-1 **CYT3DL peripheral I/O map** *(continued)*

Section	Description	Base address	Instances	Instance size	Group	Slave
Sound	Time Division Multiplexer 0 (TDM0)	0x4081 0000			8	0
	TDM0 Structures	0x4081 8000	2	0x200		
	Sound Generator 0 (SG0)	0x4082 0000			8	1
	SG0 Structures	0x4082 8000	5	0x100		
	Pulse Width Modulation 0 (PWM0)	0x4083 0000			8	2
	PWM0 Structures	0x4083 8000	2	0x100		
	Audio DAC0	0x4084 0000	1		8	3
	Mixer0	0x4088 0000			8	4
	Mixer0 Source Structures	0x4088 8000	5	0x100		
	Mixer0 Destination Structures	0x4088 C000	1			
	Mixer1	0x4089 0000			8	5
	Mixer1 Source Structures	0x4089 8000	5	0x100		
	Mixer1 Destination Structures	0x4089 C000	1			
SAR PASS	Programmable Analog Subsystem (PASS0)	0x4090 0000			9	0
	SAR0 channel controller	0x4090 0000				
	SAR0 channel structures	0x4090 0800	24 ^[20]	0x40		
	SAR1 channel structures	0x4090 1800	24	0x40		
Graphics	Video Subsystem (VIDEOSS0)	0x40A0 0000			10	0
	Display Engine	0x40AA 0000	2	0x4000		
	FPD-Link	0x40AC 0000	2	0x8000		
	MIPI CSIO	0x40AD 0000	1			

Note

20.Remaining 24 external channels are accessed from SAR1 Multiplexer. (SAR0 uses SARMUX1).

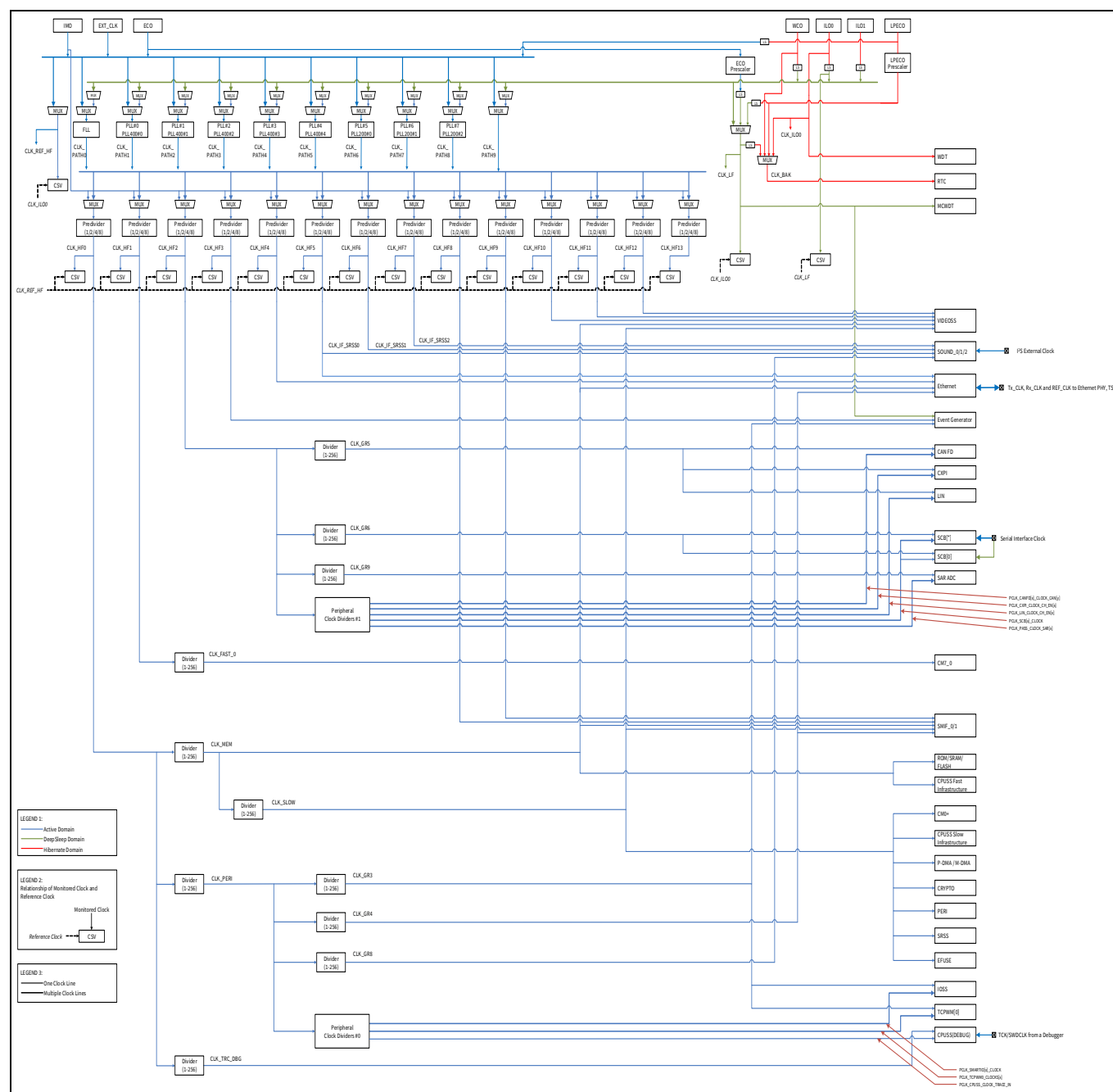


Figure 7-1 **CYT3DL clock diagram**

8 CYT3DL CPU start-up sequence

The start-up sequence is described in the following steps:

1. System Reset (@0x0000 0000)
2. CM0+ executes ROM boot (@0x0000 0004)
 - i. Applies trims
 - ii. Applies Debug Access port (DAP) access restrictions and system protection from eFuse and supervisory flash
 - iii. Authenticates flash boot (only in SECURE life-cycle stage) and transfers control to it
3. CM0+ executes flash boot (from Supervisory flash @0x1700 2000)
 - i. Debug pins are configured as per the SWD/JTAG spec^[21]
 - ii. Sets CM0+ vector offset register (CM0_VTOR part of the Arm® system space) to the beginning of flash (@0x1000 0000)
 - iii. CM0+ branches to its Reset handler
4. CM0+ starts execution
 - i. Moves CM0+ vector table to SRAM (updates CM0+ vector table base)
 - ii. Sets up wait states for different memory subsystems
 - iii. Sets up root clocks, enable core external supply (PMIC), graphics subsystem etc.
 - iv. Sets clocks for CM7_0 (CLK_HF1)
 - v. Sets CM7_0 (CM7_0_VECTOR_TABLE_BASE @0x4020 0200) vector tables to the respective locations, also and mentioned in flash (specified in the linker definition file)
 - vi. Enables the power for the CPU core CM7_0
 - vii. Disables CPU_WAIT so as to be able to be accessed by the debugger
 - viii. Releases CM7_0 from reset
 - ix. Continues execution of CM0+ user application
5. CM7_0 executes directly from either code-flash or SRAM
 - i. CM7_0 branches to its Reset handler
 - ii. Continues execution of the user application

Note

21. Port configuration of SWD/JTAG pins will be changed from the default GPIO mode to support debugging after the boot process, refer to [Table 11-1](#) for pin assignments.

9 Pin assignment

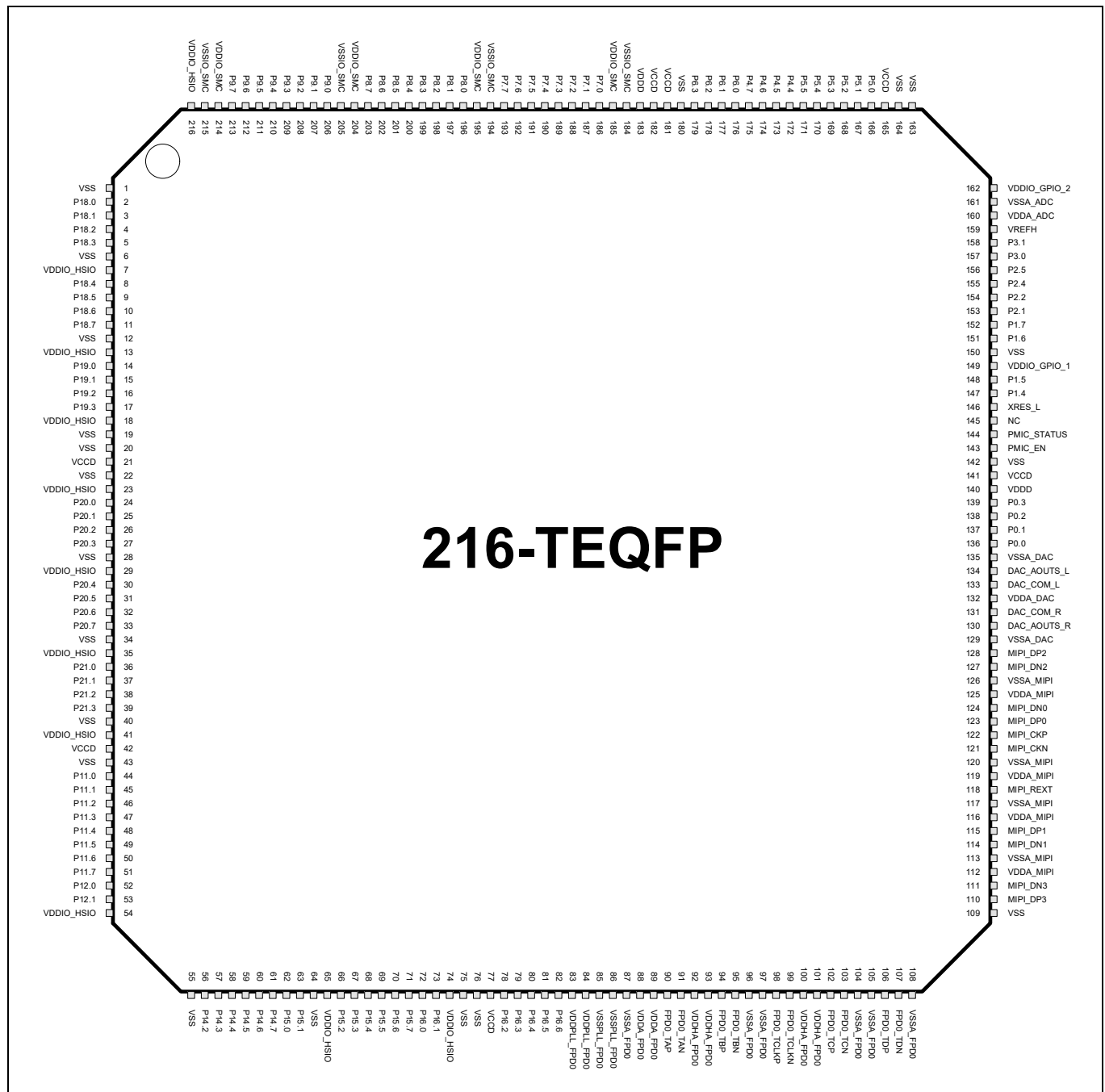


Figure 9-1 216-TEQFP pin assignment^[22]

Note

22.Connect exposure pad of TEQFP devices to the ground.

TRAVEO™ T2G 32-bit Automotive MCU

Based on Arm® Cortex®-M7 single



Pin assignment

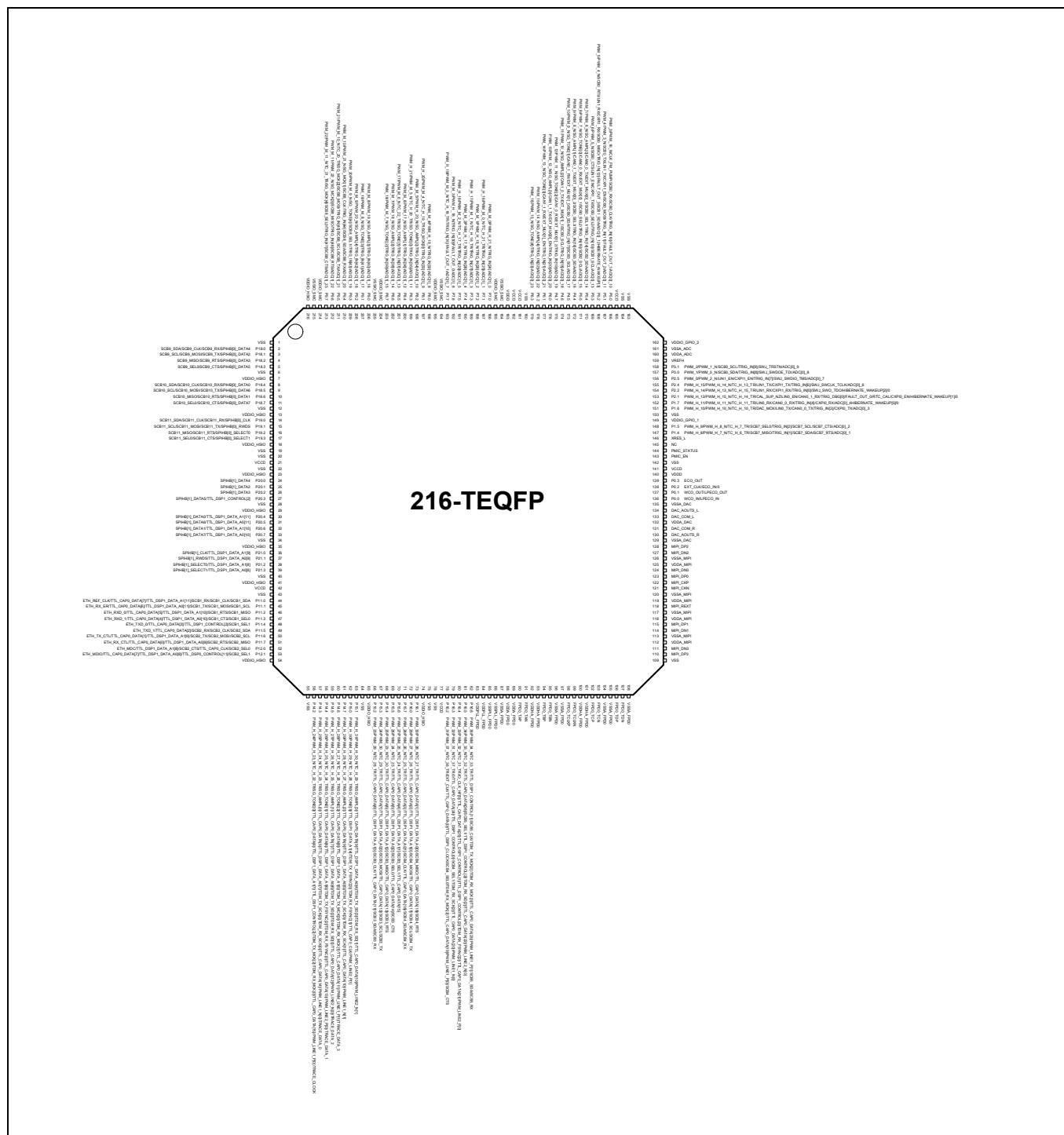


Figure 9-2 216-TEQFP pin assignment with alternate functions^[2]

10 High-speed I/O matrix connections

Table 10-1 HSIOM connections reference

Name	Number	Description
HSIOM_SEL_GPIO	0	GPIO controls 'out'
HSIOM_SEL_GPIO_DSI	1	Reserved
HSIOM_SEL_DSI_DSI	2	
HSIOM_SEL_DSI_GPIO	3	
HSIOM_SEL_AMUXA	4	
HSIOM_SEL_AMUXB	5	
HSIOM_SEL_AMUXA_DSI	6	
HSIOM_SEL_AMUXB_DSI	7	
HSIOM_SEL_ACT_0	8	Active functionality 0
HSIOM_SEL_ACT_1	9	Active functionality 1
HSIOM_SEL_ACT_2	10	Active functionality 2
HSIOM_SEL_ACT_3	11	Active functionality 3
HSIOM_SEL_DS_0	12	DeepSleep functionality 0
HSIOM_SEL_DS_1	13	DeepSleep functionality 1
HSIOM_SEL_DS_2	14	DeepSleep functionality 2
HSIOM_SEL_DS_3	15	DeepSleep functionality 3
HSIOM_SEL_ACT_4	16	Active functionality 4
HSIOM_SEL_ACT_5	17	Active functionality 5
HSIOM_SEL_ACT_6	18	Active functionality 6
HSIOM_SEL_ACT_7	19	Active functionality 7
HSIOM_SEL_ACT_8	20	Active functionality 8
HSIOM_SEL_ACT_9	21	Active functionality 9
HSIOM_SEL_ACT_10	22	Active functionality 10
HSIOM_SEL_ACT_11	23	Active functionality 11
HSIOM_SEL_ACT_12	24	Active functionality 12
HSIOM_SEL_ACT_13	25	Active functionality 13
HSIOM_SEL_ACT_14	26	Active functionality 14
HSIOM_SEL_ACT_15	27	Active functionality 15
HSIOM_SEL_DS_4	28	DeepSleep functionality 4
HSIOM_SEL_DS_5	29	DeepSleep functionality 5
HSIOM_SEL_DS_6	30	DeepSleep functionality 6
HSIOM_SEL_DS_7	31	DeepSleep functionality 7

11 Package pin list and alternate functions

Most pins have alternate functionality, as specified in [Table 11-1](#).

Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O

Name	Package		I/O Type	DeepSleep Mapping		+B input ^[29]	Analog/HV	SMARTIO
	272-BGA	216-TEQFP	HCon#0	HCon#29 ^[23]	HCon#30			
	Pin	Pin		DS #5 ^[24, 25]	DS #6			
P0.0	J18	136	GPIO_STD			Not supported	WCO_IN, LPECO_IN ^[26]	
P0.1	J17	137	GPIO_STD				WCO_OUT, LPECO_OUT ^[26]	
P0.2	G18	138	GPIO_STD				ECO_IN ^[26]	
P0.3	G17	139	GPIO_STD				ECO_OUT ^[26]	
P1.0	F15	NA	GPIO_STD			Supported		
P1.1	E15	NA	GPIO_STD					
P1.2	D18	NA	GPIO_STD					
P1.3	C18	NA	GPIO_STD				ADC[0]_0	
P1.4	B18	147	GPIO_STD			Not supported	ADC[0]_1	
P1.5	D17	148	GPIO_STD				ADC[0]_2	
P1.6	C17	151	GPIO_STD				ADC[0]_3	
P1.7	D16	152	GPIO_STD				ADC[0]_4, HIBERNATE_WAKEUP[0]	
P2.0	D15	NA	GPIO_STD			Supported	ADC[0]_5	
P2.1 ^[27]	C16	153	GPIO_STD	RTC_CAL			HIBERNATE_WAKEUP[1]	
P2.2	A17	154	GPIO_STD	SWJ_SWO_TDO		Supported	HIBERNATE_WAKEUP[2]	
P2.4	B16	155	GPIO_STD	SWJ_SWCLK_TCLK			ADC[0]_6	
P2.5	A16	156	GPIO_STD	SWJ_SWDIO_TMS			ADC[0]_7	
P3.0	C15	157	GPIO_ENH	SWJ_SWDOE_TDI	SCB0_SDA		ADC[0]_8	
P3.1	B15	158	GPIO_ENH	SWJ_TRSTN	SCB0_SCL	Supported	ADC[0]_9	
P4.0	A15	NA	GPIO_STD					
P4.1	D14	NA	GPIO_STD					
P4.2	C14	NA	GPIO_STD					

Notes

23.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).

24.DeepSleep ordering (DS#0, DS#1, DS#2) does not have any impact on choosing any alternate functions; the HSIOM module handles the individual alternate function assignment.

25.All port pin functions available in DeepSleep mode are also available in Active mode.

26.I/O pins that support an oscillator function (WCO or ECO) must be configured for high-impedance if the oscillator is enabled.

27.This I/O will have increased leakage to ground when V_{DD} is below the POR threshold.

28.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

29.See [Absolute maximum ratings](#) for +B condition and clamping current specification.

Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O (continued)

Name	Package		I/O Type	DeepSleep Mapping		+B input ^[29]	Analog/HV	SMARTIO
	272-BGA	216-TEQFP	HCon#0	HCon#29 ^[23]	HCon#30			
	Pin	Pin		DS #5 ^[24, 25]	DS #6			
P4.3	B14	NA	GPIO_STD			Supported		
P4.4	B12	172	GPIO_STD		SCB0_SEL3	Not supported	ADC[0]_16	
P4.5	A12	173	GPIO_STD		SCB0_SDA ^[28]		ADC[0]_17	
P4.6	C11	174	GPIO_STD		SCB0_SCL ^[28]		ADC[0]_18	
P4.7	B11	175	GPIO_STD				ADC[0]_19	
P5.0	A14	166	GPIO_ENH		SCB0_CLK		ADC[0]_10	
P5.1	D13	167	GPIO_ENH		SCB0_MOSI		ADC[0]_11	
P5.2	C13	168	GPIO_ENH		SCB0_MISO		ADC[0]_12 HIBERNATE_WAKEUP[3]	
P5.3	B13	169	GPIO_ENH		SCB0_SEL0		ADC[0]_13	
P5.4	A13	170	GPIO_ENH		SCB0_SEL1		ADC[0]_14	
P5.5	C12	171	GPIO_ENH		SCB0_SEL2		ADC[0]_15	
P6.0	A11	176	GPIO_STD				ADC[0]_20	
P6.1	D10	177	GPIO_STD				ADC[0]_21	
P6.2	C10	178	GPIO_STD				ADC[0]_22	
P6.3	B10	179	GPIO_STD				ADC[0]_23	
P7.0	D9	186	GPIO_SMC			Supported	ADC[1]_0	
P7.1	C9	187	GPIO_SMC				ADC[1]_1	
P7.2	B9	188	GPIO_SMC				ADC[1]_2	
P7.3	A9	189	GPIO_SMC				ADC[1]_3	
P7.4	D8	190	GPIO_SMC				ADC[1]_4	
P7.5	C8	191	GPIO_SMC				ADC[1]_5	
P7.6	B8	192	GPIO_SMC				ADC[1]_6	
P7.7	A8	193	GPIO_SMC				ADC[1]_7	
P8.0	D7	196	GPIO_SMC				ADC[1]_8	
P8.1	C7	197	GPIO_SMC				ADC[1]_9	

Notes

23.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).

24.DeepSleep ordering (DS#0, DS#1, DS#2) does not have any impact on choosing any alternate functions; the HSIOM module handles the individual alternate function assignment.

25.All port pin functions available in DeepSleep mode are also available in Active mode.

26.I/O pins that support an oscillator function (WCO or ECO) must be configured for high-impedance if the oscillator is enabled.

27.This I/O will have increased leakage to ground when V_{DD} is below the POR threshold.

28.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

29.See [Absolute maximum ratings](#) for +B condition and clamping current specification.

Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O *(continued)*

Name	Package		I/O Type	DeepSleep Mapping		+B input ^[29]	Analog/HV	SMARTIO
	272-BGA	216-TEQFP	HCon#0	HCon#29 ^[23]	HCon#30			
	Pin	Pin		DS #5 ^[24, 25]	DS #6			
P8.2	B7	198	GPIO_SMC			Supported	ADC[1]_10	
P8.3	A7	199	GPIO_SMC				ADC[1]_11	
P8.4	F6	200	GPIO_SMC				ADC[1]_12	
P8.5	D6	201	GPIO_SMC				ADC[1]_13	
P8.6	C6	202	GPIO_SMC				ADC[1]_14	
P8.7	B6	203	GPIO_SMC				ADC[1]_15	
P9.0	A6	206	GPIO_SMC				ADC[1]_16	SMARTIO9_0
P9.1	D5	207	GPIO_SMC				ADC[1]_17	SMARTIO9_1
P9.2	C5	208	GPIO_SMC				ADC[1]_18	SMARTIO9_2
P9.3	B5	209	GPIO_SMC				ADC[1]_19	SMARTIO9_3
P9.4	A5	210	GPIO_SMC				ADC[1]_20	SMARTIO9_4
P9.5	B4	211	GPIO_SMC				ADC[1]_21	SMARTIO9_5
P9.6	A4	212	GPIO_SMC				ADC[1]_22	SMARTIO9_6
P9.7	A3	213	GPIO_SMC				ADC[1]_23	SMARTIO9_7
P11.0	L3	44	HSIO_STDLN			Not supported		
P11.1	L4	45	HSIO_STDLN					
P11.2	L2	46	HSIO_STDLN					
P11.3	L1	47	HSIO_STDLN					
P11.4	M1	48	HSIO_STDLN					
P11.5	M2	49	HSIO_STDLN					
P11.6	N1	50	HSIO_STDLN					

Notes

23.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).

24.DeepSleep ordering (DS#0, DS#1, DS#2) does not have any impact on choosing any alternate functions; the HSIOM module handles the individual alternate function assignment.

25.All port pin functions available in DeepSleep mode are also available in Active mode.

26.I/O pins that support an oscillator function (WCO or ECO) must be configured for high-impedance if the oscillator is enabled.

27.This I/O will have increased leakage to ground when V_{DD} is below the POR threshold.

28.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

29.See [Absolute maximum ratings](#) for +B condition and clamping current specification.

Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O (continued)

Name	Package		I/O Type	DeepSleep Mapping		+B input ^[29]	Analog/HV	SMARTIO
	272-BGA	216-TEQFP	HCon#0	HCon#29 ^[23]	HCon#30			
	Pin	Pin		DS #5 ^[24, 25]	DS #6			
P11.7	N2	51	HSIO_STDLN			Not supported		
P12.0	M3	52	HSIO_STDLN					
P12.1	M4	53	HSIO_STDLN					
P12.2	N3	NA	HSIO_STDLN					
P12.3	N4	NA	HSIO_STDLN					
P12.4	P1	NA	HSIO_STDLN					
P12.5	P2	NA	HSIO_STDLN					
P12.6	R1	NA	HSIO_STDLN					
P12.7	R2	NA	HSIO_STDLN					
P13.0	P3	NA	HSIO_STDLN					
P13.1	P4	NA	HSIO_STDLN					
P13.2	T2	NA	HSIO_STDLN					
P13.3	T3	NA	HSIO_STDLN					
P13.4	T4	NA	HSIO_STDLN					
P13.5	U1	NA	HSIO_STDLN					
P13.6	U2	NA	HSIO_STDLN					
P13.7	V2	NA	HSIO_STDLN					
P14.0	U3	NA	HSIO_STDLN					
P14.1	V3	NA	HSIO_STDLN					
P14.2	U4	56	HSIO_STDLN					
P14.3	V4	57	HSIO_STDLN					
P14.4	R5	58	HSIO_STDLN					
P14.5	T5	59	HSIO_STDLN					
P14.6	U5	60	HSIO_STDLN					
P14.7	V5	61	HSIO_STDLN					

Notes

23.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).

24.DeepSleep ordering (DS#0, DS#1, DS#2) does not have any impact on choosing any alternate functions; the HSIOM module handles the individual alternate function assignment.

25.All port pin functions available in DeepSleep mode are also available in Active mode.

26.I/O pins that support an oscillator function (WCO or ECO) must be configured for high-impedance if the oscillator is enabled.

27.This I/O will have increased leakage to ground when V_{DD0} is below the POR threshold.

28.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

29.See [Absolute maximum ratings](#) for +B condition and clamping current specification.

Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O *(continued)*

Name	Package		I/O Type	DeepSleep Mapping		+B input ^[29]	Analog/HV	SMARTIO
	272-BGA	216-TEQFP	HCon#0	HCon#29 ^[23]	HCon#30			
	Pin	Pin		DS #5 ^[24, 25]	DS #6			
P15.0	R6	62	HSIO_STDLN			Not supported		
P15.1	T6	63	HSIO_STDLN					
P15.2	U6	66	HSIO_STDLN					
P15.3	V6	67	HSIO_STDLN					
P15.4	R7	68	HSIO_STDLN					
P15.5	T7	69	HSIO_STDLN					
P15.6	U7	70	HSIO_STDLN					
P15.7	V7	71	HSIO_STDLN					
P16.0	R8	72	HSIO_STDLN					
P16.1	T8	73	HSIO_STDLN					
P16.2	U8	78	HSIO_STDLN					
P16.3	V8	79	HSIO_STDLN					
P16.4	R9	80	HSIO_STDLN					
P16.5	T9	81	HSIO_STDLN					
P16.6	U9	82	HSIO_STDLN					
P16.7	V9	NA	HSIO_STDLN					
P17.0	T10	NA	HSIO_STDLN					
P17.1	V10	NA	HSIO_STDLN					
P18.0	B1	2	HSIO_STDLN					
P18.1	B2	3	HSIO_STDLN					
P18.2	C1	4	HSIO_STDLN					
P18.3	C2	5	HSIO_STDLN					
P18.4	D1	8	HSIO_STDLN					
P18.5	D2	9	HSIO_STDLN					
P18.6	E1	10	HSIO_STDLN					

Notes

- 23.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).
24.DeepSleep ordering (DS#0, DS#1, DS#2) does not have any impact on choosing any alternate functions; the HSIOM module handles the individual alternate function assignment.
25.All port pin functions available in DeepSleep mode are also available in Active mode.
26.I/O pins that support an oscillator function (WCO or ECO) must be configured for high-impedance if the oscillator is enabled.
27.This I/O will have increased leakage to ground when V_{DD0} is below the POR threshold.
28.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.
29.See [Absolute maximum ratings](#) for +B condition and clamping current specification.

Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O (continued)

Name	Package		I/O Type	DeepSleep Mapping		+B input ^[29]	Analog/HV	SMARTIO
	272-BGA	216-TEQFP	HCon#0	HCon#29 ^[23]	HCon#30			
	Pin	Pin		DS #5 ^[24, 25]	DS #6			
P18.7	E2	11	HSIO_STDLN			Not supported		
P19.0	C3	14	HSIO_STDLN					
P19.1	D3	15	HSIO_STDLN					
P19.2	E3	16	HSIO_STDLN					
P19.3	E4	17	HSIO_STDLN					
P20.0	F1	24	HSIO_STDLN					
P20.1	F2	25	HSIO_STDLN					
P20.2	G1	26	HSIO_STDLN					
P20.3	G2	27	HSIO_STDLN					
P20.4	H1	30	HSIO_STDLN					
P20.5	H2	31	HSIO_STDLN					
P20.6	J1	32	HSIO_STDLN					
P20.7	J2	33	HSIO_STDLN					
P21.0	G3	36	HSIO_STDLN					
P21.1	H3	37	HSIO_STDLN					
P21.2	J3	38	HSIO_STDLN					
P21.3	H4	39	HSIO_STDLN					
FPD0_TAP	T12	90						
FPD0_TAN	U12	91						
FPD0_TBP	V13	94						
FPD0_TBN	V14	95						
FPD0_TCLKP	R13	98						
FPD0_TCLKN	R14	99						
FPD0_TCP	T15	102						
FPD0_TCN	U15	103						

Notes

23.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).

24.DeepSleep ordering (DS#0, DS#1, DS#2) does not have any impact on choosing any alternate functions; the HSIOM module handles the individual alternate function assignment.

25.All port pin functions available in DeepSleep mode are also available in Active mode.

26.I/O pins that support an oscillator function (WCO or ECO) must be configured for high-impedance if the oscillator is enabled.

27.This I/O will have increased leakage to ground when V_{DD0} is below the POR threshold.

28.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

29.See [Absolute maximum ratings](#) for +B condition and clamping current specification.

Table 11-1 Pin selector and alternate pin functions in DeepSleep (DS) Mode, Analog, Smart I/O (continued)

Name	Package		I/O Type	DeepSleep Mapping		+B input ^[29]	Analog/HV	SMARTIO
	272-BGA	216-TEQFP	HCon#0	HCon#29 ^[23]	HCon#30			
	Pin	Pin		DS #5 ^[24, 25]	DS #6			
FPD0_TDP	V16	106				Not supported		
FPD0_TDN	V17	107						
MIPI_DP3	T18	110						
MIPI_DN3	R18	111						
MIPI_DN1	P17	114						
MIPI_DP1	P16	115						
MIPI_REXT	L15	118						
MIPI_CKN	N15	121						
MIPI_CKP	M15	122						
MIPI_DP0	L16	123						
MIPI_DN0	L17	124						
MIPI_DN2	M18	127						
MIPI_DP2	N18	128						
DAC_AOUTS_R	J15	130						
DAC_COM_R	J16	131						
DAC_COM_L	H15	133						
DAC_AOUTS_L	H16	134						
PMIC_EN	E16	143						
PMIC_STATUS	E17	144						
XRES_L	F16	146						

Notes

23.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).

24.DeepSleep ordering (DS#0, DS#1, DS#2) does not have any impact on choosing any alternate functions; the HSIOM module handles the individual alternate function assignment.

25.All port pin functions available in DeepSleep mode are also available in Active mode.

26.I/O pins that support an oscillator function (WCO or ECO) must be configured for high-impedance if the oscillator is enabled.

27.This I/O will have increased leakage to ground when V_{DD} is below the POR threshold.

28.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

29.See [Absolute maximum ratings](#) for +B condition and clamping current specification.

12 Power pin assignments

Table 12-1 Power pin assignments

Name	Package		Remarks
	272-BGA	216-TEQFP	
VDDD	M7, N7, G12, G13, F9	140, 183	Main supply for SRSS
VSS	A2, B3, C4, D4, F3, F4, K1, K2, K3, K4, R3, R4, T1, V1, R10, U10, H17, H18, F17, F18, A18, B17, A10, H8, H9, H10, H11, J8, J9, J10, J11, K8, K9, K10, K11, L8, L9, L10, L11	1, 6, 12, 19, 20, 22, 28, 34, 40, 43, 55, 64, 75, 76, 109, 142, 150, 163, 164, 180	Main digital ground
VDDIO_HSIO	G4, J4, H6, J6, K6, L6, M6, N6	7, 13, 18, 23, 29, 35, 41, 54, 65, 74, 216	Supply for HSIO (3.0 V - 5.5 V)
VDDIO_GPIO_1	F10, F13	149	Supply for GPIO 1 (2.7V - 5.5V)
VDDIO_GPIO_2	F8	162	Supply for GPIO 2 (2.7V - 5.5V)
VDDIO_SMC	F7, G6, G7	185, 195, 204, 214	GPIO SMC supply (2.7 V - 5.5 V)
VSSIO_SMC	NA	184, 194, 205, 215	GPIO SMC ground
VDDPLL_FPD0	N13	83, 84	Dedicated supplies for FPD0 1.15 V
VSSPLL_FPD0	NA	85, 86	Dedicated ground for FPD0
VDDHA_FPD0	T13, T14, U13, U14, V15, U16	92, 93, 100, 101	Dedicated supplies for FPD0 (3.0 V - 3.6 V)
VDDA_FPD0	N12	88, 89	Dedicated supplies for FPD0 1.15 V
VSSA_FPD0	V18, U17, T16, R15, V12, R12, V11, U11, T11, R11	87, 96, 97, 104, 105, 108	Dedicated ground for FPD0
VDDA_MIPI	M12, M13, L13	112, 116, 119, 125	Dedicated supplies for MIPI 1.15 V
VSSA_MIPI	U18, T17, R16, P15, R17, P18, N16, N17, M16, M17, L18, K18, K17, K16, K15	113, 117, 120, 126	Dedicated ground for MIPI
VCCD ^[30]	J13, K13, N8, N9, N10, N11	21, 42, 77, 141, 165, 181, 182	Main regulated supply. Driven by external PMIC.
VREFH	F12	159	High reference voltage for SAR
VREFL	D12	161	Low reference voltage for SAR
VDDA_ADC	F11	160	Main analog supply (for PASS/SAR, 2.7 V - 5.5 V)
VSSA_ADC	D11	161	Main analog ground
VDDA_DAC	H13	132	Supply for DAC (3.0 V - 3.6 V)
VSSA_DAC	G15, G16	129, 135	Ground for DAC

Note

30. The V_{CCD} pins must be connected together to ensure a low-impedance connection. (see the requirement in [Figure 26-2](#)).

13 Alternate function pin assignments

Table 13-1 Alternate pin functions in active power mode^[25, 33, 34]

	Active Mapping														
Pin	HCon#8 ^[31]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#20	HCon#21	HCon#22	HCon#23	HCon#24	HCon#25	HCon#26	HCon#27
Name	ACT#0 ^[32]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#8	ACT#9	ACT#10	ACT#11	ACT#12	ACT#13	ACT#14	ACT#15
P0.0															
P0.1															
P0.2										EXT_CLK					
P0.3															
P1.0	PWM0_H_4	PWM0_H_3_N	TC0_H_2_TR										SCB6_MISO	SCB6_RTS	
P1.1	PWM0_H_5	PWM0_H_4_N	TC0_H_3_TR										SCB6_SEL0	SCB6_CTS	
P1.2	PWM0_H_6	PWM0_H_5_N	TC0_H_4_TR										SCB7_CLK	SCB7_RX	
P1.3	PWM0_H_7	PWM0_H_6_N	TC0_H_5_TR						TRIG_DBG[1]				SCB7_MOSI	SCB7_TX	
P1.4	PWM0_H_8	PWM0_H_7_N	TC0_H_6_TR						TRIG_IN[1]				SCB7_MISO	SCB7_RTS	SCB7_SDA ^[35]
P1.5	PWM0_H_9	PWM0_H_8_N	TC0_H_7_TR						TRIG_IN[2]				SCB7_SEL0	SCB7_CTS	SCB7_SCL ^[35]
P1.6	PWM0_H_10	PWM0_H_10_N	TC0_H_10_TR						TRIG_IN[3]		DAC_MCK	LIN0_TX	CAN0_0_TX	CXPI0_TX	
P1.7	PWM0_H_11	PWM0_H_11_N	TC0_H_11_TR						TRIG_IN[4]			LIN0_RX	CAN0_0_RX	CXPI0_RX	
P2.0	PWM0_H_12	PWM0_H_12_N	TC0_H_12_TR						TRIG_IN[5]			LIN0_EN	CAN0_1_TX	CXPI0_EN	
P2.1	PWM0_H_13	PWM0_H_15_N	TC0_H_14_TR						TRIG_DBG[0]		CAL_SUP_NZ	LIN0_EN	CAN0_1_RX	CXPI0_EN	FAULT_OUT_0
P2.2	PWM0_H_14	PWM0_H_13_N	TC0_H_15_TR						TRIG_IN[0]			LIN1_RX	CXPI1_RX		
P2.4	PWM0_H_15	PWM0_H_14_N	TC0_H_13_TR						TRIG_IN[6]			LIN1_TX	CXPI1_TX		
P2.5	PWM0_0	PWM0_2_N							TRIG_IN[7]			LIN1_EN	CXPI1_EN		
P3.0	PWM0_1	PWM0_0_N							TRIG_IN[8]						
P3.1	PWM0_2	PWM0_1_N							TRIG_IN[9]						
P4.0	PWM0_H_2	PWM0_H_1_N	TC0_H_0_TR										SCB6_CLK	SCB6_RX	SCB6_SDA ^[35]
P4.1	PWM0_H_3	PWM0_H_2_N	TC0_H_1_TR										SCB6_MOSI	SCB6_TX	SCB6_SCL ^[35]
P4.2	PWM0_H_0	PWM0_H_9_N	TC0_H_8_TR										SCB6_SEL1		
P4.3	PWM0_H_1	PWM0_H_0_N	TC0_H_9_TR										SCB7_SEL1		
P4.4	PWM0_9	PWM0_8_N				EXT_MUX[0]_2			TRIG_IN[16]	SG_AMPL[1] (2)			CAN0_1_TX		SCB3_SDA ^[35]

Notes

31.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).

32.Active Mode ordering (ACT#0, ACT#1, and so on) does not have any impact on configuring alternate functions; the HSIOM module handles the alternate function assignments.

33.Refer to [Table 13-2](#) for more information on pin multiplexer abbreviations used.

34.For any function marked with an identifier (n), the AC timing is only guaranteed within the respective group “n”.

35.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

Table 13-1 Alternate pin functions in active power mode^[25, 33, 34] (continued)

Active Mapping															
Pin	HCon#8 ^[31]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#20	HCon#21	HCon#22	HCon#23	HCon#24	HCon#25	HCon#26	HCon#27
Name	ACT#0 ^[32]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#8	ACT#9	ACT#10	ACT#11	ACT#12	ACT#13	ACT#14	ACT#15
P4.5	PWM0_10	PWM0_9_N			EXT_MUX[1]_0				TRIG_IN[17]	SG_TONE[1] (2)			CAN0_1_RX		SCB3_SCL ^[35]
P4.6	PWM0_11	PWM0_10_N			EXT_MUX[1]_1				TRIG_IN[18]	SG_AMPL[2] (2)			CAN1_0_TX		
P4.7	PWM0_12	PWM0_11_N			EXT_MUX[1]_2				TRIG_IN[19]	SG_TONE[2] (2)			CAN1_0_RX		
P5.0	PWM0_3	PWM0_16_N							TRIG_IN[10]	CLK_FM_PUMP	SCB0_RX				FAULT_OUT_1
P5.1	PWM0_4	PWM0_3_N							TRIG_IN[11]		SCB0_TX	LIN1_TX	CXPI1_EN		FAULT_OUT_2
P5.2	PWM0_5	PWM0_4_N							TRIG_IN[12]		SCB0_RTS	LIN1_RX	CXPI1_RX	SCB1_SDA	FAULT_OUT_3
P5.3	PWM0_6	PWM0_5_N							TRIG_IN[13]		SCB0_CTS	LIN1_EN	CXPI1_TX	SCB1_SCL	
P5.4	PWM0_7	PWM0_6_N			EXT_MUX[0]_0				TRIG_IN[14]	SG_AMPL[0] (2)			CAN0_0_TX	SCB2_SDA	
P5.5	PWM0_8	PWM0_7_N			EXT_MUX[0]_1				TRIG_IN[15]	SG_TONE[0] (2)			CAN0_0_RX	SCB2_SCL	
P6.0	PWM0_13	PWM0_12_N			EXT_MUX[0]_EN				TRIG_IN[20]	SG_AMPL[3] (2)			CAN1_1_TX		
P6.1	PWM0_14	PWM0_13_N			EXT_MUX[1]_EN				TRIG_IN[21]	SG_TONE[3] (2)			CAN1_1_RX		
P6.2	PWM0_15	PWM0_14_N							TRIG_IN[22]	SG_AMPL[4] (0)					
P6.3	PWM0_16	PWM0_15_N							TRIG_IN[23]	SG_TONE[4] (0)					
P7.0	PWM0_M_0	PWM0_H_21_N							TRIG_IN[24]						
P7.1	PWM0_H_16	PWM0_M_0_N	TC0_H_21_TR						TRIG_IN[25]						
P7.2	PWM0_M_1	PWM0_H_16_N							TRIG_IN[26]						
P7.3	PWM0_H_17	PWM0_M_1_N	TC0_H_16_TR						TRIG_IN[27]						
P7.4	PWM0_M_2	PWM0_H_17_N							TRIG_IN[28]						
P7.5	PWM0_H_18	PWM0_M_2_N	TC0_H_17_TR						TRIG_IN[29]						
P7.6	PWM0_M_3	PWM0_H_18_N							TRIG_IN[30]						FAULT_OUT_0
P7.7	PWM0_H_19	PWM0_M_3_N	TC0_H_18_TR						TRIG_IN[31]						FAULT_OUT_1
P8.0	PWM0_M_4	PWM0_H_19_N							TRIG_IN[32]						
P8.1	PWM0_H_20	PWM0_M_4_N	TC0_H_19_TR						TRIG_IN[33]	SG_MCK[0]					
P8.2	PWM0_M_5	PWM0_H_20_N							TRIG_IN[34]	SG_AMPL[0] (3)					

Notes

- 31.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).
- 32.Active Mode ordering (ACT#0, ACT#1, and so on) does not have any impact on configuring alternate functions; the HSIOM module handles the alternate function assignments.
- 33.Refer to [Table 13-2](#) for more information on pin multiplexer abbreviations used.
- 34.For any function marked with an identifier (n), the AC timing is only guaranteed within the respective group “n”.
- 35.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

Table 13-1 Alternate pin functions in active power mode^[25, 33, 34] (continued)

Active Mapping															
Pin	HCon#8 ^[31]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#20	HCon#21	HCon#22	HCon#23	HCon#24	HCon#25	HCon#26	HCon#27
Name	ACT#0 ^[32]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#8	ACT#9	ACT#10	ACT#11	ACT#12	ACT#13	ACT#14	ACT#15
P8.3	PWM0_H_21	PWM0_M_5_N	TC0_H_20_TR						TRIG_IN[35]	SG_TONE[0] J(3)					
P8.4	PWM0_M_6	PWM0_17_N							TRIG_IN[36]	SG_AMPL[1] J(3)					
P8.5	PWM0_17	PWM0_M_6_N	TC0_22_TR						TRIG_IN[37]	SG_TONE[1] J(3)					
P8.6	PWM0_M_7	PWM0_18_N							TRIG_IN[38]	SG_AMPL[2] J(3)					
P8.7	PWM0_18	PWM0_M_7_N							TRIG_IN[39]	SG_TONE[2] J(3)					
P9.0	PWM0_M_8	PWM0_19_N							TRIG_IN[40]	SG_AMPL[3] J(3)					
P9.1	PWM0_19	PWM0_M_8_N							TRIG_IN[41]	SG_TONE[3] J(3)					
P9.2	PWM0_M_9	PWM0_20_N							TRIG_IN[42]	SG_AMPL[4] J(1)					
P9.3	PWM0_20	PWM0_M_9_N							TRIG_IN[43]	SG_TONE[4] J(1)			SCB8_SEL1		
P9.4	PWM0_M_10	PWM0_21_N							TRIG_IN[44]	SG_MCK[1]			SCB8_CLK	SCB8_RX	SCB8_SDA ^[35]
P9.5	PWM0_21	PWM0_M_10_N	TC0_20_TR						TRIG_IN[45]	SG_MCK[2]			SCB8_MOSI	SCB8_TX	SCB8_SCL ^[35]
P9.6	PWM0_M_11	PWM0_22_N							TRIG_IN[46]	SG_MCK[3]			SCB8_MISO	SCB8_RTS	
P9.7	PWM0_22	PWM0_M_11_N	TC0_21_TR						TRIG_IN[47]	SG_MCK[4]			SCB8_SEL0	SCB8_CTS	
P11.0				ETH_REF_CLK								TTL_D- SP1_DATA_ A1[11]	SCB1_RX	SCB1_SDA ^[35]	SCB1_CLK
P11.1				ETH_RX_ER								TTL_D- SP1_DATA_ A0[11]	SCB1_TX	SCB1_SCL ^[35]	SCB1_MOSI
P11.2				ETH_RXD_0								TTL_D- SP1_DATA_ A1[10]	SCB1_RTS		SCB1_MISO
P11.3				ETH_RXD_1								TTL_D- SP1_DATA_ A0[10]	SCB1_CTS		SCB1_SEL0
P11.4				ETH_TXD_0									TTL_DSP1_- CONTROL[2]		SCB1_SEL1
P11.5				ETH_TXD_1									SCB2_RX	SCB2_SDA ^[35]	SCB2_CLK
P11.6				ETH_TX_CTL								TTL_D- SP1_DATA_ A1[9]	SCB2_TX	SCB2_SCL ^[35]	SCB2_MOSI

Notes

31. High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).
32. Active Mode ordering (ACT#0, ACT#1, and so on) does not have any impact on configuring alternate functions; the HSIOM module handles the alternate function assignments.
33. Refer to [Table 13-2](#) for more information on pin multiplexer abbreviations used.
34. For any function marked with an identifier (n), the AC timing is only guaranteed within the respective group “n”.
35. See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

Table 13-1 Alternate pin functions in active power mode^[25, 33, 34] (continued)

Active Mapping															
Pin	HCon#8 ^[31]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#20	HCon#21	HCon#22	HCon#23	HCon#24	HCon#25	HCon#26	HCon#27
Name	ACT#0 ^[32]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#8	ACT#9	ACT#10	ACT#11	ACT#12	ACT#13	ACT#14	ACT#15
P11.7				ETH_RX_CTL								TTL_D- SP1_DATA_ A0[9]	SCB2_RTS		SCB2_MISO
P12.0				ETH_MDC								TTL_D- SP1_DATA_ A1[8]	SCB2_CTS		SCB2_SEL0
P12.1				ETH_MDIO								TTL_D- SP1_DATA_ A0[8]	TTL_DSP0_- CONTROL[11]		SCB2_SEL1
P12.2				ETH_TX_CLK	TDM_TX_MC K0	TDM_RX_MCK 1			PWM_LINE1_P0	SG_TONE[0 (0)		TTL_D- SP1_CONT ROL[10]	TTL_DSP0_- CONTROL[10]	SCB9_SEL1	
P12.3				ETH_RX_CLK	TDM_TX_SCK 0	TDM_RX_SCK 1			PWM_LINE1_N0	SG_AMPL[0 (0)		TTL_D- SP1_CONT ROL[9]	TTL_DSP0_- CONTROL[9]	SCB10_SEL1	
P12.4				ETH_RXD_2	TDM_TX- _FSYNC0	TDM_RX- _FSYNC1			PWM_LINE2_P0	SG_TONE[1 (0)		TTL_D- SP1_CONT ROL[8]	TTL_DSP0_- CONTROL[8]	SCB11_SEL1	
P12.5				ETH_RXD_3	TDM_TX_SD0	TDM_RX_SD1			PWM_LINE2_N0	SG_AMPL[1 (0)		TTL_D- SP1_CONT ROL[7]	TTL_DSP0_- CONTROL[7]	TRACE_- CLOCK(1)	
P12.6				ETH_TXD_2	TDM_TX_MC K[1](0)	TDM_RX_MCK [0](1)			PWM_LINE1_P[1](0)	SG_TONE[2 (0)		TTL_D- SP1_CONT ROL[6]	TTL_DSP0_- CONTROL[6]	TRACE_- DATA_0(1)	
P12.7				ETH_TXD_3	TDM_TX_SCK [1](0)	TDM_RX_SCK [0](1)			PWM_LINE1_N[1](0)	SG_AMPL[2 (0)		TTL_D- SP1_CONT ROL[5]	TTL_DSP0_- CONTROL[5]	TRACE_- DATA_1(1)	
P13.0				ETH_TX_ER	TDM_TX- _FSYNC[1](0)	TDM_RX- _FSYNC[0](1)			PWM_LINE2_P[1](0)	SG_TONE[3 (0)		TTL_D- SP1_CONT ROL[4]	TTL_DSP0_- CONTROL[4]	TRACE_- DATA_2(1)	
P13.1				ETH_TSU_- TIMER_C- MP_VAL	TDM_TX_SD[1](0)	TDM_RX_SD[0](1)			PWM_LINE2_N[1](0)	SG_AMPL[3 (0)		TTL_D- SP1_CONT ROL[3]	TTL_DSP0_- CONTROL[3]	TRACE_- DATA_3(1)	
P13.2							TTL_CAP0_DA TA[23]		PWM_MCK[0]			TTL_D- SP1_DATA_ A1[11]			
P13.3							TTL_CAP0_DA TA[22]		PWM_MCK[1]		TTL_CAP0_DAT A[26]	TTL_D- SP1_DATA_ A0[11]			
P13.4							TTL_CAP0_DA TA[21]				TTL_CAP0_DAT A[25]	TTL_D- SP1_DATA_ A1[10]			
P13.5							TTL_CAP0_DA TA[20]				TTL_CAP0_DAT A[24]	TTL_D- SP1_DATA_ A0[10]			

Notes

- 31.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).
- 32.Active Mode ordering (ACT#0, ACT#1, and so on) does not have any impact on configuring alternate functions; the HSIOM module handles the alternate function assignments.
- 33.Refer to [Table 13-2](#) for more information on pin multiplexer abbreviations used.
- 34.For any function marked with an identifier (n), the AC timing is only guaranteed within the respective group “n”.
- 35.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

Table 13-1 Alternate pin functions in active power mode^[25, 33, 34] (continued)

Active Mapping															
Pin	HCon#8 ^[31]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#20	HCon#21	HCon#22	HCon#23	HCon#24	HCon#25	HCon#26	HCon#27
Name	ACT#0 ^[32]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#8	ACT#9	ACT#10	ACT#11	ACT#12	ACT#13	ACT#14	ACT#15
P13.6							TTL_CAP0_DATA[19]				TTL_CAP0_DATA[0]	TTL_D-SP1_DATA_A1[9]			
P13.7							TTL_CAP0_DATA[18]				TTL_CAP0_DATA[1]	TTL_D-SP1_DATA_A0[9]			
P14.0	PWM0_H_22	PWM0_H_31_N	TC0_H_30_TR				TTL_CAP0_DATA[17]				TTL_CAP0_DATA[2]	TTL_D-SP1_DATA_A1[8]			
P14.1	PWM0_H_23	PWM0_H_22_N	TC0_H_31_TR				TTL_CAP0_DATA[16]				TTL_CAP0_DATA[3]	TTL_D-SP1_DATA_A0[8]			
P14.2	PWM0_H_24	PWM0_H_23_N	TC0_H_22_TR		TDM_TX_MCK[2](0)	TDM_RX_MCK0	TTL_CAP0_DATA[15]		PWM_LINE1_P[0](1)	SG_TONE[0](1)	TTL_CAP0_DATA[4]	TTL_D-SP1_DATA_A1[7]	TTL_DSP1-CONTROL[2]	TRACE_-CLOCK(0)	
P14.3	PWM0_H_25	PWM0_H_24_N	TC0_H_23_TR		TDM_TX_SCK[2](0)	TDM_RX_SCK0	TTL_CAP0_DATA[14]		PWM_LINE1_N[0](1)	SG_AMPL[0](1)	TTL_CAP0_DATA[5]	TTL_D-SP1_DATA_A0[7]		TRACE_-DATA_0(0)	
P14.4	PWM0_H_26	PWM0_H_25_N	TC0_H_24_TR		TDM_TX-_FSYNC[2](0)	TDM_RX-_FSYNC0	TTL_CAP0_DATA[13]		PWM_LINE2_P[0](1)	SG_TONE1	TTL_CAP0_DATA[6]	TTL_D-SP1_DATA_A1[6]		TRACE_-DATA_1(0)	
P14.5	PWM0_H_27	PWM0_H_26_N	TC0_H_25_TR		TDM_TX_SD[2](0)	TDM_RX_SD0	TTL_CAP0_DATA[12]		PWM_LINE2_N[0](1)	SG_AMPL1	TTL_CAP0_DATA[7]	TTL_D-SP1_DATA_A0[6]		TRACE_-DATA_2(0)	
P14.6	PWM0_H_28	PWM0_H_27_N	TC0_H_26_TR		TDM_TX_MCK[3](0)	TDM_RX_MCK[1](0)	TTL_CAP0_DATA[11]		PWM_LINE1_P1	SG_TONE[2](1)	TTL_CAP0_DATA[8]	TTL_D-SP1_DATA_A1[5]		TRACE_-DATA_3(0)	
P14.7	PWM0_H_29	PWM0_H_28_N	TC0_H_27_TR		TDM_TX_SCK[3](0)	TDM_RX_SCK[1](0)	TTL_CAP0_DATA[10]		PWM_LINE1_N1	SG_AMPL[2](1)	TTL_CAP0_DATA[9]	TTL_D-SP1_DATA_A0[5]			
P15.0	PWM0_H_30	PWM0_H_29_N	TC0_H_28_TR		TDM_TX-_FSYNC[3](0)	TDM_RX-_FSYNC[1](0)	TTL_CAP0_CLK		PWM_LINE2_P1	SG_TONE[3](1)		TTL_D-SP1_DATA_A1[4]			
P15.1	PWM0_H_31	PWM0_H_30_N	TC0_H_29_TR		TDM_TX_SD[3](0)	TDM_RX_SD[1](0)	TTL_CAP0_DATA[10]		PWM_LINE2_N1	SG_AMPL[3](1)	TTL_CAP0_DATA[9]	TTL_D-SP1_DATA_A0[4]			
P15.2	PWM0_23	PWM0_29_N	TC0_28_TR				TTL_CAP0_DATA[11]				TTL_CAP0_DATA[8]	TTL_D-SP1_DATA_A1[3]	SCB3_CLK	SCB3_RX	SCB3_SDA ^[35]
P15.3	PWM0_24	PWM0_30_N	TC0_29_TR				TTL_CAP0_DATA[12]				TTL_CAP0_DATA[7]	TTL_D-SP1_DATA_A0[3]	SCB3_MOSI	SCB3_TX	SCB3_SCL ^[35]
P15.4	PWM0_25	PWM0_23_N	TC0_30_TR				TTL_CAP0_DATA[13]				TTL_CAP0_DATA[6]	TTL_D-SP1_DATA_A1[2]	SCB3_MISO	SCB3_RTS	

Notes

31.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).

32.Active Mode ordering (ACT#0, ACT#1, and so on) does not have any impact on configuring alternate functions; the HSIOM module handles the alternate function assignments.

33.Refer to [Table 13-2](#) for more information on pin multiplexer abbreviations used.

34.For any function marked with an identifier (n), the AC timing is only guaranteed within the respective group “n”.

35.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

Table 13-1 Alternate pin functions in active power mode^[25, 33, 34] (continued)

Active Mapping															
Pin	HCon#8 ^[31]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#20	HCon#21	HCon#22	HCon#23	HCon#24	HCon#25	HCon#26	HCon#27
Name	ACT#0 ^[32]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#8	ACT#9	ACT#10	ACT#11	ACT#12	ACT#13	ACT#14	ACT#15
P15.5	PWM0_26	PWM0_24_N	TC0_23_TR				TTL_CAP0_DATA[14]				TTL_CAP0_DATA[5]	TTL_D-SP1_DATA_A0[2]	SCB3_SEL0	SCB3_CTS	
P15.6	PWM0_27	PWM0_25_N	TC0_24_TR				TTL_CAP0_DATA[15]				TTL_CAP0_DATA[4]	TTL_D-SP1_DATA_A1[1]	SCB3_SEL1		
P15.7	PWM0_28	PWM0_26_N	TC0_25_TR				TTL_CAP0_DATA[16]				TTL_CAP0_DATA[3]	TTL_D-SP1_DATA_A0[1]	SCB4_CLK	SCB4_RX	SCB4_SDA ^[35]
P16.0	PWM0_29	PWM0_27_N	TC0_26_TR				TTL_CAP0_DATA[17]				TTL_CAP0_DATA[2]	TTL_D-SP1_DATA_A1[0]	SCB4_MOSI	SCB4_TX	SCB4_SCL ^[35]
P16.1	PWM0_30	PWM0_28_N	TC0_27_TR				TTL_CAP0_DATA[18]				TTL_CAP0_DATA[1]	TTL_D-SP1_DATA_A0[0]	SCB4_MISO	SCB4_RTS	
P16.2	PWM0_31	PWM0_37_N	TC0_36_TR			TDM_RX_MCK[2](0)	TTL_CAP0_DATA[19]		PWM_LINE1_P[0](2)	EXT_CLK	TTL_CAP0_DATA[0]	TTL_D-SP1_CLOCK	SCB4_SEL0	SCB4_CTS	
P16.3	PWM0_32	PWM0_31_N	TC0_37_TR			TDM_RX_SCK[2](0)	TTL_CAP0_DATA[20]		PWM_LINE1_N[0](2)		TTL_CAP0_DATA[24]	TTL_D-SP1_CONTROL[0]	SCB4_SEL1		
P16.4	PWM0_33	PWM0_32_N	TC0_31_TR			TDM_RX-_FSYNC[2](0)	TTL_CAP0_DATA[21]		PWM_LINE2_P[0](2)	IO_CLK_HF[5]	TTL_CAP0_DATA[25]	TTL_D-SP1_CONTROL[1]	TTL_DSP1-_CONTROL[2]		
P16.5	PWM0_34	PWM0_33_N	TC0_32_TR			TDM_RX_SD[2](0)	TTL_CAP0_DATA[22]		PWM_LINE2_N[0](2)		TTL_CAP0_DATA[26]	SCB5_SEL1	TTL_DSP1-_CONTROL[2]		
P16.6	PWM0_35	PWM0_34_N	TC0_33_TR		TDM_TX_MCK[2](1)	TDM_RX_MCK[3](0)	TTL_CAP0_DATA[23]		PWM_LINE1_P[1](2)			TTL_D-SP1_CONTROL[11]	SCB5_CLK	SCB5_RX	SCB5_SDA ^[35]
P16.7	PWM0_36	PWM0_35_N	TC0_34_TR		TDM_TX_SCK[2](1)	TDM_RX_SCK[3](0)			PWM_LINE1_N[1](2)			TTL_D-SP0_CONTROL[2]	SCB5_MOSI	SCB5_TX	SCB5_SCL ^[35]
P17.0	PWM0_37	PWM0_36_N	TC0_35_TR	ETH_MDC	TDM_TX-_FSYNC[2](1)	TDM_RX-_FSYNC[3](0)			PWM_LINE2_P[1](2)			TTL_D-SP0_CONTROL[1]	SCB5_MISO	SCB5_RTS	
P17.1				ETH_MDIO	TDM_TX_SD[2](1)	TDM_RX_SD[3](0)			PWM_LINE2_N[1](2)			TTL_D-SP0_CONTROL[0]	SCB5_SEL0	SCB5_CTS	
P18.0								SCB9_CLK	SCB9_RX	SCB9_SDA ^[35]					SPIHB[0]_DATA4
P18.1								SCB9_MOSI	SCB9_TX	SCB9_SCL ^[35]					SPIHB[0]_DATA2
P18.2								SCB9_MISO	SCB9_RTS						SPIHB[0]_DATA3
P18.3								SCB9_SEL0	SCB9_CTS						SPIHB[0]_DATA5

Notes

31.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).

32.Active Mode ordering (ACT#0, ACT#1, and so on) does not have any impact on configuring alternate functions; the HSIOM module handles the alternate function assignments.

33.Refer to [Table 13-2](#) for more information on pin multiplexer abbreviations used.

34.For any function marked with an identifier (n), the AC timing is only guaranteed within the respective group “n”.

35.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

Table 13-1 Alternate pin functions in active power mode^[25, 33, 34] (continued)

	Active Mapping														
Pin	HCon#8 ^[31]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#20	HCon#21	HCon#22	HCon#23	HCon#24	HCon#25	HCon#26	HCon#27
Name	ACT#0 ^[32]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#8	ACT#9	ACT#10	ACT#11	ACT#12	ACT#13	ACT#14	ACT#15
P18.4								SCB10_CLK	SCB10_RX	SCB10_SDA ^[35]					SPIHB[0]_DATA0
P18.5								SCB10_MOSI	SCB10_TX	SCB10_SCL ^[35]					SPIHB[0]_DATA6
P18.6								SCB10_MISO	SCB10_RTS						SPIHB[0]_DATA1
P18.7								SCB10_SELECT0	SCB10_CTS						SPIHB[0]_DATA7
P19.0								SCB11_CLK	SCB11_RX	SCB11_SDA ^[35]					SPIHB[0]_CLK
P19.1								SCB11_MOSI	SCB11_TX	SCB11_SCL ^[35]					SPIHB[0]_RWDS
P19.2								SCB11_MISO	SCB11_RTS						SPIHB[0]_SELECT0
P19.3								SCB11_SELECT0	SCB11_CTS						SPIHB[0]_SELECT1
P20.0				SPIHB[1]_DATA4											
P20.1				SPIHB[1]_DATA2											
P20.2				SPIHB[1]_DATA3											
P20.3				SPIHB[1]_DATA5									TTL_DSP1_CONTROL[2]		
P20.4				SPIHB[1]_DATA0								TTL_D-SP1_DATA_A1[11]			
P20.5				SPIHB[1]_DATA6								TTL_D-SP1_DATA_A0[11]			
P20.6				SPIHB[1]_DATA1								TTL_D-SP1_DATA_A1[10]			
P20.7				SPIHB[1]_DATA7								TTL_D-SP1_DATA_A0[10]			
P21.0				SPIHB[1]_CLK								TTL_D-SP1_DATA_A1[9]			
P21.1				SPIHB[1]_RWDS								TTL_D-SP1_DATA_A0[9]			

Notes

- 31.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).
- 32.Active Mode ordering (ACT#0, ACT#1, and so on) does not have any impact on configuring alternate functions; the HSIOM module handles the alternate function assignments.
- 33.Refer to [Table 13-2](#) for more information on pin multiplexer abbreviations used.
- 34.For any function marked with an identifier (n), the AC timing is only guaranteed within the respective group “n”.
- 35.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

Table 13-1 Alternate pin functions in active power mode^[25, 33, 34] (continued)

Active Mapping															
Pin	HCon#8 ^[31]	HCon#9	HCon#10	HCon#11	HCon#16	HCon#17	HCon#18	HCon#20	HCon#21	HCon#22	HCon#23	HCon#24	HCon#25	HCon#26	HCon#27
Name	ACT#0 ^[32]	ACT#1	ACT#2	ACT#3	ACT#4	ACT#5	ACT#6	ACT#8	ACT#9	ACT#10	ACT#11	ACT#12	ACT#13	ACT#14	ACT#15
P21.2				SPIHB[1]_SELECT0								TTL_D-SP1_DATA_A1[8]			
P21.3				SPIHB[1]_SELECT1								TTL_D-SP1_DATA_A0[8]			

Notes

31.High-Speed I/O matrix connection (HCON) reference as per [Table 10-1](#).

32.Active Mode ordering (ACT#0, ACT#1, and so on) does not have any impact on configuring alternate functions; the HSIOM module handles the alternate function assignments.

33.Refer to [Table 13-2](#) for more information on pin multiplexer abbreviations used.

34.For any function marked with an identifier (n), the AC timing is only guaranteed within the respective group “n”.

35.See [Table 26-10](#) 'Serial Communication Block (SCB) specifications' for supported IO-cells and I²C modes.

13.1 Pin function description

Table 13-2 Pin function description

Sl. No.	Pin	Module	Description
1	PWMx_y	TCPWM	TCPWM 16-bit PWM (no motor control), PWM_DT and PWM_PR line out, x-TCPWM block, y-counter number
2	PWMx_y_N	TCPWM	TCPWM 16-bit PWM (no motor control), PWM_DT and PWM_PR complementary line out (N), x-TCPWM block, y-counter number
3	PWMx_M_y ^[36]	TCPWM	TCPWM 16-bit PWM with motor control line out, x-TCPWM block, y-counter number
4	PWMx_M_y_N ^[36]	TCPWM	TCPWM 16-bit PWM with motor control complementary line out (N), x-TCPWM block, y-counter number
5	PWMx_H_y	TCPWM	TCPWM 32-bit PWM, PWM_DT and PWM_PR line out, x-TCPWM block, y-counter number
6	PWMx_H_y_N	TCPWM	TCPWM 32-bit PWM, PWM_DT and PWM_PR complementary line out (N), x-TCPWM block, y-counter number
7	TCx_y_TRz	TCPWM	TCPWM 16-bit dedicated counter input triggers, x-TCPWM block, y-counter number, z-trigger number
8	TCx_H_y_TRz	TCPWM	TCPWM 32-bit dedicated counter input triggers, x-TCPWM block, y-counter number, z-trigger number
9	SCBx_RX	SCB	UART Receive, x-SCB block
10	SCBx_TX	SCB	UART Transmit, x-SCB block
11	SCBx_RTS	SCB	UART Request to Send (Handshake), x-SCB block
12	SCBx_CTS	SCB	UART Clear to Send (Handshake), x-SCB block
13	SCBx_SDA	SCB	I2C Data line, x-SCB block
14	SCBx_SCL	SCB	I2C Clock line, x-SCB block
15	SCBx_MISO	SCB	SPI Master Input Slave Output, x-SCB block
16	SCBx_MOSI	SCB	SPI Master Output Slave Input, x-SCB block
17	SCBx_CLK	SCB	SPI Serial Clock, x-SCB block
18	SCBx_SELy	SCB	SPI Slave Select, x-SCB block, y-select line
19	LINx_RX	LIN	LIN Receive line, x-LIN block
20	LINx_TX	LIN	LIN Transmit line, x-LIN block
21	LINx_EN	LIN	LIN Enable line, x-LIN block
22	CXPIx_RX	CXPI	CXPI Receive line, x-CXPI block
23	CXPIx_TX	CXPI	CXPI Transmit line, x-CXPI block
24	CXPIx_EN	CXPI	CXPI Enable line, x-CXPI block
25	CANx_y_TX	CANFD	CAN Transmit line, x-CAN block, y-channel number
26	CANx_y_RX	CANFD	CAN Receive line, x-CAN block, y-channel number
27	SPIHB_CLK	SMIF	SMIF interface clock
28	SPIHB_RWDS	SMIF	SMIF (SPI/xSPI) read-write-data-strobe line
29	SPIHB_SELx	SMIF	SMIF (SPI/xSPI) memory select line, x-select line number
30	SPIHB_DATAx	SMIF	SMIF (SPI/xSPI) memory data read and write line, x-0 to 7 data lines
31	ETHx_RX_ER	Ethernet	Ethernet receive error indication line, x-ETH module number
32	ETHx_ETH_TSU_TIMER_C-MP_VAL	Ethernet	Ethernet time stamp unit timer compare indication line, x-ETH module number
33	ETHx_MDIO	Ethernet	Ethernet management data input/output (MDIO) interface to PHY, x-ETH module number
34	ETHx_MDC	Ethernet	Ethernet management data clock (MDC) line, x-ETH module number
35	ETHx_REF_CLK	Ethernet	Ethernet reference clock line, x-ETH module number
36	ETHx_TX_CTL	Ethernet	Ethernet transmit control line, x-ETH module number
37	ETHx_TX_ER	Ethernet	Ethernet transmit error indication line, x-ETH module number

Note

36.This pin/line is intended for a direct connection to the coil of stepper motor for pointer instruments.

Alternate function pin assignments

Table 13-2 Pin function description *(continued)*

Sl. No.	Pin	Module	Description
38	ETHx_TX_CLK	Ethernet	Ethernet transmit clock line, x-ETH module number
39	ETHx_TXD_y	Ethernet	Ethernet transmit data line, x-ETH module number, y-transmit channel number
40	ETHx_RXD_y	Ethernet	Ethernet receive data line, x-ETH module number, y-receive channel number
41	ETHx_RX_CTL	Ethernet	Ethernet receive control line, x-ETH module number
42	ETHx_RX_CLK	Ethernet	Ethernet receive clock line, x-ETH module number
43	CAL_SUP_NZ	System	ETAS Calibration support line
44	FAULT_OUT_x	SRSS	Fault output line x-0 to 3
45	TRACE_DATA_x	SRSS	Trace dataout line x-0 to 3
46	TRACE_CLOCK	SRSS	Trace clock line
47	RTC_CAL	SRSS RTC	RTC calibration clock input
48	SWJ_TRSTN	SRSS	JTAG Test reset line (Active low)
49	SWJ_SWO_TDO	SRSS	JTAG Test data output/SWO (Serial Wire Output)
50	SWJ_SWCLK_TCLK	SRSS	JTAG Test clock/SWD clock (Serial Wire Clock)
51	SWJ_SWDIO_TMS	SRSS	JTAG Test mode select/SWD data (Serial Wire Data Input/Output)
52	SWJ_SWDOE_TDI	SRSS	JTAG Test data input
53	HIBERNATE_WAKEUP[x]	SRSS	Hibernate wakeup line x-0 to N (Check Table 11-1)
54	EXT_CLK	SRSS	External clock input
55	IO_CLK_HF[5]	SRSS	CLK_HF5 clock output
56	PMIC_EN	SRSS PMIC	PMIC control line, Enable output for PMIC
57	PMIC_STATUS	SRSS PMIC	PMIC status line, Power good input from PMIC
58	ADC[x]_y	PASS SAR	SAR, channel, x-SAR number, y-channel number
59	ADC[x]_M	PASS SAR	SAR motor control input, x-SAR number
60	EXT_MUX[x]_y	PASS SAR	External SAR MUX inputs, x-MUX number, y-MUX input 0 to 2
61	EXT_MUX[x]_EN	PASS SAR	External SAR MUX enable line
62	PWM_LINEx_N[y]	PCM PWM	Audio PWM complementary output line, x-PWM module instance
63	PWM_LINEx_P[y]	PCM PWM	Audio PWM output line, x-PWM module instance
64	PWM_MCK[x]	PCM PWM	Audio PWM master clock input, x-PWM module instance
65	SG_AMPL[x]	SG	Sound generator (SG) amplitude output, x-SG module number
66	SG_MCK[x]	SG	Sound generator (SG) master clock input, x-SG module number
67	SG_TONE[x]	SG	Sound generator (SG) tone output, x-SG module number
68	TDM_RX_FSYNC[x]	TDM	TDM receive frame sync, x-TDM module number
69	TDM_RX_MCK[x]	TDM	TDM receive master clock input, x-TDM module number
70	TDM_RX_SCK[x]	TDM	TDM receive bit clock, x-TDM module number
71	TDM_RX_SD[x]	TDM	TDM receive serial data, x-TDM module number
72	TDM_TX_FSYNC[x]	TDM	TDM transmit frame sync, x-TDM module number
73	TDM_TX_MCK[x]	TDM	TDM transmit master clock input, x-TDM module number
74	TDM_TX_SCK[x]	TDM	TDM transmit bit clock, x-TDM module number
75	TDM_TX_SD[x]	TDM	TDM transmit serial data, x-TDM module number
76	TTL_CAPx_CLK	VIDEO	Capture clock, x-capture module number
77	TTL_CAPx_DATA[y]	VIDEO	Capture data lines, x-capture module number, y- (0-26) data line
78	TTL_DSPx_CONTROL[y]	VIDEO	Display control line, x-display number, y-0/Invalid, 1/vertical sync signal, 2/display enable (DE)
79	TTL_DSPx_CLOCK	VIDEO	Display clock line (PCLK), x-display number
80	TTL_DSPx_DATA_A0[y]	VIDEO	Display data (A0/1 used in pairs), x-display number, y- (0-11) color data
81	TTL_DSPx_DATA_A1[y]	VIDEO	Display data (A0/1 used in pairs), x-display number, y- (0-11) color data
82	DAC_MCK	AUDIODAC	DAC external master clock input

Table 13-2 Pin function description *(continued)*

Sl. No.	Pin	Module	Description
83	DAC_AOUTS_x	AUDIODAC	DAC output signal, x-left (L) or right (R) signal
84	DAC_COM_x	AUDIODAC	DAC common signal, x-left (L) or right (R) signal
85	MIPI_DPx	VIDEO	MIPI CSI-2 positive Data-Y input signal
86	MIPI_DNx	VIDEO	MIPI CSI-2 negative Data-Y input signal
87	MIPI_CKP	VIDEO	MIPI CSI-2 positive clock input signal
88	MIPI_CKN	VIDEO	MIPI CSI-2 negative clock input signal
89	MIPI_REXT	VIDEO	MIPI CSI-2 external reference resistor pin for auto-calibration
90	FPDx_TyP	VIDEO	FPD-link positive transmit signal, x-FPD instance, y-(0-3/A-C) output signal
91	FPDx_TyN	VIDEO	FPD-link negative transmit signal, x-FPD instance, y-(0-3/A-C) output signal
92	FPDx_TCLKP	VIDEO	FPD-link positive clock signal, x-FPD instance
93	FPDx_TCLKN	VIDEO	FPD-link negative clock signal, x-FPD instance

14 Interrupts and wake-up assignments

Table 14-1 Peripheral interrupt assignments and wake-up sources

Interrupt	Source	Power mode	Description
0	cpuss_interrupts_ipc_0_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #0
1	cpuss_interrupts_ipc_1_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #1
2	cpuss_interrupts_ipc_2_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #2
3	cpuss_interrupts_ipc_3_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #3
4	cpuss_interrupts_ipc_4_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #4
5	cpuss_interrupts_ipc_5_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #5
6	cpuss_interrupts_ipc_6_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #6
7	cpuss_interrupts_ipc_7_IRQn	DeepSleep	CPUSS Inter Process Communication Interrupt #7
8	cpuss_interrupts_fault_0_IRQn	DeepSleep	CPUSS Fault Structure #0 Interrupt
9	cpuss_interrupts_fault_1_IRQn	DeepSleep	CPUSS Fault Structure #1 Interrupt
10	cpuss_interrupts_fault_2_IRQn	DeepSleep	CPUSS Fault Structure #2 Interrupt
11	cpuss_interrupts_fault_3_IRQn	DeepSleep	CPUSS Fault Structure #3 Interrupt
12	srss_interrupt_backup_IRQn	DeepSleep	BACKUP domain Interrupt
13	srss_interrupt_mcwdt_0_IRQn	DeepSleep	Multi Counter Watchdog Timer#0 interrupt
14	srss_interrupt_mcwdt_1_IRQn	DeepSleep	Multi Counter Watchdog Timer#1 interrupt
17	srss_interrupt_wdt_IRQn	DeepSleep	Hardware Watchdog Timer interrupt
18	srss_interrupt_IRQn	DeepSleep	Other combined Interrupts for SRSS (LVD, CLKCAL)
19	evtgen_0_interrupt_dpssp_IRQn	DeepSleep	Event gen DeepSleep domain interrupt
20	scb_0_interrupt_IRQn	DeepSleep	SCB0 interrupt (DeepSleep capable)
22	ioss_interrupt_vdd_IRQn	DeepSleep	I/O Supply (VDDIO, VDDA_ADC, VDDD) state change Interrupt
23	ioss_interrupt_gpio_dpssp_IRQn	DeepSleep	Consolidated Interrupt for GPIO*, All Ports
24	ioss_interrupts_gpio_dpssp_0_IRQn	DeepSleep	GPIO_STD Port #0 Interrupt
25	ioss_interrupts_gpio_dpssp_1_IRQn	DeepSleep	GPIO_STD Port #1 Interrupt
26	ioss_interrupts_gpio_dpssp_2_IRQn	DeepSleep	GPIO_STD Port #2 Interrupt
27	ioss_interrupts_gpio_dpssp_3_IRQn	DeepSleep	GPIO_STD Port #3 Interrupt
28	ioss_interrupts_gpio_dpssp_4_IRQn	DeepSleep	GPIO_STD Port #4 Interrupt
29	ioss_interrupts_gpio_dpssp_5_IRQn	DeepSleep	GPIO_STD Port #5 Interrupt
30	ioss_interrupts_gpio_dpssp_6_IRQn	DeepSleep	GPIO_STD Port #6 Interrupt
31	ioss_interrupts_gpio_dpssp_7_IRQn	DeepSleep	GPIO_SMC Port #7 Interrupt
32	ioss_interrupts_gpio_dpssp_8_IRQn	DeepSleep	GPIO_SMC Port #8 Interrupt
33	ioss_interrupts_gpio_dpssp_9_IRQn	DeepSleep	GPIO_SMC Port #9 Interrupt
50	ioss_interrupt_gpio_act_IRQn	Active	Consolidated Interrupt for HSIO*, All Ports
52	ioss_interrupts_gpio_act_11_IRQn	Active	HSIO_STDLN Port Interrupt #11 Interrupt
53	ioss_interrupts_gpio_act_12_IRQn	Active	HSIO_STDLN Port Interrupt #12 Interrupt
54	ioss_interrupts_gpio_act_13_IRQn	Active	HSIO_STDLN Port Interrupt #13 Interrupt
55	ioss_interrupts_gpio_act_14_IRQn	Active	HSIO_STDLN Port Interrupt #14 Interrupt
56	ioss_interrupts_gpio_act_15_IRQn	Active	HSIO_STDLN Port Interrupt #15 Interrupt
57	ioss_interrupts_gpio_act_16_IRQn	Active	HSIO_STDLN Port Interrupt #16 Interrupt
58	ioss_interrupts_gpio_act_17_IRQn	Active	HSIO_STDLN Port Interrupt #17 Interrupt
59	ioss_interrupts_gpio_act_18_IRQn	Active	HSIO_STDLN Port Interrupt #18 Interrupt

Table 14-1 Peripheral interrupt assignments and wake-up sources *(continued)*

Interrupt	Source	Power mode	Description
60	ioss_interrupts_gpio_act_19_IRQn	Active	HSIO_STDLN Port Interrupt #19 Interrupt
61	ioss_interrupts_gpio_act_20_IRQn	Active	HSIO_STDLN Port Interrupt #20 Interrupt
62	ioss_interrupts_gpio_act_21_IRQn	Active	HSIO_STDLN Port Interrupt #21 Interrupt
70	cpuss_interrupt_crypto_IRQn	Active	Crypto Accelerator Interrupt
71	cpuss_interrupt_fm_IRQn	Active	FLASH Macro Interrupt
72	cpuss_interrupts_cm7_0_fp_IRQn	Active	CM7_0 Floating Point operation fault
74	cpuss_interrupts_cm0_cti_0_IRQn	Active	CM0+ CTI (Cross Trigger Interface) #0
75	cpuss_interrupts_cm0_cti_1_IRQn	Active	CM0+ CTI #1
76	cpuss_interrupts_cm7_0_cti_0_IRQn	Active	CM7_0 CTI #0
77	cpuss_interrupts_cm7_0_cti_1_IRQn	Active	CM7_0 CTI #1
80	evtgen_0_interrupt_IRQn	Active	Event gen Active domain interrupt
81	smif_0_interrupt_IRQn	Active	SMIF #0 (QSPI) interrupt
82	smif_1_interrupt_IRQn	Active	SMIF #1 (QSPI) interrupt
83	eth_0_interrupt_eth_0_IRQn	Active	Ethernet #0 priority queue[0]
84	eth_0_interrupt_eth_1_IRQn	Active	Ethernet #0 priority queue[1]
85	eth_0_interrupt_eth_2_IRQn	Active	Ethernet #0 priority queue[2]
86	canfd_0_interrupt0_IRQn	Active	CAN0, Consolidated interrupt #0 for all channels
87	canfd_0_interrupt1_IRQn	Active	CAN0, Consolidated interrupt #1 for all channels
88	canfd_1_interrupt0_IRQn	Active	CAN1, Consolidated interrupt #0 for all channels
89	canfd_1_interrupt1_IRQn	Active	CAN1, Consolidated interrupt #1 for all channels
90	canfd_0_interrupts0_0_IRQn	Active	CAN0, Interrupt #0, Channel #0
91	canfd_0_interrupts0_1_IRQn	Active	CAN0, Interrupt #0, Channel #1
96	canfd_0_interrupts1_0_IRQn	Active	CAN0, Interrupt #1, Channel #0
97	canfd_0_interrupts1_1_IRQn	Active	CAN0, Interrupt #1, Channel #1
102	canfd_1_interrupts0_0_IRQn	Active	CAN1, Interrupt #0, Channel #0
103	canfd_1_interrupts0_1_IRQn	Active	CAN1, Interrupt #0, Channel #1
108	canfd_1_interrupts1_0_IRQn	Active	CAN1, Interrupt #1, Channel #0
109	canfd_1_interrupts1_1_IRQn	Active	CAN1, Interrupt #1, Channel #1
114	lin_0_interrupts_0_IRQn	Active	LIN0 Channel #0 Interrupt
115	lin_0_interrupts_1_IRQn	Active	LIN0 Channel #1 Interrupt
130	cxpi_0_interrupts_0_IRQn	Active	CXPI0 Channel #0 Interrupt
131	cxpi_0_interrupts_1_IRQn	Active	CXPI0 Channel #1 Interrupt
135	scb_1_interrupt_IRQn	Active	SCB1 Interrupt
136	scb_2_interrupt_IRQn	Active	SCB2 Interrupt
137	scb_3_interrupt_IRQn	Active	SCB3 Interrupt
138	scb_4_interrupt_IRQn	Active	SCB4 Interrupt
139	scb_5_interrupt_IRQn	Active	SCB5 Interrupt
140	scb_6_interrupt_IRQn	Active	SCB6 Interrupt
141	scb_7_interrupt_IRQn	Active	SCB7 Interrupt
142	scb_8_interrupt_IRQn	Active	SCB8 Interrupt
143	scb_9_interrupt_IRQn	Active	SCB9 Interrupt
144	scb_10_interrupt_IRQn	Active	SCB10 Interrupt
145	scb_11_interrupt_IRQn	Active	SCB11 Interrupt

Table 14-1 Peripheral interrupt assignments and wake-up sources *(continued)*

Interrupt	Source	Power mode	Description
150	videoss_0_interrupt_gfx2d_IRQn	Active	GFX2D Interrupt
151	videoss_0_interrupt_mipicsi_IRQn	Active	MIPICSI Interrupt
152	videoss_0_interrupt_videoio0_IRQn	Active	VIDEOSS I/O Interrupt #0
153	videoss_0_interrupt_videoio1_IRQn	Active	VIDEOSS I/O Interrupt #1
154	videoss_0_interrupt_videoio0_safety	Active	VIDEOSS I/O Safety Interrupt #0
155	videoss_0_interrupt_videoio1_safety	Active	VIDEOSS I/O Safety Interrupt #1
160	pass_0_interrupts_sar_0_IRQn	Active	SAR0, Logical Channel #0 Interrupt
161	pass_0_interrupts_sar_1_IRQn	Active	SAR0, Logical Channel #1 Interrupt
162	pass_0_interrupts_sar_2_IRQn	Active	SAR0, Logical Channel #2 Interrupt
163	pass_0_interrupts_sar_3_IRQn	Active	SAR0, Logical Channel #3 Interrupt
164	pass_0_interrupts_sar_4_IRQn	Active	SAR0, Logical Channel #4 Interrupt
165	pass_0_interrupts_sar_5_IRQn	Active	SAR0, Logical Channel #5 Interrupt
166	pass_0_interrupts_sar_6_IRQn	Active	SAR0, Logical Channel #6 Interrupt
167	pass_0_interrupts_sar_7_IRQn	Active	SAR0, Logical Channel #7 Interrupt
168	pass_0_interrupts_sar_8_IRQn	Active	SAR0, Logical Channel #8 Interrupt
169	pass_0_interrupts_sar_9_IRQn	Active	SAR0, Logical Channel #9 Interrupt
170	pass_0_interrupts_sar_10_IRQn	Active	SAR0, Logical Channel #10 Interrupt
171	pass_0_interrupts_sar_11_IRQn	Active	SAR0, Logical Channel #11 Interrupt
172	pass_0_interrupts_sar_12_IRQn	Active	SAR0, Logical Channel #12 Interrupt
173	pass_0_interrupts_sar_13_IRQn	Active	SAR0, Logical Channel #13 Interrupt
174	pass_0_interrupts_sar_14_IRQn	Active	SAR0, Logical Channel #14 Interrupt
175	pass_0_interrupts_sar_15_IRQn	Active	SAR0, Logical Channel #15 Interrupt
176	pass_0_interrupts_sar_16_IRQn	Active	SAR0, Logical Channel #16 Interrupt
177	pass_0_interrupts_sar_17_IRQn	Active	SAR0, Logical Channel #17 Interrupt
178	pass_0_interrupts_sar_18_IRQn	Active	SAR0, Logical Channel #18 Interrupt
179	pass_0_interrupts_sar_19_IRQn	Active	SAR0, Logical Channel #19 Interrupt
180	pass_0_interrupts_sar_20_IRQn	Active	SAR0, Logical Channel #20 Interrupt
181	pass_0_interrupts_sar_21_IRQn	Active	SAR0, Logical Channel #21 Interrupt
182	pass_0_interrupts_sar_22_IRQn	Active	SAR0, Logical Channel #22 Interrupt
183	pass_0_interrupts_sar_23_IRQn	Active	SAR0, Logical Channel #23 Interrupt
184	pass_0_interrupts_sar_24_IRQn	Active	SAR0, Logical Channel #24 Interrupt
185	pass_0_interrupts_sar_25_IRQn	Active	SAR0, Logical Channel #25 Interrupt
186	pass_0_interrupts_sar_26_IRQn	Active	SAR0, Logical Channel #26 Interrupt
187	pass_0_interrupts_sar_27_IRQn	Active	SAR0, Logical Channel #27 Interrupt
188	pass_0_interrupts_sar_28_IRQn	Active	SAR0, Logical Channel #28 Interrupt
189	pass_0_interrupts_sar_29_IRQn	Active	SAR0, Logical Channel #29 Interrupt
190	pass_0_interrupts_sar_30_IRQn	Active	SAR0, Logical Channel #30 Interrupt
191	pass_0_interrupts_sar_31_IRQn	Active	SAR0, Logical Channel #31 Interrupt
280	axi_dmac_0_interrupts_0_IRQn	Active	AXI M-DMA1, Channel#0 Interrupt
281	axi_dmac_0_interrupts_1_IRQn	Active	AXI M-DMA1, Channel#1 Interrupt
282	axi_dmac_0_interrupts_2_IRQn	Active	AXI M-DMA1, Channel#2 Interrupt
283	axi_dmac_0_interrupts_3_IRQn	Active	AXI M-DMA1, Channel#3 Interrupt
288	cpuss_interrupts_dmac_0_IRQn	Active	CPUSS M-DMA0, Channel #0 Interrupt

Table 14-1 Peripheral interrupt assignments and wake-up sources *(continued)*

Interrupt	Source	Power mode	Description
289	cpuss_interrupts_dmac_1_IRQn	Active	CPUSS M-DMA0, Channel #1 Interrupt
290	cpuss_interrupts_dmac_2_IRQn	Active	CPUSS M-DMA0, Channel #2 Interrupt
291	cpuss_interrupts_dmac_3_IRQn	Active	CPUSS M-DMA0, Channel #3 Interrupt
292	cpuss_interrupts_dmac_4_IRQn	Active	CPUSS M-DMA0, Channel #4 Interrupt
293	cpuss_interrupts_dmac_5_IRQn	Active	CPUSS M-DMA0, Channel #5 Interrupt
294	cpuss_interrupts_dmac_6_IRQn	Active	CPUSS M-DMA0, Channel #6 Interrupt
295	cpuss_interrupts_dmac_7_IRQn	Active	CPUSS M-DMA0, Channel #7 Interrupt
296	cpuss_interrupts_dw0_0_IRQn	Active	CPUSS P-DMA0, Channel #0 Interrupt
297	cpuss_interrupts_dw0_1_IRQn	Active	CPUSS P-DMA0, Channel #1 Interrupt
298	cpuss_interrupts_dw0_2_IRQn	Active	CPUSS P-DMA0, Channel #2 Interrupt
299	cpuss_interrupts_dw0_3_IRQn	Active	CPUSS P-DMA0, Channel #3 Interrupt
300	cpuss_interrupts_dw0_4_IRQn	Active	CPUSS P-DMA0, Channel #4 Interrupt
301	cpuss_interrupts_dw0_5_IRQn	Active	CPUSS P-DMA0, Channel #5 Interrupt
302	cpuss_interrupts_dw0_6_IRQn	Active	CPUSS P-DMA0, Channel #6 Interrupt
303	cpuss_interrupts_dw0_7_IRQn	Active	CPUSS P-DMA0, Channel #7 Interrupt
304	cpuss_interrupts_dw0_8_IRQn	Active	CPUSS P-DMA0, Channel #8 Interrupt
305	cpuss_interrupts_dw0_9_IRQn	Active	CPUSS P-DMA0, Channel #9 Interrupt
306	cpuss_interrupts_dw0_10_IRQn	Active	CPUSS P-DMA0, Channel #10 Interrupt
307	cpuss_interrupts_dw0_11_IRQn	Active	CPUSS P-DMA0, Channel #11 Interrupt
308	cpuss_interrupts_dw0_12_IRQn	Active	CPUSS P-DMA0, Channel #12 Interrupt
309	cpuss_interrupts_dw0_13_IRQn	Active	CPUSS P-DMA0, Channel #13 Interrupt
310	cpuss_interrupts_dw0_14_IRQn	Active	CPUSS P-DMA0, Channel #14 Interrupt
311	cpuss_interrupts_dw0_15_IRQn	Active	CPUSS P-DMA0, Channel #15 Interrupt
312	cpuss_interrupts_dw0_16_IRQn	Active	CPUSS P-DMA0, Channel #16 Interrupt
313	cpuss_interrupts_dw0_17_IRQn	Active	CPUSS P-DMA0, Channel #17 Interrupt
314	cpuss_interrupts_dw0_18_IRQn	Active	CPUSS P-DMA0, Channel #18 Interrupt
315	cpuss_interrupts_dw0_19_IRQn	Active	CPUSS P-DMA0, Channel #19 Interrupt
316	cpuss_interrupts_dw0_20_IRQn	Active	CPUSS P-DMA0, Channel #20 Interrupt
317	cpuss_interrupts_dw0_21_IRQn	Active	CPUSS P-DMA0, Channel #21 Interrupt
318	cpuss_interrupts_dw0_22_IRQn	Active	CPUSS P-DMA0, Channel #22 Interrupt
319	cpuss_interrupts_dw0_23_IRQn	Active	CPUSS P-DMA0, Channel #23 Interrupt
320	cpuss_interrupts_dw0_24_IRQn	Active	CPUSS P-DMA0, Channel #24 Interrupt
321	cpuss_interrupts_dw0_25_IRQn	Active	CPUSS P-DMA0, Channel #25 Interrupt
322	cpuss_interrupts_dw0_26_IRQn	Active	CPUSS P-DMA0, Channel #26 Interrupt
323	cpuss_interrupts_dw0_27_IRQn	Active	CPUSS P-DMA0, Channel #27 Interrupt
324	cpuss_interrupts_dw0_28_IRQn	Active	CPUSS P-DMA0, Channel #28 Interrupt
325	cpuss_interrupts_dw0_29_IRQn	Active	CPUSS P-DMA0, Channel #29 Interrupt
326	cpuss_interrupts_dw0_30_IRQn	Active	CPUSS P-DMA0, Channel #30 Interrupt
327	cpuss_interrupts_dw0_31_IRQn	Active	CPUSS P-DMA0, Channel #31 Interrupt
328	cpuss_interrupts_dw0_32_IRQn	Active	CPUSS P-DMA0, Channel #32 Interrupt
329	cpuss_interrupts_dw0_33_IRQn	Active	CPUSS P-DMA0, Channel #33 Interrupt
330	cpuss_interrupts_dw0_34_IRQn	Active	CPUSS P-DMA0, Channel #34 Interrupt
331	cpuss_interrupts_dw0_35_IRQn	Active	CPUSS P-DMA0, Channel #35 Interrupt

Table 14-1 Peripheral interrupt assignments and wake-up sources *(continued)*

Interrupt	Source	Power mode	Description
332	cpuss_interrupts_dw0_36_IRQn	Active	CPUSS P-DMA0, Channel #36 Interrupt
333	cpuss_interrupts_dw0_37_IRQn	Active	CPUSS P-DMA0, Channel #37 Interrupt
334	cpuss_interrupts_dw0_38_IRQn	Active	CPUSS P-DMA0, Channel #38 Interrupt
335	cpuss_interrupts_dw0_39_IRQn	Active	CPUSS P-DMA0, Channel #39 Interrupt
336	cpuss_interrupts_dw0_40_IRQn	Active	CPUSS P-DMA0, Channel #40 Interrupt
337	cpuss_interrupts_dw0_41_IRQn	Active	CPUSS P-DMA0, Channel #41 Interrupt
338	cpuss_interrupts_dw0_42_IRQn	Active	CPUSS P-DMA0, Channel #42 Interrupt
339	cpuss_interrupts_dw0_43_IRQn	Active	CPUSS P-DMA0, Channel #43 Interrupt
340	cpuss_interrupts_dw0_44_IRQn	Active	CPUSS P-DMA0, Channel #44 Interrupt
341	cpuss_interrupts_dw0_45_IRQn	Active	CPUSS P-DMA0, Channel #45 Interrupt
342	cpuss_interrupts_dw0_46_IRQn	Active	CPUSS P-DMA0, Channel #46 Interrupt
343	cpuss_interrupts_dw0_47_IRQn	Active	CPUSS P-DMA0, Channel #47 Interrupt
344	cpuss_interrupts_dw0_48_IRQn	Active	CPUSS P-DMA0, Channel #48 Interrupt
345	cpuss_interrupts_dw0_49_IRQn	Active	CPUSS P-DMA0, Channel #49 Interrupt
346	cpuss_interrupts_dw0_50_IRQn	Active	CPUSS P-DMA0, Channel #50 Interrupt
347	cpuss_interrupts_dw0_51_IRQn	Active	CPUSS P-DMA0, Channel #51 Interrupt
348	cpuss_interrupts_dw0_52_IRQn	Active	CPUSS P-DMA0, Channel #52 Interrupt
349	cpuss_interrupts_dw0_53_IRQn	Active	CPUSS P-DMA0, Channel #53 Interrupt
350	cpuss_interrupts_dw0_54_IRQn	Active	CPUSS P-DMA0, Channel #54 Interrupt
351	cpuss_interrupts_dw0_55_IRQn	Active	CPUSS P-DMA0, Channel #55 Interrupt
352	cpuss_interrupts_dw0_56_IRQn	Active	CPUSS P-DMA0, Channel #56 Interrupt
353	cpuss_interrupts_dw0_57_IRQn	Active	CPUSS P-DMA0, Channel #57 Interrupt
354	cpuss_interrupts_dw0_58_IRQn	Active	CPUSS P-DMA0, Channel #58 Interrupt
355	cpuss_interrupts_dw0_59_IRQn	Active	CPUSS P-DMA0, Channel #59 Interrupt
356	cpuss_interrupts_dw0_60_IRQn	Active	CPUSS P-DMA0, Channel #60 Interrupt
357	cpuss_interrupts_dw0_61_IRQn	Active	CPUSS P-DMA0, Channel #61 Interrupt
358	cpuss_interrupts_dw0_62_IRQn	Active	CPUSS P-DMA0, Channel #62 Interrupt
359	cpuss_interrupts_dw0_63_IRQn	Active	CPUSS P-DMA0, Channel #63 Interrupt
360	cpuss_interrupts_dw0_64_IRQn	Active	CPUSS P-DMA0, Channel #64 Interrupt
361	cpuss_interrupts_dw0_65_IRQn	Active	CPUSS P-DMA0, Channel #65 Interrupt
362	cpuss_interrupts_dw0_66_IRQn	Active	CPUSS P-DMA0, Channel #66 Interrupt
363	cpuss_interrupts_dw0_67_IRQn	Active	CPUSS P-DMA0, Channel #67 Interrupt
364	cpuss_interrupts_dw0_68_IRQn	Active	CPUSS P-DMA0, Channel #68 Interrupt
365	cpuss_interrupts_dw0_69_IRQn	Active	CPUSS P-DMA0, Channel #69 Interrupt
366	cpuss_interrupts_dw0_70_IRQn	Active	CPUSS P-DMA0, Channel #70 Interrupt
367	cpuss_interrupts_dw0_71_IRQn	Active	CPUSS P-DMA0, Channel #71 Interrupt
368	cpuss_interrupts_dw0_72_IRQn	Active	CPUSS P-DMA0, Channel #72 Interrupt
369	cpuss_interrupts_dw0_73_IRQn	Active	CPUSS P-DMA0, Channel #73 Interrupt
370	cpuss_interrupts_dw0_74_IRQn	Active	CPUSS P-DMA0, Channel #74 Interrupt
371	cpuss_interrupts_dw0_75_IRQn	Active	CPUSS P-DMA0, Channel #75 Interrupt
424	cpuss_interrupts_dw1_0_IRQn	Active	CPUSS P-DMA1, Channel #0 Interrupt
425	cpuss_interrupts_dw1_1_IRQn	Active	CPUSS P-DMA1, Channel #1 Interrupt
426	cpuss_interrupts_dw1_2_IRQn	Active	CPUSS P-DMA1, Channel #2 Interrupt

Table 14-1 Peripheral interrupt assignments and wake-up sources *(continued)*

Interrupt	Source	Power mode	Description
427	cpuss_interrupts_dw1_3_IRQn	Active	CPUSS P-DMA1, Channel #3 Interrupt
428	cpuss_interrupts_dw1_4_IRQn	Active	CPUSS P-DMA1, Channel #4 Interrupt
429	cpuss_interrupts_dw1_5_IRQn	Active	CPUSS P-DMA1, Channel #5 Interrupt
430	cpuss_interrupts_dw1_6_IRQn	Active	CPUSS P-DMA1, Channel #6 Interrupt
431	cpuss_interrupts_dw1_7_IRQn	Active	CPUSS P-DMA1, Channel #7 Interrupt
432	cpuss_interrupts_dw1_8_IRQn	Active	CPUSS P-DMA1, Channel #8 Interrupt
433	cpuss_interrupts_dw1_9_IRQn	Active	CPUSS P-DMA1, Channel #9 Interrupt
434	cpuss_interrupts_dw1_10_IRQn	Active	CPUSS P-DMA1, Channel #10 Interrupt
435	cpuss_interrupts_dw1_11_IRQn	Active	CPUSS P-DMA1, Channel #11 Interrupt
436	cpuss_interrupts_dw1_12_IRQn	Active	CPUSS P-DMA1, Channel #12 Interrupt
437	cpuss_interrupts_dw1_13_IRQn	Active	CPUSS P-DMA1, Channel #13 Interrupt
438	cpuss_interrupts_dw1_14_IRQn	Active	CPUSS P-DMA1, Channel #14 Interrupt
439	cpuss_interrupts_dw1_15_IRQn	Active	CPUSS P-DMA1, Channel #15 Interrupt
440	cpuss_interrupts_dw1_16_IRQn	Active	CPUSS P-DMA1, Channel #16 Interrupt
441	cpuss_interrupts_dw1_17_IRQn	Active	CPUSS P-DMA1, Channel #17 Interrupt
442	cpuss_interrupts_dw1_18_IRQn	Active	CPUSS P-DMA1, Channel #18 Interrupt
443	cpuss_interrupts_dw1_19_IRQn	Active	CPUSS P-DMA1, Channel #19 Interrupt
444	cpuss_interrupts_dw1_20_IRQn	Active	CPUSS P-DMA1, Channel #20 Interrupt
445	cpuss_interrupts_dw1_21_IRQn	Active	CPUSS P-DMA1, Channel #21 Interrupt
446	cpuss_interrupts_dw1_22_IRQn	Active	CPUSS P-DMA1, Channel #22 Interrupt
447	cpuss_interrupts_dw1_23_IRQn	Active	CPUSS P-DMA1, Channel #23 Interrupt
448	cpuss_interrupts_dw1_24_IRQn	Active	CPUSS P-DMA1, Channel #24 Interrupt
449	cpuss_interrupts_dw1_25_IRQn	Active	CPUSS P-DMA1, Channel #25 Interrupt
450	cpuss_interrupts_dw1_26_IRQn	Active	CPUSS P-DMA1, Channel #26 Interrupt
451	cpuss_interrupts_dw1_27_IRQn	Active	CPUSS P-DMA1, Channel #27 Interrupt
452	cpuss_interrupts_dw1_28_IRQn	Active	CPUSS P-DMA1, Channel #28 Interrupt
453	cpuss_interrupts_dw1_29_IRQn	Active	CPUSS P-DMA1, Channel #29 Interrupt
454	cpuss_interrupts_dw1_30_IRQn	Active	CPUSS P-DMA1, Channel #30 Interrupt
455	cpuss_interrupts_dw1_31_IRQn	Active	CPUSS P-DMA1, Channel #31 Interrupt
456	cpuss_interrupts_dw1_32_IRQn	Active	CPUSS P-DMA1, Channel #32 Interrupt
457	cpuss_interrupts_dw1_33_IRQn	Active	CPUSS P-DMA1, Channel #33 Interrupt
458	cpuss_interrupts_dw1_34_IRQn	Active	CPUSS P-DMA1, Channel #34 Interrupt
459	cpuss_interrupts_dw1_35_IRQn	Active	CPUSS P-DMA1, Channel #35 Interrupt
460	cpuss_interrupts_dw1_36_IRQn	Active	CPUSS P-DMA1, Channel #36 Interrupt
461	cpuss_interrupts_dw1_37_IRQn	Active	CPUSS P-DMA1, Channel #37 Interrupt
462	cpuss_interrupts_dw1_38_IRQn	Active	CPUSS P-DMA1, Channel #38 Interrupt
463	cpuss_interrupts_dw1_39_IRQn	Active	CPUSS P-DMA1, Channel #39 Interrupt
464	cpuss_interrupts_dw1_40_IRQn	Active	CPUSS P-DMA1, Channel #40 Interrupt
465	cpuss_interrupts_dw1_41_IRQn	Active	CPUSS P-DMA1, Channel #41 Interrupt
466	cpuss_interrupts_dw1_42_IRQn	Active	CPUSS P-DMA1, Channel #42 Interrupt
467	cpuss_interrupts_dw1_43_IRQn	Active	CPUSS P-DMA1, Channel #43 Interrupt
468	cpuss_interrupts_dw1_44_IRQn	Active	CPUSS P-DMA1, Channel #44 Interrupt
469	cpuss_interrupts_dw1_45_IRQn	Active	CPUSS P-DMA1, Channel #45 Interrupt

Table 14-1 Peripheral interrupt assignments and wake-up sources *(continued)*

Interrupt	Source	Power mode	Description
470	cpuss_interrupts_dw1_46_IRQn	Active	CPUSS P-DMA1, Channel #46 Interrupt
471	cpuss_interrupts_dw1_47_IRQn	Active	CPUSS P-DMA1, Channel #47 Interrupt
472	cpuss_interrupts_dw1_48_IRQn	Active	CPUSS P-DMA1, Channel #48 Interrupt
473	cpuss_interrupts_dw1_49_IRQn	Active	CPUSS P-DMA1, Channel #49 Interrupt
474	cpuss_interrupts_dw1_50_IRQn	Active	CPUSS P-DMA1, Channel #50 Interrupt
475	cpuss_interrupts_dw1_51_IRQn	Active	CPUSS P-DMA1, Channel #51 Interrupt
476	cpuss_interrupts_dw1_52_IRQn	Active	CPUSS P-DMA1, Channel #52 Interrupt
477	cpuss_interrupts_dw1_53_IRQn	Active	CPUSS P-DMA1, Channel #53 Interrupt
478	cpuss_interrupts_dw1_54_IRQn	Active	CPUSS P-DMA1, Channel #54 Interrupt
479	cpuss_interrupts_dw1_55_IRQn	Active	CPUSS P-DMA1, Channel #55 Interrupt
480	cpuss_interrupts_dw1_56_IRQn	Active	CPUSS P-DMA1, Channel #56 Interrupt
481	cpuss_interrupts_dw1_57_IRQn	Active	CPUSS P-DMA1, Channel #57 Interrupt
482	cpuss_interrupts_dw1_58_IRQn	Active	CPUSS P-DMA1, Channel #58 Interrupt
483	cpuss_interrupts_dw1_59_IRQn	Active	CPUSS P-DMA1, Channel #59 Interrupt
484	cpuss_interrupts_dw1_60_IRQn	Active	CPUSS P-DMA1, Channel #60 Interrupt
485	cpuss_interrupts_dw1_61_IRQn	Active	CPUSS P-DMA1, Channel #61 Interrupt
486	cpuss_interrupts_dw1_62_IRQn	Active	CPUSS P-DMA1, Channel #62 Interrupt
487	cpuss_interrupts_dw1_63_IRQn	Active	CPUSS P-DMA1, Channel #63 Interrupt
488	cpuss_interrupts_dw1_64_IRQn	Active	CPUSS P-DMA1, Channel #64 Interrupt
489	cpuss_interrupts_dw1_65_IRQn	Active	CPUSS P-DMA1, Channel #65 Interrupt
490	cpuss_interrupts_dw1_66_IRQn	Active	CPUSS P-DMA1, Channel #66 Interrupt
491	cpuss_interrupts_dw1_67_IRQn	Active	CPUSS P-DMA1, Channel #67 Interrupt
492	cpuss_interrupts_dw1_68_IRQn	Active	CPUSS P-DMA1, Channel #68 Interrupt
493	cpuss_interrupts_dw1_69_IRQn	Active	CPUSS P-DMA1, Channel #69 Interrupt
494	cpuss_interrupts_dw1_70_IRQn	Active	CPUSS P-DMA1, Channel #70 Interrupt
495	cpuss_interrupts_dw1_71_IRQn	Active	CPUSS P-DMA1, Channel #71 Interrupt
496	cpuss_interrupts_dw1_72_IRQn	Active	CPUSS P-DMA1, Channel #72 Interrupt
497	cpuss_interrupts_dw1_73_IRQn	Active	CPUSS P-DMA1, Channel #73 Interrupt
498	cpuss_interrupts_dw1_74_IRQn	Active	CPUSS P-DMA1, Channel #74 Interrupt
499	cpuss_interrupts_dw1_75_IRQn	Active	CPUSS P-DMA1, Channel #75 Interrupt
500	cpuss_interrupts_dw1_76_IRQn	Active	CPUSS P-DMA1, Channel #76 Interrupt
501	cpuss_interrupts_dw1_77_IRQn	Active	CPUSS P-DMA1, Channel #77 Interrupt
502	cpuss_interrupts_dw1_78_IRQn	Active	CPUSS P-DMA1, Channel #78 Interrupt
503	cpuss_interrupts_dw1_79_IRQn	Active	CPUSS P-DMA1, Channel #79 Interrupt
504	cpuss_interrupts_dw1_80_IRQn	Active	CPUSS P-DMA1, Channel #80 Interrupt
505	cpuss_interrupts_dw1_81_IRQn	Active	CPUSS P-DMA1, Channel #81 Interrupt
506	cpuss_interrupts_dw1_82_IRQn	Active	CPUSS P-DMA1, Channel #82 Interrupt
507	cpuss_interrupts_dw1_83_IRQn	Active	CPUSS P-DMA1, Channel #83 Interrupt
552	tcpwm_0_interrupts_0_IRQn	Active	TCPWM0 Group #0, Counter #0 Interrupt
553	tcpwm_0_interrupts_1_IRQn	Active	TCPWM0 Group #0, Counter #1 Interrupt
554	tcpwm_0_interrupts_2_IRQn	Active	TCPWM0 Group #0, Counter #2 Interrupt
555	tcpwm_0_interrupts_3_IRQn	Active	TCPWM0 Group #0, Counter #3 Interrupt
556	tcpwm_0_interrupts_4_IRQn	Active	TCPWM0 Group #0, Counter #4 Interrupt

Table 14-1 Peripheral interrupt assignments and wake-up sources *(continued)*

Interrupt	Source	Power mode	Description
557	tcpwm_0_interrupts_5_IRQn	Active	TCPWM0 Group #0, Counter #5 Interrupt
558	tcpwm_0_interrupts_6_IRQn	Active	TCPWM0 Group #0, Counter #6 Interrupt
559	tcpwm_0_interrupts_7_IRQn	Active	TCPWM0 Group #0, Counter #7 Interrupt
560	tcpwm_0_interrupts_8_IRQn	Active	TCPWM0 Group #0, Counter #8 Interrupt
561	tcpwm_0_interrupts_9_IRQn	Active	TCPWM0 Group #0, Counter #9 Interrupt
562	tcpwm_0_interrupts_10_IRQn	Active	TCPWM0 Group #0, Counter #10 Interrupt
563	tcpwm_0_interrupts_11_IRQn	Active	TCPWM0 Group #0, Counter #11 Interrupt
564	tcpwm_0_interrupts_12_IRQn	Active	TCPWM0 Group #0, Counter #12 Interrupt
565	tcpwm_0_interrupts_13_IRQn	Active	TCPWM0 Group #0, Counter #13 Interrupt
566	tcpwm_0_interrupts_14_IRQn	Active	TCPWM0 Group #0, Counter #14 Interrupt
567	tcpwm_0_interrupts_15_IRQn	Active	TCPWM0 Group #0, Counter #15 Interrupt
568	tcpwm_0_interrupts_16_IRQn	Active	TCPWM0 Group #0, Counter #16 Interrupt
569	tcpwm_0_interrupts_17_IRQn	Active	TCPWM0 Group #0, Counter #17 Interrupt
570	tcpwm_0_interrupts_18_IRQn	Active	TCPWM0 Group #0, Counter #18 Interrupt
571	tcpwm_0_interrupts_19_IRQn	Active	TCPWM0 Group #0, Counter #19 Interrupt
572	tcpwm_0_interrupts_20_IRQn	Active	TCPWM0 Group #0, Counter #20 Interrupt
573	tcpwm_0_interrupts_21_IRQn	Active	TCPWM0 Group #0, Counter #21 Interrupt
574	tcpwm_0_interrupts_22_IRQn	Active	TCPWM0 Group #0, Counter #22 Interrupt
575	tcpwm_0_interrupts_23_IRQn	Active	TCPWM0 Group #0, Counter #23 Interrupt
576	tcpwm_0_interrupts_24_IRQn	Active	TCPWM0 Group #0, Counter #24 Interrupt
577	tcpwm_0_interrupts_25_IRQn	Active	TCPWM0 Group #0, Counter #25 Interrupt
578	tcpwm_0_interrupts_26_IRQn	Active	TCPWM0 Group #0, Counter #26 Interrupt
579	tcpwm_0_interrupts_27_IRQn	Active	TCPWM0 Group #0, Counter #27 Interrupt
580	tcpwm_0_interrupts_28_IRQn	Active	TCPWM0 Group #0, Counter #28 Interrupt
581	tcpwm_0_interrupts_29_IRQn	Active	TCPWM0 Group #0, Counter #29 Interrupt
582	tcpwm_0_interrupts_30_IRQn	Active	TCPWM0 Group #0, Counter #30 Interrupt
583	tcpwm_0_interrupts_31_IRQn	Active	TCPWM0 Group #0, Counter #31 Interrupt
584	tcpwm_0_interrupts_32_IRQn	Active	TCPWM0 Group #0, Counter #32 Interrupt
585	tcpwm_0_interrupts_33_IRQn	Active	TCPWM0 Group #0, Counter #33 Interrupt
586	tcpwm_0_interrupts_34_IRQn	Active	TCPWM0 Group #0, Counter #34 Interrupt
587	tcpwm_0_interrupts_35_IRQn	Active	TCPWM0 Group #0, Counter #35 Interrupt
588	tcpwm_0_interrupts_36_IRQn	Active	TCPWM0 Group #0, Counter #36 Interrupt
589	tcpwm_0_interrupts_37_IRQn	Active	TCPWM0 Group #0, Counter #37 Interrupt
616	tcpwm_0_interrupts_256_IRQn	Active	TCPWM0 Group #1, Counter #0 Interrupt
617	tcpwm_0_interrupts_257_IRQn	Active	TCPWM0 Group #1, Counter #1 Interrupt
618	tcpwm_0_interrupts_258_IRQn	Active	TCPWM0 Group #1, Counter #2 Interrupt
619	tcpwm_0_interrupts_259_IRQn	Active	TCPWM0 Group #1, Counter #3 Interrupt
620	tcpwm_0_interrupts_260_IRQn	Active	TCPWM0 Group #1, Counter #4 Interrupt
621	tcpwm_0_interrupts_261_IRQn	Active	TCPWM0 Group #1, Counter #5 Interrupt
622	tcpwm_0_interrupts_262_IRQn	Active	TCPWM0 Group #1, Counter #6 Interrupt
623	tcpwm_0_interrupts_263_IRQn	Active	TCPWM0 Group #1, Counter #7 Interrupt
624	tcpwm_0_interrupts_264_IRQn	Active	TCPWM0 Group #1, Counter #8 Interrupt
625	tcpwm_0_interrupts_265_IRQn	Active	TCPWM0 Group #1, Counter #9 Interrupt

Table 14-1 Peripheral interrupt assignments and wake-up sources *(continued)*

Interrupt	Source	Power mode	Description
626	tcpwm_0_interrupts_266_IRQn	Active	TCPWM0 Group #1, Counter #10 Interrupt
627	tcpwm_0_interrupts_267_IRQn	Active	TCPWM0 Group #1, Counter #11 Interrupt
680	tcpwm_0_interrupts_512_IRQn	Active	TCPWM0 Group #2, Counter #0 Interrupt
681	tcpwm_0_interrupts_513_IRQn	Active	TCPWM0 Group #2, Counter #1 Interrupt
682	tcpwm_0_interrupts_514_IRQn	Active	TCPWM0 Group #2, Counter #2 Interrupt
683	tcpwm_0_interrupts_515_IRQn	Active	TCPWM0 Group #2, Counter #3 Interrupt
684	tcpwm_0_interrupts_516_IRQn	Active	TCPWM0 Group #2, Counter #4 Interrupt
685	tcpwm_0_interrupts_517_IRQn	Active	TCPWM0 Group #2, Counter #5 Interrupt
686	tcpwm_0_interrupts_518_IRQn	Active	TCPWM0 Group #2, Counter #6 Interrupt
687	tcpwm_0_interrupts_519_IRQn	Active	TCPWM0 Group #2, Counter #7 Interrupt
688	tcpwm_0_interrupts_520_IRQn	Active	TCPWM0 Group #2, Counter #8 Interrupt
689	tcpwm_0_interrupts_521_IRQn	Active	TCPWM0 Group #2, Counter #9 Interrupt
690	tcpwm_0_interrupts_522_IRQn	Active	TCPWM0 Group #2, Counter #10 Interrupt
691	tcpwm_0_interrupts_523_IRQn	Active	TCPWM0 Group #2, Counter #11 Interrupt
692	tcpwm_0_interrupts_524_IRQn	Active	TCPWM0 Group #2, Counter #12 Interrupt
693	tcpwm_0_interrupts_525_IRQn	Active	TCPWM0 Group #2, Counter #13 Interrupt
694	tcpwm_0_interrupts_526_IRQn	Active	TCPWM0 Group #2, Counter #14 Interrupt
695	tcpwm_0_interrupts_527_IRQn	Active	TCPWM0 Group #2, Counter #15 Interrupt
696	tcpwm_0_interrupts_528_IRQn	Active	TCPWM0 Group #2, Counter #16 Interrupt
697	tcpwm_0_interrupts_529_IRQn	Active	TCPWM0 Group #2, Counter #17 Interrupt
698	tcpwm_0_interrupts_530_IRQn	Active	TCPWM0 Group #2, Counter #18 Interrupt
699	tcpwm_0_interrupts_531_IRQn	Active	TCPWM0 Group #2, Counter #19 Interrupt
700	tcpwm_0_interrupts_532_IRQn	Active	TCPWM0 Group #2, Counter #20 Interrupt
701	tcpwm_0_interrupts_533_IRQn	Active	TCPWM0 Group #2, Counter #21 Interrupt
702	tcpwm_0_interrupts_534_IRQn	Active	TCPWM0 Group #2, Counter #22 Interrupt
703	tcpwm_0_interrupts_535_IRQn	Active	TCPWM0 Group #2, Counter #23 Interrupt
704	tcpwm_0_interrupts_536_IRQn	Active	TCPWM0 Group #2, Counter #24 Interrupt
705	tcpwm_0_interrupts_537_IRQn	Active	TCPWM0 Group #2, Counter #25 Interrupt
706	tcpwm_0_interrupts_538_IRQn	Active	TCPWM0 Group #2, Counter #26 Interrupt
707	tcpwm_0_interrupts_539_IRQn	Active	TCPWM0 Group #2, Counter #27 Interrupt
708	tcpwm_0_interrupts_540_IRQn	Active	TCPWM0 Group #2, Counter #28 Interrupt
709	tcpwm_0_interrupts_541_IRQn	Active	TCPWM0 Group #2, Counter #29 Interrupt
710	tcpwm_0_interrupts_542_IRQn	Active	TCPWM0 Group #2, Counter #30 Interrupt
711	tcpwm_0_interrupts_543_IRQn	Active	TCPWM0 Group #2, Counter #31 Interrupt
752	tdm_0_interrupts_tx_0_IRQn	Active	TDM0 TX #0 Interrupt
753	tdm_0_interrupts_rx_0_IRQn	Active	TDM0 RX #0 Interrupt
754	tdm_0_interrupts_tx_1_IRQn	Active	TDM0 TX #1 Interrupt
755	tdm_0_interrupts_rx_1_IRQn	Active	TDM0 RX #1 Interrupt
756	tdm_0_interrupts_tx_2_IRQn	Active	TDM0 TX #2 Interrupt
757	tdm_0_interrupts_rx_2_IRQn	Active	TDM0 RX #2 Interrupt
758	tdm_0_interrupts_tx_3_IRQn	Active	TDM0 TX #3 Interrupt
759	tdm_0_interrupts_rx_3_IRQn	Active	TDM0 RX #3 Interrupt
760	sg_0_interrupts_0_IRQn	Active	SG0 #0 Interrupt

Table 14-1 Peripheral interrupt assignments and wake-up sources *(continued)*

Interrupt	Source	Power mode	Description
761	sg_0_interrupts_1_IRQn	Active	SG0 #1 Interrupt
762	sg_0_interrupts_2_IRQn	Active	SG0 #2 Interrupt
763	sg_0_interrupts_3_IRQn	Active	SG0 #3 Interrupt
764	sg_0_interrupts_4_IRQn	Active	SG0 #4 Interrupt
768	pwm_0_interrupts_0_IRQn	Active	PCM-PWM0 #0 Interrupt
769	pwm_0_interrupts_1_IRQn	Active	PCM-PWM0 #1 Interrupt
776	dac_0_interrupt_IRQn	Active	Audio DAC interrupt
780	mixer_0_interrupt_dst_IRQn	Active	MIXER0 Destination interrupt
781	mixer_0_interrupts_src_0_IRQn	Active	MIXER0 Source #0 Interrupt
782	mixer_0_interrupts_src_1_IRQn	Active	MIXER0 Source #1 Interrupt
783	mixer_0_interrupts_src_2_IRQn	Active	MIXER0 Source #2 Interrupt
784	mixer_0_interrupts_src_3_IRQn	Active	MIXER0 Source #3 Interrupt
785	mixer_0_interrupts_src_4_IRQn	Active	MIXER0 Source #4 Interrupt
789	mixer_1_interrupt_dst_IRQn	Active	MIXER1 Destination interrupt
790	mixer_1_interrupts_src_0_IRQn	Active	MIXER1 Source #0 Interrupt
791	mixer_1_interrupts_src_1_IRQn	Active	MIXER1 Source #1 Interrupt
792	mixer_1_interrupts_src_2_IRQn	Active	MIXER1 Source #2 Interrupt
793	mixer_1_interrupts_src_3_IRQn	Active	MIXER1 Source #3 Interrupt
794	mixer_1_interrupts_src_4_IRQn	Active	MIXER1 Source #4 Interrupt

15 Core interrupt types

Table 15-1 Core interrupt types

Interrupt	Source	Power Mode	Description
0	CPUIntIdx0_IRQn ^[37]	DeepSleep	CPU User Interrupt #0
1	CPUIntIdx1_IRQn ^[37]	DeepSleep	CPU User Interrupt #1
2	CPUIntIdx2_IRQn	DeepSleep	CPU User Interrupt #2
3	CPUIntIdx3_IRQn	DeepSleep	CPU User Interrupt #3
4	CPUIntIdx4_IRQn	DeepSleep	CPU User Interrupt #4
5	CPUIntIdx5_IRQn	DeepSleep	CPU User Interrupt #5
6	CPUIntIdx6_IRQn	DeepSleep	CPU User Interrupt #6
7	CPUIntIdx7_IRQn	DeepSleep	CPU User Interrupt #7
8	Internal0_IRQn	Active	Internal Software Interrupt #0
9	Internal1_IRQn	Active	Internal Software Interrupt #1
10	Internal2_IRQn	Active	Internal Software Interrupt #2
11	Internal3_IRQn	Active	Internal Software Interrupt #3
12	Internal4_IRQn	Active	Internal Software Interrupt #4
13	Internal5_IRQn	Active	Internal Software Interrupt #5
14	Internal6_IRQn	Active	Internal Software Interrupt #6
15	Internal7_IRQn	Active	Internal Software Interrupt #7

Note

37. User interrupt cannot be used for CM0+ application, as it is used internally by system calls. Note, this does not impact CM7 application.



38. The diagram shows only the TRIG_LABEL; the final trigger formation is based on the formula TRIG_{PREFIX(IN/OUT)}_{MUX-x}_{TRIG_LABEL} and the information provided in [Table 17-1](#), and [Table 18-1](#).

17 Triggers group inputs

Table 17-1 Trigger inputs

Input	Trigger Label (TRIG_LABEL)	Description
MUX Group 0: P-DMA0_0_15 trigger multiplexer		
1:32	PDMA0_TR_OUT[0:31]	Allow P-DMA0 to chain to itself. Channels 0 - 32 are general purpose channels available for chaining
33:48	PDMA1_TR_OUT[0:15]	Cross connections from P-DMA1 to P-DMA0, Channels 0-15 are used
49:56	MDMA_TR_OUT[0:7]	Cross connections from M-DMA0 to P-DMA0
57:58	CAN0_TT_TR_OUT[0:1]	CAN0 TT Sync Outputs
59:60	CAN1_TT_TR_OUT[0:1]	CAN1 TT Sync Outputs
61:84	HSIOM_IO_INPUT[0:23]	I/O Inputs
85:88	FAULT_TR_OUT[0:3]	Fault events
MUX Group 1: P-DMA0_16_31 trigger multiplexer		
1:38	TCPWM0_16_TR_OUT0[0:37]	16-bit TCPWM0 counters
39:50	TCPWM0_16M_TR_OUT0[0:11]	16-bit Motor enhanced TCPWM0 counters
51:82	TCPWM0_32_TR_OUT0[0:31]	32-bit TCPWM0 counters
83:84	PASS_GEN_TR_OUT[0:1]	PASS0 SAR events
85:86	CTI_TR_OUT[0:1]	Trace events
87:90	EVTGEN_TR_OUT[0:3]	Event generator triggers
MUX Group 2: P-DMA1_0_15 trigger multiplexer		
1:16	PDMA1_TR_OUT[0:15]	Allow P-DMA1 to chain to itself. Channels 0 - 15 are dedicated for chaining
17:48	PDMA0_TR_OUT[0:31]	Cross connections from P-DMA0 to P-DMA1, channels 0-31 are used.
49:72	HSIOM_IO_INPUT[24:47]	I/O Inputs
MUX Group 3: M-DMA0 trigger multiplexer		
1:8	TCPWM0_16_TR_OUT0[0:7]	16-bit TCPWM0 counters
9:16	TCPWM0_32_TR_OUT0[0:7]	32-bit TCPWM0 counters
17:20	AXIDMA_TR_OUT[0:3]	AXI M-DMA1 triggers
MUX Group 4: TCPWM0 Trigger multiplexer		
1:32	PDMA0_TR_OUT[0:31]	General purpose P-DMA0 triggers
33:48	PDMA1_TR_OUT[0:15]	General purpose P-DMA1 triggers
49:56	MDMA_TR_OUT[0:7]	M-DMA0 triggers
57:94	TCPWM0_16_TR_OUT0[0:37]	16-bit TCPWM0 counters
95:106	TCPWM0_16M_TR_OUT0[0:11]	16-bit Motor enhanced TCPWM0 counters
107:138	TCPWM0_32_TR_OUT0[0:31]	32-bit TCPWM0 counters
139	SMIF0_TX_TR_OUT	SMIF0 TX trigger
140	SMIF0_RX_TR_OUT	SMIF0 RX trigger
141	SMIF1_TX_TR_OUT	SMIF1 TX trigger
142	SMIF1_RX_TR_OUT	SMIF1 RX trigger
143:146	AXIDMA_TR_OUT[0:3]	AXI M-DMA1 triggers
151:154	TDM0_TX_TR_OUT[0:3]	TDM0 TX trigger
155:158	TDM0_RX_TR_OUT[0:3]	TDM0 RX trigger
159:163	SG0_TR_COMPLETE[0:4]	SG0 TX complete trigger
164:165	PWM0_TX_TR_OUT[0:1]	PCM-PWM0 TX trigger
166:170	MIXER0_TR_SRC_REQ_OUT[0:4]	MIXER0 SRC trigger
171	MIXER0_TR_DST_REQ_OUT	MIXER0 DST trigger
172:176	MIXER1_TR_SRC_REQ_OUT[0:4]	MIXER1 SRC trigger

Triggers group inputs

Table 17-1 Trigger inputs *(continued)*

Input	Trigger Label (TRIG_LABEL)	Description
177	MIXER1_TR_DST_REQ_OUT	MIXER1 DST trigger
178	AUDIODAC0_TX_TR_OUT	AUDIO DAC0 TX trigger
MUX Group 5: TCPWM0_20_31 Trigger multiplexer		
1:2	CAN0_DBG_TR_OUT[0:1]	CAN0 DMA events
3:4	CAN0_FIFO0_TR_OUT[0:1]	CAN0 FIFO0 events
5:6	CAN0_FIFO1_TR_OUT[0:1]	CAN0 FIFO1 events
7:8	CAN1_DBG_TR_OUT[0:1]	CAN1 DMA events
9:10	CAN1_FIFO0_TR_OUT[0:1]	CAN1 FIFO0 events
11:12	CAN1_FIFO1_TR_OUT[0:1]	CAN1 FIFO1 events
13:14	CAN0_TT_TR_OUT[0:1]	CAN0 TT Sync Outputs
15:16	CAN1_TT_TR_OUT[0:1]	CAN1 TT Sync Outputs
17:24	EVTGEN_TR_OUT[4:11]	Event generator triggers
MUX Group 6: TCPWM0_32_59 Trigger Multiplexer		
1:16	TCPWM0_16_TR_OUT1[0:15]	16-bit TCPWM0 counters
17	SCB_TX_TR_OUT[0]	SCB0 TX trigger
18	SCB_RX_TR_OUT[0]	SCB0 RX trigger
19	SCB_I2C_SCL_TR_OUT[0]	SCB0 I ² C trigger
20	SCB_TX_TR_OUT[1]	SCB1 TX trigger
21	SCB_RX_TR_OUT[1]	SCB1 RX trigger
22	SCB_I2C_SCL_TR_OUT[1]	SCB1 I ² C trigger
23	SCB_TX_TR_OUT[2]	SCB2 TX trigger
24	SCB_RX_TR_OUT[2]	SCB2 RX trigger
25	SCB_I2C_SCL_TR_OUT[2]	SCB2 I ² C trigger
26	SCB_TX_TR_OUT[3]	SCB3 TX trigger
27	SCB_RX_TR_OUT[3]	SCB3 RX trigger
28	SCB_I2C_SCL_TR_OUT[3]	SCB3 I ² C trigger
29	SCB_TX_TR_OUT[4]	SCB4 TX trigger
30	SCB_RX_TR_OUT[4]	SCB4 RX trigger
31	SCB_I2C_SCL_TR_OUT[4]	SCB4 I ² C trigger
32	SCB_TX_TR_OUT[5]	SCB5 TX trigger
33	SCB_RX_TR_OUT[5]	SCB5 RX trigger
34	SCB_I2C_SCL_TR_OUT[5]	SCB5 I ² C trigger
35	SCB_TX_TR_OUT[6]	SCB6 TX trigger
36	SCB_RX_TR_OUT[6]	SCB6 RX trigger
37	SCB_I2C_SCL_TR_OUT[6]	SCB6 I ² C trigger
38	SCB_TX_TR_OUT[7]	SCB7 TX trigger
39	SCB_RX_TR_OUT[7]	SCB7 RX trigger
40	SCB_I2C_SCL_TR_OUT[7]	SCB7 I ² C trigger
41	SCB_TX_TR_OUT[8]	SCB8 TX trigger
42	SCB_RX_TR_OUT[8]	SCB8 RX trigger
43	SCB_I2C_SCL_TR_OUT[8]	SCB8 I ² C trigger
44	SCB_TX_TR_OUT[9]	SCB9 TX trigger
45	CB_RX_TR_OUT[9]	SCB9 RX trigger
46	SCB_I2C_SCL_TR_OUT[9]	SCB9 I ² C trigger
47	SCB_TX_TR_OUT[10]	SCB10 TX trigger

Triggers group inputs

Table 17-1 Trigger inputs *(continued)*

Input	Trigger Label (TRIG_LABEL)	Description
48	SCB_RX_TR_OUT[10]	SCB10 RX trigger
49	SCB_I2C_SCL_TR_OUT[10]	SCB10 I ² C trigger
50	SCB_TX_TR_OUT[11]	SCB11 TX trigger
51	SCB_RX_TR_OUT[11]	SCB11 RX trigger
52	SCB_I2C_SCL_TR_OUT[11]	SCB11 I ² C trigger
53:54	PASS_GEN_TR_OUT[0:1]	PASS0 SAR events
55:102	HSIOM_IO_INPUT[0:47]	I/O Inputs
103:104	CTI_TR_OUT[0:1]	Trace events
105:108	FAULT_TR_OUT[0:3]	Fault events
109:110	CXPI_TX_TR_OUT[0:1]	CXPI0 events
111:112	CXPI_RX_TR_OUT[0:1]	CXPI0 events
MUX Group 7: PASS0 SAR trigger multiplexer		
1:32	PDMA0_TR_OUT[0:31]	General-purpose P-DMA0 triggers
33:70	TCPWM0_16_TR_OUT0[0:37]	16-bit TCPWM0 counters
71:82	TCPWM0_16M_TR_OUT0[0:11]	16-bit Motor enhanced TCPWM0 counters
83:114	TCPWM0_32_TR_OUT0[0:31]	32-bit TCPWM0 counters
115:122	HSIOM_IO_INPUT[0:7]	I/O Inputs
123	EVTGEN_TR_OUT[12]	Event generator triggers
MUX Group 8: CAN TT Sync trigger multiplexer		
1:2	CAN0_TT_TR_OUT[0:1]	CAN0 TT Sync Outputs
3:4	CAN1_TT_TR_OUT[0:1]	CAN1 TT Sync Outputs
MUX Group 9: Debug trigger multiplexer		
1:5	TR_GROUP10_OUTPUT[0:4]	Output from debug reduction multiplexer #1
6:10	TR_GROUP11_OUTPUT[0:4]	Output from debug reduction multiplexer #2
11:15	TR_GROUP12_OUTPUT[0:4]	Output from debug reduction multiplexer #3
MUX Group 10: Debug Reduction #1		
1:76	PDMA0_TR_OUT[0:75]	General purpose P-DMA0 triggers
77:88	SCB_TX_TR_OUT[0:11]	SCB TX triggers
89:100	SCB_RX_TR_OUT[0:11]	SCB RX triggers
101:112	SCB_I2C_SCL_TR_OUT[0:11]	SCB I ² C triggers
113:114	CAN0_DBG_TR_OUT[0:1]	CAN0 DMA
115:116	CAN0_FIFO0_TR_OUT[0:1]	CAN0 FIFO0
117:118	CAN0_FIFO1_TR_OUT[0:1]	CAN0 FIFO1
119:120	CAN0_TT_TR_OUT[0:1]	CAN0 TT Sync Outputs
121:122	CAN1_DBG_TR_OUT[0:1]	CAN1 DMA
123:124	CAN1_FIFO0_TR_OUT[0:1]	CAN1 FIFO0
125:126	CAN1_FIFO1_TR_OUT[0:1]	CAN1 FIFO1
127:128	CAN1_TT_TR_OUT[0:1]	CAN1 TT Sync Outputs
129:130	CTI_TR_OUT[0:1]	Trace events
131:134	FAULT_TR_OUT[0:3]	Fault events
135:150	EVTGEN_TR_OUT[0:15]	EVTGEN Triggers
MUX Group 11: Debug Reduction #2		
1:32	TCPWM0_32_TR_OUT0[0:31]	32-bit TCPWM0 counters
33:44	TCPWM0_16M_TR_OUT0[0:11]	16-bit Motor enhanced TCPWM0 counters
45:82	TCPWM0_16_TR_OUT0[0:37]	16-bit TCPWM0 counters

Triggers group inputs

Table 17-1 Trigger inputs *(continued)*

Input	Trigger Label (TRIG_LABEL)	Description
83	SMIF0_TX_TR_OUT	SMIF0 TX trigger
84	SMIF0_RX_TR_OUT	SMIF0 RX trigger
85	SMIF1_TX_TR_OUT	SMIF1 TX trigger
86	SMIF1_RX_TR_OUT	SMIF1 RX trigger
87:90	AXIDMA_TR_OUT[0:3]	AXI M-DMA1 triggers
95:98	TDM0_TX_TR_OUT[0:3]	TDM0 TX trigger
99:102	TDM0_RX_TR_OUT[0:3]	TDM0 RX trigger
103:107	SG0_TX_TR_OUT[0:4]	SG0 TX trigger
108:109	PWM0_TX_TR_OUT[0:1]	PCM-PWM0 TX trigger
110	AUDIODAC0_TX_TR_OUT	AUDIO DAC0 TX trigger
111:115	MIXER0_TR_SRC_REQ_OUT[0:4]	MIXER0 SRC trigger
116	MIXER0_TR_DST_REQ_OUT	MIXER0 DST trigger
117:121	MIXER1_TR_SRC_REQ_OUT[0:4]	MIXER1 SRC trigger
122	MIXER1_TR_DST_REQ_OUT	MIXER1 DST trigger
123:170	HSIOM_IO_INPUT[0:47]	I/O inputs
171:172	CXPI_TX_TR_OUT[0:1]	CXPI0 TX trigger
173:174	CXPI_RX_TR_OUT[0:1]	CXPI0 RX trigger
MUX Group 12: Debug Reduction #3		
1:84	PDMA1_TR_OUT[0:83]	General purpose P-DMA1 triggers
85:92	MDMA_TR_OUT[0:7]	M-DMA0 triggers
93:124	TCPWM0_32_TR_OUT1[0:31]	32-bit TCPWM0 counters
125:136	TCPWM0_16M_TR_OUT1[0:11]	16-bit Motor enhanced TCPWM0 counters
137:174	TCPWM0_16_TR_OUT1[0:37]	16-bit TCPWM0 counters
175:176	PASS_GEN_TR_OUT[0:1]	PASS0 SAR events
MUX Group 13: AXI M-DMA trigger multiplexer		
1:4	TCPWM0_16_TR_OUT0[0:3]	16-bit TCPWM0 counters
5:8	TCPWM0_32_TR_OUT0[0:3]	32-bit TCPWM0 counters
9:12	AXIDMA_TR_OUT[0:3]	AXI M-DMA1 triggers

Triggers group outputs

18 Triggers group outputs

Table 18-1 Trigger outputs

Output	Trigger	Description
MUX Group 0: P-DMA0_0_15 trigger multiplexer		
0:15	PDMA0_TR_IN[0:15]	Triggers to P-DMA0[0:15]
MUX Group 1: P-DMA0_16_31 trigger multiplexer		
0:15	PDMA0_TR_IN[16:31]	Triggers to P-DMA0[16:31]
MUX Group 2: P-DMA1_0_15 trigger multiplexer		
0:15	PDMA1_TR_IN[0:15]	Triggers to P-DMA1
MUX Group 3: M-DMA0 trigger multiplexer		
0:7	MDMA_TR_IN[0:7]	Triggers to M-DMA0
MUX Group 4: TCPWM0 Trigger multiplexer		
0:19	TCPWM0_ALL_CNT_TR_IN[0:19]	Triggers to TCPWM0
MUX Group 5: TCPWM0_20_31 Trigger multiplexer		
0:11	TCPWM0_ALL_CNT_TR_IN[20:31]	Triggers to TCPWM0
MUX Group 6: TCPWM0_32_59 Trigger multiplexer		
0:27	TCPWM0_ALL_CNT_TR_IN[32:59]	Triggers to TCPWM0
MUX Group 7: PASS0 SAR trigger multiplexer		
0:3	PASS_GEN_TR_IN[0:3]	Triggers to PASS0 SAR
MUX Group 8: CAN TT Sync trigger multiplexer		
0:1	CAN0_TT_TR_IN[0:1]	CAN0 TT Sync Inputs
2:3	CAN1_TT_TR_IN[0:1]	CAN1 TT Sync Inputs
MUX Group 9: Debug trigger multiplexer		
0	HSIOM_IO_OUTPUT[0]	To HSIOM as an output
1	HSIOM_IO_OUTPUT[1]	To HSIOM as an output
2:3	CTI_TR_IN[0:1]	To the Cross Trigger system
4	PERI_DEBUG_FREEZE_TR_IN	Signal to Freeze PERI operation
5	PASS_DEBUG_FREEZE_TR_IN	Signal to Freeze PASS0 SAR operation
6	SRSS_WDT_DEBUG_FREEZE_TR_IN	Signal to Freeze WDT operation
7	SRSS_MCWDT_DEBUG_FREEZE_TR_IN[2]	Signal to Freeze MCWDT2 operation
8	SRSS_MCWDT_DEBUG_FREEZE_TR_IN[1]	Signal to Freeze MCWDT1 operation
9	SRSS_MCWDT_DEBUG_FREEZE_TR_IN[0]	Signal to Freeze MCWDT0 operation
10	TCPWM0_DEBUG_FREEZE_TR_IN	Signal to Freeze TCPWM0 operation
12	TDM0_DEBUG_FREEZE_TR_IN	Signal to Freeze TDM0 operation
13	SG0_DEBUG_FREEZE_TR_IN	Signal to Freeze SG0 operation
14	PWM0_DEBUG_FREEZE_TR_IN	Signal to Freeze PWM0 operation
15	MIXER0_DEBUG_FREEZE_TR_IN	Signal to Freeze MIXER0 operation
16	MIXER1_DEBUG_FREEZE_TR_IN	Signal to Freeze MIXER1 operation
17	AUDIODAC0_DEBUG_FREEZE_TR_IN	Signal to Freeze AUDIO DAC0 operation
MUX Group 10: Debug Reduction #1		
0:4	TR_GROUP9_INPUT[1:5]	To main debug multiplexer
MUX Group 11: Debug Reduction #2		
0:4	TR_GROUP9_INPUT[6:10]	To main debug multiplexer
MUX Group 12: Debug Reduction #3		
0:4	TR_GROUP9_INPUT[11:15]	To main debug multiplexer
MUX Group 13: AXI-DMA trigger multiplexer		
0:3	AXIDMA_TR_IN[0:3]	Triggers to AXI M-DMA1

Triggers one-to-one

19 Triggers one-to-one

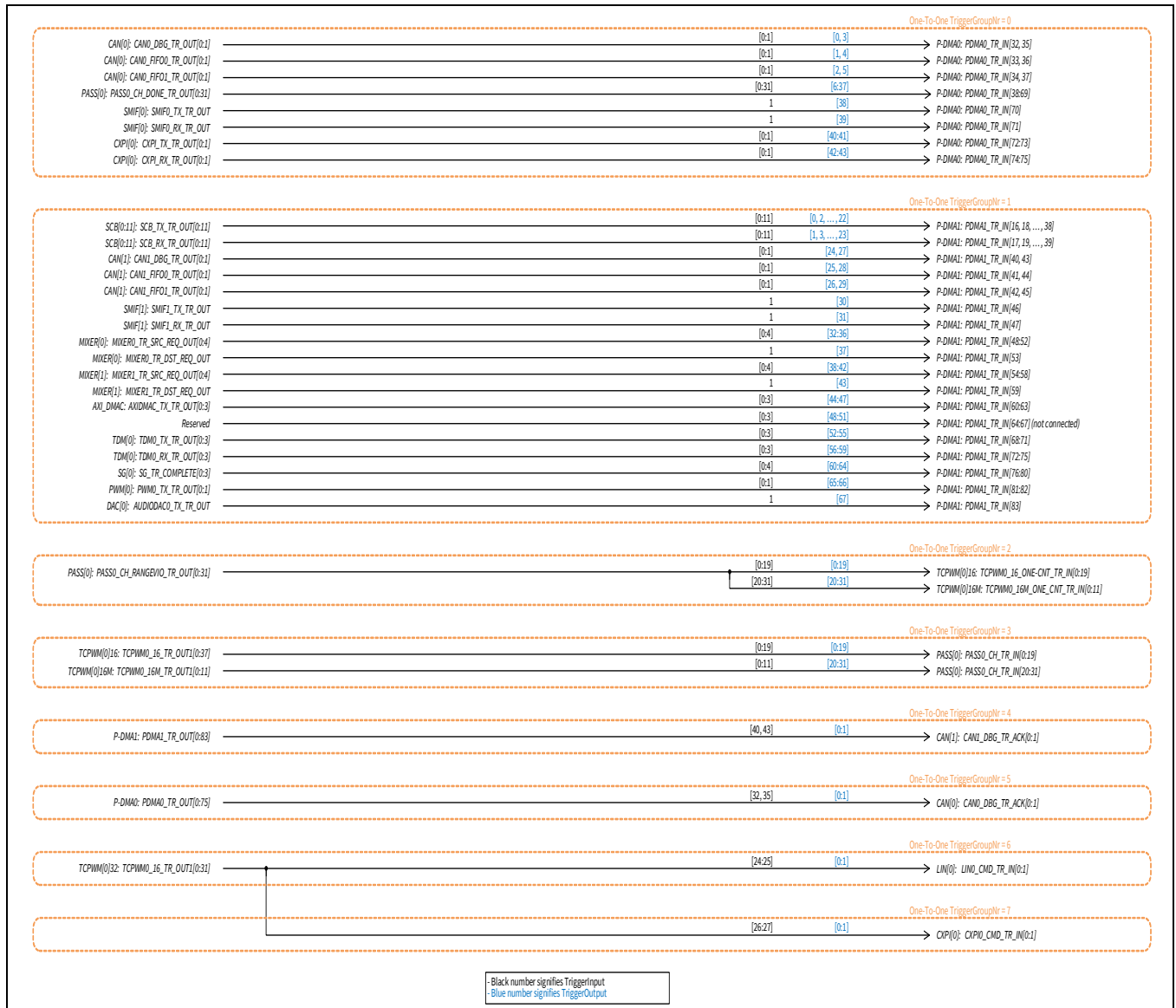


Figure 19-1 Triggers one-to-one^[39]

Note

39. The diagram shows only the TRIG_LABEL; the final trigger formation is based on the formula TRIG_{PREFIX(IN_1TO1/OUT_1-TO1)}_{x}_{TRIG_LABEL} and the information provided in [Table 19-1](#).

Triggers one-to-one

Table 19-1 Triggers 1:1

Input	Trigger In	Trigger Out	Description
MUX Group 0: CAN0 to P-DMA0 Triggers			
0	CAN0_DBG_TR_OUT[0]	PDMA0_TR_IN[32]	CAN0, Channel #0 P-DMA0 trigger
1	CAN0_FIFO0_TR_OUT[0]	PDMA0_TR_IN[33]	CAN0, Channel #0 FIFO0 trigger
2	CAN0_FIFO1_TR_OUT[0]	PDMA0_TR_IN[34]	CAN0, Channel #0 FIFO1 trigger
3	CAN0_DBG_TR_OUT[1]	PDMA0_TR_IN[35]	CAN0, Channel #1 P-DMA0 trigger
4	CAN0_FIFO0_TR_OUT[1]	PDMA0_TR_IN[36]	CAN0, Channel #1 FIFO0 trigger
5	CAN0_FIFO1_TR_OUT[1]	PDMA0_TR_IN[37]	CAN0, Channel #1 FIFO1 trigger
6:37	PASS0_CH_DONE_TR_OUT[0:31]	PDMA0_TR_IN[38:69]	PASS0 SAR0 to P-DMA0 direct connect
38	SMIF0_TX_TR_OUT	PDMA0_TR_IN[70]	SMIF TX to P-DMA0 Trigger
39	SMIF0_RX_TR_OUT	PDMA0_TR_IN[71]	SMIF RX to P-DMA0 Trigger
40:41	CXPI0_TX_TR_OUT[0:1]	PDMA0_TR_IN[72:73]	CXPI 0 TX P-DMA0 Triggers
42:43	CXPI0_RX_TR_OUT[0:1]	PDMA0_TR_IN[74:75]	CXPI 0 RX P-DMA0 Triggers
MUX Group 1: SCBx to P-DMA1 Triggers			
0	SCB0_TX_TR_OUT	PDMA1_TR_IN[16]	SCB0 to P-DMA1 Trigger
1	SCB0_RX_TR_OUT	PDMA1_TR_IN[17]	SCB0 to P-DMA1 Trigger
2	SCB1_TX_TR_OUT	PDMA1_TR_IN[18]	SCB1 to P-DMA1 Trigger
3	SCB1_RX_TR_OUT	PDMA1_TR_IN[19]	SCB1 to P-DMA1 Trigger
4	SCB2_TX_TR_OUT	PDMA1_TR_IN[20]	SCB2 to P-DMA1 Trigger
5	SCB2_RX_TR_OUT	PDMA1_TR_IN[21]	SCB2 to P-DMA1 Trigger
6	SCB3_TX_TR_OUT	PDMA1_TR_IN[22]	SCB3 to P-DMA1 Trigger
7	SCB3_RX_TR_OUT	PDMA1_TR_IN[23]	SCB3 to P-DMA1 Trigger
8	SCB4_TX_TR_OUT	PDMA1_TR_IN[24]	SCB4 to P-DMA1 Trigger
9	SCB4_RX_TR_OUT	PDMA1_TR_IN[25]	SCB4 to P-DMA1 Trigger
10	SCB5_TX_TR_OUT	PDMA1_TR_IN[26]	SCB5 to P-DMA1 Trigger
11	SCB5_RX_TR_OUT	PDMA1_TR_IN[27]	SCB5 to P-DMA1 Trigger
12	SCB6_TX_TR_OUT	PDMA1_TR_IN[28]	SCB6 to P-DMA1 Trigger
13	SCB6_RX_TR_OUT	PDMA1_TR_IN[29]	SCB6 to P-DMA1 Trigger
14	SCB7_TX_TR_OUT	PDMA1_TR_IN[30]	SCB7 to P-DMA1 Trigger
15	SCB7_RX_TR_OUT	PDMA1_TR_IN[31]	SCB7 to P-DMA1 Trigger
16	SCB8_TX_TR_OUT	PDMA1_TR_IN[32]	SCB8 to P-DMA1 Trigger
17	SCB8_RX_TR_OUT	PDMA1_TR_IN[33]	SCB8 to P-DMA1 Trigger
18	SCB9_TX_TR_OUT	PDMA1_TR_IN[34]	SCB9 to P-DMA1 Trigger
19	SCB9_RX_TR_OUT	PDMA1_TR_IN[35]	SCB9 to P-DMA1 Trigger
20	SCB10_TX_TR_OUT	PDMA1_TR_IN[36]	SCB10 to P-DMA1 Trigger
21	SCB10_RX_TR_OUT	PDMA1_TR_IN[37]	SCB10 to P-DMA1 Trigger
22	SCB11_TX_TR_OUT	PDMA1_TR_IN[38]	SCB11 to P-DMA1 Trigger
23	SCB11_RX_TR_OUT	PDMA1_TR_IN[39]	SCB11 to P-DMA1 Trigger
24	CAN1_DBG_TR_OUT[0]	PDMA1_TR_IN[40]	CAN1 Channel #0 P-DMA1 trigger
25	CAN1_FIFO0_TR_OUT[0]	PDMA1_TR_IN[41]	CAN1 Channel #0 FIFO0 trigger
26	CAN1_FIFO1_TR_OUT[0]	PDMA1_TR_IN[42]	CAN1 Channel #0 FIFO1 trigger
27	CAN1_DBG_TR_OUT[1]	PDMA1_TR_IN[43]	CAN1 Channel #1 P-DMA1 trigger
28	CAN1_FIFO0_TR_OUT[1]	PDMA1_TR_IN[44]	CAN1 Channel #1 FIFO0 trigger
29	CAN1_FIFO1_TR_OUT[1]	PDMA1_TR_IN[45]	CAN1 Channel #1 FIFO1 trigger
30	SMIF1_TX_TR_OUT	PDMA1_TR_IN[46]	SMIF1 TX to P-DMA1 Trigger

Triggers one-to-one

Table 19-1 Triggers 1:1 (continued)

Input	Trigger In	Trigger Out	Description
31	SMIF1_RX_TR_OUT	PDMA1_TR_IN[47]	SMIF1 RX to P-DMA1 Trigger
32:36	MIXER0_TR_SRC_REQ_OUT[0:4]	PDMA1_TR_IN[48:52]	MIXER0 to P-DMA1 trigger
37	MIXER0_TR_DST_REQ_OUT	PDMA1_TR_IN[53]	MIXER0 to P-DMA1 trigger
38:42	MIXER1_TR_SRC_REQ_OUT[0:4]	PDMA1_TR_IN[54:58]	MIXER1 to P-DMA1 trigger
43	MIXER1_TR_DST_REQ_OUT	PDMA1_TR_IN[59]	MIXER1 to P-DMA1 trigger
44:47	AXIDMA_TR_OUT[0:3]	PDMA1_TR_IN[60:63]	AXI M-DMA1 to P-DMA1 trigger
52:55	TDM0_TX_TR_OUT[0:3]	PDMA1_TR_IN[68:71]	TDM0 TX to P-DMA1 trigger
56:59	TDM0_RX_TR_OUT[0:3]	PDMA1_TR_IN[72:75]	TDM0 RX to P-DMA1 trigger
60:64	SG0_TX_TR_OUT[0:4]	PDMA1_TR_IN[76:80]	SG0 TX to P-DMA1 trigger
65:66	PWM0_TX_TR_OUT[0:1]	PDMA1_TR_IN[81:82]	PWM0 TX to P-DMA1 trigger
67	AUDIODAC0_TX_TR_OUT	PDMA1_TR_IN[83]	AUDIODAC0 to P-DMA1 trigger
MUX Group 2: PASS SARx to TCPWM1 direct connect			
0	PASS0_CH_RANGEVIO_TR_OUT[0]	TCPWM0_16_ONE_CNT_TR_IN[0]	SAR0 ch#0 ^[40] , range violation to TCPWM0 Group#0 Counter#00 trig=2
1	PASS0_CH_RANGEVIO_TR_OUT[1]	TCPWM0_16_ONE_CNT_TR_IN[1]	SAR0 ch#1, range violation to TCPWM0 Group#0 Counter#01 trig=2
2	PASS0_CH_RANGEVIO_TR_OUT[2]	TCPWM0_16_ONE_CNT_TR_IN[2]	SAR0 ch#2, range violation to TCPWM0 Group#0 Counter#02 trig=2
3	PASS0_CH_RANGEVIO_TR_OUT[3]	TCPWM0_16_ONE_CNT_TR_IN[3]	SAR0 ch#3, range violation to TCPWM0 Group#0 Counter#03 trig=2
4	PASS0_CH_RANGEVIO_TR_OUT[4]	TCPWM0_16_ONE_CNT_TR_IN[4]	SAR0 ch#4, range violation to TCPWM0 Group#0 Counter#04 trig=2
5	PASS0_CH_RANGEVIO_TR_OUT[5]	TCPWM0_16_ONE_CNT_TR_IN[5]	SAR0 ch#5, range violation to TCPWM0 Group#0 Counter#05 trig=2
6	PASS0_CH_RANGEVIO_TR_OUT[6]	TCPWM0_16_ONE_CNT_TR_IN[6]	SAR0 ch#6, range violation to TCPWM0 Group#0 Counter#06 trig=2
7	PASS0_CH_RANGEVIO_TR_OUT[7]	TCPWM0_16_ONE_CNT_TR_IN[7]	SAR0 ch#7, range violation to TCPWM0 Group#0 Counter#07 trig=2
8	PASS0_CH_RANGEVIO_TR_OUT[8]	TCPWM0_16_ONE_CNT_TR_IN[8]	SAR0 ch#8, range violation to TCPWM0 Group#0 Counter#08 trig=2
9	PASS0_CH_RANGEVIO_TR_OUT[9]	TCPWM0_16_ONE_CNT_TR_IN[9]	SAR0 ch#9, range violation to TCPWM0 Group#0 Counter#09 trig=2
10	PASS0_CH_RANGEVIO_TR_OUT[10]	TCPWM0_16_ONE_CNT_TR_IN[10]	SAR0 ch#10, range violation to TCPWM0 Group#0 Counter#10 trig=2
11	PASS0_CH_RANGEVIO_TR_OUT[11]	TCPWM0_16_ONE_CNT_TR_IN[11]	SAR0 ch#11, range violation to TCPWM0 Group#0 Counter#11 trig=2
12	PASS0_CH_RANGEVIO_TR_OUT[12]	TCPWM0_16_ONE_CNT_TR_IN[12]	SAR0 ch#12, range violation to TCPWM0 Group#0 Counter#12 trig=2
13	PASS0_CH_RANGEVIO_TR_OUT[13]	TCPWM0_16_ONE_CNT_TR_IN[13]	SAR0 ch#13, range violation to TCPWM0 Group#0 Counter#13 trig=2
14	PASS0_CH_RANGEVIO_TR_OUT[14]	TCPWM0_16_ONE_CNT_TR_IN[14]	SAR0 ch#14, range violation to TCPWM0 Group#0 Counter#14 trig=2
15	PASS0_CH_RANGEVIO_TR_OUT[15]	TCPWM0_16_ONE_CNT_TR_IN[15]	SAR0 ch#15, range violation to TCPWM0 Group#0 Counter#15 trig=2
16	PASS0_CH_RANGEVIO_TR_OUT[16]	TCPWM0_16_ONE_CNT_TR_IN[16]	SAR0 ch#16, range violation to TCPWM0 Group#0 Counter#16 trig=2
17	PASS0_CH_RANGEVIO_TR_OUT[17]	TCPWM0_16_ONE_CNT_TR_IN[17]	SAR0 ch#17, range violation to TCPWM0 Group#0 Counter#17 trig=2
18	PASS0_CH_RANGEVIO_TR_OUT[18]	TCPWM0_16_ONE_CNT_TR_IN[18]	SAR0 ch#18, range violation to TCPWM0 Group#0 Counter#18 trig=2
19	PASS0_CH_RANGEVIO_TR_OUT[19]	TCPWM0_16_ONE_CNT_TR_IN[19]	SAR0 ch#19, range violation to TCPWM0 Group#0 Counter#19 trig=2
20	PASS0_CH_RANGEVIO_TR_OUT[20]	TCPWM0_16M_ONE_CNT_TR_IN[0]	SAR0 ch#20, range violation to TCPWM0 Group#1 Counter#00 trig=2
21	PASS0_CH_RANGEVIO_TR_OUT[21]	TCPWM0_16M_ONE_CNT_TR_IN[1]	SAR0 ch#21, range violation to TCPWM0 Group#1 Counter#01 trig=2

Note

40. Each logical channel of SAR ADC[x] can be connected to any of the SAR ADC[x]_y external pin. (x = 0, or 1, or, 2 and y=0 to max 31)

Triggers one-to-one

Table 19-1 Triggers 1:1 (continued)

Input	Trigger In	Trigger Out	Description
22	PASS0_CH_RANGEVIO_TR_OUT[22]	TCPWM0_16M_ONE_CNT_TR_IN[2]	SAR0 ch#22, range violation to TCPWM0 Group#1 Counter#02 trig=2
23	PASS0_CH_RANGEVIO_TR_OUT[23]	TCPWM0_16M_ONE_CNT_TR_IN[3]	SAR0 ch#23, range violation to TCPWM0 Group#1 Counter#03 trig=2
24	PASS0_CH_RANGEVIO_TR_OUT[24]	TCPWM0_16M_ONE_CNT_TR_IN[4]	SAR0 ch#24, range violation to TCPWM0 Group#1 Counter#04 trig=2
25	PASS0_CH_RANGEVIO_TR_OUT[25]	TCPWM0_16M_ONE_CNT_TR_IN[5]	SAR0 ch#25, range violation to TCPWM0 Group#1 Counter#05 trig=2
26	PASS0_CH_RANGEVIO_TR_OUT[26]	TCPWM0_16M_ONE_CNT_TR_IN[6]	SAR0 ch#26, range violation to TCPWM0 Group#1 Counter#06 trig=2
27	PASS0_CH_RANGEVIO_TR_OUT[27]	TCPWM0_16M_ONE_CNT_TR_IN[7]	SAR0 ch#27, range violation to TCPWM0 Group#1 Counter#07 trig=2
28	PASS0_CH_RANGEVIO_TR_OUT[28]	TCPWM0_16M_ONE_CNT_TR_IN[8]	SAR0 ch#28, range violation to TCPWM0 Group#1 Counter#08 trig=2
29	PASS0_CH_RANGEVIO_TR_OUT[29]	TCPWM0_16M_ONE_CNT_TR_IN[9]	SAR0 ch#29, range violation to TCPWM0 Group#1 Counter#09 trig=2
30	PASS0_CH_RANGEVIO_TR_OUT[30]	TCPWM0_16M_ONE_CNT_TR_IN[10]	SAR0 ch#30, range violation to TCPWM0 Group#1 Counter#10 trig=2
31	PASS0_CH_RANGEVIO_TR_OUT[31]	TCPWM0_16M_ONE_CNT_TR_IN[11]	SAR0 ch#31, range violation to TCPWM0 Group#1 Counter#11 trig=2
MUX Group 3: TCPWM0 to PASS SARx			
0:19	TCPWM0_16_TR_OUT1[0:19]	PASS0_CH_TR_IN[0:19]	TCPWM0 Group #0 Counter #00 through 19 (PWM0_0 to PWM0_19) to SAR0 ch#0 through SAR0 ch#19
20:31	TCPWM0_16M_TR_OUT1[0:11]	PASS0_CH_TR_IN[20:31]	TCPWM0 Group #1 Counter #00 through 11 (PWM0_M_0 to PWM0_M_11) to SAR0 ch#20 through SAR0 ch#31
MUX Group 4: Acknowledge triggers from P-DMA1 to CAN1			
0	PDMA1_TR_OUT[40]	CAN1_DBG_TR_ACK[0]	CAN1 Channel#0 P-DMA1 acknowledge
1	PDMA1_TR_OUT[43]	CAN1_DBG_TR_ACK[1]	CAN1 Channel#1 P-DMA1 acknowledge
MUX Group 5: Acknowledge triggers from P-DMA0 to CAN0			
0	PDMA0_TR_OUT[32]	CAN0_DBG_TR_ACK[0]	CAN0 Channel#0 P-DMA0 acknowledge
1	PDMA0_TR_OUT[35]	CAN0_DBG_TR_ACK[1]	CAN0 Channel#1 P-DMA0 acknowledge
MUX Group 6: TCPWM0 to LIN0 triggers			
0:1	TCPWM0_16_TR_OUT1[24:25]	LIN0_CMD_TR_IN[0:1]	TCPWM0 (Group #0 Counter #24 to #25) to LIN0
MUX Group 7: TCPWM0_TO_CXPI (TCPWM0 to CXPI)			
0:1	TCPWM0_16_TR_OUT1[26:27]	CXPI0_CMD_TR_IN[0:1]	TCPWM0 (Group #0 Counter #24 to #25) to CXPI0

20 Peripheral clocks

Table 20-1 Peripheral clock assignments

Output	Destination	Description
CPUSS Root Clocks (Group 0)		
0	PCLK_CPUSS_CLOCK_TRACE_IN	Trace clock
1	PCLK_SMARTIO9_CLOCK	Smart I/O #9
2	PCLK_TCPWM0_CLOCKS0	TCPWM0 Group #0, Counter #0
3	PCLK_TCPWM0_CLOCKS1	TCPWM0 Group #0, Counter #1
4	PCLK_TCPWM0_CLOCKS2	TCPWM0 Group #0, Counter #2
5	PCLK_TCPWM0_CLOCKS3	TCPWM0 Group #0, Counter #3
6	PCLK_TCPWM0_CLOCKS4	TCPWM0 Group #0, Counter #4
7	PCLK_TCPWM0_CLOCKS5	TCPWM0 Group #0, Counter #5
8	PCLK_TCPWM0_CLOCKS6	TCPWM0 Group #0, Counter #6
9	PCLK_TCPWM0_CLOCKS7	TCPWM0 Group #0, Counter #7
10	PCLK_TCPWM0_CLOCKS8	TCPWM0 Group #0, Counter #8
11	PCLK_TCPWM0_CLOCKS9	TCPWM0 Group #0, Counter #9
12	PCLK_TCPWM0_CLOCKS10	TCPWM0 Group #0, Counter #10
13	PCLK_TCPWM0_CLOCKS11	TCPWM0 Group #0, Counter #11
14	PCLK_TCPWM0_CLOCKS12	TCPWM0 Group #0, Counter #12
15	PCLK_TCPWM0_CLOCKS13	TCPWM0 Group #0, Counter #13
16	PCLK_TCPWM0_CLOCKS14	TCPWM0 Group #0, Counter #14
17	PCLK_TCPWM0_CLOCKS15	TCPWM0 Group #0, Counter #15
18	PCLK_TCPWM0_CLOCKS16	TCPWM0 Group #0, Counter #16
19	PCLK_TCPWM0_CLOCKS17	TCPWM0 Group #0, Counter #17
20	PCLK_TCPWM0_CLOCKS18	TCPWM0 Group #0, Counter #18
21	PCLK_TCPWM0_CLOCKS19	TCPWM0 Group #0, Counter #19
22	PCLK_TCPWM0_CLOCKS20	TCPWM0 Group #0, Counter #20
23	PCLK_TCPWM0_CLOCKS21	TCPWM0 Group #0, Counter #21
24	PCLK_TCPWM0_CLOCKS22	TCPWM0 Group #0, Counter #22
25	PCLK_TCPWM0_CLOCKS23	TCPWM0 Group #0, Counter #23
26	PCLK_TCPWM0_CLOCKS24	TCPWM0 Group #0, Counter #24
27	PCLK_TCPWM0_CLOCKS25	TCPWM0 Group #0, Counter #25
28	PCLK_TCPWM0_CLOCKS26	TCPWM0 Group #0, Counter #26
29	PCLK_TCPWM0_CLOCKS27	TCPWM0 Group #0, Counter #27
30	PCLK_TCPWM0_CLOCKS28	TCPWM0 Group #0, Counter #28
31	PCLK_TCPWM0_CLOCKS29	TCPWM0 Group #0, Counter #29
32	PCLK_TCPWM0_CLOCKS30	TCPWM0 Group #0, Counter #30
33	PCLK_TCPWM0_CLOCKS31	TCPWM0 Group #0, Counter #31
34	PCLK_TCPWM0_CLOCKS32	TCPWM0 Group #0, Counter #32
35	PCLK_TCPWM0_CLOCKS33	TCPWM0 Group #0, Counter #33
36	PCLK_TCPWM0_CLOCKS34	TCPWM0 Group #0, Counter #34
37	PCLK_TCPWM0_CLOCKS35	TCPWM0 Group #0, Counter #35
38	PCLK_TCPWM0_CLOCKS36	TCPWM0 Group #0, Counter #36
39	PCLK_TCPWM0_CLOCKS37	TCPWM0 Group #0, Counter #37
40	PCLK_TCPWM0_CLOCKS256	TCPWM0 Group #1, Counter #0

Peripheral clocks

Table 20-1 Peripheral clock assignments (continued)

Output	Destination	Description
41	PCLK_TCPWM0_CLOCKS257	TCPWM0 Group #1, Counter #1
42	PCLK_TCPWM0_CLOCKS258	TCPWM0 Group #1, Counter #2
43	PCLK_TCPWM0_CLOCKS259	TCPWM0 Group #1, Counter #3
44	PCLK_TCPWM0_CLOCKS260	TCPWM0 Group #1, Counter #4
45	PCLK_TCPWM0_CLOCKS261	TCPWM0 Group #1, Counter #5
46	PCLK_TCPWM0_CLOCKS262	TCPWM0 Group #1, Counter #6
47	PCLK_TCPWM0_CLOCKS263	TCPWM0 Group #1, Counter #7
48	PCLK_TCPWM0_CLOCKS264	TCPWM0 Group #1, Counter #8
49	PCLK_TCPWM0_CLOCKS265	TCPWM0 Group #1, Counter #9
50	PCLK_TCPWM0_CLOCKS266	TCPWM0 Group #1, Counter #10
51	PCLK_TCPWM0_CLOCKS267	TCPWM0 Group #1, Counter #11
52	PCLK_TCPWM0_CLOCKS512	TCPWM0 Group #2, Counter #0
53	PCLK_TCPWM0_CLOCKS513	TCPWM0 Group #2, Counter #1
54	PCLK_TCPWM0_CLOCKS514	TCPWM0 Group #2, Counter #2
55	PCLK_TCPWM0_CLOCKS515	TCPWM0 Group #2, Counter #3
56	PCLK_TCPWM0_CLOCKS516	TCPWM0 Group #2, Counter #4
57	PCLK_TCPWM0_CLOCKS517	TCPWM0 Group #2, Counter #5
58	PCLK_TCPWM0_CLOCKS518	TCPWM0 Group #2, Counter #6
59	PCLK_TCPWM0_CLOCKS519	TCPWM0 Group #2, Counter #7
60	PCLK_TCPWM0_CLOCKS520	TCPWM0 Group #2, Counter #8
61	PCLK_TCPWM0_CLOCKS521	TCPWM0 Group #2, Counter #9
62	PCLK_TCPWM0_CLOCKS522	TCPWM0 Group #2, Counter #10
63	PCLK_TCPWM0_CLOCKS523	TCPWM0 Group #2, Counter #11
64	PCLK_TCPWM0_CLOCKS524	TCPWM0 Group #2, Counter #12
65	PCLK_TCPWM0_CLOCKS525	TCPWM0 Group #2, Counter #13
66	PCLK_TCPWM0_CLOCKS526	TCPWM0 Group #2, Counter #14
67	PCLK_TCPWM0_CLOCKS527	TCPWM0 Group #2, Counter #15
68	PCLK_TCPWM0_CLOCKS528	TCPWM0 Group #2, Counter #16
69	PCLK_TCPWM0_CLOCKS529	TCPWM0 Group #2, Counter #17
70	PCLK_TCPWM0_CLOCKS530	TCPWM0 Group #2, Counter #18
71	PCLK_TCPWM0_CLOCKS531	TCPWM0 Group #2, Counter #19
72	PCLK_TCPWM0_CLOCKS532	TCPWM0 Group #2, Counter #20
73	PCLK_TCPWM0_CLOCKS533	TCPWM0 Group #2, Counter #21
74	PCLK_TCPWM0_CLOCKS534	TCPWM0 Group #2, Counter #22
75	PCLK_TCPWM0_CLOCKS535	TCPWM0 Group #2, Counter #23
76	PCLK_TCPWM0_CLOCKS536	TCPWM0 Group #2, Counter #24
77	PCLK_TCPWM0_CLOCKS537	TCPWM0 Group #2, Counter #25
78	PCLK_TCPWM0_CLOCKS538	TCPWM0 Group #2, Counter #26
79	PCLK_TCPWM0_CLOCKS539	TCPWM0 Group #2, Counter #27
80	PCLK_TCPWM0_CLOCKS540	TCPWM0 Group #2, Counter #28
81	PCLK_TCPWM0_CLOCKS541	TCPWM0 Group #2, Counter #29
82	PCLK_TCPWM0_CLOCKS542	TCPWM0 Group #2, Counter #30
83	PCLK_TCPWM0_CLOCKS543	TCPWM0 Group #2, Counter #31

Peripheral clocks

Table 20-1 **Peripheral clock assignments** *(continued)*

Output	Destination	Description
COMM Root Clocks (Group 1)		
0	PCLK_CANFD0_CLOCK_CAN0	CAN0, Channel #0
1	PCLK_CANFD0_CLOCK_CAN1	CAN0, Channel #1
2	PCLK_CANFD1_CLOCK_CAN0	CAN1, Channel #0
3	PCLK_CANFD1_CLOCK_CAN1	CAN1, Channel #1
4	PCLK_LIN0_CLOCK_CH_EN0	LIN0, Channel #0
5	PCLK_LIN0_CLOCK_CH_EN1	LIN0, Channel #1
6	PCLK_CXPI0_CLOCK_CH_EN0	CXPI0, Channel #0
7	PCLK_CXPI0_CLOCK_CH_EN1	CXPI0, Channel #1
8	PCLK_SCB0_CLOCK	SCB0
9	PCLK_SCB1_CLOCK	SCB1
10	PCLK_SCB2_CLOCK	SCB2
11	PCLK_SCB3_CLOCK	SCB3
12	PCLK_SCB4_CLOCK	SCB4
13	PCLK_SCB5_CLOCK	SCB5
14	PCLK_SCB6_CLOCK	SCB6
15	PCLK_SCB7_CLOCK	SCB7
16	PCLK_SCB8_CLOCK	SCB8
17	PCLK_SCB9_CLOCK	SCB9
18	PCLK_SCB10_CLOCK	SCB10
19	PCLK_SCB11_CLOCK	SCB11
20	PCLK_PASS0_CLOCK_SAR0	SAR0

21 Faults

Table 21-1 Fault assignments

Fault	Source	Description
0	CPUSS_MPU_VIO_0	CM0+ S MPU violation DATA0[31:0]: Violating address. DATA1[0]: User read. DATA1[1]: User write. DATA1[2]: User execute. DATA1[3]: Privileged read. DATA1[4]: Privileged write. DATA1[5]: Privileged execute. DATA1[6]: Non-secure. DATA1[11:8]: Master identifier. DATA1[15:12]: Protection context identifier. DATA1[31]: '0' MPU violation; '1': S MPU violation.
1	CPUSS_MPU_VIO_1	Crypto S MPU violation. See CPUSS_MPU_VIO_0 description.
2	CPUSS_MPU_VIO_2	P-DMA0 MPU/S MPU violation. See CPUSS_MPU_VIO_0 description.
3	CPUSS_MPU_VIO_3	P-DMA1 MPU/S MPU violation. See CPUSS_MPU_VIO_0 description.
4	CPUSS_MPU_VIO_4	M-DMA0 MPU/S MPU violation. See CPUSS_MPU_VIO_0 description.
9	CPUSS_MPU_VIO_9	ETH0 MPU/S MPU violation. See CPUSS_MPU_VIO_0 description.
11	CPUSS_MPU_VIO_11	AXI M-DMA1 MPU/S MPU violation. See CPUSS_MPU_VIO_0 description.
12	CPUSS_MPU_VIO_12	VIDEOSS0 MPU/S MPU violation. See CPUSS_MPU_VIO_0 description.
14	CPUSS_MPU_VIO_14	CM7_0 MPU/S MPU violation. See CPUSS_MPU_VIO_0 description.
15	CPUSS_MPU_VIO_15	Test Controller MPU/S MPU violation. See CPUSS_MPU_VIO_0 description.
16	CPUSS_CM7_0_CACHE_C_ECC	Correctable ECC error in CM7_0 Cache memories DATA0[16:2]: location information: Tag/Data SRAM, Way, Index and line Offset, see CM7 UGRM IEBR0/DEBR0 description for details. DATA0[31]: 0=Instruction cache, 1= Data cache
17	CPUSS_CM7_0_CACHE_NC_ECC	Non Correctable ECC error in CM7_0 Cache memories. See CPUSS_CM7_0 - CACHE_C_ECC description
18	CPUSS_CM7_0_TCM_C_ECC	Correctable ECC error in CM7_0 TCM memory DATA0[23:2]: Violating address. DATA1[7:0]: Syndrome of code word (at address offset 0x0). DATA1[31:30]: 0= ITCM, 2=D0TCM, 3=D1TCM
19	CPUSS_CM7_0_TCM_NC_ECC	Non Correctable ECC error in CM7_0 TCM memory. See CPUSS_CM7_0_TCM_C_ECC description.
24	PERI_PERI_ECC	Peripheral protection SRAM correctable ECC violation DATA0[10:0]: Violating address. DATA1[7:0]: Syndrome of SRAM word.
25	PERI_PERI_NC_ECC	Peripheral protection SRAM non-correctable ECC violation
26	PERI_MS_VIO_0	CM0+ Peripheral Master Interface PPU violation DATA0[31:0]: Violating address. DATA1[0]: User read. DATA1[1]: User write. DATA1[2]: User execute. DATA1[3]: Privileged read. DATA1[4]: Privileged write. DATA1[5]: Privileged execute. DATA1[6]: Non-secure. DATA1[11:8]: Master identifier. DATA1[15:12]: Protection context identifier. DATA1[31:28]: "0": master interface, PPU violation, "1": timeout detected, "2": bus error, other: undefined.
27	PERI_MS_VIO_1	CM7_0 Peripheral Master Interface PPU violation. See PERI_MS_VIO_0 description.
29	PERI_MS_VIO_3	P-DMA0 Peripheral Master Interface PPU violation. See PERI_MS_VIO_0 description.
30	PERI_MS_VIO_4	P-DMA1 Peripheral Master Interface PPU violation. See PERI_MS_VIO_0 description.

Faults

Table 21-1 Fault assignments (continued)

Fault	Source	Description
32	PERI_GROUP_VIO_0	Peripheral Group #0 violation. DATA0[31:0]: Violating address. DATA1[0]: User read. DATA1[1]: User write. DATA1[2]: User execute. DATA1[3]: Privileged read. DATA1[4]: Privileged write. DATA1[5]: Privileged execute. DATA1[6]: Non-secure. DATA1[11:8]: Master identifier. DATA1[15:12]: Protection context identifier. DATA1[31:28]: "0": decoder or peripheral bus error, other: undefined.
33	PERI_GROUP_VIO_1	Peripheral Group #1 violation. See PERI_GROUP_VIO_0 description.
34	PERI_GROUP_VIO_2	Peripheral Group #2 violation. See PERI_GROUP_VIO_0 description.
35	PERI_GROUP_VIO_3	Peripheral Group #3 violation. See PERI_GROUP_VIO_0 description.
36	PERI_GROUP_VIO_4	Peripheral Group #4 violation. See PERI_GROUP_VIO_0 description.
37	PERI_GROUP_VIO_5	Peripheral Group #5 violation. See PERI_GROUP_VIO_0 description.
38	PERI_GROUP_VIO_6	Peripheral Group #6 violation. See PERI_GROUP_VIO_0 description.
40	PERI_GROUP_VIO_8	Peripheral Group #8 violation. See PERI_GROUP_VIO_0 description.
41	PERI_GROUP_VIO_9	Peripheral Group #9 violation. See PERI_GROUP_VIO_0 description.
42	PERI_GROUP_VIO_10	Peripheral Group #10 violation. See PERI_GROUP_VIO_0 description.
48	CPUSS_FLASHC_MAIN_BUS_ERR	Flash controller main flash bus error FAULT_DATA0[26:0]: Violating address. Append 5'b00010 as most significant bits to derive 32-bit system address. FAULT_DATA1[11:8]: Master identifier.
49	CPUSS_FLASHC_MAIN_C_ECC	Flash controller main flash correctable ECC violation DATA[26:0]: Violating address. Append 5'b00010 as most significant bits to derive 32-bit system address. DATA1[7:0]: Syndrome of 64-bit word (at address offset 0x00). DATA1[15:8]: Syndrome of 64-bit word (at address offset 0x08). DATA1[23:16]: Syndrome of 64-bit word (at address offset 0x10). DATA1[31:24]: Syndrome of 64-bit word (at address offset 0x18).
50	CPUSS_FLASHC_MAIN_NC_ECC	Flash controller main flash non-correctable ECC violation. See CPUSS_FLASHC_MAIN_C_ECC description.
51	CPUSS_FLASHC_WORK_BUS_ERR	Flash controller work-flash bus error. See CPUSS_FLASHC_MAIN_BUS_ERR description.
52	CPUSS_FLASHC_WORK_C_ECC	Flash controller work flash correctable ECC violation. DATA0[26:0]: Violating address. Append 5'b00010 as most significant bits to derive 32-bit system address. DATA1[6:0]: Syndrome of 32-bit word.
53	CPUSS_FLASHC_WORK_NC_ECC	Flash controller work-flash non-correctable ECC violation. See CPUSS_FLASHC_WORK_C_ECC description.
54	CPUSS_FLASHC_CM0_CA_C_ECC	Flash controller CM0+ cache correctable ECC violation. DATA0[26:0]: Violating address. DATA1[6:0]: Syndrome of 32-bit SRAM word (at address offset 0x0). DATA1[14:8]: Syndrome of 32-bit SRAM word (at address offset 0x4). DATA1[22:16]: Syndrome of 32-bit SRAM word (at address offset 0x8). DATA1[30:24]: Syndrome of 32-bit SRAM word (at address offset 0xc).
55	CPUSS_FLASHC_CM0_CA_NC_ECC	Flash controller CM0+ cache non-correctable ECC violation. See CPUSS_FLASHC_CM0_CA_C_ECC description.
56	CPUSS_FM_SRAMC_C_ECC	Flash code storage SRAM memory correctable ECC violation: DATA0[15:0]: Address location in the eCT Flash SRAM. DATA1[6:0]: Syndrome of 32-bit SRAM word.
57	CPUSS_FM_SRAMC_NC_ECC	Flash code storage SRAM memory non-correctable ECC violation: See CPUSS_FM_SRAMC_C_ECC description.
58	CPUSS_RAMC0_C_ECC	System memory controller 0 correctable ECC violation: DATA0[31:0]: Violating address. DATA1[6:0]: Syndrome of 32-bit SRAM code word.
59	CPUSS_RAMC0_NC_ECC	System memory controller 0 non-correctable ECC violation. See CPUSS_RAMC0_C_ECC description.

Faults

Table 21-1 **Fault assignments** *(continued)*

Fault	Source	Description
60	CPUSS_RAMC1_C_ECC	System memory controller 1 correctable ECC violation. See CPUSS_RAMC0_C_ECC description.
61	CPUSS_RAMC1_NC_ECC	System memory controller 1 non-correctable ECC violation. See CPUSS_RAMC0_C_ECC description.
62	CPUSS_RAMC2_C_ECC	System memory controller 2 correctable ECC violation. See CPUSS_RAMC0_C_ECC description.
63	CPUSS_RAMC2_NC_ECC	System memory controller 2 non-correctable ECC violation. See CPUSS_RAMC0_C_ECC description.
64	CPUSS_CRYPT0_C_ECC	Crypto memory correctable ECC violation. DATA0[31:0]: Violating address. DATA1[6:0]: Syndrome of Least Significant 32-bit SRAM. DATA1[14:8]: Syndrome of Most Significant 32-bit SRAM.
65	CPUSS_CRYPT0_NC_ECC	Crypto memory non-correctable ECC violation. See CPUSS_CRYPT0_C_ECC description.
66	CPUSS_DW0_C_ECC	P-DMA0 memory correctable ECC violation: DATA0[11:0]: Violating DW SRAM address (word address, assuming byte addressable). DATA1[6:0]: Syndrome of 32-bit SRAM code word.
67	CPUSS_DW0_NC_ECC	P-DMA0 memory non-correctable ECC violation. See CPUSS_DW0_C_ECC description.
68	CPUSS_DW1_C_ECC	P-DMA1 memory correctable ECC violation. See CPUSS_DW0_C_ECC description.
69	CPUSS_DW1_NC_ECC	P-DMA1 memory non-correctable ECC violation. See CPUSS_DW0_C_ECC description.
70	CANFD_0_CAN_C_ECC	CAN0 message buffer correctable ECC violation: DATA0[15:0]: Violating address. DATA0[22:16]: ECC violating data[38:32] from MRAM. DATA0[27:24]: Master ID: 0-7 = CAN channel ID within mxttcanfd cluster, 8 = AHB I/F DATA1[31:0]: ECC violating data[31:0] from MRAM.
71	CANFD_0_CAN_NC_ECC	CAN0 message buffer non-correctable ECC violation: DATA0[15:0]: Violating address. DATA0[22:16]: ECC violating data[38:32] from MRAM (not for Address Error). DATA0[27:24]: Master ID: 0-7 = CAN channel ID within mxttcanfd cluster, 8 = AHB I/F DATA0[30]: Write access, only possible for Address Error DATA0[31]: Address Error: a CAN channel did an MRAM access above MRAM_SIZE DATA1[31:0]: ECC violating data[31:0] from MRAM (not for Address Error).
72	CANFD_1_CAN_C_ECC	CAN1 message buffer correctable ECC violation. See CANFD_0_CAN_C_ECC description.
73	CANFD_1_CAN_NC_ECC	CAN1 message buffer non-correctable ECC violation. See CANFD_0_CAN_NC_ECC description.
82	VIDEOSS_0_VRPU_RD_0	VIDEOSS Fault Reporting VRPU read 0: DATA0[31:0]: Violating address. DATA1[0]: User read. DATA1[1]: User write. DATA1[2]: User execute. DATA1[3]: Privileged read. DATA1[4]: Privileged write. DATA1[5]: Privileged execute. DATA1[6]: Non-secure. DATA1[11:8]: Master identifier. DATA1[15:12]: Protection context identifier. DATA1[31:28]: "0": decoder or peripheral bus error, other: undefined.
83	VIDEOSS_0_VRPU_RD_1	VIDEOSS Fault Reporting VRPU read 1. See VIDEOSS_0_VRPU_RD_0 description.
84	VIDEOSS_0_VRPU_RD_2	VIDEOSS Fault Reporting VRPU read 2. See VIDEOSS_0_VRPU_RD_0 description.
85	VIDEOSS_0_VRPU_RD_3	VIDEOSS Fault Reporting VRPU read 3. See VIDEOSS_0_VRPU_RD_0 description.
86	VIDEOSS_0_VRPU_RD_4	VIDEOSS Fault Reporting VRPU read 4. See VIDEOSS_0_VRPU_RD_0 description.
87	VIDEOSS_0_VRPU_WR_0	VIDEOSS Fault Reporting VRPU write 0. See VIDEOSS_0_VRPU_RD_0 description.

Faults

Table 21-1 **Fault assignments** *(continued)*

Fault	Source	Description
88	VIDEOSS_0_VRPU_WR_1	VIDEOSS Fault Reporting VRPU write 1. See VIDEOSS_0_VRPU_RD_0 description.
90	SRSS_FAULT_CSV	Consolidated fault output for clock supervisors. Multiple CSV can detect a violation at the same time. DATA0[15:0]: CLK_HF* root CSV violation flags. DATA0[24]: CLK_REF CSV violation flag (reference clock for CLK_HF CSVs) DATA0[25]: CLK_LF CSV violation flag DATA0[26]: CLK_HVILO CSV violation flag
91	SRSS_FAULT_SSV	Consolidated fault output for supply supervisors. Multiple CSV can detect a violation at the same time. DATA0[0]: BOD on VDDA_ADC DATA[1]: OVD on VDDA_ADC DATA[16]: LVD/HVD #1 DATA0[17]: LVD/HVD #2
92	SRSS_FAULT_MCWDT0	Fault output for MCWDT0 (all sub-counters) Multiple counters can detect a violation at the same time. DATA0[0]: MCWDT sub counter 0 LOWER_LIMIT DATA0[1]: MCWDT sub counter 0 UPPER_LIMIT DATA0[2]: MCWDT sub counter 1 LOWER_LIMIT DATA0[3]: MCWDT sub counter 1 UPPER_LIMIT
93	SRSS_FAULT_MCWDT1	Fault output for MCWDT1 (all sub-counters). See SRSS_FAULT_MCWDT0 description.

22 Peripheral protection unit fixed structure pairs

Protection pair is a pair PPU structures, a master, and a slave structure. The master structure protects the slave structure, and the slave structure protects resources such as peripheral registers, or the peripheral itself.

Refer to [Table 6-1](#) for the FX PPU Base address.

Table 22-1 PPU fixed structure pairs

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
0	PERI_MAIN	0x40000200	0x00000040	Peripheral Interconnect main
1	PERI_SECURE	0x40002000	0x00000004	Peripheral interconnect secure
2	PERI_GR0_GROUP	0x40004010	0x00000004	Peripheral Group #0 main
3	PERI_GR1_GROUP	0x40004050	0x00000004	Peripheral Group #1 main
4	PERI_GR2_GROUP	0x40004090	0x00000004	Peripheral Group #2 main
5	PERI_GR3_GROUP	0x400040C0	0x00000020	Peripheral Group #3 main
6	PERI_GR4_GROUP	0x40004100	0x00000020	Peripheral Group #4 main
7	PERI_GR5_GROUP	0x40004140	0x00000020	Peripheral Group #5 main
8	PERI_GR6_GROUP	0x40004180	0x00000020	Peripheral Group #6 main
9	PERI_GR8_GROUP	0x40004200	0x00000020	Peripheral Group #8 main
10	PERI_GR9_GROUP	0x40004240	0x00000020	Peripheral Group #9 main
11	PERI_GR10_GROUP	0x40004280	0x00000020	Peripheral Group #10 main
12	PERI_GR0_BOOT	0x40004020	0x00000004	Peripheral Group #0 boot
13	PERI_GR1_BOOT	0x40004060	0x00000004	Peripheral Group #1 boot
14	PERI_GR2_BOOT	0x400040A0	0x00000004	Peripheral Group #2 boot
15	PERI_GR3_BOOT	0x400040E0	0x00000004	Peripheral Group #3 boot
16	PERI_GR4_BOOT	0x40004120	0x00000004	Peripheral Group #4 boot
17	PERI_GR5_BOOT	0x40004160	0x00000004	Peripheral Group #5 boot
18	PERI_GR6_BOOT	0x400041A0	0x00000004	Peripheral Group #6 boot
19	PERI_GR8_BOOT	0x40004220	0x00000004	Peripheral Group #8 boot
20	PERI_GR9_BOOT	0x40004260	0x00000004	Peripheral Group #9 boot
21	PERI_GR10_BOOT	0x400042A0	0x00000004	Peripheral Group #10 boot
22	PERI_TR	0x40008000	0x00008000	Peripheral trigger multiplexer
23	PERI_MS_BOOT	0x40030000	0x00001000	Peripheral master slave boot
24	PERI_PCLK_MAIN	0x40040000	0x00004000	Peripheral clock main
25	CRYPTO_MAIN	0x40100000	0x00000400	Crypto main
26	CRYPTO_CRYPT0	0x40101000	0x00000800	Crypto MMIO (Memory Mapped I/O)
27	CRYPTO_BOOT	0x40102000	0x00000100	Crypto boot
28	CRYPTO_KEY0	0x40102100	0x00000004	Crypto Key #0
29	CRYPTO_KEY1	0x40102120	0x00000004	Crypto Key #1
30	CRYPTO_BUF	0x40108000	0x00002000	Crypto buffer
31	CPUSS_CM7_0	0x40200000	0x00000400	CM7_0 CPU core
32	Reserved	0x40200500	0x00000020	
33	CPUSS_CM0	0x40201000	0x00001000	CM0+ CPU core
34	CPUSS_BOOT ^[41]	0x40202000	0x00000200	CPUSS boot
35	CPUSS_CM0_INT	0x40208000	0x00001000	CPUSS CM0+ interrupts
36	CPUSS_CM7_0_INT	0x4020A000	0x00001000	CPUSS CM7_0 interrupts
37	Reserved	0x4020C000	0x00001000	

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Peripheral protection unit fixed structure pairs

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
38	FAULT_STRUCT0_MAIN	0x40210000	0x00000100	CPUSS Fault Structure #0 main
39	FAULT_STRUCT1_MAIN	0x40210100	0x00000100	CPUSS Fault Structure #1 main
40	FAULT_STRUCT2_MAIN	0x40210200	0x00000100	CPUSS Fault Structure #2 main
41	FAULT_STRUCT3_MAIN	0x40210300	0x00000100	CPUSS Fault Structure #3 main
42	IPC_STRUCT0_IPC	0x40220000	0x00000020	CPUSS IPC Structure #0
43	IPC_STRUCT1_IPC	0x40220020	0x00000020	CPUSS IPC Structure #1
44	IPC_STRUCT2_IPC	0x40220040	0x00000020	CPUSS IPC Structure #2
45	IPC_STRUCT3_IPC	0x40220060	0x00000020	CPUSS IPC Structure #3
46	IPC_STRUCT4_IPC	0x40220080	0x00000020	CPUSS IPC Structure #4
47	IPC_STRUCT5_IPC	0x402200A0	0x00000020	CPUSS IPC Structure #5
48	IPC_STRUCT6_IPC	0x402200C0	0x00000020	CPUSS IPC Structure #6
49	IPC_STRUCT7_IPC	0x402200E0	0x00000020	CPUSS IPC Structure #7
50	IPC_INTR_STRUCT0_INTR	0x40221000	0x00000010	CPUSS IPC Interrupt Structure #0
51	IPC_INTR_STRUCT1_INTR	0x40221020	0x00000010	CPUSS IPC Interrupt Structure #1
52	IPC_INTR_STRUCT2_INTR	0x40221040	0x00000010	CPUSS IPC Interrupt Structure #2
53	IPC_INTR_STRUCT3_INTR	0x40221060	0x00000010	CPUSS IPC Interrupt Structure #3
54	IPC_INTR_STRUCT4_INTR	0x40221080	0x00000010	CPUSS IPC Interrupt Structure #4
55	IPC_INTR_STRUCT5_INTR	0x402210A0	0x00000010	CPUSS IPC Interrupt Structure #5
56	IPC_INTR_STRUCT6_INTR	0x402210C0	0x00000010	CPUSS IPC Interrupt Structure #6
57	IPC_INTR_STRUCT7_INTR	0x402210E0	0x00000010	CPUSS IPC Interrupt Structure #7
58	PROT_SMPU_MAIN	0x40230000	0x00000040	Peripheral protection S MPU main
59	PROT_MPU0_MAIN	0x40234000	0x00000004	Peripheral protection MPU #0 main
60	PROT_MPU9_MAIN	0x40236400	0x00000400	Peripheral protection MPU #9 main
61	PROT_MPU11_MAIN	0x40236C00	0x00000004	Peripheral protection MPU #11 main
62	PROT_MPU12_MAIN	0x40237000	0x00000400	Peripheral protection MPU #12 main
63	PROT_MPU14_MAIN	0x40237800	0x00000004	Peripheral protection MPU #14 main
64	PROT_MPU15_MAIN	0x40237C00	0x00000400	Peripheral protection MPU #15 main
65	FLASHC_MAIN	0x40240000	0x00000008	Flash controller main
66	FLASHC_CMD	0x40240008	0x00000004	Flash controller command
67	FLASHC_DFT	0x40240200	0x00000100	Flash controller tests
68	FLASHC_CM0	0x40240400	0x00000080	Flash controller CM0+
69	FLASHC_CM7_0	0x402404E0	0x00000004	Flash controller CM7_0
70	FLASHC_CRYPT0	0x40240580	0x00000004	Flash controller Crypto
71	FLASHC_DW0	0x40240600	0x00000004	Flash controller P-DMA0
72	FLASHC_DW1	0x40240680	0x00000004	Flash controller P-DMA1
73	FLASHC_DMAC	0x40240700	0x00000004	Flash controller M-DMA0
74	FLASHC_FlashMgmt ^[41]	0x4024F000	0x00000080	Flash management
75	FLASHC_MainSafety	0x4024F400	0x00000008	Flash controller main safety
76	FLASHC_WorkSafety	0x4024F500	0x00000004	Flash controller work safety
77	SRSS_GENERAL	0x40260000	0x00000400	SRSS General
78	SRSS_MAIN	0x40261000	0x00001000	SRSS main
79	SRSS_SECURE	0x40262000	0x00002000	SRSS secure
80	MCWDT0_CONFIG	0x40268000	0x00000080	MCWDT #0 configuration

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
81	MCWDT1_CONFIG	0x40268100	0x00000080	MCWDT #1 configuration
82	MCWDT0_MAIN	0x40268080	0x00000040	MCWDT #0 main
83	MCWDT1_MAIN	0x40268180	0x00000040	MCWDT #1 main
84	WDT_CONFIG	0x4026C000	0x00000020	System WDT configuration
85	WDT_MAIN	0x4026C040	0x00000020	System WDT main
86	BACKUP_BACKUP	0x40270000	0x00010000	SRSS backup
87	DW0_DW	0x40280000	0x00000100	P-DMA0 main
88	DW1_DW	0x40290000	0x00000100	P-DMA1 main
89	DW0_DW_CRC	0x40280100	0x00000080	P-DMA0 CRC
90	DW1_DW_CRC	0x40290100	0x00000080	P-DMA1 CRC
91	DW0_CH_STRUCT0_CH	0x40288000	0x00000040	P-DMA0 Channel #0
92	DW0_CH_STRUCT1_CH	0x40288040	0x00000040	P-DMA0 Channel #1
93	DW0_CH_STRUCT2_CH	0x40288080	0x00000040	P-DMA0 Channel #2
94	DW0_CH_STRUCT3_CH	0x402880C0	0x00000040	P-DMA0 Channel #3
95	DW0_CH_STRUCT4_CH	0x40288100	0x00000040	P-DMA0 Channel #4
96	DW0_CH_STRUCT5_CH	0x40288140	0x00000040	P-DMA0 Channel #5
97	DW0_CH_STRUCT6_CH	0x40288180	0x00000040	P-DMA0 Channel #6
98	DW0_CH_STRUCT7_CH	0x402881C0	0x00000040	P-DMA0 Channel #7
99	DW0_CH_STRUCT8_CH	0x40288200	0x00000040	P-DMA0 Channel #8
100	DW0_CH_STRUCT9_CH	0x40288240	0x00000040	P-DMA0 Channel #9
101	DW0_CH_STRUCT10_CH	0x40288280	0x00000040	P-DMA0 Channel #10
102	DW0_CH_STRUCT11_CH	0x402882C0	0x00000040	P-DMA0 Channel #11
103	DW0_CH_STRUCT12_CH	0x40288300	0x00000040	P-DMA0 Channel #12
104	DW0_CH_STRUCT13_CH	0x40288340	0x00000040	P-DMA0 Channel #13
105	DW0_CH_STRUCT14_CH	0x40288380	0x00000040	P-DMA0 Channel #14
106	DW0_CH_STRUCT15_CH	0x402883C0	0x00000040	P-DMA0 Channel #15
107	DW0_CH_STRUCT16_CH	0x40288400	0x00000040	P-DMA0 Channel #16
108	DW0_CH_STRUCT17_CH	0x40288440	0x00000040	P-DMA0 Channel #17
109	DW0_CH_STRUCT18_CH	0x40288480	0x00000040	P-DMA0 Channel #18
110	DW0_CH_STRUCT19_CH	0x402884C0	0x00000040	P-DMA0 Channel #19
111	DW0_CH_STRUCT20_CH	0x40288500	0x00000040	P-DMA0 Channel #20
112	DW0_CH_STRUCT21_CH	0x40288540	0x00000040	P-DMA0 Channel #21
113	DW0_CH_STRUCT22_CH	0x40288580	0x00000040	P-DMA0 Channel #22
114	DW0_CH_STRUCT23_CH	0x402885C0	0x00000040	P-DMA0 Channel #23
115	DW0_CH_STRUCT24_CH	0x40288600	0x00000040	P-DMA0 Channel #24
116	DW0_CH_STRUCT25_CH	0x40288640	0x00000040	P-DMA0 Channel #25
117	DW0_CH_STRUCT26_CH	0x40288680	0x00000040	P-DMA0 Channel #26
118	DW0_CH_STRUCT27_CH	0x402886C0	0x00000040	P-DMA0 Channel #27
119	DW0_CH_STRUCT28_CH	0x40288700	0x00000040	P-DMA0 Channel #28
120	DW0_CH_STRUCT29_CH	0x40288740	0x00000040	P-DMA0 Channel #29
121	DW0_CH_STRUCT30_CH	0x40288780	0x00000040	P-DMA0 Channel #30
122	DW0_CH_STRUCT31_CH	0x402887C0	0x00000040	P-DMA0 Channel #31
123	DW0_CH_STRUCT32_CH	0x40288800	0x00000040	P-DMA0 Channel #32

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Peripheral protection unit fixed structure pairs

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
124	DW0_CH_STRUCT33_CH	0x40288840	0x00000040	P-DMA0 Channel #33
125	DW0_CH_STRUCT34_CH	0x40288880	0x00000040	P-DMA0 Channel #34
126	DW0_CH_STRUCT35_CH	0x402888C0	0x00000040	P-DMA0 Channel #35
127	DW0_CH_STRUCT36_CH	0x40288900	0x00000040	P-DMA0 Channel #36
128	DW0_CH_STRUCT37_CH	0x40288940	0x00000040	P-DMA0 Channel #37
129	DW0_CH_STRUCT38_CH	0x40288980	0x00000040	P-DMA0 Channel #38
130	DW0_CH_STRUCT39_CH	0x402889C0	0x00000040	P-DMA0 Channel #39
131	DW0_CH_STRUCT40_CH	0x40288A00	0x00000040	P-DMA0 Channel #40
132	DW0_CH_STRUCT41_CH	0x40288A40	0x00000040	P-DMA0 Channel #41
133	DW0_CH_STRUCT42_CH	0x40288A80	0x00000040	P-DMA0 Channel #42
134	DW0_CH_STRUCT43_CH	0x40288AC0	0x00000040	P-DMA0 Channel #43
135	DW0_CH_STRUCT44_CH	0x40288B00	0x00000040	P-DMA0 Channel #44
136	DW0_CH_STRUCT45_CH	0x40288B40	0x00000040	P-DMA0 Channel #45
137	DW0_CH_STRUCT46_CH	0x40288B80	0x00000040	P-DMA0 Channel #46
138	DW0_CH_STRUCT47_CH	0x40288BC0	0x00000040	P-DMA0 Channel #47
139	DW0_CH_STRUCT48_CH	0x40288C00	0x00000040	P-DMA0 Channel #48
140	DW0_CH_STRUCT49_CH	0x40288C40	0x00000040	P-DMA0 Channel #49
141	DW0_CH_STRUCT50_CH	0x40288C80	0x00000040	P-DMA0 Channel #50
142	DW0_CH_STRUCT51_CH	0x40288CC0	0x00000040	P-DMA0 Channel #51
143	DW0_CH_STRUCT52_CH	0x40288D00	0x00000040	P-DMA0 Channel #52
144	DW0_CH_STRUCT53_CH	0x40288D40	0x00000040	P-DMA0 Channel #53
145	DW0_CH_STRUCT54_CH	0x40288D80	0x00000040	P-DMA0 Channel #54
146	DW0_CH_STRUCT55_CH	0x40288DC0	0x00000040	P-DMA0 Channel #55
147	DW0_CH_STRUCT56_CH	0x40288E00	0x00000040	P-DMA0 Channel #56
148	DW0_CH_STRUCT57_CH	0x40288E40	0x00000040	P-DMA0 Channel #57
149	DW0_CH_STRUCT58_CH	0x40288E80	0x00000040	P-DMA0 Channel #58
150	DW0_CH_STRUCT59_CH	0x40288EC0	0x00000040	P-DMA0 Channel #59
151	DW0_CH_STRUCT60_CH	0x40288F00	0x00000040	P-DMA0 Channel #60
152	DW0_CH_STRUCT61_CH	0x40288F40	0x00000040	P-DMA0 Channel #61
153	DW0_CH_STRUCT62_CH	0x40288F80	0x00000040	P-DMA0 Channel #62
154	DW0_CH_STRUCT63_CH	0x40288FC0	0x00000040	P-DMA0 Channel #63
155	DW0_CH_STRUCT64_CH	0x40289000	0x00000040	P-DMA0 Channel #64
156	DW0_CH_STRUCT65_CH	0x40289040	0x00000040	P-DMA0 Channel #65
157	DW0_CH_STRUCT66_CH	0x40289080	0x00000040	P-DMA0 Channel #66
158	DW0_CH_STRUCT67_CH	0x402890C0	0x00000040	P-DMA0 Channel #67
159	DW0_CH_STRUCT68_CH	0x40289100	0x00000040	P-DMA0 Channel #68
160	DW0_CH_STRUCT69_CH	0x40289140	0x00000040	P-DMA0 Channel #69
161	DW0_CH_STRUCT70_CH	0x40289180	0x00000040	P-DMA0 Channel #70
162	DW0_CH_STRUCT71_CH	0x402891C0	0x00000040	P-DMA0 Channel #71
163	DW0_CH_STRUCT72_CH	0x40289200	0x00000040	P-DMA0 Channel #72
164	DW0_CH_STRUCT73_CH	0x40289240	0x00000040	P-DMA0 Channel #73
165	DW0_CH_STRUCT74_CH	0x40289280	0x00000040	P-DMA0 Channel #74
166	DW0_CH_STRUCT75_CH	0x402892C0	0x00000040	P-DMA0 Channel #75

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
167	DW1_CH_STRUCT0_CH	0x40298000	0x00000040	P-DMA1 Channel #0
168	DW1_CH_STRUCT1_CH	0x40298040	0x00000040	P-DMA1 Channel #1
169	DW1_CH_STRUCT2_CH	0x40298080	0x00000040	P-DMA1 Channel #2
170	DW1_CH_STRUCT3_CH	0x402980C0	0x00000040	P-DMA1 Channel #3
171	DW1_CH_STRUCT4_CH	0x40298100	0x00000040	P-DMA1 Channel #4
172	DW1_CH_STRUCT5_CH	0x40298140	0x00000040	P-DMA1 Channel #5
173	DW1_CH_STRUCT6_CH	0x40298180	0x00000040	P-DMA1 Channel #6
174	DW1_CH_STRUCT7_CH	0x402981C0	0x00000040	P-DMA1 Channel #7
175	DW1_CH_STRUCT8_CH	0x40298200	0x00000040	P-DMA1 Channel #8
176	DW1_CH_STRUCT9_CH	0x40298240	0x00000040	P-DMA1 Channel #9
177	DW1_CH_STRUCT10_CH	0x40298280	0x00000040	P-DMA1 Channel #10
178	DW1_CH_STRUCT11_CH	0x402982C0	0x00000040	P-DMA1 Channel #11
179	DW1_CH_STRUCT12_CH	0x40298300	0x00000040	P-DMA1 Channel #12
180	DW1_CH_STRUCT13_CH	0x40298340	0x00000040	P-DMA1 Channel #13
181	DW1_CH_STRUCT14_CH	0x40298380	0x00000040	P-DMA1 Channel #14
182	DW1_CH_STRUCT15_CH	0x402983C0	0x00000040	P-DMA1 Channel #15
183	DW1_CH_STRUCT16_CH	0x40298400	0x00000040	P-DMA1 Channel #16
184	DW1_CH_STRUCT17_CH	0x40298440	0x00000040	P-DMA1 Channel #17
185	DW1_CH_STRUCT18_CH	0x40298480	0x00000040	P-DMA1 Channel #18
186	DW1_CH_STRUCT19_CH	0x402984C0	0x00000040	P-DMA1 Channel #19
187	DW1_CH_STRUCT20_CH	0x40298500	0x00000040	P-DMA1 Channel #20
188	DW1_CH_STRUCT21_CH	0x40298540	0x00000040	P-DMA1 Channel #21
189	DW1_CH_STRUCT22_CH	0x40298580	0x00000040	P-DMA1 Channel #22
190	DW1_CH_STRUCT23_CH	0x402985C0	0x00000040	P-DMA1 Channel #23
191	DW1_CH_STRUCT24_CH	0x40298600	0x00000040	P-DMA1 Channel #24
192	DW1_CH_STRUCT25_CH	0x40298640	0x00000040	P-DMA1 Channel #25
193	DW1_CH_STRUCT26_CH	0x40298680	0x00000040	P-DMA1 Channel #26
194	DW1_CH_STRUCT27_CH	0x402986C0	0x00000040	P-DMA1 Channel #27
195	DW1_CH_STRUCT28_CH	0x40298700	0x00000040	P-DMA1 Channel #28
196	DW1_CH_STRUCT29_CH	0x40298740	0x00000040	P-DMA1 Channel #29
197	DW1_CH_STRUCT30_CH	0x40298780	0x00000040	P-DMA1 Channel #30
198	DW1_CH_STRUCT31_CH	0x402987C0	0x00000040	P-DMA1 Channel #31
199	DW1_CH_STRUCT32_CH	0x40298800	0x00000040	P-DMA1 Channel #32
200	DW1_CH_STRUCT33_CH	0x40298840	0x00000040	P-DMA1 Channel #33
201	DW1_CH_STRUCT34_CH	0x40298880	0x00000040	P-DMA1 Channel #34
202	DW1_CH_STRUCT35_CH	0x402988C0	0x00000040	P-DMA1 Channel #35
203	DW1_CH_STRUCT36_CH	0x40298900	0x00000040	P-DMA1 Channel #36
204	DW1_CH_STRUCT37_CH	0x40298940	0x00000040	P-DMA1 Channel #37
205	DW1_CH_STRUCT38_CH	0x40298980	0x00000040	P-DMA1 Channel #38
206	DW1_CH_STRUCT39_CH	0x402989C0	0x00000040	P-DMA1 Channel #39
207	DW1_CH_STRUCT40_CH	0x40298A00	0x00000040	P-DMA1 Channel #40
208	DW1_CH_STRUCT41_CH	0x40298A40	0x00000040	P-DMA1 Channel #41
209	DW1_CH_STRUCT42_CH	0x40298A80	0x00000040	P-DMA1 Channel #42

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
210	DW1_CH_STRUCT43_CH	0x40298AC0	0x00000040	P-DMA1 Channel #43
211	DW1_CH_STRUCT44_CH	0x40298B00	0x00000040	P-DMA1 Channel #44
212	DW1_CH_STRUCT45_CH	0x40298B40	0x00000040	P-DMA1 Channel #45
213	DW1_CH_STRUCT46_CH	0x40298B80	0x00000040	P-DMA1 Channel #46
214	DW1_CH_STRUCT47_CH	0x40298BC0	0x00000040	P-DMA1 Channel #47
215	DW1_CH_STRUCT48_CH	0x40298C00	0x00000040	P-DMA1 Channel #48
216	DW1_CH_STRUCT49_CH	0x40298C40	0x00000040	P-DMA1 Channel #49
217	DW1_CH_STRUCT50_CH	0x40298C80	0x00000040	P-DMA1 Channel #50
218	DW1_CH_STRUCT51_CH	0x40298CC0	0x00000040	P-DMA1 Channel #51
219	DW1_CH_STRUCT52_CH	0x40298D00	0x00000040	P-DMA1 Channel #52
220	DW1_CH_STRUCT53_CH	0x40298D40	0x00000040	P-DMA1 Channel #53
221	DW1_CH_STRUCT54_CH	0x40298D80	0x00000040	P-DMA1 Channel #54
222	DW1_CH_STRUCT55_CH	0x40298DC0	0x00000040	P-DMA1 Channel #55
223	DW1_CH_STRUCT56_CH	0x40298E00	0x00000040	P-DMA1 Channel #56
224	DW1_CH_STRUCT57_CH	0x40298E40	0x00000040	P-DMA1 Channel #57
225	DW1_CH_STRUCT58_CH	0x40298E80	0x00000040	P-DMA1 Channel #58
226	DW1_CH_STRUCT59_CH	0x40298EC0	0x00000040	P-DMA1 Channel #59
227	DW1_CH_STRUCT60_CH	0x40298F00	0x00000040	P-DMA1 Channel #60
228	DW1_CH_STRUCT61_CH	0x40298F40	0x00000040	P-DMA1 Channel #61
229	DW1_CH_STRUCT62_CH	0x40298F80	0x00000040	P-DMA1 Channel #62
230	DW1_CH_STRUCT63_CH	0x40298FC0	0x00000040	P-DMA1 Channel #63
231	DW1_CH_STRUCT64_CH	0x40299000	0x00000040	P-DMA1 Channel #64
232	DW1_CH_STRUCT65_CH	0x40299040	0x00000040	P-DMA1 Channel #65
233	DW1_CH_STRUCT66_CH	0x40299080	0x00000040	P-DMA1 Channel #66
234	DW1_CH_STRUCT67_CH	0x402990C0	0x00000040	P-DMA1 Channel #67
235	DW1_CH_STRUCT68_CH	0x40299100	0x00000040	P-DMA1 Channel #68
236	DW1_CH_STRUCT69_CH	0x40299140	0x00000040	P-DMA1 Channel #69
237	DW1_CH_STRUCT70_CH	0x40299180	0x00000040	P-DMA1 Channel #70
238	DW1_CH_STRUCT71_CH	0x402991C0	0x00000040	P-DMA1 Channel #71
239	DW1_CH_STRUCT72_CH	0x40299200	0x00000040	P-DMA1 Channel #72
240	DW1_CH_STRUCT73_CH	0x40299240	0x00000040	P-DMA1 Channel #73
241	DW1_CH_STRUCT74_CH	0x40299280	0x00000040	P-DMA1 Channel #74
242	DW1_CH_STRUCT75_CH	0x402992C0	0x00000040	P-DMA1 Channel #75
243	DW1_CH_STRUCT76_CH	0x40299300	0x00000040	P-DMA1 Channel #76
244	DW1_CH_STRUCT77_CH	0x40299340	0x00000040	P-DMA1 Channel #77
245	DW1_CH_STRUCT78_CH	0x40299380	0x00000040	P-DMA1 Channel #78
246	DW1_CH_STRUCT79_CH	0x402993C0	0x00000040	P-DMA1 Channel #79
247	DW1_CH_STRUCT80_CH	0x40299400	0x00000040	P-DMA1 Channel #80
248	DW1_CH_STRUCT81_CH	0x40299440	0x00000040	P-DMA1 Channel #81
249	DW1_CH_STRUCT82_CH	0x40299480	0x00000040	P-DMA1 Channel #82
250	DW1_CH_STRUCT83_CH	0x402994C0	0x00000040	P-DMA1 Channel #83
251	DMAC_TOP	0x402A0000	0x00000010	M-DMA0 main
252	DMAC_CH0_CH	0x402A1000	0x00000100	M-DMA0 Channel #0

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Peripheral protection unit fixed structure pairs

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
253	DMAC_CH1_CH	0x402A1100	0x00000100	M-DMA0 Channel #1
254	DMAC_CH2_CH	0x402A1200	0x00000100	M-DMA0 Channel #2
255	DMAC_CH3_CH	0x402A1300	0x00000100	M-DMA0 Channel #3
256	DMAC_CH4_CH	0x402A1400	0x00000100	M-DMA0 Channel #4
257	DMAC_CH5_CH	0x402A1500	0x00000100	M-DMA0 Channel #5
258	DMAC_CH6_CH	0x402A1600	0x00000100	M-DMA0 Channel #6
259	DMAC_CH7_CH	0x402A1700	0x00000100	M-DMA0 Channel #7
260	AXI_DMAC_TOP	0x402B0000	0x00000008	AXI M-DMA1 main
261	AXI_DMAC_SEC	0x402B0008	0x00000004	AXI M-DMA1 active secure channels
262	AXI_DMAC_NONSEC	0x402B000C	0x00000004	AXI M-DMA1 active non-secure channels
263	AXI_DMAC_CH0_CH	0x402B1000	0x00000100	AXI M-DMA1 Channel #0
264	AXI_DMAC_CH1_CH	0x402B1100	0x00000100	AXI M-DMA1 Channel #1
265	AXI_DMAC_CH2_CH	0x402B1200	0x00000100	AXI M-DMA1 Channel #2
266	AXI_DMAC_CH3_CH	0x402B1300	0x00000100	AXI M-DMA1 Channel #3
267	EFUSE_CTL	0x402C0000	0x00000200	EFUSE control
268	EFUSE_DATA	0x402C0800	0x00000200	EFUSE data
269	Reserved	0x402F0000	0x00001000	
270	HSIOM_PRT0_PRT	0x40300000	0x00000008	HSIOM Port #0
271	HSIOM_PRT1_PRT	0x40300010	0x00000008	HSIOM Port #1
272	HSIOM_PRT2_PRT	0x40300020	0x00000008	HSIOM Port #2
273	HSIOM_PRT3_PRT	0x40300030	0x00000008	HSIOM Port #3
274	HSIOM_PRT4_PRT	0x40300040	0x00000008	HSIOM Port #4
275	HSIOM_PRT5_PRT	0x40300050	0x00000008	HSIOM Port #5
276	HSIOM_PRT6_PRT	0x40300060	0x00000008	HSIOM Port #6
277	HSIOM_PRT7_PRT	0x40300070	0x00000008	HSIOM Port #7
278	HSIOM_PRT8_PRT	0x40300080	0x00000008	HSIOM Port #8
279	HSIOM_PRT9_PRT	0x40300090	0x00000008	HSIOM Port #9
280	HSIOM_PRT10_PRT	0x403000A0	0x00000008	HSIOM Port #10
281	HSIOM_PRT11_PRT	0x403000B0	0x00000008	HSIOM Port #11
282	HSIOM_PRT12_PRT	0x403000C0	0x00000008	HSIOM Port #12
283	HSIOM_PRT13_PRT	0x403000D0	0x00000008	HSIOM Port #13
284	HSIOM_PRT14_PRT	0x403000E0	0x00000008	HSIOM Port #14
285	HSIOM_PRT15_PRT	0x403000F0	0x00000008	HSIOM Port #15
286	HSIOM_PRT16_PRT	0x40300100	0x00000008	HSIOM Port #16
287	HSIOM_PRT17_PRT	0x40300110	0x00000008	HSIOM Port #17
288	HSIOM_PRT18_PRT	0x40300120	0x00000008	HSIOM Port #18
289	HSIOM_PRT19_PRT	0x40300130	0x00000008	HSIOM Port #19
290	HSIOM_PRT20_PRT	0x40300140	0x00000008	HSIOM Port #20
291	HSIOM_PRT21_PRT	0x40300150	0x00000008	HSIOM Port #21
292	HSIOM_AMUX	0x40302000	0x00000020	HSIOM Analog multiplexer
293	HSIOM_MON	0x40302200	0x00000010	HSIOM monitor
294	GPIO_PRT0_PRT	0x40310000	0x00000040	GPIO_STD Port #0
295	GPIO_PRT1_PRT	0x40310080	0x00000040	GPIO_STD Port #1

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Peripheral protection unit fixed structure pairs

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
296	GPIO_PRT2_PRT	0x40310100	0x00000040	GPIO_STD Port #2
297	GPIO_PRT3_PRT	0x40310180	0x00000040	GPIO_ENH Port #3
298	GPIO_PRT4_PRT	0x40310200	0x00000040	GPIO_STD Port #4
299	GPIO_PRT5_PRT	0x40310280	0x00000040	GPIO_ENH Port #5
300	GPIO_PRT6_PRT	0x40310300	0x00000040	GPIO_STD Port #6
301	GPIO_PRT7_PRT	0x40310380	0x00000040	GPIO_STD Port #7
302	GPIO_PRT8_PRT	0x40310400	0x00000040	GPIO_STD Port #8
303	GPIO_PRT9_PRT	0x40310480	0x00000040	GPIO_SMC Port #9
304	GPIO_PRT10_PRT	0x40310500	0x00000040	GPIO_SMC Port #10
305	GPIO_PRT11_PRT	0x40310580	0x00000040	GPIO_SMC Port #11
306	GPIO_PRT12_PRT	0x40310600	0x00000040	GPIO_SMC Port #12
307	GPIO_PRT13_PRT	0x40310680	0x00000040	HSIO_STDLN Port #13
308	GPIO_PRT14_PRT	0x40310700	0x00000040	HSIO_STDLN Port #14
309	GPIO_PRT15_PRT	0x40310780	0x00000040	HSIO_STDLN Port #15
310	GPIO_PRT16_PRT	0x40310800	0x00000040	HSIO_STDLN Port #16
311	GPIO_PRT17_PRT	0x40310880	0x00000040	HSIO_STDLN Port #17
312	GPIO_PRT18_PRT	0x40310900	0x00000040	HSIO_STDLN Port #18
313	GPIO_PRT19_PRT	0x40310980	0x00000040	HSIO_STDLN Port #19
314	GPIO_PRT20_PRT	0x40310A00	0x00000040	HSIO_STDLN Port #20
315	GPIO_PRT21_PRT	0x40310A80	0x00000040	HSIO_STDLN Port #21
316	GPIO_PRT0_CFG	0x40310040	0x00000020	GPIO_STD Port #0 Configuration
317	GPIO_PRT1_CFG	0x403100C0	0x00000020	GPIO_STD Port #1 Configuration
318	GPIO_PRT2_CFG	0x40310140	0x00000020	GPIO_STD Port #2 Configuration
319	GPIO_PRT3_CFG	0x403101C0	0x00000020	GPIO_ENH Port #3 Configuration
320	GPIO_PRT4_CFG	0x40310240	0x00000020	GPIO_STD Port #4 Configuration
321	GPIO_PRT5_CFG	0x403102C0	0x00000020	GPIO_ENH Port #5 Configuration
322	GPIO_PRT6_CFG	0x40310340	0x00000020	GPIO_STD Port #6 Configuration
323	GPIO_PRT7_CFG	0x403103C0	0x00000020	GPIO_STD Port #7 Configuration
324	GPIO_PRT8_CFG	0x40310440	0x00000020	GPIO_STD Port #8 Configuration
325	GPIO_PRT9_CFG	0x403104C0	0x00000020	GPIO_SMC Port #9 Configuration
326	GPIO_PRT10_CFG	0x40310540	0x00000008	GPIO_SMC Port #10 Configuration
327	GPIO_PRT11_CFG	0x403105C0	0x00000040	GPIO_SMC Port #11 Configuration
328	GPIO_PRT12_CFG	0x40310640	0x00000040	GPIO_SMC Port #12 Configuration
329	GPIO_PRT13_CFG	0x403106C0	0x00000040	HSIO_STDLN Port #13 Configuration
330	GPIO_PRT14_CFG	0x40310740	0x00000040	HSIO_STDLN Port #14 Configuration
331	GPIO_PRT15_CFG	0x403107C0	0x00000040	HSIO_STDLN Port #15 Configuration
332	GPIO_PRT16_CFG	0x40310840	0x00000040	HSIO_STDLN Port #16 Configuration
333	GPIO_PRT17_CFG	0x403108C0	0x00000040	HSIO_STDLN Port #17 Configuration
334	GPIO_PRT18_CFG	0x40310940	0x00000040	HSIO_STDLN Port #18 Configuration
335	GPIO_PRT19_CFG	0x403109C0	0x00000040	HSIO_STDLN Port #19 Configuration
336	GPIO_PRT20_CFG	0x40310A40	0x00000040	HSIO_STDLN Port #20 Configuration
337	GPIO_PRT21_CFG	0x40310AC0	0x00000040	HSIO_STDLN Port #21 Configuration
338	GPIO_GPIO	0x40314000	0x00000040	GPIO main

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Peripheral protection unit fixed structure pairs

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
339	GPIO_TEST	0x40315000	0x00000008	GPIO test
340	SMARTIO_PRT9_PRT	0x40320900	0x00000100	SMART I/O #9
341	TCPWM0_GRP0_CNT0_CNT	0x40380000	0x00000080	TCPWM0 Group #0, Counter #0
342	TCPWM0_GRP0_CNT1_CNT	0x40380080	0x00000080	TCPWM0 Group #0, Counter #1
343	TCPWM0_GRP0_CNT2_CNT	0x40380100	0x00000080	TCPWM0 Group #0, Counter #2
344	TCPWM0_GRP0_CNT3_CNT	0x40380180	0x00000080	TCPWM0 Group #0, Counter #3
345	TCPWM0_GRP0_CNT4_CNT	0x40380200	0x00000080	TCPWM0 Group #0, Counter #4
346	TCPWM0_GRP0_CNT5_CNT	0x40380280	0x00000080	TCPWM0 Group #0, Counter #5
347	TCPWM0_GRP0_CNT6_CNT	0x40380300	0x00000080	TCPWM0 Group #0, Counter #6
348	TCPWM0_GRP0_CNT7_CNT	0x40380380	0x00000080	TCPWM0 Group #0, Counter #7
349	TCPWM0_GRP0_CNT8_CNT	0x40380400	0x00000080	TCPWM0 Group #0, Counter #8
350	TCPWM0_GRP0_CNT9_CNT	0x40380480	0x00000080	TCPWM0 Group #0, Counter #9
351	TCPWM0_GRP0_CNT10_CNT	0x40380500	0x00000080	TCPWM0 Group #0, Counter #10
352	TCPWM0_GRP0_CNT11_CNT	0x40380580	0x00000080	TCPWM0 Group #0, Counter #11
353	TCPWM0_GRP0_CNT12_CNT	0x40380600	0x00000080	TCPWM0 Group #0, Counter #12
354	TCPWM0_GRP0_CNT13_CNT	0x40380680	0x00000080	TCPWM0 Group #0, Counter #13
355	TCPWM0_GRP0_CNT14_CNT	0x40380700	0x00000080	TCPWM0 Group #0, Counter #14
356	TCPWM0_GRP0_CNT15_CNT	0x40380780	0x00000080	TCPWM0 Group #0, Counter #15
357	TCPWM0_GRP0_CNT16_CNT	0x40380800	0x00000080	TCPWM0 Group #0, Counter #16
358	TCPWM0_GRP0_CNT17_CNT	0x40380880	0x00000080	TCPWM0 Group #0, Counter #17
359	TCPWM0_GRP0_CNT18_CNT	0x40380900	0x00000080	TCPWM0 Group #0, Counter #18
360	TCPWM0_GRP0_CNT19_CNT	0x40380980	0x00000080	TCPWM0 Group #0, Counter #19
361	TCPWM0_GRP0_CNT20_CNT	0x40380A00	0x00000080	TCPWM0 Group #0, Counter #20
362	TCPWM0_GRP0_CNT21_CNT	0x40380A80	0x00000080	TCPWM0 Group #0, Counter #21
363	TCPWM0_GRP0_CNT22_CNT	0x40380B00	0x00000080	TCPWM0 Group #0, Counter #22
364	TCPWM0_GRP0_CNT23_CNT	0x40380B80	0x00000080	TCPWM0 Group #0, Counter #23
365	TCPWM0_GRP0_CNT24_CNT	0x40380C00	0x00000080	TCPWM0 Group #0, Counter #24
366	TCPWM0_GRP0_CNT25_CNT	0x40380C80	0x00000080	TCPWM0 Group #0, Counter #25
367	TCPWM0_GRP0_CNT26_CNT	0x40380D00	0x00000080	TCPWM0 Group #0, Counter #26
368	TCPWM0_GRP0_CNT27_CNT	0x40380D80	0x00000080	TCPWM0 Group #0, Counter #27
369	TCPWM0_GRP0_CNT28_CNT	0x40380E00	0x00000080	TCPWM0 Group #0, Counter #28
370	TCPWM0_GRP0_CNT29_CNT	0x40380E80	0x00000080	TCPWM0 Group #0, Counter #29
371	TCPWM0_GRP0_CNT30_CNT	0x40380F00	0x00000080	TCPWM0 Group #0, Counter #30
372	TCPWM0_GRP0_CNT31_CNT	0x40380F80	0x00000080	TCPWM0 Group #0, Counter #31
373	TCPWM0_GRP0_CNT32_CNT	0x40381000	0x00000080	TCPWM0 Group #0, Counter #32
374	TCPWM0_GRP0_CNT33_CNT	0x40381080	0x00000080	TCPWM0 Group #0, Counter #33
375	TCPWM0_GRP0_CNT34_CNT	0x40381100	0x00000080	TCPWM0 Group #0, Counter #34
376	TCPWM0_GRP0_CNT35_CNT	0x40381180	0x00000080	TCPWM0 Group #0, Counter #35
377	TCPWM0_GRP0_CNT36_CNT	0x40381200	0x00000080	TCPWM0 Group #0, Counter #36
378	TCPWM0_GRP0_CNT37_CNT	0x40381280	0x00000080	TCPWM0 Group #0, Counter #37
379	TCPWM0_GRP1_CNT0_CNT	0x40388000	0x00000080	TCPWM0 Group #1, Counter #0
380	TCPWM0_GRP1_CNT1_CNT	0x40388080	0x00000080	TCPWM0 Group #1, Counter #1
381	TCPWM0_GRP1_CNT2_CNT	0x40388100	0x00000080	TCPWM0 Group #1, Counter #2

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Peripheral protection unit fixed structure pairs

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
382	TCPWM0_GRP1_CNT3_CNT	0x40388180	0x00000080	TCPWM0 Group #1, Counter #3
383	TCPWM0_GRP1_CNT4_CNT	0x40388200	0x00000080	TCPWM0 Group #1, Counter #4
384	TCPWM0_GRP1_CNT5_CNT	0x40388280	0x00000080	TCPWM0 Group #1, Counter #5
385	TCPWM0_GRP1_CNT6_CNT	0x40388300	0x00000080	TCPWM0 Group #1, Counter #6
386	TCPWM0_GRP1_CNT7_CNT	0x40388380	0x00000080	TCPWM0 Group #1, Counter #7
387	TCPWM0_GRP1_CNT8_CNT	0x40388400	0x00000080	TCPWM0 Group #1, Counter #8
388	TCPWM0_GRP1_CNT9_CNT	0x40388480	0x00000080	TCPWM0 Group #1, Counter #9
389	TCPWM0_GRP1_CNT10_CNT	0x40388500	0x00000080	TCPWM0 Group #1, Counter #10
390	TCPWM0_GRP1_CNT11_CNT	0x40388580	0x00000080	TCPWM0 Group #1, Counter #11
391	TCPWM0_GRP2_CNT0_CNT	0x40390000	0x00000080	TCPWM0 Group #2, Counter #0
392	TCPWM0_GRP2_CNT1_CNT	0x40390080	0x00000080	TCPWM0 Group #2, Counter #1
393	TCPWM0_GRP2_CNT2_CNT	0x40390100	0x00000080	TCPWM0 Group #2, Counter #2
394	TCPWM0_GRP2_CNT3_CNT	0x40390180	0x00000080	TCPWM0 Group #2, Counter #3
395	TCPWM0_GRP2_CNT4_CNT	0x40390200	0x00000080	TCPWM0 Group #2, Counter #4
396	TCPWM0_GRP2_CNT5_CNT	0x40390280	0x00000080	TCPWM0 Group #2, Counter #5
397	TCPWM0_GRP2_CNT6_CNT	0x40390300	0x00000080	TCPWM0 Group #2, Counter #6
398	TCPWM0_GRP2_CNT7_CNT	0x40390380	0x00000080	TCPWM0 Group #2, Counter #7
399	TCPWM0_GRP2_CNT8_CNT	0x40390400	0x00000080	TCPWM0 Group #2, Counter #8
400	TCPWM0_GRP2_CNT9_CNT	0x40390480	0x00000080	TCPWM0 Group #2, Counter #9
401	TCPWM0_GRP2_CNT10_CNT	0x40390500	0x00000080	TCPWM0 Group #2, Counter #10
402	TCPWM0_GRP2_CNT11_CNT	0x40390580	0x00000080	TCPWM0 Group #2, Counter #11
403	TCPWM0_GRP2_CNT12_CNT	0x40390600	0x00000080	TCPWM0 Group #2, Counter #12
404	TCPWM0_GRP2_CNT13_CNT	0x40390680	0x00000080	TCPWM0 Group #2, Counter #13
405	TCPWM0_GRP2_CNT14_CNT	0x40390700	0x00000080	TCPWM0 Group #2, Counter #14
406	TCPWM0_GRP2_CNT15_CNT	0x40390780	0x00000080	TCPWM0 Group #2, Counter #15
407	TCPWM0_GRP2_CNT16_CNT	0x40390800	0x00000080	TCPWM0 Group #2, Counter #16
408	TCPWM0_GRP2_CNT17_CNT	0x40390880	0x00000080	TCPWM0 Group #2, Counter #17
409	TCPWM0_GRP2_CNT18_CNT	0x40390900	0x00000080	TCPWM0 Group #2, Counter #18
410	TCPWM0_GRP2_CNT19_CNT	0x40390980	0x00000080	TCPWM0 Group #2, Counter #19
411	TCPWM0_GRP2_CNT20_CNT	0x40390A00	0x00000080	TCPWM0 Group #2, Counter #20
412	TCPWM0_GRP2_CNT21_CNT	0x40390A80	0x00000080	TCPWM0 Group #2, Counter #21
413	TCPWM0_GRP2_CNT22_CNT	0x40390B00	0x00000080	TCPWM0 Group #2, Counter #22
414	TCPWM0_GRP2_CNT23_CNT	0x40390B80	0x00000080	TCPWM0 Group #2, Counter #23
415	TCPWM0_GRP2_CNT24_CNT	0x40390C00	0x00000080	TCPWM0 Group #2, Counter #24
416	TCPWM0_GRP2_CNT25_CNT	0x40390C80	0x00000080	TCPWM0 Group #2, Counter #25
417	TCPWM0_GRP2_CNT26_CNT	0x40390D00	0x00000080	TCPWM0 Group #2, Counter #26
418	TCPWM0_GRP2_CNT27_CNT	0x40390D80	0x00000080	TCPWM0 Group #2, Counter #27
419	TCPWM0_GRP2_CNT28_CNT	0x40390E00	0x00000080	TCPWM0 Group #2, Counter #28
420	TCPWM0_GRP2_CNT29_CNT	0x40390E80	0x00000080	TCPWM0 Group #2, Counter #29
421	TCPWM0_GRP2_CNT30_CNT	0x40390F00	0x00000080	TCPWM0 Group #2, Counter #30
422	TCPWM0_GRP2_CNT31_CNT	0x40390F80	0x00000080	TCPWM0 Group #2, Counter #31
423	EVTGEN0	0x403F0000	0x00001000	Event generator #0
424	SMIF0	0x40420000	0x00001000	Serial Memory Interface #0

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Peripheral protection unit fixed structure pairs

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
425	SMIF1	0x40430000	0x00001000	Serial Memory Interface #1
426	ETH0	0x40480000	0x00010000	Ethernet0
427	LIN0_MAIN	0x40500000	0x00000008	LIN0, main
428	LIN0_CH0_CH	0x40508000	0x00000100	LIN0, Channel #0
429	LIN0_CH1_CH	0x40508100	0x00000100	LIN0, Channel #1
430	CXPI0_MAIN	0x40510000	0x00000008	CXPI0, main
431	CXPI0_CH0_CH	0x40518000	0x00000100	CXPI0, Channel #0
432	CXPI0_CH1_CH	0x40518100	0x00000100	CXPI0, Channel #1
433	CANFD0_CH0_CH	0x40520000	0x00000200	CAN0, Channel #0
434	CANFD0_CH1_CH	0x40520200	0x00000200	CAN0, Channel #1
435	CANFD1_CH0_CH	0x40540000	0x00000200	CAN1, Channel #0
436	CANFD1_CH1_CH	0x40540200	0x00000200	CAN1, Channel #1
437	CANFD0_MAIN	0x40521000	0x00000100	CAN0 main
438	CANFD1_MAIN	0x40541000	0x00000100	CAN1 main
439	CANFD0_BUF	0x40530000	0x00010000	CAN0 buffer
440	CANFD1_BUF	0x40550000	0x00010000	CAN1 buffer
441	SCB0	0x40600000	0x00010000	SCB0
442	SCB1	0x40610000	0x00010000	SCB1
443	SCB2	0x40620000	0x00010000	SCB2
444	SCB3	0x40630000	0x00010000	SCB3
445	SCB4	0x40640000	0x00010000	SCB4
446	SCB5	0x40650000	0x00010000	SCB5
447	SCB6	0x40660000	0x00010000	SCB6
448	SCB7	0x40670000	0x00010000	SCB7
449	SCB8	0x40680000	0x00010000	SCB8
450	SCB9	0x40690000	0x00010000	SCB9
451	SCB10	0x406A0000	0x00010000	SCB10
452	SCB11	0x406B0000	0x00010000	SCB11
453	TDM0_TDM_STRUCT0_TDM_TX_STRUCT_TX	0x40818000	0x00000100	TDM0 TX Structure #0
454	TDM0_TDM_STRUCT1_TDM_TX_STRUCT_TX	0x40818200	0x00000100	TDM0 TX Structure #1
455	TDM0_TDM_STRUCT2_TDM_TX_STRUCT_TX	0x40818400	0x00000100	TDM0 TX Structure #2
456	TDM0_TDM_STRUCT3_TDM_TX_STRUCT_TX	0x40818600	0x00000100	TDM0 TX Structure #3
457	TDM0_TDM_STRUCT0_TDM_RX_STRUCT_RX	0x40818100	0x00000100	TDM0 RX Structure #0
458	TDM0_TDM_STRUCT1_TDM_RX_STRUCT_RX	0x40818300	0x00000100	TDM0 RX Structure #1
459	TDM0_TDM_STRUCT2_TDM_RX_STRUCT_RX	0x40818500	0x00000100	TDM0 RX Structure #2
460	TDM0_TDM_STRUCT3_TDM_RX_STRUCT_RX	0x40818700	0x00000100	TDM0 RX Structure #3
461	SG0_SG_STRUCT0_TX	0x40828000	0x00000100	SG0 TX Structure #0
462	SG0_SG_STRUCT1_TX	0x40828100	0x00000100	SG0 TX Structure #1
463	SG0_SG_STRUCT2_TX	0x40828200	0x00000100	SG0 TX Structure #2
464	SG0_SG_STRUCT3_TX	0x40828300	0x00000100	SG0 TX Structure #3
465	SG0_SG_STRUCT4_TX	0x40828400	0x00000100	SG0 TX Structure #4
466	PWM0_MAIN	0x40830000	0x00000010	PW0 Main
467	PWM0_TX0_TX	0x40838000	0x00000100	PWM0 TX0

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Peripheral protection unit fixed structure pairs

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
468	PWM0_TX1_TX	0x40838100	0x00000100	PWM0 TX1
469	DAC0_MAIN	0x40840000	0x00000100	DAC0 Main
470	MIXER0_MIXER_SRC_STRUCT0_SRC	0x40888000	0x00000100	MIXER0 Source Structure #0
471	MIXER0_MIXER_SRC_STRUCT1_SRC	0x40888100	0x00000100	MIXER0 Source Structure #1
472	MIXER0_MIXER_SRC_STRUCT2_SRC	0x40888200	0x00000100	MIXER0 Source Structure #2
473	MIXER0_MIXER_SRC_STRUCT3_SRC	0x40888300	0x00000100	MIXER0 Source Structure #3
474	MIXER0_MIXER_SRC_STRUCT4_SRC	0x40888400	0x00000100	MIXER0 Source Structure #4
475	MIXER1_MIXER_SRC_STRUCT0_SRC	0x40898000	0x00000100	MIXER1 Source Structure #0
476	MIXER1_MIXER_SRC_STRUCT1_SRC	0x40898100	0x00000100	MIXER1 Source Structure #1
477	MIXER1_MIXER_SRC_STRUCT2_SRC	0x40898200	0x00000100	MIXER1 Source Structure #2
478	MIXER1_MIXER_SRC_STRUCT3_SRC	0x40898300	0x00000100	MIXER1 Source Structure #3
479	MIXER1_MIXER_SRC_STRUCT4_SRC	0x40898400	0x00000100	MIXER1 Source Structure #4
480	MIXER0_MIXER_DST_STRUCT_DST	0x4088C000	0x00000100	MIXER0 Destination Structure
481	MIXER1_MIXER_DST_STRUCT_DST	0x4089C000	0x00000100	MIXER1 Destination Structure
482	PASS0_SAR0_SAR	0x40900000	0x00000400	PASS SAR0
483	PASS0_SAR1_SAR	0x40901000	0x00000008	PASS SAR1
484	PASS0_SAR0_CH0_CH	0x40900800	0x00000040	SAR0, Channel #0
485	PASS0_SAR0_CH1_CH	0x40900840	0x00000040	SAR0, Channel #1
486	PASS0_SAR0_CH2_CH	0x40900880	0x00000040	SAR0, Channel #2
487	PASS0_SAR0_CH3_CH	0x409008C0	0x00000040	SAR0, Channel #3
488	PASS0_SAR0_CH4_CH	0x40900900	0x00000040	SAR0, Channel #4
489	PASS0_SAR0_CH5_CH	0x40900940	0x00000040	SAR0, Channel #5
490	PASS0_SAR0_CH6_CH	0x40900980	0x00000040	SAR0, Channel #6
491	PASS0_SAR0_CH7_CH	0x409009C0	0x00000040	SAR0, Channel #7
492	PASS0_SAR0_CH8_CH	0x40900A00	0x00000040	SAR0, Channel #8
493	PASS0_SAR0_CH9_CH	0x40900A40	0x00000040	SAR0, Channel #9
494	PASS0_SAR0_CH10_CH	0x40900A80	0x00000040	SAR0, Channel #10
495	PASS0_SAR0_CH11_CH	0x40900AC0	0x00000040	SAR0, Channel #11
496	PASS0_SAR0_CH12_CH	0x40900B00	0x00000040	SAR0, Channel #12
497	PASS0_SAR0_CH13_CH	0x40900B40	0x00000040	SAR0, Channel #13
498	PASS0_SAR0_CH14_CH	0x40900B80	0x00000040	SAR0, Channel #14
499	PASS0_SAR0_CH15_CH	0x40900BC0	0x00000040	SAR0, Channel #15
500	PASS0_SAR0_CH16_CH	0x40900C00	0x00000040	SAR0, Channel #16
501	PASS0_SAR0_CH17_CH	0x40900C40	0x00000040	SAR0, Channel #17
502	PASS0_SAR0_CH18_CH	0x40900C80	0x00000040	SAR0, Channel #18
503	PASS0_SAR0_CH19_CH	0x40900CC0	0x00000040	SAR0, Channel #19
504	PASS0_SAR0_CH20_CH	0x40900D00	0x00000040	SAR0, Channel #20
505	PASS0_SAR0_CH21_CH	0x40900D40	0x00000040	SAR0, Channel #21
506	PASS0_SAR0_CH22_CH	0x40900D80	0x00000040	SAR0, Channel #22
507	PASS0_SAR0_CH23_CH	0x40900DC0	0x00000040	SAR0, Channel #23
508	PASS0_SAR0_CH24_CH	0x40900E00	0x00000040	SAR0, Channel #24
509	PASS0_SAR0_CH25_CH	0x40900E40	0x00000040	SAR0, Channel #25
510	PASS0_SAR0_CH26_CH	0x40900E80	0x00000040	SAR0, Channel #26

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Peripheral protection unit fixed structure pairs

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
511	PASS0_SAR0_CH27_CH	0x40900EC0	0x00000040	SAR0, Channel #27
512	PASS0_SAR0_CH28_CH	0x40900F00	0x00000040	SAR0, Channel #28
513	PASS0_SAR0_CH29_CH	0x40900F40	0x00000040	SAR0, Channel #29
514	PASS0_SAR0_CH30_CH	0x40900F80	0x00000040	SAR0, Channel #30
515	PASS0_SAR0_CH31_CH	0x40900FC0	0x00000040	SAR0, Channel #31
516	PASS0_TOP	0x409F0000	0x00001000	PASS0 SAR main
517	VIDEOSS0_VCFG_VIDEOSSCFG	0x40A00000	0x00000400	VIDEOSS#0 Configuration
518	VIDEOSS0_VCFG_VRAM	0x40A00400	0x00000400	VIDEOSS#0 VRAM Configuration
519	VIDEOSS0_GPU_GFX2D	0x40A40000	0x00040000	VIDEOSS#0 Graphics 2D Core
520	VIDEOSS0_VIDEOIOCFG_VIRQ_VIDEOIOCFG	0x40A80020	0x00000020	VIDEOSS#0 I/O Configuration
521	VIDEOSS0_CAPIFC0_FRAMEDUMP	0x40A80400	0x00000400	VIDEOSS#0 Frame Dump Unit
522	VIDEOSS0_CAPIFC0_CAPENG0	0x40A81000	0x00001000	VIDEOSS#0 Capture Engine#0
523	VIDEOSS0_DSPCFG_COMPENGCFG	0x40A90000	0x00002000	VIDEOSS#0 Composition Engine Configuration
524	VIDEOSS0_DSPSEC0_CONSTFRAME0	0x40A92000	0x00000400	VIDEOSS#0 Constant Frame#0 (Content)
525	VIDEOSS0_DSPSEC0_EXTDST0	0x40A92400	0x00000400	VIDEOSS#0 ExtDst#0 (Content)
526	VIDEOSS0_DSPPRIM0_CONSTFRAME4	0x40A92800	0x00000400	VIDEOSS#0 Constant Frame#4 (Content)
527	VIDEOSS0_DSPPRIM0_EXTDST4	0x40A92C00	0x00000400	VIDEOSS#0 ExtDst#4 (Safety)
528	VIDEOSS0_DSPSEC1_CONSTFRAME1	0x40A93000	0x00000400	VIDEOSS#0 Constant Frame#1 (Content)
529	VIDEOSS0_DSPSEC1_EXTDST1	0x40A93400	0x00000400	VIDEOSS#0 ExtDst#1 (Safety)
530	VIDEOSS0_DSPPRIM1_CONSTFRAME5	0x40A93800	0x00000400	VIDEOSS#0 Constant Frame#5 (Safety)
531	VIDEOSS0_DSPPRIM1_EXTDST5	0x40A93C00	0x00000400	VIDEOSS#0 ExtDst#5 (Safety)
532	VIDEOSS0_CAPIFC0_EXTSRC4	0x40A94000	0x00000400	VIDEOSS#0 ExtSrc#4 (Capture)
533	VIDEOSS0_CAPIFC0_STORE4	0x40A94400	0x00000400	VIDEOSS#0 Store#4 (Capture)
534	VIDEOSS0_DSPLAYER1_FETCHLAYER0	0x40A94800	0x00000400	VIDEOSS#0 Fetch Layer#0 (Display)
535	VIDEOSS0_DSPLAYER2_FETCHDECODE4	0x40A94C00	0x00000400	VIDEOSS#0 Fetch Decode#4 (Capture)
536	VIDEOSS0_DSPLAYER2_FETCHECO4	0x40A95000	0x00000400	VIDEOSS#0 Fetch Eco#4 (Capture)
537	VIDEOSS0_DSPLAYER3_FETCHWARP1	0x40A95800	0x00000400	VIDEOSS#0 Fetch Warp#1 (Display)
538	VIDEOSS0_DSPLAYER3_FETCHECO1	0x40A95C00	0x00000400	VIDEOSS#0 Fetch Eco#1 (Display)
539	VIDEOSS0_DSPLAYER4_FETCHLAYER1	0x40A96000	0x00000400	VIDEOSS#0 Fetch Layer#1 (Display)
540	VIDEOSS0_DSPLAYER5_FETCHDECODE0	0x40A96400	0x00000400	VIDEOSS#0 Fetch Decode#0 (Display)
541	VIDEOSS0_DSPVPB_GAMMACOR4	0x40A96800	0x00000400	Video Processing Block #0 GammaCor (Capture)
542	VIDEOSS0_DSPVPB_MATRIX4	0x40A96C00	0x00000400	Video Processing Block #0 Matrix (Capture)
543	VIDEOSS0_DSPVPB_GPSCALER4	0x40A97000	0x00000400	GPScaler #4 (Capture)
544	VIDEOSS0_DSPVPB_HISTOGRAM4	0x40A97400	0x00000400	Video Processing Block #0 Histogram (Capture)
545	VIDEOSS0_DSPBLEND1_LAYERBLEND1	0x40A97800	0x00000400	LayerBlend #1 (Display, Alpha Plane 1)
546	VIDEOSS0_DSPBLEND2_LAYERBLEND2	0x40A97C00	0x00000400	LayerBlend #2 (Display, Alpha Plane 2)
547	VIDEOSS0_DSPBLEND3_LAYERBLEND3	0x40A98000	0x00000400	LayerBlend #3 (Display, Alpha Plane 3)
548	VIDEOSS0_DSPBLEND4_LAYERBLEND4	0x40A98400	0x00000400	LayerBlend #4 (Display, Alpha Plane 4)
549	VIDEOSS0_DSPBLEND5_LAYERBLEND5	0x40A98800	0x00000400	LayerBlend #5 (Display, Alpha Plane 5)
550	VIDEOSS0_CAPIFC0_EXTSRC8	0x40A98C00	0x00000400	ExtSrc #8 (Display)
551	VIDEOSS0_DSPCFG0_DISENGCFG0	0x40AA0000	0x00000400	VIDEOSS#0 Display Engine#0 Configuration
552	VIDEOSS0_DSPMON0_SIG0	0x40AA1000	0x00000400	VIDEOSS#0 Display Engine#0 Signature Unit#0
553	VIDEOSS0_DSPCFG0_FRAMEGEN0	0x40AA2000	0x00000400	VIDEOSS#0 Display Engine#0 Frame Generator#0

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Peripheral protection unit fixed structure pairs

Table 22-1 PPU fixed structure pairs (continued)

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
554	VIDEOSS0_DSPCOL0_GAMMACOR0	0x40AA2400	0x00000400	VIDEOSS#0 Display Engine#0 Gamma Correction Unit#0
555	VIDEOSS0_DSPCOL0_DITHER0	0x40AA2800	0x00000400	VIDEOSS#0 Display Engine#0 Dither Unit#0
556	VIDEOSS0_DSIFC0_TCON0	0x40AA3000	0x00000800	VIDEOSS#0 Display Engine#0 Timing Controller#0
557	VIDEOSS0_DSPCFG1_DISENGCFG1	0x40AA4000	0x00000400	VIDEOSS#0 Display Engine#1 Configuration
558	VIDEOSS0_DSPMON1_SIG1	0x40AA5000	0x00000400	VIDEOSS#0 Display Engine#1 Signature Unit#1
559	VIDEOSS0_DSPCFG1_FRAMEGEN1	0x40AA6000	0x00000400	VIDEOSS#0 Display Engine#1 Frame Generator
560	VIDEOSS0_DSPCOL1_GAMMACOR1	0x40AA6400	0x00000400	VIDEOSS#0 Display Engine#1 Gamma Correction Unit#1
561	VIDEOSS0_DSPCOL1_DITHER1	0x40AA6800	0x00000400	VIDEOSS#0 Display Engine#1 Dither Unit#1
562	VIDEOSS0_DSIFC1_TCON1	0x40AA7000	0x00000800	VIDEOSS#0 Display Engine#1 Timing Controller#1
563	VIDEOSS0_DSIFC0_FPDLINK0	0x40AC0000	0x00000400	VIDEOSS#0 Display interface0 FPD-Link#0
564	VIDEOSS0_MIPICSI0_MIPICSI_STRUCT_MIPIC-SI_WRAP_MAIN	0x40AD0000	0x00000100	VIDEOSS#0 MIPICSI#0 D-PHY wrapper configuration and status
565	VIDEOSS0_MIPICSI0_MIPICSI_STRUCT_MIPIC-SI_CORE_3PIP	0x40AD0200	0x00000080	VIDEOSS#0 MIPICSI#0 RX Core through APB interface
566	VIDEOSS0_VRPU_MAIN	0x40AF0000	0x00000080	VIDEOSS#0 VRPU Configuration
567	VIDEOSS0_GFX_MPU_RD0_MAIN	0x40AF4000	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
568	VIDEOSS0_GFX_MPU_RD1_MAIN	0x40AF4400	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
569	VIDEOSS0_GFX_MPU_RD2_MAIN	0x40AF4800	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
570	VIDEOSS0_GFX_MPU_RD3_MAIN	0x40AF4C00	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
571	VIDEOSS0_GFX_MPU_RD4_MAIN	0x40AF5000	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
572	VIDEOSS0_GFX_MPU_RD5_MAIN	0x40AF5400	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
573	VIDEOSS0_GFX_MPU_RD6_MAIN	0x40AF5800	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
574	VIDEOSS0_GFX_MPU_RD7_MAIN	0x40AF5C00	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
575	VIDEOSS0_GFX_MPU_RD8_MAIN	0x40AF6000	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
576	VIDEOSS0_GFX_MPU_RD9_MAIN	0x40AF6400	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
577	VIDEOSS0_GFX_MPU_RD10_MAIN	0x40AF6800	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
578	VIDEOSS0_GFX_MPU_RD11_MAIN	0x40AF6C00	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
579	VIDEOSS0_GFX_MPU_RD12_MAIN	0x40AF7000	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
580	VIDEOSS0_GFX_MPU_RD13_MAIN	0x40AF7400	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
581	VIDEOSS0_GFX_MPU_RD14_MAIN	0x40AF7800	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
582	VIDEOSS0_GFX_MPU_RD15_MAIN	0x40AF7C00	0x00000004	VIDEOSS#0 MPU Configuration for Read Masters
583	VIDEOSS0_GFX_MPU_WR0_MAIN	0x40AF8000	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
584	VIDEOSS0_GFX_MPU_WR1_MAIN	0x40AF8400	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
585	VIDEOSS0_GFX_MPU_WR2_MAIN	0x40AF8800	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
586	VIDEOSS0_GFX_MPU_WR3_MAIN	0x40AF8C00	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
587	VIDEOSS0_GFX_MPU_WR4_MAIN	0x40AF9000	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
588	VIDEOSS0_GFX_MPU_WR5_MAIN	0x40AF9400	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
589	VIDEOSS0_GFX_MPU_WR6_MAIN	0x40AF9800	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
590	VIDEOSS0_GFX_MPU_WR7_MAIN	0x40AF9C00	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
591	VIDEOSS0_GFX_MPU_WR8_MAIN	0x40AFA000	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
592	VIDEOSS0_GFX_MPU_WR9_MAIN	0x40AFA400	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
593	VIDEOSS0_GFX_MPU_WR10_MAIN	0x40AFA800	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
594	VIDEOSS0_GFX_MPU_WR11_MAIN	0x40AFAC00	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
595	VIDEOSS0_GFX_MPU_WR12_MAIN	0x40AFB000	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

Table 22-1 PPU fixed structure pairs *(continued)*

Pair No.	PPU Fixed Structure Pair	Address	Size	Description
596	VIDEOSS0_GFX_MPU_WR13_MAIN	0x40AFB400	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
597	VIDEOSS0_GFX_MPU_WR14_MAIN	0x40AFB800	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
598	VIDEOSS0_GFX_MPU_WR15_MAIN	0x40AFBC00	0x00000004	VIDEOSS#0 MPU Configuration for Write Masters
599	PD_PD	0x40B00000	0x00000100	VIDEOSS#0 Power Domain Control

Note

41.Fixed PPU is configured inside the Boot and user is not allowed to change the attributes of this PPU.

23 Bus masters

The Arbiter (part of flash controller) performs priority-based arbitration based on the master identifier. Each bus master has a dedicated 4-bit master identifier. This master identifier is used for bus arbitration and IPC functionality.

Table 23-1 Bus masters for access and protection control

ID No.	Master ID	Description
0	CPUSS_MS_ID_CM0	Master ID for CM0+
1	CPUSS_MS_ID_CRYPT0	Master ID for Crypto
2	CPUSS_MS_ID_DW0	Master ID for P-DMA0
3	CPUSS_MS_ID_DW1	Master ID for P-DMA1
4	CPUSS_MS_ID_DMAC	Master ID for M-DMA0
9	CPUSS_MS_ID_FAST0	Master ID for External AXI Master 0 (Ethernet#0)
11	CPUSS_MS_ID_FAST2	Master ID for M-DMA1 (AXI DMA)
12	CPUSS_MS_ID_FAST3	Master ID for VIDEO Subsystem
14	CPUSS_MS_ID_CM7_0	Master ID for CM7_0
15	CPUSS_MS_ID_TC	Master ID for DAP Tap Controller

24 Miscellaneous configuration

Table 24-1 Miscellaneous configuration for CYT3DL devices

Sl. No.	Configuration	Number/ Instances	Description
0	SRSS_NUM_CLKPATH	11	Number of clock paths. One for each of FLL, PLL, Direct, and CSV
1	SRSS_NUM_HFROOT	14	Number of CLK_HFs present
2	PERI_PC_NR	8	Number of protection contexts
3	PERI_PERI_PCLK_PCLK_GROUP_NR	2	Number of asynchronous PCLK groups
4	PERI_PERI_PCLK_PCLK_GROUP_NR0_GR_DIV_8_VECT	9	Group 0, Number of divide-by-8 clock dividers
5	PERI_PERI_PCLK_PCLK_GROUP_NR0_GR_DIV_16_VECT	16	Group 0, Number of divide-by-16 clock dividers
6	PERI_PERI_PCLK_PCLK_GROUP_NR0_GR_DIV_16_5_VECT	7	Group 0, Number of divide-by-16.5 clock dividers
7	PERI_PERI_PCLK_PCLK_GROUP_NR0_GR_DIV_24_5_VECT	3	Group 0, Number of divide-by-24.5 clock dividers
8	PERI_PERI_PCLK_PCLK_GROUP_NR0_GR_CLOCK_VECT	84	Group 0, Number of programmable clocks [1, 256]
9	PERI_PERI_PCLK_PCLK_GROUP_NR1_GR_DIV_8_VECT	3	Group 1, Number of divide-by-8 clock dividers
10	PERI_PERI_PCLK_PCLK_GROUP_NR1_GR_DIV_16_VECT	4	Group 1, Number of divide-by-16 clock dividers
11	PERI_PERI_PCLK_PCLK_GROUP_NR1_GR_DIV_24_5_VECT	7	Group 1, Number of divide-by-24.5 clock dividers
12	PERI_PERI_PCLK_PCLK_GROUP_NR1_GR_CLOCK_VECT	21	Group 1, Number of programmable clocks [1, 256]
13	CPUSS_CM0P_MPU_NR	8	Number of MPU regions in CM0+
14	CPUSS_CM7_0_FPU_LVL	2	CM7_0 Floating point unit configuration. 0 - No FPU 1 - Single precision FPU 2 - Single and Double precision FPU
15	CPUSS_CM7_0_MPU_NR	16	Number of MPU regions in CM7_0
16	CPUSS_CM7_0_ICACHE_SIZE	16	CM7_0 Instruction cache (ICACHE) size in KB
17	CPUSS_CM7_0_DCACHE_SIZE	16	CM7_0 Data cache size (DCACHE) in KB
18	CPUSS_CM7_0_ITCM_SIZE	64	CM7_0 Instruction TCM (ITCM) size in KB
19	CPUSS_CM7_0_DTCM_SIZE	64	CM7_0 Data TCM (DTCM) size in KB
26	CPUSS_DW0_CH_NR	76	Number of P-DMA0 channels
27	CPUSS_DW1_CH_NR	84	Number of P-DMA1 channels
28	CPUSS_DMACH_CH_NR	8	Number of M-DMA0 controller channels
29	CPUSS_CRYPTOP_BUFF_SIZE	2048	Number of 32-bit words in the IP internal memory buffer (to allow for a 256-B, 512-B, 1-KB, 2-KB, 4-KB, 8-KB, 16-KB, and 32-KB memory buffer)
30	CPUSS_FAULT_FAULT_NR	4	Number of fault structures
31	CPUSS_IPC_IPC_NR	8	Number of IPC structures 0 - Reserved for CM0+ access 1 - Reserved for CM7_0 access 2 - Reserved for DAP access Remaining for user purposes
32	CPUSS_PROT_SMPU_STRUCT_NR	16	Number of S MPU protection structures
33	SCB0_EZ_DATA_NR	256	Number of EZ memory bytes. This memory is used in EZ mode, CMD_RESP mode and FIFO mode. Note: Only SCB0 supports EZ mode
34	TCPWM_TR_ONE_CNT_NR	1	Number of input triggers per counter, routed to one counter
35	TCPWM_TR_ALL_CNT_NR	60	Number of input triggers routed to all counters, based on the pin package
36	TCPWM_GRP_NR	3	Number of TCPWM0 counter groups
37	TCPWM_GRP_NR0_GRP_GRP_CNT_NR	38	Number of counters per TCPWM0 Group #0
38	TCPWM_GRP_NR0_CNT_GRP_CNT_WIDTH	16	Counter width in number of bits per TCPWM0 Group #0
39	TCPWM_GRP_NR1_GRP_GRP_CNT_NR	12	Number of counters per TCPWM0 Group #1

Miscellaneous configuration

Table 24-1 Miscellaneous configuration for CYT3DL devices *(continued)*

Sl. No.	Configuration	Number/ Instances	Description
40	TCPWM_GRP_NR1_CNT_GRP_CNT_WIDTH	16	Counter width in number of bits per TCPWM0 Group #1
41	TCPWM_GRP_NR2_GRP_GRP_CNT_NR	32	Number of counters per TCPWM0 Group #2
42	TCPWM_GRP_NR2_CNT_GRP_CNT_WIDTH	32	Counter width in number of bits per TCPWM0 Group #2
43	CANFD0_MRAM_SIZE / CANFD1_MRAM_SIZE	16	Message RAM size in KB shared by all the channels
44	EVTGEN_COMP_STRUCT_NR	16	Number of Event Generator comparator structures

25 Development support

CYT3DL has a rich set of documentation, programming tools, and online resources to assist during the development process. Visit www.infineon.com to find out more.

25.1 Documentation

A suite of documentation supports CYT3DL to ensure that you can find answers to your questions quickly. This section contains a list of some of the key documents.

25.1.1 Software user guide

A step-by-step guide for using the sample driver library along with third-party IDEs such as IAR EWARM and GHS Multi.

25.1.2 Technical reference manual

The Technical Reference Manual (TRM) contains all the technical detail needed to use a CYT3DL device, including a complete description of all registers. The TRM is available in the documentation section at www.infineon.com.

25.2 Tools

CYT3DL is supported on third-party development tool ecosystems such as IAR and GHS. The device is also supported by Infineon programming utilities for programming, erasing, or reading using Infineon MiniProg4 or Segger J-link. More details are available in the documentation section at www.infineon.com.

26 Electrical specifications

26.1 Absolute maximum ratings

Use of this device under conditions outside the min and max limits listed in **Table 26-1** may cause permanent damage to the device. Exposure to conditions within the limits of **Table 26-1** but beyond those of normal operation for extended periods of time may affect device reliability. The maximum storage temperature is 150°C in compliance with JEDEC Standard JESD22-A103, High Temperature Storage Life. When operated under conditions within the limits of **Table 26-1** but beyond those of normal operation, the device may not operate to specification.

Power considerations

The average chip-junction temperature, T_J , in °C, may be calculated using Equation 1:

$$T_J = T_A + (P_D \times \theta_{JA})$$

Equation. 1

Where:

T_A is the ambient temperature in °C.

θ_{JA} is the package junction-to-ambient thermal resistance, in °C/W.

P_D is the sum of P_{INT} and P_{IO} ($P_D = P_{INT} + P_{IO}$).

P_{INT} is the chip internal power. ($P_{INT} = V_{DDD} \times I_{DD} + V_{CCD} \times I_{CC} + V_{DDA} \times I_{VDDA}$)

P_{IO} represents the power dissipation on input and output pins; user determined.

For most applications, $P_{IO} < P_{INT}$ and may be neglected.

On the other hand, P_{IO} may be significant if the device is configured to continuously drive external modules and/or memories.

WARNING:

- The recommended operating conditions are required to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are guaranteed when the device is operated under these conditions.
- Operation under any conditions other than these conditions may adversely affect reliability of device and can result in device failure.
- No guarantee is made with respect to any use, operating conditions, or combinations not represented in this datasheet. If you want to operate the device under any condition other than listed herein, contact the sales representatives.

Electrical specifications

Table 26-1 Absolute maximum ratings

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID10	V_{DDD_ABS}	Power supply voltage (V_{DDD}) ^[40, 41]	$V_{SS} - 0.3$	–	$V_{SS} + 6.0$	V	See Table 3-4 for assignment of ports to supply domains
Notes 42. Ensure that $V_{DDD} \geq (V_{DDIO_GPIO_1/2} - 0.3 \text{ V})$. 43. These parameters are based on the condition that $V_{SS} = V_{SSA_ADC} = V_{SSA_DAC} = V_{SSA_MIPI} = V_{SSA_FPD} = 0.0 \text{ V}$. 44. A current-limiting resistor must be provided such that the current at the I/O pin does not exceed rated values at any time during power transitions. Refer to Figure 26-1 for more information on the recommended circuit. 45. V_{DDD} and V_{DDD_ABS} must be sufficiently loaded or protected to prevent them from being pulled out of the recommended operating range by the clamp current. 46. Clamp current can be applied to any I/O pin as long as it is within the limits of Table 11-1 and only when the part is powered. 47. When the conditions of Table 11-1 are met, V_{CLAMP_ABS} supersedes $V_{SS} + 6.0$ and V_{I_ABS} . 48. The maximum output current is the peak current flowing through any one GPIO I/O. 49. The total output current is the maximum current flowing through all GPIO I/Os (GPIO_STDL and GPIO_ENH). 50. The maximum output current is the peak current flowing through any one SMC I/O. 51. The total output current is the maximum current flowing through all SMC I/Os (GPIO_SMC). 52. The maximum output current is the peak current flowing through any one FPD-link I/O output. 53. The total output current is the maximum current flowing through all FPD-link I/O outputs. 54. The maximum output current is the peak current flowing through any one HSIO I/O. 55. The total output current is the maximum current flowing through all HSIO I/Os (HSIO_STDLN).							
SID10H	$V_{DDA_FPD0_ABS}$	(V_{DDA_FPD0}) ^[41] . Core-supply for FPD-Link	$V_{SSA_FPD0} - 0.3$	–	$V_{SSA_FPD0} + 1.21$	V	
SID10J	$V_{DDA_MIPI_ABS}$	Power supply voltage (V_{DDA_MIPI}) ^[41] . Supply for MIPI D-PHY	$V_{SSA_MIPI} - 0.3$	–	$V_{SSA_MIPI} + 1.21$	V	
SID45	$V_{DDA_DAC_ABS}$	Power supply voltage (V_{DDA_DAC}) ^[41] . Supply for Audio DAC	$V_{SSA_DAC} - 0.3$	–	$V_{SSA_DAC} + 4.0$	V	
SID11	$V_{DDA_ADC_ABS}$	Analog power supply voltage (V_{DDA_ADC}) ^[41] . Supply for SAR ADC	$V_{SSA_ADC} - 0.3$	–	$V_{SSA_ADC} + 6.0$	V	
SID12	V_{REFH_ABS}	SAR Analog reference voltage, high ^[41]	$V_{SSA_ADC} - 0.3$	–	$V_{SSA_ADC} + 6.0$	V	$V_{REFH} \leq (V_{DDA_ADC} + 0.3 \text{ V})$
SID12A	V_{REFL_ABS}	SAR Analog reference voltage, low ^[41]	$V_{SSA_ADC} - 0.3$	–	$V_{SSA_ADC} + 0.3$	V	
SID13	V_{CCD_ABS}	Power supply voltage (V_{CCD})	$V_{SS} - 0.3$	–	$V_{SS} + 1.21$	V	
SID15A	$V_{I_GPIO_ABS}$	Input voltage ^[41]	$V_{SS} - 0.5$	–	$V_{DDIO_GPIO} + 0.5$	V	See Table 3-4 for assignment of ports to supply domains
SID15B	$V_{I_SMC_ABS}$	Input voltage ^[41]	$V_{SS} - 0.5$	–	$V_{DDIO_SMC} + 0.5$	V	See Table 3-4 for assignment of ports to supply domains
SID15C	$V_{I_HSIO_ABS}$	Input voltage ^[41]	$V_{SS} - 0.5$	–	$V_{DDIO_HSIO} + 0.5$	V	See Table 3-4 for assignment of ports to supply domains
SID15F	$V_{I_MIPI_ABS}$	Input voltage ^[41]	$V_{SSA_MIPI} - 0.3$	–	$V_{DDA_MIPI} + 0.3$	V	
SID16	$V_{I_ADC_ABS}$	Analog input voltage to ADC ^[41]	$V_{SSA_ADC} - 0.3$	–	$V_{DDA_ADC} + 0.3$	V	See Table 3-4 for assignment of ports to supply domains
SID17A	$V_{O_GPIO_ABS}$	Output voltage ^[41]	$V_{SS} - 0.3$	–	$V_{DDIO_GPIO} + 0.3$	V	See Table 3-4 for assignment of ports to supply domains
SID17B	$V_{O_SMC_ABS}$	Output voltage ^[41]	$V_{SS} - 0.3$	–	$V_{DDIO_SMC} + 0.3$	V	See Table 3-4 for assignment of ports to supply domains
SID17C	$V_{O_HSIO_ABS}$	Output voltage ^[41]	$V_{SS} - 0.3$	–	$V_{DDIO_HSIO} + 0.3$	V	See Table 3-4 for assignment of ports to supply domains
SID17G	$V_{O_FPD0_ABS}$	Output voltage ^[41]	$V_{SSA_FPD0} - 0.3$	–	$V_{DDA_FPD0} + 0.3$	V	
SID17H	$V_{O_PMIC_EN_ABS}$	Output voltage ^[41]	$V_{SS} - 0.3$	–	$V_{DDD} + 0.3$	V	For the pin PMIC_EN
SID18	$ I_{CLAMP_ABS} $	Maximum clamp current ^[44, 45, 46, 47]	–5	–	5	mA	Applicable to general purpose I/O pins

Electrical specifications

Table 26-1 Absolute maximum ratings (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/ conditions
SID18A	ΣI_{CLAMP_ABS}	Total maximum clamp current	-25	-	25	mA	Applicable to I/O pins in total for $V_{DDIO_GPIO_X}$
SID18B	$ I_{CLAMP_ABS} $	Maximum clamp current ^[44, 45, 46, 47]	-52	-	52	mA	Applicable to SMC I/O pins
SID18C	ΣI_{CLAMP_ABS}	Total maximum clamp current	-624	-	624	mA	Applicable to SMC I/O pins clamping current occurred by sudden switching-off of inductive load (stepper motor coil) in total for V_{DDIO_SMC}
SID18D	$ I_{CLAMP_ABS} $	Maximum clamp current ^[44, 45, 46, 47]	-5	-	5	mA	Applicable to HSIO_STDLN
SID18E	ΣI_{CLAMP_ABS}	Total maximum clamp current	-25	-	25	mA	Applicable to I/O pins in total for V_{DDIO_HSIO}
SID20	$I_{OL1_GPIO_ABS}$	LOW-level maximum output current for GPIO ^[48]	-	-	3.5	mA	Setting is 1 mA
SID21	$I_{OL2_GPIO_ABS}$	LOW-level maximum output current for GPIO ^[48]	-	-	7	mA	Setting is 2 mA
SID22	$I_{OL3_GPIO_ABS}$	LOW-level maximum output current for GPIO ^[48]	-	-	10	mA	Setting is 5 mA
SID22A	$I_{OL4_GPIO_ABS}$	LOW-level maximum output current for GPIO ^[48]	-	-	10	mA	Setting is 6 mA
SID23A	$I_{OL_PMIC_EN_ABS}$	Sink maximum current	-	-	4	mA	For the pin PMIC_EN. Required to add a current limiting series resistor of 1.25 kΩ - 5 kΩ to the PMIC_EN output.
SID23B	$\Sigma I_{OL_P_MIC_EN_ABS}$	Sink average current	-	-	1	mA	For the pin PMIC_EN. The average output current is defined as the value of the average current flowing through any one of the corresponding pins for a 10 ms period. The average value is the operation current × the operation ratio. The operation current period over the average current spec should be less than 100 ns. Required to add a current limiting series resistor of 1.25 kΩ - 5 kΩ to the PMIC_EN output.
SID26	$\Sigma I_{OL_GPIO_ABS}$	LOW-level total output current for GPIO ^[49]	-	-	50	mA	
SID26A	$I_{OL_SMC_ABS}$	LOW-level maximum output current for SMC ^[50]	-	-	52	mA	Setting is 30 mA at -40°C
SID26B	$\Sigma I_{OL_SMC_ABS}$	LOW-level total output current for SMC ^[51]	-	-	300	mA	25°C < T _A ≤ 105°C For S-grade devices
SID26B_125	$\Sigma I_{OL_SMC_ABS}$	LOW-level total output current for SMC ^[51]	-	-	300	mA	25°C < T _A ≤ 125°C For E-grade devices
SID26I	$\Sigma I_{OL_SMC_ABS}$	LOW-level total output current for SMC ^[51]	-	-	450	mA	-40°C ≤ T _A ≤ 25°C
SID26E	$I_{OL_FPD_ABS}$	LOW-level maximum output current for FPD-link ^[52]	-	-	24	mA	
SID26F	$\Sigma I_{OL_FPD_ABS}$	LOW-level total output current for FPD-link ^[53]	-	-	120	mA	

Notes

 42. Ensure that $V_{DD} \geq (V_{DDIO_GPIO_1} - 0.3 \text{ V}) \geq (V_{DDIO_GPIO_2} - 0.3 \text{ V})$.

 43. These parameters are based on the condition that $V_{SS} = V_{SSA_ADC} = V_{SSA_DAC} = V_{SSA_MIPI} = V_{SSA_FPD} = 0.0 \text{ V}$.

 44. A current-limiting resistor must be provided such that the current at the I/O pin does not exceed rated values at any time, including during power transients. Refer to [Figure 26-1](#) for more information on the recommended circuit.

 45. V_{DD} and V_{DDIO} must be sufficiently loaded or protected to prevent them from being pulled out of the recommended operating range by the clamp current.

 46. Clamp current can be applied to pins as listed in [Table 11-1](#) and only when the part is powered.

 47. When the conditions of [41], [42], [43], and SID18/A/B/C/D/E are met, $|I_{CLAMP_ABS}|$ supersedes V_{IA_ABS} and V_{I_ABS} .

48. The maximum output current is the peak current flowing through any one GPIO I/O.

49. The total output current is the maximum current flowing through all GPIO I/Os (GPIO_STD, and GPIO_ENH).

50. The maximum output current is the peak current flowing through any one SMC I/O.

51. The total output current is the maximum current flowing through all SMC I/Os (GPIO_SMC).

52. The maximum output current is the peak current flowing through any one FPD-link I/O output.

53. The total output current is the maximum current flowing through all FPD-link I/O outputs.

54. The maximum output current is the peak current flowing through any one HSIO I/O

55. The total output current is the maximum current flowing through all HSIO I/Os (HSIO_STDLN).

Electrical specifications

Table 26-1 Absolute maximum ratings (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/ conditions
SID26G	$I_{OL_HSIO_ABS}$	LOW-level maximum output current for HSIO ^[54]	–	–	15	mA	
SID26H	$\Sigma I_{OL_HSIO_ABS}$	LOW-level total output current for HSIO ^[55]	–	–	150	mA	
SID27	$I_{OH1_GPIO_ABS}$	HIGH-level maximum output current for GPIO ^[48]	–	–	–3.5	mA	Setting is 1 mA
SID28	$I_{OH2_GPIO_ABS}$	HIGH-level maximum output current for GPIO ^[48]	–	–	–7	mA	Setting is 2 mA
SID29	$I_{OH3_GPIO_ABS}$	HIGH-level maximum output current for GPIO ^[48]	–	–	–10	mA	Setting is 5 mA
SID29A	$I_{OH4_GPIO_ABS}$	HIGH-level maximum output current for GPIO ^[48]	–	–	–10	mA	Setting is 6 mA
SID30A	$I_{OH_PMIC_EN_ABS}$	Source maximum current	–	–	–4	mA	For the pin PMIC_EN. Required to add a current limiting series resistor of 1.25 kΩ – 5 kΩ to the PMIC_EN output.
SID30B	$\Sigma I_{OH_P_MIC_EN_ABS}$	Source average current	–	–	–1	mA	For the pin PMIC_EN. The average output current is defined as the value of the average current flowing through any one of the corresponding pins for a 10 ms period. The average value is the operation current × the operation ratio. The operation current period over the average current spec should be less than 100 ns. Required to add a current limiting series resistor of 1.25 kΩ – 5 kΩ to the PMIC_EN output.
SID33	$\Sigma I_{OH1_GPIO_ABS}$	HIGH-level total output current for GPIO ^[49]	–	–	–50	mA	
SID33A	$I_{OH_SMC_ABS}$	HIGH-level maximum output current for SMC ^[50]	–	–	–52	mA	Setting is 30 mA at –40°C
SID33B	$\Sigma I_{OH_SMC_ABS}$	HIGH-level total output current for SMC ^[51]	–	–	–300	mA	25°C < T _A ≤ 105°C For S-grade devices
SID33B_125	$\Sigma I_{OH_SMC_ABS}$	HIGH-level total output current for SMC ^[51]	–	–	–300	mA	25°C < T _A ≤ 125°C For E-grade devices
SID33I	$\Sigma I_{OH_SMC_ABS}$	HIGH-level total output current for SMC	–	–	–450	mA	–40°C ≤ T _A ≤ 25°C
SID33E	$I_{OH_FPD_ABS}$	HIGH-level maximum output current for FPD-link ^[52]	–	–	–24	mA	
SID33F	$\Sigma I_{OH_FPD_ABS}$	HIGH-level total output current for FPDlink ^[53]	–	–	–120	mA	
SID33G	$I_{OH_HSIO_ABS}$	HIGH-level maximum output current for HSIO ^[54]	–	–	–15	mA	
SID33H	$\Sigma I_{OH_HSIO_ABS}$	HIGH-level total output current for HSIO ^[55]	–	–	–150	mA	
SID34_2	P _D	Power dissipation	–	–	2500	mW	25°C < T _A ≤ 105°C For S-grade devices

Notes

42. Ensure that $V_{DD} \geq (V_{DDIO_GPIO_1} - 0.3 \text{ V}) \geq (V_{DDIO_GPIO_2} - 0.3 \text{ V})$.
43. These parameters are based on the condition that $V_{SS} = V_{SSA_ADC} = V_{SSA_DAC} = V_{SSA_MIP1} = V_{SSA_FPD} = 0.0 \text{ V}$.
44. A current-limiting resistor must be provided such that the current at the I/O pin does not exceed rated values at any time, including during power transients. Refer to **Figure 26-1** for more information on the recommended circuit.
45. V_{DD} and V_{DDIO} must be sufficiently loaded or protected to prevent them from being pulled out of the recommended operating range by the clamp current.
46. Clamp current can be applied to pins as listed in **Table 11-1** and only when the part is powered.
47. When the conditions of [41], [42], [43], and SID18/A/B/C/D/E are met, I_{CLAMP_ABS} supersedes V_{IA_ABS} and V_{I_ABS} .
48. The maximum output current is the peak current flowing through any one GPIO I/O.
49. The total output current is the maximum current flowing through all GPIO I/Os (GPIO_STD, and GPIO_ENH).
50. The maximum output current is the peak current flowing through any one SMC I/O.
51. The total output current is the maximum current flowing through all SMC I/Os (GPIO_SMC).
52. The maximum output current is the peak current flowing through any one FPD-link I/O output.
53. The total output current is the maximum current flowing through all FPD-link I/O outputs.
54. The maximum output current is the peak current flowing through any one HSIO I/O.
55. The total output current is the maximum current flowing through all HSIO I/Os (HSIO_STDLN).

Electrical specifications

Table 26-1 Absolute maximum ratings (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/ conditions
SID34_2_125	P_D	Power dissipation	–	–	1400	mW	25°C < T_A ≤ 125°C (for E-grade devices) BGA-272: 1400 mW; TEQFP-216: 1600 mW, based on R_{th}
SID36	T_A	Operating ambient temperature	–40	–	105	°C	For S-grade devices
SID36_125	T_A	Operating ambient temperature	–40	–	125	°C	For E-grade devices
SID38	T_{STG}	Storage temperature	–55	–	150	°C	
SID39	T_J	Operating junction temperature	–40	–	150	°C	
SID39A	V_{ESD_HBM}	Electrostatic discharge human body model	2000	–	–	V	
SID39B1	V_{ESD_CDM1}	Electrostatic discharge charged device model for corner pins	750	–	–	V	
SID39B2	V_{ESD_CDM2}	Electrostatic discharge charged device model for all other pins	500	–	–	V	
SID39C	I_{LU}	The maximum pin current the device can tolerate before triggering a latch-up	–100	–	100	mA	

Notes

42. Ensure that $V_{DD} \geq (V_{DDIO_GPIO_1} - 0.3\text{ V}) \geq (V_{DDIO_GPIO_2} - 0.3\text{ V})$.
43. These parameters are based on the condition that $V_{SS} = V_{SSA_ADC} = V_{SSA_DAC} = V_{SSA_MIPI} = V_{SSA_FPD} = 0.0\text{ V}$.
44. A current-limiting resistor must be provided such that the current at the I/O pin does not exceed rated values at any time, including during power transients. Refer to [Figure 26-1](#) for more information on the recommended circuit.
45. V_{DD} and V_{DDIO} must be sufficiently loaded or protected to prevent them from being pulled out of the recommended operating range by the clamp current.
46. Clamp current can be applied to pins as listed in [Table 11-1](#) and only when the part is powered.
47. When the conditions of [41], [42], [43], and SID18/A/B/C/D/E are met, $|I_{CLAMP_ABS}|$ supersedes V_{IA_ABS} and V_{I_ABS} .
48. The maximum output current is the peak current flowing through any one GPIO I/O.
49. The total output current is the maximum current flowing through all GPIO I/Os (GPIO_STD, and GPIO_ENH).
50. The maximum output current is the peak current flowing through any one SMC I/O.
51. The total output current is the maximum current flowing through all SMC I/Os (GPIO_SMC).
52. The maximum output current is the peak current flowing through any one FPD-link I/O output.
53. The total output current is the maximum current flowing through all FPD-link I/O outputs.
54. The maximum output current is the peak current flowing through any one HSIO I/O.
55. The total output current is the maximum current flowing through all HSIO I/Os (HSIO_STDLN).

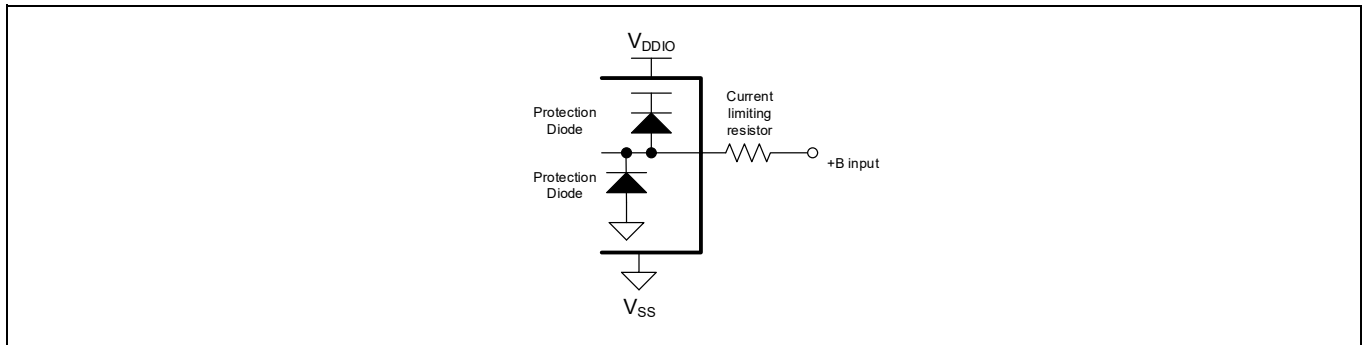


Figure 26-1 Example of a recommended circuit^[56]

WARNING:

Semiconductor devices may be permanently damaged by application of stress (including, without limitation, voltage, current, or temperature) in excess of absolute maximum ratings. Do not exceed any of these ratings.

Note

56.+B is the positive battery voltage around 45 V.

26.2 Recommended operating conditions

Table 26-2 Device-level specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
Recommended operating conditions							
SID40	$V_{DDDD}, V_{DDDA_ADC}, V_{DDIO_GPIO}, V_{DDIO_SMC}$	Power supply voltage ^[57]	2.7 ^[58]	–	5.5 ^[59]	V	V_{DDIO_GPIO} ($V_{DDIO_GPIO_1/2}$)
SID40A	V_{DDIO_EFP}	Power supply voltage for eFuse programming ^[60]	3.0	–	5.5	V	$V_{DDIO_GPIO_1}$ for this product, when programming eFuses
SID40B	V_{DDIO_HSIO}	Power supply voltage	3.0	3.3	3.6	V	
SID40E	V_{DDPLL_FPD0} ^[61]	Power supply voltage (V_{DDPLL_FPD0}). Supply for FPD-link PLLs.	1.09	1.15	1.21	V	
SID40F	V_{DDHA_FPD0}	Power supply voltage (V_{DDHA_FPD0}). Supply for FPD-link line drivers.	3.0	3.3	3.6	V	
SID40G	V_{DDA_FPD0} ^[61]	Power supply voltage (V_{DDA_FPD0}). Core-supply for FPD-link.	1.09	1.15	1.21	V	
SID40H	V_{DDA_MIPI} ^[61]	Power supply voltage (V_{DDA_MIPI}). Supply for D-PHY.	1.09	1.15	1.21	V	
SID40J	V_{CCD} ^[61]	External V_{CCD} power supply	1.09	1.15	1.21	V	External V_{CCD} power supply range when externally supplied at V_{CCD} . V_{CCD} must not be driven by an external supply at startup. See related application note for correct startup sequence.
SID41	C_{S1}	Smoothing capacitor ^[62, 63]	30.8	94	103.4	μF	
SID43	V_{DDA_DAC}	High voltage supply	3.0	3.3	3.6	V	

Notes

57. Ensure $V_{DDIO_GPIO_1} \geq 0.8 \times V_{DDA_ADC}$ when SARMUX0 is enabled.

58. 3.0 V $\pm 10\%$ is supported with a lower BOD setting option. This setting provides robust protection for internal timing but BOD reset occurs at a voltage below the specified operating conditions. A higher BOD setting option is available (consistent with down to 3.0 V) and guarantees that all operating conditions are met.

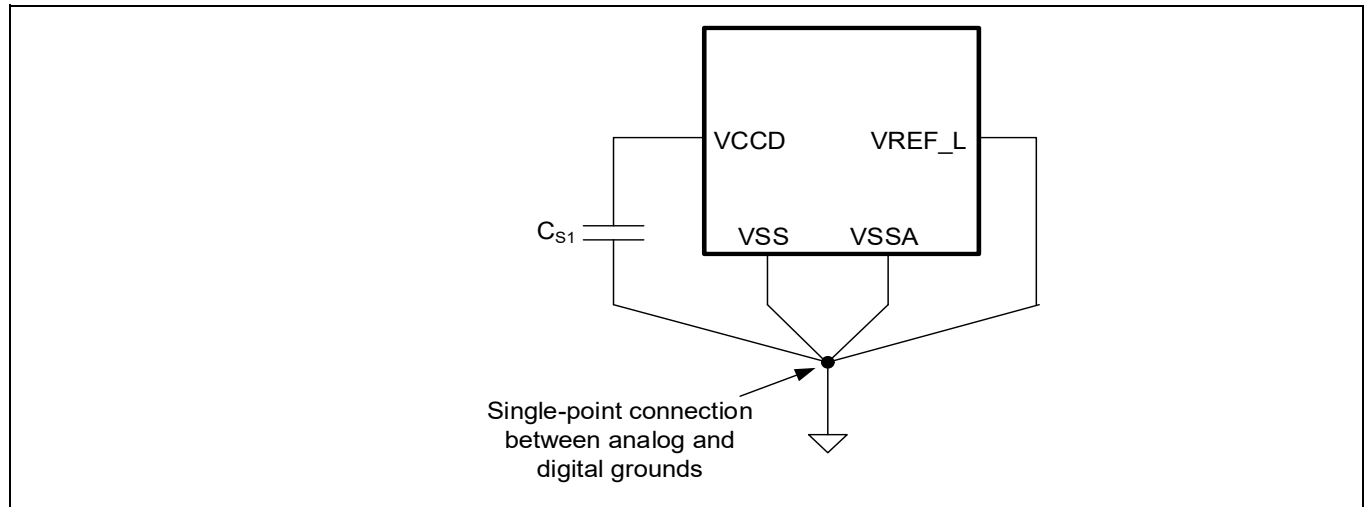
59. 5.0 V $\pm 10\%$ is supported with a higher OVD setting option. This setting provides robust protection for internal and interface timing, but OVD reset occurs at a voltage above the specified operating conditions. A lower OVD setting option is available (consistent with up to 5.0 V) and guarantees that all operating conditions are met. Voltage overshoot to a higher OVD setting range for V_{DDDD} and V_{DDA_ADC} is permissible, provided the duration is less than 2 hours cumulated. Note that during overshoot voltage condition electrical parameters are not guaranteed.

60. eFuse programming must be executed with the part in a “quiet” state, with minimal activity (preferably only JTAG or a single LIN/CAN channel on V_{DDDD} domain).

61. Analog and digital supply rails to be shorted on the PCB ($V_{DDPLL_FPD0} = V_{DDA_FPD0} = V_{DDA_MIPI} = V_{CCD}$). These supply rails must be connected to the same power supply of V_{CCD} . This supply voltage needs to be filtered in order to eliminate any PLL jitters. It is recommended to use a noise filter to reduce the noise ripple for the FPD-LINK and MIPI-PHY supply.

62. Only one smoothing capacitor, C_{S1} is required per chip (not per VCCD pin). The VCCD pins should be connected together to ensure a low-impedance connection (see the recommendation in [Figure 26-2](#)).

63. Capacitors used for power supply decoupling or filtering are operated under a continuous DC-bias. Many capacitors used with DC power across them provide less than their target capacitance, and their capacitance is not constant across their working voltage range. When selecting capacitors for use with this device, ensure that the selected components provide the required capacitance under the specific operating conditions of temperature and voltage used in your design. While the temperature coefficient is normally found within a parts catalog (such as, X7R, C0G, Y5V), the matching voltage coefficient may only be available on the component datasheet or direct from the manufacturer. Use of components that do not provide the required capacitance under the actual operating conditions may cause the device to operate to less than datasheet specifications.


Figure 26-2 Smoothing capacitor

Smoothing capacitor should be placed as close as possible to the VCCD pin.

Table 26-3 DC specifications, CPU current, and transition time specifications

All specifications are valid for $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ for S-grade devices and $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ for E-grade devices, and for 2.7 V to 5.5 V except where noted.

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
Execute with Flash							
SID51C	I_{CC1}	V_{CCD} current in external PMIC mode	–	450	950	mA	Typ: $T_A = 25^{\circ}\text{C}$, $V_{CCD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 105^{\circ}\text{C}$, $T_J = 150^{\circ}\text{C}$, $V_{CCD} = 1.21\text{ V}$, process worst (FF) (Maximum expected V_{CCD} when $T_J = 150^{\circ}\text{C}$ is reached due to self-heating) For S-grade devices
SID51C_125	I_{CC1}	V_{CCD} current in external PMIC mode	–	450	950	mA	Typ: $T_A = 25^{\circ}\text{C}$, $V_{CCD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 125^{\circ}\text{C}$, $T_J = 150^{\circ}\text{C}$, $V_{CCD} = 1.21\text{ V}$, process worst (FF) (Maximum expected V_{CCD} when $T_J = 150^{\circ}\text{C}$ is reached due to self-heating); For E-grade devices

Electrical specifications

Table 26-3 DC specifications, CPU current, and transition time specifications *(continued)*

 All specifications are valid for $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ for S-grade devices and $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ for E-grade devices, and for 2.7 V to 5.5 V except where noted.

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID52C	I_{DD1}	V_{DDP} current in external PMIC mode, Use case with VIDEOSS (V_{DDP} current for SID51C use case)	–	7	10	mA	Cortex®-M7 at 240 MHz generated by PLL with ECO reference, executing Dhrystone from flash with cache enabled. Cortex®-M0+ is sleeping at 100 MHz. Graphics Engine at 200 MHz, operating 2D rendering, drawing, capture, output on 2 displays. All other peripherals, peripheral clocks, interrupts, CSV, DMA, ECO are enabled. No I/O toggling. Typ: $T_A = 25^{\circ}\text{C}$, $V_{CCD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 105^{\circ}\text{C}$, $V_{CCD} = 1.21\text{ V}$, process worst (FF); For S-grade devices
SID52C_125	I_{DD1}	V_{DDP} current in external PMIC mode, Use case with VIDEOSS (V_{DDP} current for SID51C use case)	–	7	10	mA	Cortex®-M7 at 240 MHz generated by PLL with ECO reference, executing Dhrystone from flash with cache enabled. Cortex®-M0+ is sleeping at 100 MHz. Graphics Engine at 200 MHz, operating 2D rendering, drawing, capture, output on 2 displays. All other peripherals, peripheral clocks, interrupts, CSV, DMA, ECO are enabled. No I/O toggling. Typ: $T_A = 25^{\circ}\text{C}$, $V_{CCD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 125^{\circ}\text{C}$, $V_{CCD} = 1.21\text{ V}$, process worst (FF); For E-grade devices

Table 26-3 DC specifications, CPU current, and transition time specifications *(continued)*

All specifications are valid for $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ for S-grade devices and $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ for E-grade devices, and for 2.7 V to 5.5 V except where noted.

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID56	I_{DD1}	V_{DDD} current in internal regulator mode, Execute from flash; Cortex®-M7 CPU in Active mode	–	8	38	mA	Cortex®-M7 at 8 MHz generated by IMO reference, executing Dhrystone from flash with cache enabled. Cortex®-M0+ is sleeping at 8 MHz. All clocks at 8MHz generated by IMO. VIDEOSS power switched off. All other peripherals, peripheral clocks, interrupts, CSV, DMA, PLL, ECO are disabled. No IO toggling. Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDD} = 5.0\text{ V}$, process typ (TT) Max: $T_A = 85^{\circ}\text{C}$, $V_{DDD} = 5.5\text{ V}$, process worst (FF)
SID50A	I_{DD1}	V_{DDD} current in internal regulator mode. Cortex®-M7/M0+ CPUs in Sleep mode	–	28	70	mA	Clocks running at max frequency, All CPUs in Sleep mode. VIDEOSS power switched off. All other peripherals, peripheral clocks, interrupts, CSV, DMA, ECO are disabled. No IO toggling. Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDD} = 5.0\text{ V}$, process typ (TT) Max: $T_A = 85^{\circ}\text{C}$, $V_{DDD} = 5.5\text{ V}$, process worst (FF)
SID50C	I_{DD1}	V_{DDD} current in internal regulator mode. Cortex®-M7/M0+ CPUs in Sleep mode (room temp)	–	–	40	mA	Clocks running at max frequency, All CPUs in Sleep mode. VIDEOSS power switched off All other peripherals, peripheral clocks, interrupts, CSV, DMA, ECO are disabled. No IO toggling. Max: $T_A = 25^{\circ}\text{C}$, $V_{DDD} = 5.5\text{ V}$, process worst (FF)

Electrical specifications

Table 26-3 DC specifications, CPU current, and transition time specifications *(continued)*

 All specifications are valid for $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ for S-grade devices and $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ for E-grade devices, and for 2.7 V to 5.5 V except where noted.

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID50B	I_{CC1}	V_{CCD} current in external PMIC mode. Cortex®-M7/M0+ CPUs in Sleep mode. VIDEOSS in sleep mode (clocks off)	–	30	500	mA	Clocks running at max frequency, All CPUs in Sleep mode. VIDEOSS in sleep mode All other peripherals, peripheral clocks, interrupts, CSV, DMA, ECO are disabled. No IO toggling. Typ: $T_A = 25^{\circ}\text{C}$, $V_{DD} = 5.0\text{ V}$, $V_{CCD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 105^{\circ}\text{C}$, $V_{DD} = 5.5\text{ V}$, $V_{CCD} = 1.21\text{ V}$, process worst (FF); For S-grade devices
SID50B_125	I_{CC1}	V_{CCD} current in external PMIC mode. Cortex®-M7/M0+ CPUs in Sleep mode. VIDEOSS in sleep mode (clocks off)	–	30	500	mA	Clocks running at max frequency, All CPUs in Sleep mode. VIDEOSS in sleep mode All other peripherals, peripheral clocks, interrupts, CSV, DMA, ECO are disabled. No IO toggling. Typ: $T_A = 25^{\circ}\text{C}$, $V_{DD} = 5.0\text{ V}$, $V_{CCD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 125^{\circ}\text{C}$, $V_{DD} = 5.5\text{ V}$, $V_{CCD} = 1.21\text{ V}$, process worst (FF); For E-grade devices
DeepSleep Mode							
SID59_3	I_{DD_DS32A}	V_{DD} current in internal regulator mode. 32 KB SRAM retention, LPECO(4 MHz) operation in DeepSleep mode.	–	150	–	μA	Deep Sleep Mode (RTC and EVTGEN operating, all other peripherals off, CAN MRAM disabled), CM0+ and CM7_0 retain, CM7_1 power switched OFF Typ: $T_A = 25^{\circ}\text{C}$, $V_{DD} = 5.0\text{ V}$, $V_{CCD} = 1.1\text{ V}$, process typ (TT) FPD-Link/MIPI Standby currents not included

Electrical specifications

Table 26-3 DC specifications, CPU current, and transition time specifications (continued)

 All specifications are valid for $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ for S-grade devices and $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ for E-grade devices, and for 2.7 V to 5.5 V except where noted.

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID59A_3	I_{DD_DS32A}	V_{DD} current in internal regulator mode. 32 KB SRAM retention, LPECO(4 MHz) operation in DeepSleep mode.	–	–	250	μA	Deep Sleep Mode (RTC at 32kHz and EVTGEN operating, all other peripherals off, CAN MRAM disabled), CM0+ and CM7_0 retain Max: $V_{DD} = 5.5\text{ V}$, $T_A = 25^{\circ}\text{C}$, process worst (FF) FPD-Link/MIPI Standby currents not included
SID60_3	I_{DD_DS32B}	V_{DD} current in internal regulator mode. 32 KB SRAM retention, LPECO(4 MHz) operation in DeepSleep mode.	–	–	2500	μA	DeepSleep Mode (RTC and Event generator operating, all other peripherals off, CAN MRAM disabled), CM0+ and CM7_0 retain, CM7_1 power switched OFF Max: $V_{DD} = 5.5\text{ V}$, $T_A = 85^{\circ}\text{C}$, process worst (FF) FPD-Link/MIPI Standby currents not included
SID64_3	I_{DD_DS32C}	V_{DD} current in internal regulator mode. 32 KB SRAM retention, ILO operation in DeepSleep mode.	–	50	2500	μA	DeepSleep Mode (RTC and Event generator operating, all other peripherals off, CAN MRAM disabled) CM0+ and CM7_0 retain, CM7_1 power switched OFF Typ: $T_A = 25^{\circ}\text{C}$, $V_{DD} = 5.0\text{ V}$, process typ (TT) Max: $T_A = 85^{\circ}\text{C}$, $V_{DD} = 5.5\text{ V}$, process worst (FF) FPD-Link/MIPI Standby currents not included
SID64A_3	I_{DD_DS32D}	32 KB SRAM retention, ILO operation in DeepSleep mode	–	–	150	μA	DeepSleep Mode (RTC at 32kHz and Event generator operating, all other peripherals off, CAN MRAM disabled) CM0+ and CM7_0 retain Max: $T_A = 25^{\circ}\text{C}$, $V_{DD} = 5.5\text{ V}$, process worst (FF) FPD-Link/MIPI Standby currents not included
Hibernate Mode							
SID66	I_{DD_HIB1}	V_{DD} current, Hibernate Mode + RTC at 32.768 KHz	–	–	20	μA	$T_A = 25^{\circ}\text{C}$ using ILO, $V_{DD} = 5.0\text{ V}$

Electrical specifications

Table 26-3 DC specifications, CPU current, and transition time specifications (continued)

All specifications are valid for $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ for S-grade devices and $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ for E-grade devices, and for 2.7 V to 5.5 V except where noted.

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID66A	I_{DD_HIB2}	V_{DD} current, Hibernate Mode + RTC at 32.768 KHz	–	–	40	μA	$T_A = 25^{\circ}\text{C}$, using WCO, $V_{DD} = 5.0\text{ V}$
SID66B	I_{DD_HIB3}	V_{DD} current, Hibernate Mode + RTC at 32.768 KHz	–	–	75	μA	$T_A = 85^{\circ}\text{C}$, using WCO, $V_{DD} = 5.5\text{ V}$
SID66C	I_{DD_HIB4}	V_{DD} current, Hibernate Mode + RTC at 32.768 KHz	–	–	150	μA	$T_A = 25^{\circ}\text{C}$ using LPECO 4 MHz, 20 pF load of LPECO $V_{DD} = 5.0\text{ V}$
SID66D	I_{DD_HIB5}	V_{DD} current, Hibernate Mode + RTC at 32.768 KHz	–	–	215	μA	$T_A = 85^{\circ}\text{C}$, using LPECO 4 MHz, 20 pF load of LPECO $V_{DD} = 5.5\text{ V}$
Power Mode Transition Times							
SID69_1	t_{ACT_DS}	Power down time from ACTIVE to DEEPSLEEP (using the internal regulator)	–	–	2.8	μs	When IMO is already running and all HFCLK roots are at least 8 MHz. HFCLK roots that are slower than this will require additional time to turn off.
SID69A	t_{ACT_DS}	Power down time from ACTIVE to DeepSleep (using external PMIC)	–	–	6.5	μs	When IMO is already running and all HFCLK roots are at least 8 MHz. HFCLK roots that are slower than this will require additional time to turn off. The time for the PMIC to deassert its power good signal is not included.
SID67	t_{DS_ACT}	DeepSleep to Active transition time (IMO clock, flash execution)	–	–	26	μs	When using 8 MHz IMO. Measured from wakeup interrupt during DeepSleep until Flash execution. $T_A \geq -5^{\circ}\text{C}$ Note: At temperatures below -5°C the DeepSleep to Active transition time can be higher than the max time indicated by as much as 20 μs
SID67A	$t_{DS_ACT_FLL}$	DeepSleep to Active transition time (FLL clock, flash execution)	–	–	26	μs	When using FLL to generate 96 MHz from the 8-MHz IMO. Measured from wakeup interrupt during DeepSleep until Flash execution. $T_A \geq -5^{\circ}\text{C}$ Note: At temperatures below -5°C the DeepSleep to Active transition time can be higher than the max time indicated by as much as 20 μs

Electrical specifications

Table 26-3 DC specifications, CPU current, and transition time specifications (continued)

All specifications are valid for $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ for S-grade devices and $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ for E-grade devices, and for 2.7 V to 5.5 V except where noted.

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID67B	$t_{\text{DS_ACT_PLL}}$	DeepSleep to Active transition time (PLL clock)	–	–	60	μs	When using PLL to generate 96 MHz from the 8-MHz IMO. Measured from wakeup interrupt during DeepSleep until PLL locks. $T_A \geq -5^{\circ}\text{C}$ Note: At temperatures below -5°C the DeepSleep to Active transition time can be higher than the max time indicated by as much as 20 μs
SID68C	$t_{\text{HIB_ACT}}$	Release time from HV reset (POR, BOD, OVD, OCD, WDT, Hibernate wakeup, or XRES_L) until CM0+ begins executing ROM boot	–	–	650	μs	Without boot runtime with max. 103.4 μF smoothing capacitor per SID41, no FPD/MIPI filter connected Guaranteed by Design
SID68D	$t_{\text{HIB_ACT}}$	Release time from HV reset (POR, BOD, OVD, OCD, WDT, Hibernate wakeup, or XRES_L) until CM0+ begins executing ROM boot	–	–	1040	μs	Without boot runtime with max. 103.4 μF smoothing capacitor per SID41 + max. 5x11 μF FPD/MIPI filter caps Guaranteed by Design
SID68A	$t_{\text{LVR_ACT}}$	Release time from LV reset (Fault, Internal system reset, MCWDT, or CSV) during Active/Sleep until CM0+ begins executing ROM boot	8	–	10	μs	Without boot runtime. Guaranteed by design
SID68B	$t_{\text{LVR_DS}}$	Release time from LV reset (Fault, or MCWDT) during DeepSleep until CM0+ begins executing ROM boot	–	–	15	μs	Without boot runtime. Guaranteed by design
SID79	$t_{\text{HIBWAKE-UP_PW}}$	Pulse width for wakeup from Hibernate mode on HIBER-ANTE_WAKEUP pins	90	–	–	ns	Guaranteed by design
SID80A	$t_{\text{RB_N}}$	ROM boot startup time or wakeup time from hibernate in NORMAL protection state	–	–	1700	μs	FAST_BOOT = 1, CM0+ clocked at 100 MHz
SID80B	$t_{\text{RB_S}}$	ROM boot startup time or wakeup time from hibernate in SECURE protection state	–	–	2300	μs	FAST_BOOT = 1, CM0+ clocked at 100 MHz
SID81A	t_{FB}	Flash boot startup time or wakeup time from hibernate in NORMAL/SECURE protection state	–	–	190	μs	FAST_BOOT = 1, TOC2_FLAGS=0x2CF, CM0+ clocked at 100 MHz, Listen window = 0 ms

Electrical specifications

Table 26-3 DC specifications, CPU current, and transition time specifications (continued)

 All specifications are valid for $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ for S-grade devices and $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ for E-grade devices, and for 2.7 V to 5.5 V except where noted.

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID81B	$t_{\text{FB_A}}$	Flash boot with app authentication time in NORMAL/SECURE protection state	–	–	5000	μs	FAST_BOOT = 1, TOC2_FLAGS = 0x24F, CM0+ clocked at 100 MHz, Listen window = 0 ms, Public key exponent e = 0x010001, APP size is 64 KB with the last 256 bytes being a digital signature in RSASSA-PKCS1-v1.5 Valid for RSA2K.
SID81C	$t_{\text{FB_B}}$	Flash boot with app authentication time in NORMAL/SECURE protection state	–	–	8150	μs	FAST_BOOT = 1, TOC2_FLAGS = 0x24F, CM0+ clocked at 100 MHz, Listen window = 0 ms, Public key exponent e = 0x010001, APP size is 64 KB with the last 384 bytes being a digital signature in RSASSA-PKCS1-v1.5 Valid for RSA3K.

Regulator Specifications

SID600	V_{CCD}	Internal regulator core supply voltage (transient range)	1.05	1.1	1.15	V	
SID600A	$V_{\text{CCD_S}}$	Internal regulator core supply voltage (static range, no load)	1.075	1.1	1.125	V	Guaranteed by design
SID601	$I_{\text{DDD_ACT}}$	Regulator operating current in Active/Sleep mode	–	900	1500	μA	Guaranteed by design
SID602	$I_{\text{DDD_DPSLP}}$	Regulator operating current in DeepSleep mode	–	1.5	20	μA	Guaranteed by design
SID603	I_{RUSH}	In-rush current	–	–	850	mA	
SID604	I_{ILDOUT}	Internal regulator output current for operation	–	–	300	mA	
SID606	V_{IL}	PMIC digital input LOW voltage (% V_{DDD})	–	–	$0.3 \times V_{\text{DDD}}$	V	
SID606A	V_{IH}	PMIC digital input HIGH voltage (% V_{DDD})	$0.7 \times V_{\text{DDD}}$	–	–	V	
SID606B	V_{HYST}	PMIC digital input hysteresis (% V_{DDD})	$0.05 \times V_{\text{DDD}}$	–	–	V	
SID607	V_{OL}	PMIC digital output LOW voltage	–	–	0.5	V	$I_{\text{OL}} = 1 \text{ mA}$
SID607A	V_{OH}	PMIC digital output HIGH voltage	$V_{\text{DDD}} - 0.5$	–	–	V	$I_{\text{OH}} = -1 \text{ mA}$

26.3 Reset specifications

Table 26-4 XRES_L Reset

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
XRES_L DC specifications							
SID73	I _{IDD_XRES}	I _{DD} when XRES_L asserted	–	–	1.7	mA	Max: T _A = 105°C, V _{DDD} = 5.5 V, process worst (FF); For S-grade devices
SID73_125	I _{IDD_XRES}	I _{DD} when XRES_L asserted	–	–	1.7	mA	Max: T _A = 125°C, V _{DDD} = 5.5 V, process worst (FF); For E-grade devices
SID74	V _{IH}	Input voltage high threshold	0.7 × V _{DDD}	–	–	V	CMOS Input
SID75	V _{IL}	Input voltage low threshold	–	–	0.3 × V _{DDD}	V	CMOS Input
SID76	R _{PULLUP}	Pull-up resistor	7	–	20	kΩ	
SID77	C _{IN}	Input capacitance	–	–	5	pF	
SID78	V _{HYSXRES}	Input voltage hysteresis	0.05 × V _{DDD}	–	–	V	
SID82	I _{DDIO_HSIO}	I _{DDIO_HSIO} when XRES_L is asserted	–	1.5	300	μA	Typ: T _A = 25°C, V _{DDIO_HSIO} = 3.3 V, process typ (TT) Max: T _A = 105°C, V _{DDIO_HSIO} = 3.6 V, process worst (FF); For S-grade devices
SID82_125	I _{DDIO_HSIO}	I _{DDIO_HSIO} when XRES_L is asserted	–	1.5	300	μA	Typ: T _A = 25°C, V _{DDIO_HSIO} = 3.3 V, process typ (TT) Max: T _A = 125°C, V _{DDIO_HSIO} = 3.6 V, process worst (FF); For E-grade devices
SID82_1	I _{DDIO_H-SIO_1}	I _{DDIO_HSIO} when XRES_L is asserted	–	–	4.5	μA	Max: T _A = 25°C, V _{DDIO_HSIO} = 3.6 V, process worst (FF)
SID82_2	I _{DDIO_H-SIO_2}	I _{DDIO_HSIO} when XRES_L is asserted	–	–	36	μA	Max: T _A = 85°C, V _{DDIO_HSIO} = 3.6 V, process worst (FF)
SID83	I _{DDIO_SMC}	I _{DDIO_SMC} when XRES_L is asserted	–	0.06	90	μA	Typ: T _A = 25°C, V _{DDIO_SMC} = 5.0 V, process typ (TT) Max: T _A = 105°C, V _{DDIO_SMC} = 5.5 V, process worst (FF); For S-grade devices

Table 26-4 XRES_L Reset (continued)

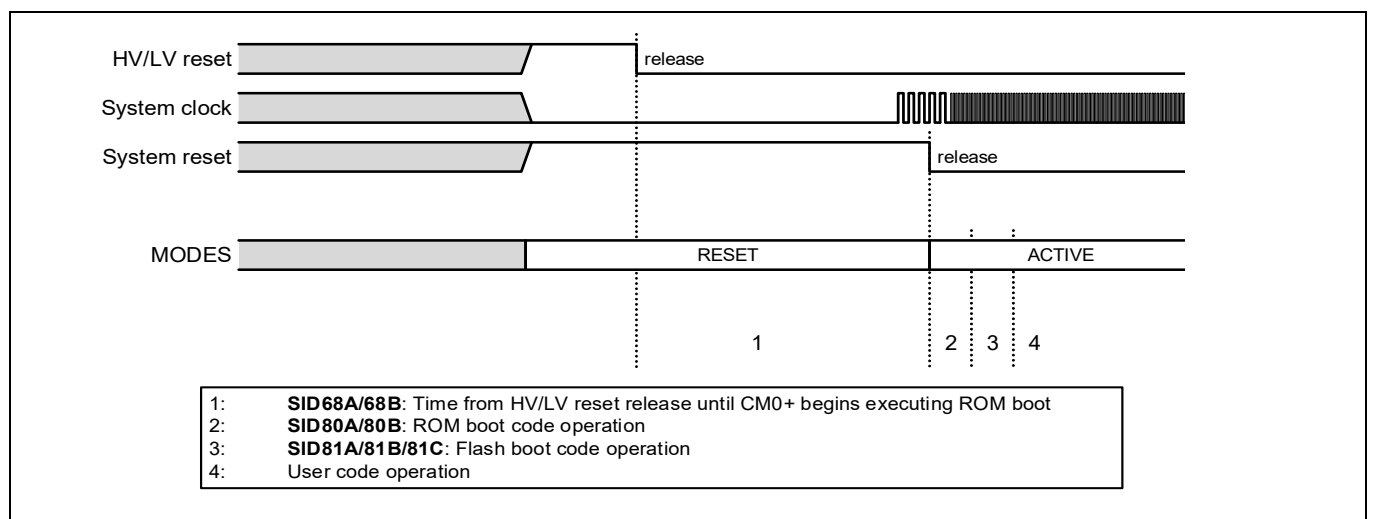
Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID83_125	I _{DDIO_SMC}	I _{DDIO_SMC} when XRES_L is asserted	–	0.06	90	μA	Typ: T _A = 25°C, V _{DDIO_SMC} = 5.0 V, process typ (TT) Max: T _A = 125°C, V _{DDIO_SMC} = 5.5 V, process worst (FF); For E-grade devices
SID83_1	I _{DDIO_SMC_1}	I _{DDIO_SMC} when XRES_L is asserted	–	–	0.2	μA	Max: T _A = 25°C, V _{DDIO_SMC} = 5.5 V, process worst (FF)
SID83_2	I _{DDIO_SMC_2}	I _{DDIO_SMC} when XRES_L is asserted	–	–	3	μA	Max: T _A = 85°C, V _{DDIO_SMC} = 5.5 V, process worst (FF)
SID84	I _{DDIO_G-PIO_1}	I _{DDIO_GPIO_1} when XRES_L is asserted	–	0.05	40	μA	Typ: T _A = 25°C, V _{DDIO_GPIO_1} = 5.0 V, process typ (TT) Max: T _A = 105°C, V _{DDIO_GPIO_1} = 5.5 V, process worst (FF); For S-grade devices
SID84_125	I _{DDIO_G-PIO_1}	I _{DDIO_GPIO_1} when XRES_L is asserted	–	0.05	40	μA	Typ: T _A = 25°C, V _{DDIO_GPIO_1} = 5.0 V, process typ (TT) Max: T _A = 125°C, V _{DDIO_GPIO_1} = 5.5 V, process worst (FF); For E-grade devices
SID84_1	I _{DDIO_GPI-O_1_1}	I _{DDIO_GPIO_1} when XRES_L is asserted	–	–	0.15	μA	Max: T _A = 25°C, V _{DDIO_GPIO_1} = 5.5 V, process worst (FF)
SID84_2	I _{DDIO_GPI-O_1_2}	I _{DDIO_GPIO_1} when XRES_L is asserted	–	–	1.2	μA	Max: T _A = 85°C, V _{DDIO_GPIO_1} = 5.5 V, process worst (FF)
SID85	I _{DDIO_G-PIO_2}	I _{DDIO_GPIO_2} when XRES_L is asserted	–	0.05	50	μA	Typ: T _A = 25°C, V _{DDIO_GPIO_2} = 5.0 V, process typ (TT) Max: T _A = 105°C, V _{DDIO_GPIO_2} = 5.5 V, process worst (FF); For S-grade devices
SID85_125	I _{DDIO_G-PIO_2}	I _{DDIO_GPIO_2} when XRES_L is asserted	–	0.05	50	μA	Typ: T _A = 25°C, V _{DDIO_GPIO_2} = 5.0 V, process typ (TT) Max: T _A = 125°C, V _{DDIO_GPIO_2} = 5.5 V, process worst (FF); For E-grade devices
SID85_1	I _{DDIO_GPI-O_2_1}	I _{DDIO_GPIO_2} when XRES_L is asserted	–	–	0.15	μA	Max: T _A = 25°C, V _{DDIO_GPIO_2} = 5.5 V, process worst (FF)

Table 26-4 XRES_L Reset (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID85_2	$I_{DDIO_GPIO_2_2}$	$I_{DDIO_GPIO_2}$ when XRES_L is asserted	–	–	1.2	μA	Max: $T_A = 85^\circ\text{C}$, $V_{DDIO_GPIO_2} = 5.5\text{ V}$, process worst (FF)

XRES_L AC specifications

SID70	t_{XRES_ACT}	XRES_L deasserted to Active transition time	–	–	265	μs	Without boot runtime. Guaranteed by design
SID71	t_{XRES_PW}	XRES_L pulse width	5	–	–	μs	
SID72	t_{XRES_FT}	Pulse suppression width	100	–	–	ns	


Figure 26-3 Reset sequence

26.4 I/O Specifications

Table 26-5 I/O specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
GPIO_STD specifications (5-V I/Os, except GPIO_ENH)							
SID650	V _{OL1}	Output voltage LOW level	–	–	0.6	V	I _{OL} = 6 mA CFG_OUT/DRIVE_SEL<1:0> = 0b00 V _{DDIO_GPIO} ≥ 4.5 V
SID651	V _{OL2}	Output voltage LOW level	–	–	0.4	V	I _{OL} = 5 mA CFG_OUT/DRIVE_SEL<1:0> = 0b0X V _{DDIO_GPIO} ≥ 4.5 V
SID651D	V _{OL2}	Output voltage LOW level	–	–	0.4	V	I _{OL} = 2 mA CFG_OUT/DRIVE_SEL<1:0> = 0b0X 2.7 V ≤ V _{DDIO_GPIO} < 4.5 V
SID652	V _{OL3}	Output voltage LOW level	–	–	0.4	V	I _{OL} = 2 mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 V _{DDIO_GPIO} ≥ 4.5 V
SID652D	V _{OL3}	Output voltage LOW level	–	–	0.4	V	I _{OL} = 1 mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 2.7 V ≤ V _{DDIO_GPIO} < 4.5 V
SID653	V _{OL4}	Output voltage LOW level	–	–	0.4	V	I _{OL} = 1 mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 V _{DDIO_GPIO} ≥ 4.5 V
SID653D	V _{OL4}	Output voltage LOW level	–	–	0.4	V	I _{OL} = 0.5 mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 2.7 V ≤ V _{DDIO_GPIO} < 4.5 V
SID654	V _{OH1}	Output voltage HIGH level	V _{DDIO_GPIO} – 0.5	–	–	V	I _{OH} = –5 mA CFG_OUT/DRIVE_SEL<1:0> = 0b00 V _{DDIO_GPIO} ≥ 4.5 V
SID654D	V _{OH1}	Output voltage HIGH level	V _{DDIO_GPIO} – 0.5	–	–	V	I _{OH} = –2 mA CFG_OUT/DRIVE_SEL<1:0> = 0b00 2.7 V ≤ V _{DDIO_GPIO} < 4.5 V
SID655	V _{OH2}	Output voltage HIGH level	V _{DDIO_GPIO} – 0.5	–	–	V	I _{OH} = –5 mA CFG_OUT/DRIVE_SEL<1:0> = 0b01 V _{DDIO_GPIO} ≥ 4.5 V
SID655D	V _{OH2}	Output voltage HIGH level	V _{DDIO_GPIO} – 0.5	–	–	V	I _{OH} = –2 mA CFG_OUT/DRIVE_SEL<1:0> = 0b01 2.7 V ≤ V _{DDIO_GPIO} < 4.5 V
SID656	V _{OH3}	Output voltage HIGH level	V _{DDIO_GPIO} – 0.5	–	–	V	I _{OH} = –2 mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 V _{DDIO_GPIO} ≥ 4.5 V
SID656D	V _{OH3}	Output voltage HIGH level	V _{DDIO_GPIO} – 0.5	–	–	V	I _{OH} = –1 mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 2.7 V ≤ V _{DDIO_GPIO} < 4.5 V
SID657	V _{OH4}	Output voltage HIGH level	V _{DDIO_GPIO} – 0.5	–	–	V	I _{OH} = –1 mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 V _{DDIO_GPIO} ≥ 4.5 V
SID657D	V _{OH4}	Output voltage HIGH level	V _{DDIO_GPIO} – 0.5	–	–	V	I _{OH} = –0.5 mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 2.7 V ≤ V _{DDIO_GPIO} < 4.5 V
SID658	R _{PD}	Pull-down resistance	25	50	100	kΩ	
SID659	R _{PJ}	Pull-up resistance	25	50	100	kΩ	
SID660	V _{IH_CMOS}	Input voltage HIGH threshold in CMOS mode	0.7 × V _{DDIO_GPIO}	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b0
SID661	V _{IH_TTL}	Input voltage HIGH threshold in TTL mode	2.0	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b1
SID662	V _{IH_AUTO}	Input voltage HIGH threshold in AUTO mode	0.8 × V _{DDIO_GPIO}	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b1 CFG_IN/VTRIP_SEL<0:0> = 0b0 4.5 V ≤ V _{DDIO_GPIO} ≤ 5.5 V
SID663	V _{IL_CMOS}	Input voltage LOW threshold in CMOS mode	–	–	0.3 × V _{DDIO_GPIO}	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b0
SID664	V _{IL_TTL}	Input voltage LOW threshold in TTL mode	–	–	0.8	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b1

Table 26-5 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID665	V_{IL_AUTO}	Input voltage LOW threshold in AUTO mode	–	–	$0.5 \times V_{DDIO_GPIO}$	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0>= 0b1 CFG_IN/VTRIP_SEL<0:0>= 0b0 $4.5\text{ V} \leq V_{DDIO_GPIO} \leq 5.5\text{ V}$
SID666	V_{HYST_CMOS}	Hysteresis in CMOS mode	$0.05 \times V_{DDIO_GPIO}$	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0>= 0b0 CFG_IN/VTRIP_SEL<0:0>= 0b0
SID668	V_{HYST_AUTO}	Hysteresis in AUTO mode	$0.05 \times V_{DDIO_GPIO}$	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0>= 0b1 CFG_IN/VTRIP_SEL<0:0>= 0b0 $4.5\text{ V} \leq V_{DDIO_GPIO} \leq 5.5\text{ V}$
SID669	C_{IN}	Input pin capacitance	–	–	5	pF	Test condition: 10/100MHz
SID670	I_{IL}	Input leakage current	–1	–	1	μA	$V_{DDIO_GPIO_x} = V_{DD} = V_{DDA_ADC} = 5.5\text{ V}$, $V_{SS} < V_I < V_{DDIO_GPIO_x}$ $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$ This is valid for the pin which do not have ADC input functionality; For S-grade devices.
SID670_125	I_{IL}	Input leakage current	–1	–	1	μA	$V_{DDIO_GPIO_x} = V_{DD} = V_{DDA_ADC} = 5.5\text{ V}$, $V_{SS} < V_I < V_{DDIO_GPIO_x}$ $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ This is valid for the pin which do not have ADC input functionality; For E-grade devices.
SID671	$t_{R_F_FAST}$	Rise time or fall time (10% to 90% of V_{DDIO_GPIO})	1	–	10	ns	CFG_OUT/DRIVE_SEL<1:0>= 0b00, 20-pF load, entire V_{DDIO_GPIO} range
SID672	$t_{R_F_FAST}$	Rise time or fall time (10% to 90% of V_{DDIO_GPIO})	1	–	20	ns	CFG_OUT/DRIVE_SEL<1:0>= 0b00, 50-pF load, entire V_{DDIO_GPIO} range, guaranteed by design
SID673	$t_{R_F_FAST}$	Rise time or fall time (10% to 90% of V_{DDIO_GPIO})	1	–	20	ns	CFG_OUT/DRIVE_SEL<1:0>= 0b01, 20-pF load, entire V_{DDIO_GPIO} range, guaranteed by design
SID674	$t_{R_F_FAST}$	Rise time or fall time (10% to 90% of V_{DDIO_GPIO})	1	–	20	ns	CFG_OUT/DRIVE_SEL<1:0>= 0b10, 10-pF load, entire V_{DDIO_GPIO} range, guaranteed by design
SID675	$t_{R_F_FAST}$	Rise time or fall time (10% to 90% of V_{DDIO_GPIO})	1	–	20	ns	CFG_OUT/DRIVE_SEL<1:0>= 0b11, 6-pF load, entire V_{DDIO_GPIO} range, guaranteed by design
GPIO_SMC specifications (Stepper Motor Control, 5-V I/Os)							
SID650A	V_{OL2}	Output voltage LOW level	–	–	0.6	V	$I_{OL} = 6\text{ mA}$ CFG_OUT/DRIVE_SEL<1:0>= 0b01 $V_{DDIO_SMC} \geq 4.5\text{ V}$
SID651A	V_{OL2}	Output voltage LOW level	–	–	0.4	V	$I_{OL} = 5\text{ mA}$ CFG_OUT/DRIVE_SEL<1:0>= 0b01 $V_{DDIO_SMC} \geq 4.5\text{ V}$
SID651E	V_{OL2}	Output voltage LOW level	–	–	0.4	V	$I_{OL} = 2\text{ mA}$ CFG_OUT/DRIVE_SEL<1:0>= 0b01 $2.7\text{ V} \leq V_{DDIO_SMC} < 4.5\text{ V}$

Electrical specifications

Table 26-5 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID652A	V _{OL3}	Output voltage LOW level	–	–	0.4	V	I _{OL} = 2 mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 V _{DDIO_SMC} ≥ 4.5 V
SID652E	V _{OL3}	Output voltage LOW level	–	–	0.4	V	I _{OL} = 1 mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 2.7 V ≤ V _{DDIO_SMC} < 4.5 V
SID653A	V _{OL4}	Output voltage LOW level	–	–	0.4	V	I _{OL} = 1 mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 V _{DDIO_SMC} ≥ 4.5 V
SID653E	V _{OL4}	Output voltage LOW level	–	–	0.4	V	I _{OL} = 0.5 mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 2.7 V ≤ V _{DDIO_SMC} < 4.5 V
SID653B	V _{OL5}	Output voltage LOW level	–	–	0.5	V	I _{OL} = 30 mA CFG_OUT/DRIVE_SEL<1:0> = 0b00 CFG_OUT/SLOW<0:0> = 0b1 25°C < T _A ≤ 105°C V _{DDIO_SMC} ≥ 4.5 V For S-grade devices
SID653B_125	V _{OL5}	Output voltage LOW level	–	–	0.5	V	I _{OL} = 30 mA CFG_OUT/DRIVE_SEL<1:0> = 0b00 CFG_OUT/SLOW<0:0> = 0b1 25°C < T _A ≤ 125°C V _{DDIO_SMC} ≥ 4.5 V For E-grade devices
SID653C	V _{OL5}	Output voltage LOW level	–	–	0.5	V	I _{OL} = 40 mA CFG_OUT/DRIVE_SEL<1:0> = 0b00 CFG_OUT/SLOW<0:0> = 0b1 –30°C < T _A ≤ 25°C V _{DDIO_SMC} ≥ 4.5 V
SID653H	V _{OL5}	Output voltage LOW level	–	–	0.5	V	I _{OL} = 52 mA CFG_OUT/DRIVE_SEL<1:0> = 0b00 CFG_OUT/SLOW<0:0> = 0b1 –40°C ≤ T _A ≤ –30°C V _{DDIO_SMC} ≥ 4.5 V
SID654A	V _{OH2}	Output voltage HIGH level	V _{DDIO_SMC} – 0.5	–	–	V	I _{OH} = –5 mA CFG_OUT/DRIVE_SEL<1:0> = 0b01 V _{DDIO_SMC} ≥ 4.5 V
SID654E	V _{OH2}	Output voltage HIGH level	V _{DDIO_SMC} – 0.5	–	–	V	I _{OH} = –2 mA CFG_OUT/DRIVE_SEL<1:0> = 0b01 2.7 V ≤ V _{DDIO_SMC} < 4.5 V
SID656A	V _{OH3}	Output voltage HIGH level	V _{DDIO_SMC} – 0.5	–	–	V	I _{OH} = –2 mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 V _{DDIO_SMC} ≥ 4.5 V
SID656E	V _{OH3}	Output voltage HIGH level	V _{DDIO_SMC} – 0.5	–	–	V	I _{OH} = –1 mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 2.7 V ≤ V _{DDIO_SMC} < 4.5 V
SID657A	V _{OH4}	Output voltage HIGH level	V _{DDIO_SMC} – 0.5	–	–	V	I _{OH} = –1 mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 V _{DDIO_SMC} ≥ 4.5 V
SID657E	V _{OH4}	Output voltage HIGH level	V _{DDIO_SMC} – 0.5	–	–	V	I _{OH} = –0.5 mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 2.7 V ≤ V _{DDIO_SMC} < 4.5 V
SID657B	V _{OH5}	Output voltage HIGH level	V _{DDIO_SMC} – 0.5	–	–	V	I _{OL} = –30 mA CFG_OUT/DRIVE_SEL<1:0> = 0b00 CFG_OUT/SLOW<0:0> = 0b1 25°C < T _A ≤ 105°C V _{DDIO_SMC} ≥ 4.5 V For S-grade devices
SID657B_125	V _{OH5}	Output voltage HIGH level	V _{DDIO_SMC} – 0.5	–	–	V	I _{OL} = –30 mA CFG_OUT/DRIVE_SEL<1:0> = 0b00 CFG_OUT/SLOW<0:0> = 0b1 25°C < T _A ≤ 125°C V _{DDIO_SMC} ≥ 4.5 V For E-grade devices
SID657C	V _{OH5}	Output voltage HIGH level	V _{DDIO_SMC} – 0.5	–	–	V	I _{OL} = –40 mA CFG_OUT/DRIVE_SEL<1:0> = 0b00 CFG_OUT/SLOW<0:0> = 0b1 –30°C < T _A ≤ 25°C V _{DDIO_SMC} ≥ 4.5 V

Electrical specifications

Table 26-5 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID657I	V_{OH5}	Output voltage HIGH level	$V_{DDIO_SMC} - 0.5$	–	–	V	$I_{OL} = -52 \text{ mA}$ CFG_OUT/DRIVE_SEL<1:0> = 0b00 CFG_OUT/SLOW<0:0> = 0b1 $-40^{\circ}\text{C} \leq T_A \leq -30^{\circ}\text{C}$ $V_{DDIO_SMC} \geq 4.5 \text{ V}$
SID658A	R_{PD}	Pull-down resistance	25	50	100	k Ω	
SID659A	R_{PU}	Pull-up resistance	25	50	100	k Ω	
SID659B	V_{OUT}	Mid range voltage level	2.45	–	2.55	V	CFG/DRIVE_MODE<2:0> = 0b001
SID660A	V_{IH_CMOS}	Input voltage HIGH threshold in CMOS mode	$0.7 \times V_{DDIO_SMC}$	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b0
SID661A	V_{IH_TTL}	Input voltage HIGH threshold in TTL mode	2	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b1
SID662A	V_{IH_AUTO}	Input voltage HIGH threshold in AUTO mode	$0.8 \times V_{DDIO_SMC}$	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b1 CFG_IN/VTRIP_SEL<0:0> = 0b0 $4.5 \text{ V} \leq V_{DDIO_SMC} \leq 5.5 \text{ V}$
SID663A	V_{IL_CMOS}	Input voltage LOW threshold in CMOS mode	–	–	$0.3 \times V_{DDIO_SMC}$	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b0
SID664A	V_{IL_TTL}	Input voltage LOW threshold in TTL mode	–	–	0.8	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b1
SID665A	V_{IL_AUTO}	Input voltage LOW threshold in AUTO mode	–	–	$0.5 \times V_{DDIO_SMC}$	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b1 CFG_IN/VTRIP_SEL<0:0> = 0b0 $4.5 \text{ V} \leq V_{DDIO_SMC} \leq 5.5 \text{ V}$
SID666A	V_{HYST_CMOS}	Hysteresis in CMOS mode	$0.05 \times V_{DDIO_SMC}$	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b0
SID668A	V_{HYST_AUTO}	Hysteresis in AUTO mode	$0.05 \times V_{DDIO_SMC}$	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b1 CFG_IN/VTRIP_SEL<0:0> = 0b0 $4.5 \text{ V} \leq V_{DDIO_SMC} \leq 5.5 \text{ V}$
SID669A	C_{IN}	Input pin capacitance	–	–	7	pF	Test condition: 10/100MHz
SID670A	I_{IL}	Input leakage current	–2	–	2	μA	$V_{DDIO_SMC} = V_{DD} = 5.5 \text{ V}$, $V_{SS} < V_I < V_{DDIO_SMC}$ $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ This is valid for the pin which do not have ADC input functionality; For S-grade devices
SID670A_125	I_{IL}	Input leakage current	–2	–	2	μA	$V_{DDIO_SMC} = V_{DD} = 5.5 \text{ V}$, $V_{SS} < V_I < V_{DDIO_SMC}$ $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ This is valid for the pin which do not have ADC input functionality; For E-grade devices
SID673A	$t_{R_F_FAST}$	Rise time or fall time (10% to 90% of V_{DDIO_SMC})	1	–	20	ns	5 mA drive strength 20-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_OUT/SLOW<0:0> = 0b0, guaranteed by design

Electrical specifications

Table 26-5 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID674A	$t_{R_F_FAST}$	Rise time or fall time (10% to 90% of V_{DDIO_SMC})	1	–	20	ns	2 mA drive strength 10-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b10, CFG_OUT/SLOW<0:0> = 0b0, guaranteed by design
SID675A	$t_{R_F_FAST}$	Rise time or fall time (10% to 90% of V_{DDIO_SMC})	1	–	20	ns	1 mA drive strength 6-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b11, CFG_OUT/SLOW<0:0> = 0b0, guaranteed by design
SID676A	$t_{R_F_SMC_SLOW}$	Rise time or fall time (10% to 90% of V_{DDIO_SMC})	15	–	80	ns	30 mA drive strength No load, CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_OUT/SLOW<0:0> = 0b1
SID676B	$t_{R_F_SMC_SLOW}$	Rise time or fall time (10% to 90% of V_{DDIO_SMC})	25	–	100	ns	30 mA drive strength 85-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_OUT/SLOW<0:0> = 0b1
SID676C	$t_{R_F_SMC_SLOW}$	Rise time or fall time (10% to 90% of V_{DDIO_SMC})	100	–	200	ns	30 mA drive strength 2.7-nF load, CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_OUT/SLOW<0:0> = 0b1

GPIO_ENH Specifications

SID650C	V_{OL1}	Output voltage LOW level	–	–	0.6	V	$I_{OL} = 6$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b0X $V_{DDIO_GPIO} \geq 4.5$ V
SID650D	V_{OL1}	Output voltage LOW level	–	–	0.4	V	$I_{OL} = 5$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b0X $V_{DDIO_GPIO} \geq 4.5$ V
SID651C	V_{OL1}	Output voltage LOW level	–	–	0.4	V	$I_{OL} = 2$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b0X 2.7 V $\leq V_{DDIO_GPIO} < 4.5$ V
SID652C	V_{OL3}	Output voltage LOW level	–	–	0.4	V	$I_{OL} = 2$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 $V_{DDIO_GPIO} \geq 4.5$ V
SID652F	V_{OL3}	Output voltage LOW level	–	–	0.4	V	$I_{OL} = 1$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 2.7 V $\leq V_{DDIO_GPIO} < 4.5$ V
SID653F	V_{OL4}	Output voltage LOW level	–	–	0.4	V	$I_{OL} = 1$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 $V_{DDIO_GPIO} \geq 4.5$ V
SID653G	V_{OL4}	Output voltage LOW level	–	–	0.4	V	$I_{OL} = 0.5$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 2.7 V $\leq V_{DDIO_GPIO} < 4.5$ V
SID654C	V_{OH1}	Output voltage HIGH level	$V_{DDIO_GPIO} - 0.5$	–	–	V	$I_{OH} = -5$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b0X $V_{DDIO_GPIO} \geq 4.5$ V
SID654G	V_{OH1}	Output voltage HIGH level	$V_{DDIO_GPIO} - 0.5$	–	–	V	$I_{OH} = -2$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b0X 2.7 V $\leq V_{DDIO_GPIO} < 4.5$ V
SID655C	V_{OH3}	Output voltage HIGH level	$V_{DDIO_GPIO} - 0.5$	–	–	V	$I_{OH} = -2$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 $V_{DDIO_GPIO} \geq 4.5$ V
SID656C	V_{OH3}	Output voltage HIGH level	$V_{DDIO_GPIO} - 0.5$	–	–	V	$I_{OH} = -1$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b10 2.7 V $\leq V_{DDIO_GPIO} < 4.5$ V
SID657G	V_{OH4}	Output voltage HIGH level	$V_{DDIO_GPIO} - 0.5$	–	–	V	$I_{OH} = -1$ mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 $V_{DDIO_GPIO} \geq 4.5$ V

Electrical specifications

Table 26-5 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID657H	V _{OH4}	Output voltage HIGH level	V _{DDIO_GPIO} – 0.5	–	–	V	I _{OH} = –0.5 mA CFG_OUT/DRIVE_SEL<1:0> = 0b11 2.7 V ≤ V _{DDIO_GPIO} < 4.5 V
SID658C	R _{PD}	Pull-down resistance	25	50	100	kΩ	
SID659C	R _{PU}	Pull-up resistance	25	50	100	kΩ	
SID660C	V _{IH_CMOS}	Input voltage HIGH threshold in CMOS mode	0.7 × V _{DDIO_GPIO}	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b0
SID661C	V _{IH_TTL}	Input voltage HIGH threshold in TTL mode	2	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b1
SID662C	V _{IH_AUTO}	Input voltage HIGH threshold in AUTO mode	0.8 × V _{DDIO_GPIO}	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b1 CFG_IN/VTRIP_SEL<0:0> = 0b0 4.5 V ≤ V _{DDIO_GPIO} ≤ 5.5 V
SID663C	V _{IL_CMOS}	Input voltage LOW threshold in CMOS mode	–	–	0.3 × V _{DDIO_GPIO}	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b0
SID664C	V _{IL_TTL}	Input voltage LOW threshold in TTL mode	–	–	0.8	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b1
SID665C	V _{IL_AUTO}	Input voltage LOW threshold in AUTO mode	–	–	0.5 × V _{DDIO_GPIO}	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b1 CFG_IN/VTRIP_SEL<0:0> = 0b0 4.5 V ≤ V _{DDIO_GPIO} ≤ 5.5 V
SID666C	V _{HYST_CMOS}	Hysteresis in CMOS mode	0.05 × V _{DDIO_GPIO}	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b0
SID668C	V _{HYST_AUTO}	Hysteresis in AUTO mode	0.05 × V _{DDIO_GPIO}	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b1 CFG_IN/VTRIP_SEL<0:0> = 0b0 4.5 V ≤ V _{DDIO_GPIO} ≤ 5.5 V
SID669C	C _{IN}	Input pin capacitance	–	–	5	pF	Test condition: 10/100MHz
SID670C	I _{IL}	Input leakage current	–1	–	1	μA	V _{DDIO_GPIO} = V _{DD} = 5.5 V, V _{SS} < V _I < V _{DDIO_GPIO} –40°C ≤ T _A ≤ 105°C For S-grade devices
SID670C_125	I _{IL}	Input leakage current	–1	–	1	μA	V _{DDIO_GPIO} = V _{DD} = 5.5 V, V _{SS} < V _I < V _{DDIO_GPIO} –40°C ≤ T _A ≤ 125°C For E-grade devices
SID671C	t _{R_F_FAST}	Rise time or fall time (10% to 90% of V _{DDIO_GPIO})	1	–	10	ns	20-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_OUT/SLOW<0:0> = 0b0, entire V _{DDIO_GPIO} range
SID672C	t _{R_F_FAST}	Rise time or fall time (10% to 90% of V _{DDIO_GPIO})	1	–	20	ns	50-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_OUT/SLOW<0:0> = 0b0, entire V _{DDIO_GPIO} range, guaranteed by design
SID673C	t _{R_F_FAST}	Rise time or fall time (10% to 90% of V _{DDIO_GPIO})	1	–	20	ns	20-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_OUT/SLOW<0:0> = 0b0, entire V _{DDIO_GPIO} range, guaranteed by design
SID674C	t _{R_F_FAST}	Rise time or fall time (10% to 90% of V _{DDIO_GPIO})	1	–	20	ns	10-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b10, CFG_OUT/SLOW<0:0> = 0b0, entire V _{DDIO_GPIO} range, guaranteed by design

Electrical specifications

Table 26-5 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID675C	$t_{R_F_FAST}$	Rise time or fall time (10% to 90% of V_{DDIO_GPIO})	1	–	20	ns	6-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b11, CFG_OUT/SLOW<0:0> = 0b0, entire V_{DDIO_GPIO} range, guaranteed by design
SID676E	$t_{F_I2C_SLOW}$	Fall time (30% to 70% of V_{DDIO_GPIO})	$20 \times (V_{DDIO_GPIO} / 5.5)$	–	250	ns	10-pF to 400-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_OUT/SLOW<0:0> = 0b1, minimum $R_{PU} = 400 \Omega$
SID677C	$t_{R_F_SLOW}$	Rise time or fall time (10% to 90% of V_{DDIO_GPIO})	$20 \times (V_{DDIO_GPIO} / 5.5)$	–	160	ns	20-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_OUT/SLOW<0:0> = 0b1, output frequency = 1 MHz
SID678C	$t_{R_F_SLOW}$	Rise time or fall time (10% to 90% of V_{DDIO_GPIO})	$20 \times (V_{DDIO_GPIO} / 5.5)$	–	250	ns	400-pF load, CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_OUT/SLOW<0:0> = 0b1, output frequency = 400 kHz, guaranteed by design
HSIO_STDLN Specifications (3 V I/Os)							
SID650E	V_{OL0}	Output LOW voltage level	–	–	0.4	V	$I_{OL} = 10 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b000
SID651F	V_{OL0}	Output LOW voltage level	–	–	0.2	V	$I_{OL} = 0.1 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b000
SID654I	V_{OL1}	Output LOW voltage level	–	–	0.4	V	$I_{OL} = 10 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b001 $3.0 \text{ V} \leq V_{DDIO_HSIO} \leq 3.6 \text{ V}$
SID655G	V_{OL2}	Output LOW voltage level	–	–	0.4	V	$I_{OL} = 2 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b010 $3.0 \text{ V} \leq V_{DDIO_HSIO} \leq 3.6 \text{ V}$
SID656G	V_{OL3}	Output LOW voltage level	–	–	0.4	V	$I_{OL} = 1 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b011 $3.0 \text{ V} \leq V_{DDIO_HSIO} \leq 3.6 \text{ V}$
SID656H	V_{OL4}	Output LOW voltage level	–	–	0.4	V	$I_{OL} = 0.5 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b100 $3.0 \text{ V} \leq V_{DDIO_HSIO} \leq 3.6 \text{ V}$
SID657J	V_{OH0}	Output HIGH voltage level	$V_{DDIO_HSIO} - 0.4$	–	–	V	$I_{OH} = -10 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b000
SID658D	V_{OH0}	Output HIGH voltage level	$V_{DDIO_HSIO} - 0.2$	–	–	V	$I_{OH} = -0.1 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b000
SID661F	V_{OH1}	Output HIGH voltage level	$V_{DDIO_HSIO} - 0.4$	–	–	V	$I_{OH} = -10 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b001 $3.0 \text{ V} \leq V_{DDIO_HSIO} \leq 3.6 \text{ V}$
SID662F	V_{OH2}	Output HIGH voltage level	$V_{DDIO_HSIO} - 0.4$	–	–	V	$I_{OH} = -2 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b010 $3.0 \text{ V} \leq V_{DDIO_HSIO} \leq 3.6 \text{ V}$
SID663E	V_{OH3}	Output HIGH voltage level	$V_{DDIO_HSIO} - 0.4$	–	–	V	$I_{OH} = -1 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b011 $3.0 \text{ V} \leq V_{DDIO_HSIO} \leq 3.6 \text{ V}$

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Table 26-5 I/O specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID663F	V_{OH4}	Output HIGH voltage level	$V_{DDIO_HSIO} - 0.4$	–	–	V	$I_{OH} = -0.5 \text{ mA}$ CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b100 $3.0 \text{ V} \leq V_{DDIO_HSIO} \leq 3.6 \text{ V}$
SID664D	R_{PD}	Pull-down resistance	25	50	100	k Ω	
SID665F	R_{PU}	Pull-up resistance	25	50	100	k Ω	
SID665H	V_{IH3}	Input Voltage HIGH threshold	1.7	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b1 CFG_IN/VTRIP_SEL<0:0> = 0b1
SID667G	V_{IH0}	Input Voltage HIGH threshold	$0.7 \times V_{DDIO_HSIO}$	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b0
SID667I	V_{IH1}	Input Voltage HIGH threshold	2	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b1
SID667H	V_{IL3}	Input Voltage LOW threshold	–	–	0.9	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b1 CFG_IN/VTRIP_SEL<0:0> = 0b1
SID671F	V_{IL0}	Input Voltage LOW threshold	–	–	$0.3 \times V_{DDIO_HSIO}$	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b0
SID671G	V_{IL1}	Input Voltage LOW threshold	–	–	0.8	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b1
SID674D	V_{HYST_CMOS}	Hysteresis in CMOS mode	$0.05 \times V_{DDIO_HSIO}$	–	–	V	CFG_IN_AU-TOLVL/VTRIP_SEL<0:0> = 0b0 CFG_IN/VTRIP_SEL<0:0> = 0b0
SID675D	C_{IN}	Input pin capacitance	–	–	5	pF	Test condition: 10/100MHz
SID676H	I_{IL12}	Input leakage current	–1	–	1	μA	$V_{DDIO_HSIO} = 3.6 \text{ V}$, $V_{SS} < V_I < V_{DDIO_HSIO}$ $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$ For S-grade devices
SID676H_125	I_{IL12}	Input leakage current	–1	–	1	μA	$V_{DDIO_HSIO} = 3.6 \text{ V}$, $V_{SS} < V_I < V_{DDIO_HSIO}$ $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ For E-grade devices
GPIO Input Specifications							
SID98	t_{FT}	Analog glitch filter (pulse suppression width)	–	–	50 ^[64]	ns	One filter per port group (required for some I ² C speeds)
SID99	t_{INT}	Minimum pulse width for GPIO interrupt	160	–	–	ns	

Note

64.If a longer pulse suppression width is necessary, use Smart I/O.

26.5 Analog peripherals

26.5.1 SAR ADC

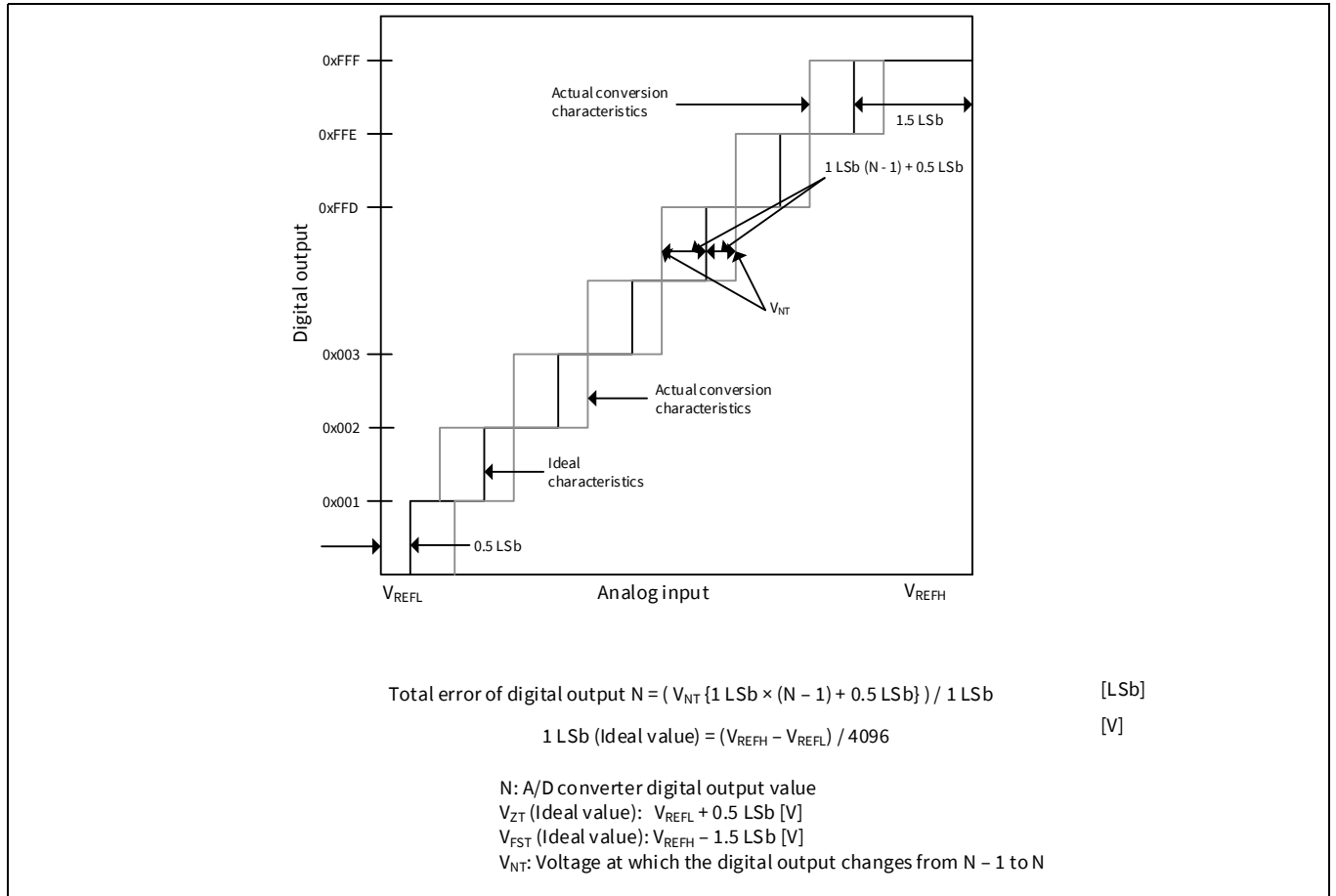


Figure 26-4 ADC characteristics and error descriptions

Table 26-6 12-bit SAR ADC DC specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID100	A_RES	SAR ADC resolution	–	–	12	bits	
SID101	V_{A_INV}	Input voltage range	V_{REFL}	–	V_{REFH}	V	
SID102	V_{REFH}	SAR ADC HIGH reference voltage range	2.7	–	V_{DDA_ADC}	V	ADC performance degrades when high reference is higher than supply
SID103	V_{REFL}	SAR ADC LOW reference voltage range	V_{SSA_ADC}	–	V_{SSA_ADC}	V	ADC performance degrades when low reference is lower than ground
SID103A	V_{BAND_GAP}	Internal band gap reference voltage	0.882	0.9	0.918	V	

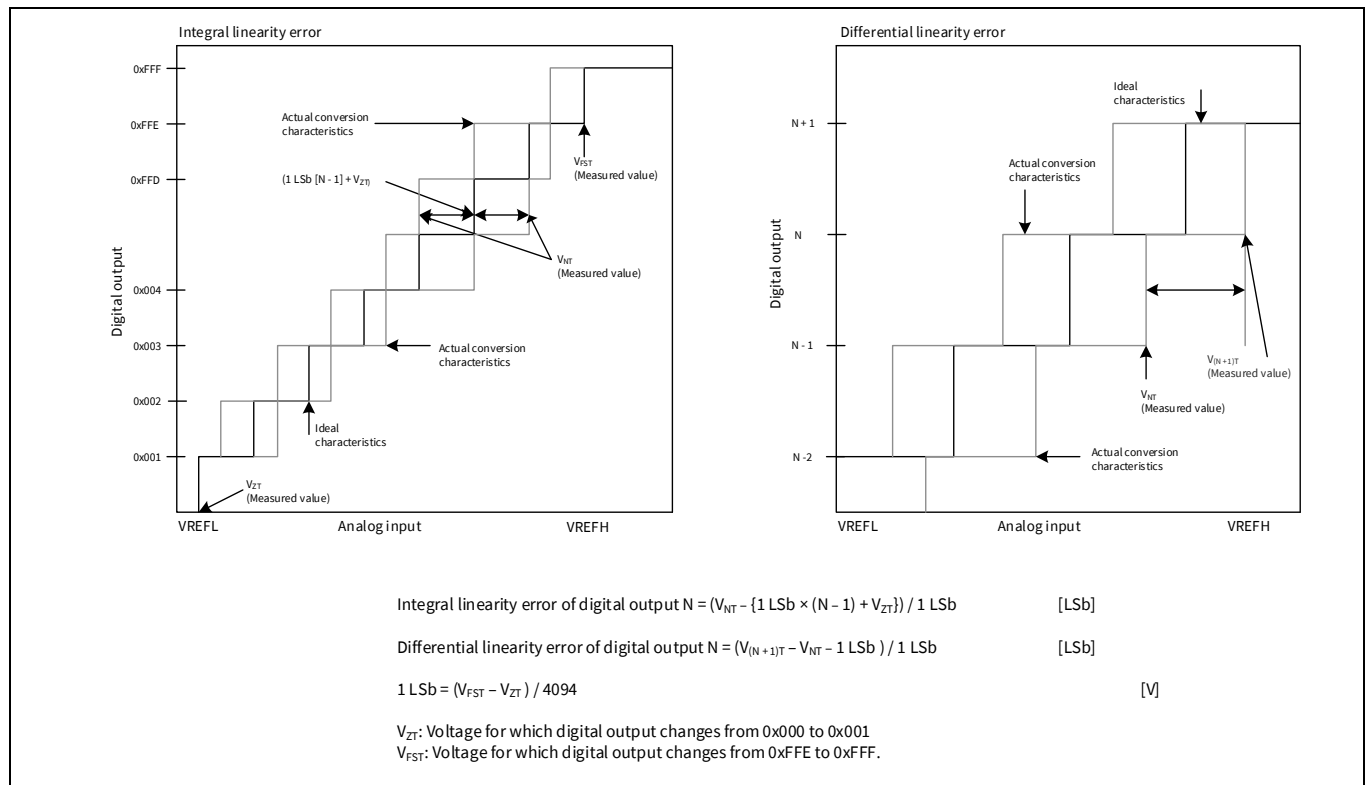


Figure 26-5 Integral and differential linearity errors

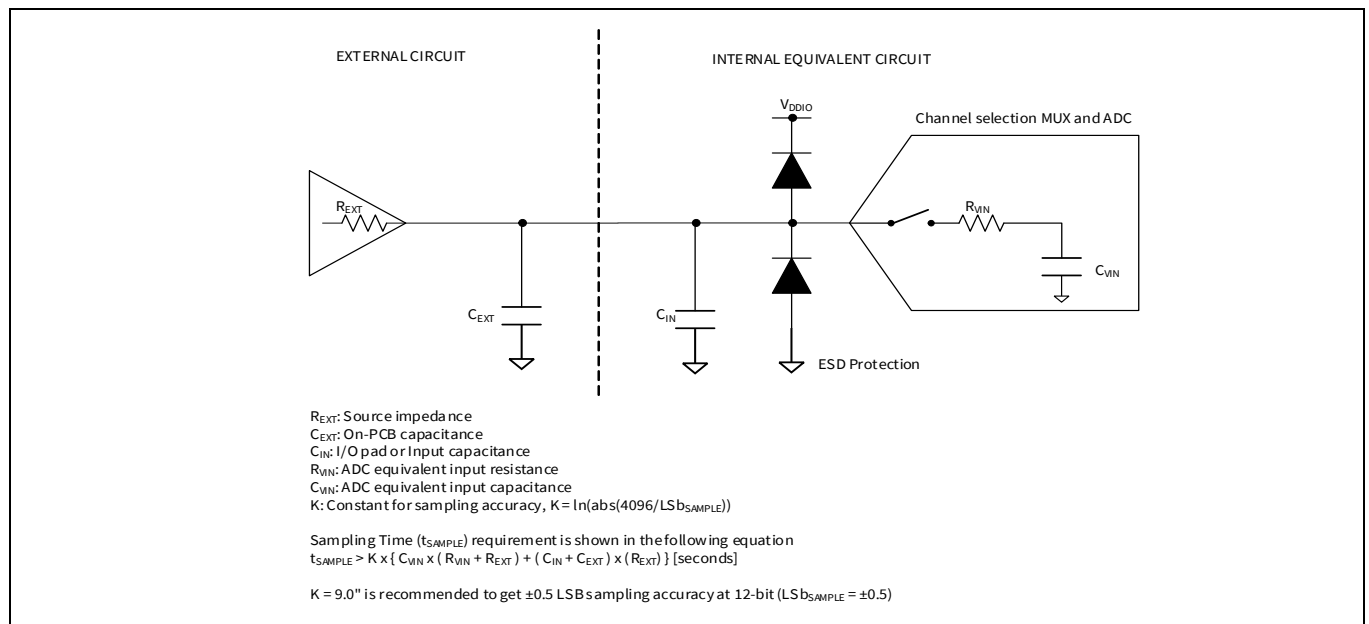


Figure 26-6 ADC equivalent circuit for analog input

Table 26-7 SAR ADC AC specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID104	V _{ZT}	Zero transition voltage	-20	-	20	mV	V _{DDA_ADC} = 2.7 V to 5.5 V, -40°C ≤ T _A ≤ 105°C before offset adjustment; For S-grade devices
SID104_125	V _{ZT}	Zero transition voltage	-20	-	20	mV	V _{DDA_ADC} = 2.7 V to 5.5 V, -40°C ≤ T _A ≤ 125°C before offset adjustment; For E-grade devices
SID105	V _{FST}	Full-scale transition voltage	-20	-	20	mV	V _{DDA_ADC} = 2.7 V to 5.5 V, -40°C ≤ T _A ≤ 105°C before offset adjustment; For S-grade devices
SID105_125	V _{FST}	Full-scale transition voltage	-20	-	20	mV	V _{DDA_ADC} = 2.7 V to 5.5 V, -40°C ≤ T _A ≤ 125°C before offset adjustment; For E-grade devices
SID114	f _{ADC}	ADC operating frequency	2	-	26.67	MHz	
SID113	t _{S_4P5}	Analog input sample time (4.5 V ≤ V _{DDA_ADC}) for channels of SARMUX0	412	-	-	ns	SARMUX0 inputs are direct into the ADC Guaranteed by design
SID113A	t _{S_2P7}	Analog input sample time (2.7 V ≤ V _{DDA_ADC}) for channels of SARMUX0	824	-	-	ns	SARMUX0 inputs are direct into the ADC Guaranteed by design
SID113B	t _{S_DR_4P5}	Analog input sample time when input is from diagnostic reference (4.5 V ≤ V _{DDA_ADC})	2	-	-	μs	Guaranteed by design
SID113C	t _{S_DR_2P7}	Analog input sample time when input is from diagnostic reference (2.7 V ≤ V _{DDA_ADC})	2.5	-	-	μs	Guaranteed by design
SID113D	t _{S_TS}	Analog input sample time for temperature sensor	7	-	-	μs	Guaranteed by design
SID106	t _{ST1}	Max throughput (sample per second) for channels of SARMUX0	-	-	1	Msp/s	4.5 V ≤ V _{DDA_ADC} ≤ 5.5 V, 80 MHz / 3 = 26.67 MHz, 11 sampling cycles, 15 conversion cycles
SID106A	t _{ST2}	Max throughput (sample per second) for channels of SARMUX0	-	-	0.5	Msp/s	2.7 V ≤ V _{DDA_ADC} < 4.5 V 80 MHz / 6 = 13.3 MHz, 11 sampling cycles, 15 conversion cycles
SID107	C _{VIN}	ADC input sampling capacitance	-	-	4.8	pF	Guaranteed by design
SID108	R _{VIN1}	Input path ON resistance (4.5 V to 5.5 V)	-	-	9.4	kΩ	Guaranteed by design
SID108A	R _{VIN2}	Input path ON resistance (2.7 V to 4.5 V)	-	-	13.9	kΩ	Guaranteed by design
SID108B	R _{DREF1}	Diagnostic path ON resistance (4.5 V to 5.5 V)	-	-	40	kΩ	Guaranteed by design
SID108C	R _{DREF2}	Diagnostic path ON resistance (2.7 V to 4.5 V)	-	-	50	kΩ	Guaranteed by design
SID119	ACC_RLAD	Diagnostic reference resistor ladder accuracy	-4	-	4	%	

Table 26-7 SAR ADC AC specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID109	A_TE	Total error	-5	-	5	LSb	$V_{DDA_ADC} = V_{REFH} = 2.7\text{ V to }5.5\text{ V}$, $V_{REFL} = V_{SSA_ADC}$ $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ Total error after offset and gain adjustment at 12-bit resolution mode; For S-grade devices
SID109_125	A_TE	Total error	-5	-	5	LSb	$V_{DDA_ADC} = V_{REFH} = 2.7\text{ V to }5.5\text{ V}$, $V_{REFL} = V_{SSA_ADC}$ $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ Total error after offset and gain adjustment at 12-bit resolution mode; For E-grade devices
SID109A	A_TEB	Total error	-12	-	12	LSb	$V_{DDA_ADC} = V_{REFH} = 2.7\text{ V to }5.5\text{ V}$, $V_{REFL} = V_{SSA_ADC}$ $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ Total Error before offset and gain adjustment at 12-bit resolution mode; For S-grade devices
SID109A_125	A_TEB	Total error	-12	-	12	LSb	$V_{DDA_ADC} = V_{REFH} = 2.7\text{ V to }5.5\text{ V}$, $V_{REFL} = V_{SSA_ADC}$ $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ Total Error before offset and gain adjustment at 12-bit resolution mode; For E-grade devices
SID110	A_INL	Integral nonlinearity	-2.5	-	2.5	LSb	$V_{DDA_ADC} = 2.7\text{ V to }5.5\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$; For S-grade devices
SID110_125	A_INL	Integral nonlinearity	-2.5	-	2.5	LSb	$V_{DDA_ADC} = 2.7\text{ V to }5.5\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$; For E-grade devices
SID111	A_DNL	Differential nonlinearity	-0.99	-	1.9	LSb	$V_{DDA_ADC} = 2.7\text{ V to }5.5\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ For S-grade devices
SID111_125	A_DNL	Differential nonlinearity	-0.99	-	1.9	LSb	$V_{DDA_ADC} = 2.7\text{ V to }5.5\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ For E-grade devices
SID112	A_GE	Measure the ADC output with input switching through all input channels of one ADC	-7	-	7	LSb	$V_{DDA_ADC} = 2.7\text{ V to }5.5\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ For S-grade devices
SID112_125	A_GE	Measure the ADC output with input switching through all input channels of one ADC	-7	-	7	LSb	$V_{DDA_ADC} = 2.7\text{ V to }5.5\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ For E-grade devices

Electrical specifications

Table 26-7 SAR ADC AC specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID115	I_{AIC}	Analog input leakage current (GPIO_STD)	-350	-	350	nA	When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ For S-grade devices
SID115_125	I_{AIC}	Analog input leakage current (GPIO_STD)	-350	-	350	nA	When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ For E-grade devices
SID115B	I_{AIC}	Analog input leakage current (GPIO_ENH)	-700	-	700	nA	When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ For S-grade devices
SID115B_125	I_{AIC}	Analog input leakage current (GPIO_ENH)	-700	-	700	nA	When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ For E-grade devices
SID115D	I_{AIC}	Analog input leakage current (GPIO_SMC)	-1075	-	1075	nA	When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ For S-grade devices
SID115D_125	I_{AIC}	Analog input leakage current (GPIO_SMC)	-1075	-	1075	nA	When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ For E-grade devices
SID115A	I_{AIC2}	Analog input leakage current (GPIO_STD)	-	-	165	nA	When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ For S-grade devices
SID115A_125	I_{AIC2}	Analog input leakage current (GPIO_STD)	-	-	165	nA	When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ For E-grade devices
SID115C	I_{AIC2}	Analog input leakage current (GPIO_ENH)	-	-	515	nA	When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ For S-grade devices
SID115C_125	I_{AIC2}	Analog input leakage current (GPIO_ENH)	-	-	515	nA	When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ For E-grade devices

Table 26-7 SAR ADC AC specifications (continued)

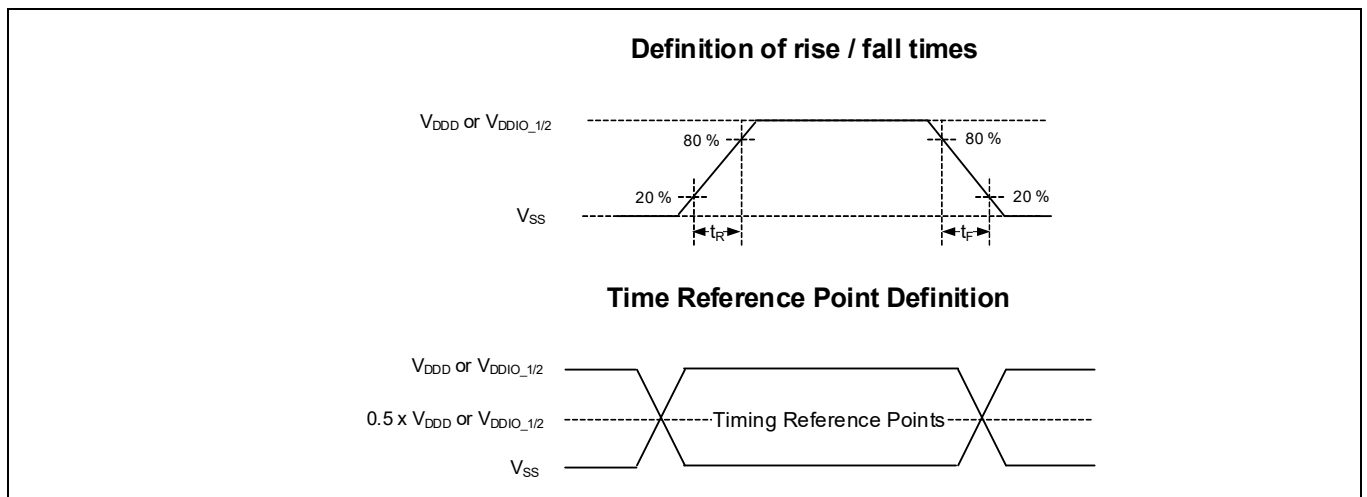
Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID115E	I_{AIC2}	Analog input leakage current (GPIO_SMC)	–	–	1015	nA	When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ For S-grade devices
SID115E_125	I_{AIC2}	Analog input leakage current (GPIO_SMC)	–	–	1015	nA	When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ For E-grade devices
SID116	$I_{DIAGREF}$	Diagnostic reference current	–	–	70	μA	
SID117	I_{VDDA}	Analog power supply current while ADC is operating	–	360	550	μA	Per enabled ADC, without diagnosis
SID117A	I_{VDDA_DS}	Analog power supply current while ADC is not operating	–	1	21	μA	Per enabled ADC
SID118	I_{VREF}	Analog reference voltage current while ADC is operating	–	360	550	μA	Per enabled ADC, without diagnosis
SID118A	I_{VREF_LEAK}	Analog reference voltage current while ADC is not operating	–	1.8	5	μA	Per enabled ADC
SID118B	$t_{S_4P5_1}$	Analog input sample time ($4.5\text{ V} \leq V_{DDA_ADC}$) for channels of SARMUX1	824	–	–	ns	Additional delay for SARMUX1 due to additional switches in the path to the ADC Guaranteed by Design
SID118C	$t_{S_2P7_1}$	Analog input sample time ($2.7\text{ V} \leq V_{DDA_ADC}$) for channels of SARMUX1	1648	–	–	ns	Additional delay for SARMUX1 due to additional switches in the path to the ADC Guaranteed by Design
SID119A	t_{ST3}	Max throughput (sample per second) for channels of SARMUX1	–	–	0.5	Msp/s	$4.5\text{ V} \leq V_{DDA_ADC} \leq 5.5\text{ V}$ 80 MHz / 6 = 13.3 MHz, 11 sampling cycles, 15 conversion cycles
SID119B	t_{ST4}	Max throughput (sample per second) for channels of SARMUX1	–	–	0.25	Msp/s	$2.7\text{ V} \leq V_{DDA_ADC} < 4.5\text{ V}$ 80 MHz / 12 = 6.67 MHz, 11 sampling cycles, 15 conversion cycles

Table 26-8 Temperature sensor specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID201	$T_{\text{SENSACC_TR}}$	Temperature sensor accuracy trimmed	-5	-	5	°C	This spec is valid for the following two conditions: 1. $3.0\text{ V} \leq V_{\text{DDA_ADC}} = V_{\text{REFH}} \leq 3.6\text{ V}$ and $3.0\text{ V} \leq V_{\text{DD}} \leq 3.6\text{ V}$ 2. $4.5\text{ V} \leq V_{\text{DDA_ADC}} = V_{\text{REFH}} \leq 5.5\text{ V}$ and $4.5\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}$ (Calibrated accuracy by factory trimming)
SID202	$T_{\text{SENSAC_C_STD}}$	Temperature sensor accuracy standard	-10	-	10	°C	This spec applies to all valid combinations for $V_{\text{DDA_ADC}} = V_{\text{REFH}}$ and V_{DD} , which are not covered by SID201 (Uncalibrated accuracy)

26.6 AC specifications

Unless otherwise noted, the timings are defined with the guidelines mentioned in the [Figure 26-7](#).


Figure 26-7 AC timings specifications

26.7 Digital peripherals

Table 26-9 TCPWM specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID120	f_C	TCPWM operating frequency	–	–	100	MHz	f_C = peripheral clock
SID121	$t_{PWMENEXT}$	Input trigger pulse width for all trigger events	$2 / f_C$	–	–	ns	Trigger Events can be Stop, Start, Reload, Count, Capture, or Kill depending on which mode of operation is selected.
SID122	t_{PWMEXT}	Output trigger pulse widths	$2 / f_C$	–	–	ns	Minimum possible width of Overflow, Underflow, and Counter = Compare (CC) value trigger outputs
SID123	t_{CRES}	Resolution of counter	$1 / f_C$	–	–	ns	Minimum time between successive counts
SID124	t_{PWMRES}	PWM resolution	$1 / f_C$	–	–	ns	Minimum pulse width of PWM output
SID125	t_{QRES}	Quadrature inputs resolution	$2 / f_C$	–	–	ns	Minimum pulse width between Quadrature phase inputs.

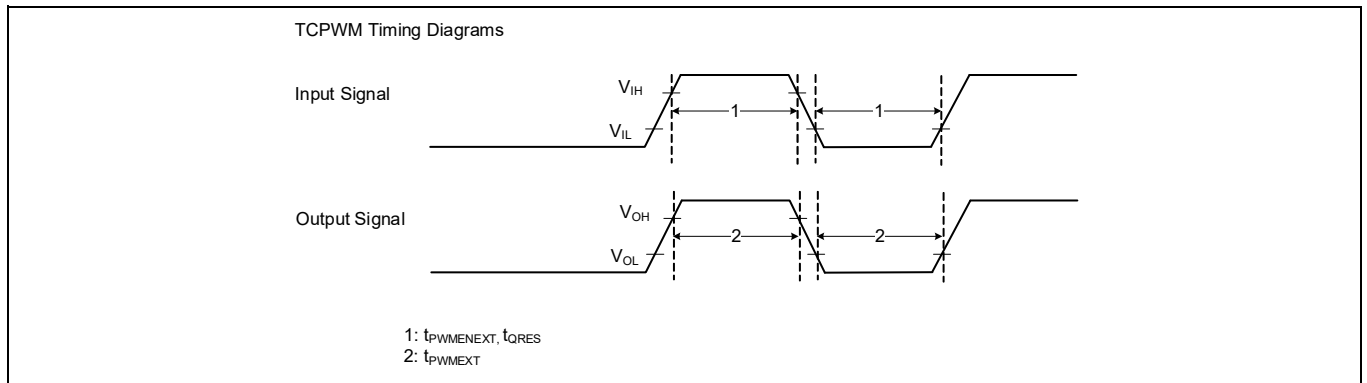

Figure 26-8 TCPWM timing diagrams

Table 26-10 SCB specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID129	f_{SCB}	SCB operating frequency	–	–	100	MHz	
SID129_2	t_{SPI_TRANS}	SCB input transition in SPI mode	–	–	4	ns	
SID129_3	t_{SPI_TRANS}	SCB output transition in SPI mode	–	–	10	ns	Valid for HSIO_STDLN
SID129_4	t_{SPI_TRANS}	SCB output transition in SPI mode	–	–	20	ns	Valid for GPIO_STD, GPIO_ENH, GPIO_SMC

I²C Interface-Standard-mode
Recommended I/O Configuration:

GPIO_STD: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100
GPIO_ENH: CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100, CFG_OUT/SLOW<0:0> = 0b1
GPIO_SMC: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100, CFG_OUT/SLOW<0:0> = 0b0
HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b010, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100, CFG_SLEW_EXT/SLEW<2:0> = 0b000
 (Note: SID138 is not valid for HSIO_STDLN)

SID130	f_{SCL}	SCL clock frequency	–	–	100	kHz	
SID131	$t_{HD;STA}$	Hold time, START condition	4000	–	–	ns	
SID132	t_{LOW}	Low period of SCL	4700	–	–	ns	
SID133	t_{HIGH}	High period of SCL	4000	–	–	ns	
SID134	$t_{SU;STA}$	Setup time for a repeated START	4700	–	–	ns	
SID135	$t_{HD;DAT}$	Data hold time, for receiver	0	–	–	ns	
SID136	$t_{SU;DAT}$	Data setup time	250	–	–	ns	
SID138	t_F	Fall time of SCL and SDA	–	–	300	ns	Input and output Output: Only valid for GPIO_ENH, GPIO_SMC, GPIO_STD
SID139	$t_{SU;STO}$	Setup time for STOP	4000	–	–	ns	
SID140	t_{BUF}	Bus-free time between START and STOP	4700	–	–	ns	
SID141	C_B	Capacitive load for each bus line	–	–	400	pF	
SID142	$t_{VD;DAT}$	Time for data signal from SCL LOW to SDA output	–	–	3450	ns	
SID143	$t_{VD;ACK}$	Data valid acknowledge time	–	–	3450	ns	

I²C Interface-Fast-mode
Recommended I/O Configuration:

GPIO_STD: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100
GPIO_ENH: CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100, CFG_OUT/SLOW<0:0> = 0b1
GPIO_SMC: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100, CFG_OUT/SLOW<0:0> = 0b1
HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b010, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100, CFG_SLEW_EXT/SLEW<2:0> = 0b000
 (Note: SID158 is not valid for GPIO_STD, HSIO_STDLN)

SID150	f_{SCL}	SCL clock frequency	–	–	400 ^[65]	kHz	
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Note

65. In order to drive full bus load at 400 kHz, 6 mA I_{OL} is required at 0.6 V V_{OL} .
 66. In order to drive full bus load at 1 MHz, 20 mA I_{OL} is required at 0.4 V V_{OL} .

Table 26-10 SCB specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID151	$t_{HD;STA}$	Hold time, START condition	600	–	–	ns	
SID152	t_{LOW}	Low period of SCL	1300	–	–	ns	
SID153	t_{HIGH}	High period of SCL	600	–	–	ns	
SID154	$t_{SU;STA}$	Setup time for a repeated START	600	–	–	ns	
SID155	$t_{HD;DAT}$	Data hold time, for receiver	0	–	–	ns	
SID156	$t_{SU;DAT}$	Data setup time	100	–	–	ns	
SID158	t_F	Fall time of SCL and SDA	$20 \times (V_{DDIO_G_PIO}/5.5)$	–	300	ns	Input and output Output: Only valid for GPIO_ENH, GPIO_SMC
SID159	$t_{SU;STO}$	Setup time for STOP	600	–	–	ns	
SID160	t_{BUF}	Bus free time between START and STOP	1300	–	–	ns	
SID161	C_B	Capacitive load for each bus line	–	–	400	pF	
SID162	$t_{VD;DAT}$	Time for data signal from SCL LOW to SDA output	–	–	900	ns	
SID163	$t_{VD;ACK}$	Data valid acknowledge time	–	–	900	ns	
SID164	t_{SP}	Pulse width of spikes that must be suppressed by the input filter	–	–	50	ns	

I²C Interface-Fast-Plus mode
Recommended I/O Configuration:
GPIO_STD: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100

GPIO_ENH: CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100, CFG_OUT/SLOW<0:0> = 0b1

GPIO_SMC: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100, CFG_OUT/SLOW<0:0> = 0b0

HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b010, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG/DRIVE_MODE<2:0> = 0b100, CFG_SLEW_EXT/SLEW<2:0> = 0b000

(Note: SID178 is not valid for GPIO_STD, GPIO_SMC, and HSIO_STDLN)

SID170	f_{SCL}	SCL clock frequency	–	–	1 ^[66]	MHz	
SID171	$t_{HD;STA}$	Hold time, START condition	260	–	–	ns	
SID172	t_{LOW}	Low period of SCL	500	–	–	ns	
SID173	t_{HIGH}	High period of SCL	260	–	–	ns	
SID174	$t_{SU;STA}$	Setup time for a repeated START	260	–	–	ns	
SID175	$t_{HD;DAT}$	Data hold time, for receiver	0	–	–	ns	
SID176	$t_{SU;DAT}$	Data setup time	50	–	–	ns	
SID178	t_F	Fall time of SCL and SDA	$20 \times (V_{DDIO_G_PIO}/5.5)$	–	160	ns	Input and output, 20pF load Output: Only for GPIO_ENH

Note

 65.In order to drive full bus load at 400 kHz, 6 mA I_{OL} is required at 0.6 V V_{OL} .

 66.In order to drive full bus load at 1 MHz, 20 mA I_{OL} is required at 0.4 V V_{OL} .

Table 26-10 SCB specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID179	$t_{SU;STO}$	Setup time for STOP	260	–	–	ns	
SID180	t_{BUF}	Bus free time between START and STOP	500	–	–	ns	
SID181	C_B	Capacitive load for each bus line	–	–	20	pF	
SID182	$t_{VD;DAT}$	Time for data signal from SCL LOW to SDA output	–	–	450	ns	
SID183	$t_{VD;ACK}$	Data valid acknowledge time	–	–	450	ns	
SID184	t_{SP}	Pulse width of spikes that must be suppressed by the input filter	–	–	50	ns	

SPI Interface
Recommended I/O Configuration: (Applicable to all below modes)
HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b010, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG_SLEW_EXT/SLEW<0:0> = 0b0

For SPI speeds ≤ 12.5 MHz
GPIO_STD: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0

GPIO_ENH: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG_OUT/SLOW<0:0> = 0b0

GPIO_SMC: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG_OUT/SLOW<0:0> = 0b0

SPI Interface Master (Full-clock mode: LATE_MISO_SAMPLE = 1, GPIO)

SID190	f_{SPI}	SPI operating frequency	–	–	12.5	MHz	Do not use half-clock mode: LATE_MISO_SAMPLE = 0 SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 12.5 Mbps for instances on GPIO_STD, GPIO_ENH, GPIO_SMC
SID191	t_{DMO}	SPI Master: MOSI valid after SCLK driving edge	–	–	15	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 12.5 Mbps for instances on GPIO_STD, GPIO_ENH, GPIO_SMC
SID192	t_{DSI}	SPI Master: MISO valid before SCLK capturing edge	40	–	–	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 12.5 Mbps for instances on GPIO_STD, GPIO_ENH, GPIO_SMC
SID193	t_{HMO}	SPI Master: Previous MOSI data hold time	0	–	–	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 12.5 Mbps for instances on GPIO_STD, GPIO_ENH, GPIO_SMC
SID194	$t_{W_SCLK_H_L}$	SPI SCLK pulse width HIGH or LOW	$0.4 \times (1/f_{SPI})$	$0.5 \times (1/f_{SPI})$	$0.6 \times (1/f_{SPI})$	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 12.5 Mbps for instances on GPIO_STD, GPIO_ENH, GPIO_SMC
SID195	t_{VSS}	SPI Master: MOSI valid after SSEL falling edge (CPHA=0)	–	–	12	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 12.5 Mbps for instances on GPIO_STD, GPIO_ENH, GPIO_SMC

Note

65. In order to drive full bus load at 400 kHz, 6 mA I_{OL} is required at 0.6 V V_{OL} .

66. In order to drive full bus load at 1 MHz, 20 mA I_{OL} is required at 0.4 V V_{OL} .

Table 26-10 SCB specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID196	t_{DHI}	SPI Master: MISO hold time after SCLK capturing edge	0	–	–	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 12.5 Mbps for instances on GPIO_STD, GPIO_ENH, GPIO_SMC
SID198	t_{EN_SETUP}	SSEL valid, before the first SCK capturing edge	$0.5 \times (1/f_{SPI})$	–	–	ns	Min is half clock period
SID199	t_{EN_SHOLD}	SSEL hold, after the last SCK capturing edge	$0.5 \times (1/f_{SPI})$	–	–	ns	Min is half clock period
SID197	C_{SPIM_MS}	SPI Capacitive Load	–	–	20	pF	

SPI Interface Master (Full-clock mode: LATE_MISO_SAMPLE = 1, HSIO)

SID190A	f_{SPI}	SPI operating frequency	–	–	20	MHz	Do not use half-clock mode: LATE_MISO_SAMPLE = 0 SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 20 Mbps For 20 Mbps, SCB operating frequency (f_{SCB}) must be configured to 80 MHz for instances on HSIO_STDLN
SID191A	t_{DMO}	SPI Master: MOSI valid after SCLK driving edge	–	–	9	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 20 Mbps For 20 Mbps, SCB operating frequency (f_{SCB}) must be configured to 80 MHz for instances on HSIO_STDLN
SID192A	t_{DSI}	SPI Master: MISO valid before SCLK capturing edge	25	–	–	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 20 Mbps For 20 Mbps, SCB operating frequency (f_{SCB}) must be configured to 80 MHz for instances on HSIO_STDLN
SID193A	t_{HMO}	SPI Master: Previous MOSI data hold time	0	–	–	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 20 Mbps For 20 Mbps, SCB operating frequency (f_{SCB}) must be configured to 80 MHz for instances on HSIO_STDLN
SID194A	$t_{W_SCLK_H_L}$	SPI SCLK pulse width HIGH or LOW	$0.4 \times (1/f_{SPI})$	$0.5 \times (1/f_{SPI})$	$0.6 \times (1/f_{SPI})$	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 20 Mbps For 20 Mbps, SCB operating frequency (f_{SCB}) must be configured to 80 MHz for instances on HSIO_STDLN

Note

65. In order to drive full bus load at 400 kHz, 6 mA I_{OL} is required at 0.6 V V_{OL} .

66. In order to drive full bus load at 1 MHz, 20 mA I_{OL} is required at 0.4 V V_{OL} .

Table 26-10 SCB specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID195A	t_{VSS}	SPI Master: MOSI valid after SSEL falling edge (CPHA=0)	–	–	12	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 20 Mbps For 20 Mbps, SCB operating frequency (f_{SCB}) must be configured to 80 MHz for instances on HSIO_STDLN
SID196A	t_{DHI}	SPI Master: MISO hold time after SCLK capturing edge	0	–	–	ns	SPI Master (Full-clock mode: LATE_MISO_SAMPLE = 1) – 20 Mbps For 20 Mbps, SCB operating frequency (f_{SCB}) must be configured to 80 MHz for instances on HSIO_STDLN
SID197A	C_{SPIM_MS}	SPI Capacitive Load	–	–	20	pF	
SID198A	t_{EN_SETUP}	SSEL valid, before the first SCK capturing edge	$0.5 \times (1/f_{SPI})$	–	–	ns	Min is half clock period
SID199A	t_{EN_SHOLD}	SSEL hold, after the last SCK capturing edge	$0.5 \times (1/f_{SPI})$	–	–	ns	Min is half clock period

SPI Interface Slave (internally clocked, GPIO and HSIO)

SID205	f_{SPI_INT}	SPI operating frequency	–	–	12.5	MHz	SPI Slave, internally clocked
SID206	t_{DMI_INT}	SPI Slave: MOSI Valid before Scklock capturing edge	5	–	–	ns	SPI Slave, internally clocked
SID207	t_{DSO_INT}	SPI Slave: MISO Valid after Scklock driving edge, in the internal-clocked mode	–	–	60	ns	SPI Slave, internally clocked
SID208	t_{HSO_INT}	SPI Slave: Previous MISO data hold time	3	–	–	ns	SPI Slave, internally clocked
SID209	$t_{EN_SETUP_INT}$	SPI Slave: SSEL valid to first SCK valid edge	33	–	–	ns	SPI Slave, internally clocked
SID210	$t_{EN_HOLD_INT}$	SPI Slave Select active (LOW) from last SCLK hold	33	–	–	ns	SPI Slave, internally clocked
SID211	$t_{EN_SETUP_PRE}$	SPI Slave: from SSEL valid, to SCK falling edge before the first data bit	20	–	–	ns	SPI Slave, internally clocked
SID212	$t_{EN_HOLD_PRE}$	SPI Slave: from SCK falling edge before the first data bit, to SSEL invalid	20	–	–	ns	SPI Slave, internally clocked
SID213	$t_{EN_SETUP_CO}$	SPI Slave: from SSEL valid, to SCK falling edge in the first data bit	20	–	–	ns	SPI Slave, internally clocked
SID214	$t_{EN_HOLD_CO}$	SPI Slave: from SCK falling edge in the first data bit, to SSEL invalid	20	–	–	ns	SPI Slave, internally clocked

Note

65. In order to drive full bus load at 400 kHz, 6 mA I_{OL} is required at 0.6 V V_{OL} .
66. In order to drive full bus load at 1 MHz, 20 mA I_{OL} is required at 0.4 V V_{OL} .

Table 26-10 SCB specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID215	$t_{W_DIS_INT}$	SPI Slave Select inactive time	40	–	–	ns	SPI Slave, internally clocked
SID216	$t_{W_SCLKH_INT}$	SPI SCLK pulse width HIGH	32	–	–	ns	SPI Slave, internally clocked
SID217	$t_{W_SCLKL_INT}$	SPI SCLK pulse width LOW	32	–	–	ns	SPI Slave, internally clocked
SID218	t_{SIH_INT}	SPI MOSI hold from SCLK	20	–	–	ns	SPI Slave, internally clocked
SID219	C_{SPIS_INT}	SPI Capacitive Load	–	–	20	pF	SPI Slave, internally clocked

SPI Interface Slave (externally clocked, GPIO and HSIO)

SID220	f_{SPI_EXT}	SPI operating frequency	–	–	12.5	MHz	SPI Slave, externally clocked: 12.5 Mbps
SID221	t_{DMI_EXT}	SPI Slave: MOSI Valid before Scklock capturing edge	8	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID222	t_{DSO_EXT}	SPI Slave: MISO Valid after Scklock driving edge, in the external-clocked mode	–	–	30	ns	SPI Slave, externally clocked: 12.5 Mbps
SID223	t_{HSO_EXT}	SPI Slave: Previous MISO data hold time	5	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID224	$t_{EN_SETUP_EXT}$	SPI Slave: SSEL valid to first SCK valid edge	20	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID225	$t_{EN_HOLD_EXT}$	SPI Slave Select active (LOW) from last SCLK hold	20	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID226	$t_{W_DIS_EXT}$	SPI Slave Select inactive time	20	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID227	$t_{W_SCLKH_EXT}$	SPI SCLK pulse width HIGH	32	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID228	$t_{W_SCLKL_EXT}$	SPI SCLK pulse width LOW	32	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID229	t_{SIH_EXT}	SPI MOSI hold from SCLK	5	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID230	C_{SPIS_EXT}	SPI Capacitive Load	–	–	20	pF	SPI Slave, externally clocked: 12.5 Mbps
SID231	t_{VSS_EXT}	SPI Slave: MISO valid after SSEL falling edge (CPHA = 0)	–	–	33	ns	SPI Slave, externally clocked: 12.5 Mbps

SPI Interface Slave (internally clocked, SMC I/O)

SID205_2	f_{SPI_INT}	SPI operating frequency	–	–	12.5	MHz	SPI Slave, internally clocked
SID206_2	t_{DMI_INT}	SPI Slave: MOSI Valid before Scklock capturing edge	5	–	–	ns	SPI Slave, internally clocked

Note

65. In order to drive full bus load at 400 kHz, 6 mA I_{OL} is required at 0.6 V V_{OL} .
66. In order to drive full bus load at 1 MHz, 20 mA I_{OL} is required at 0.4 V V_{OL} .

Table 26-10 SCB specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID207_2	t_{DSO_INT}	SPI Slave: MISO Valid after Sclock driving edge, in the internal-clocked mode	–	–	64	ns	SPI Slave, internally clocked
SID208_2	t_{HSO_INT}	SPI Slave: Previous MISO data hold time	3	–	–	ns	SPI Slave, internally clocked
SID209_2	$t_{EN_SETUP_INT}$	SPI Slave: SSEL valid to first SCK valid edge	33	–	–	ns	SPI Slave, internally clocked
SID210_2	$t_{EN_HOLD_INT}$	SPI Slave Select active (LOW) from last SCLK hold	33	–	–	ns	SPI Slave, internally clocked
SID211_2	$t_{EN_SETUP_PRE}$	SPI Slave: from SSEL valid, to SCK falling edge before the first data bit	20	–	–	ns	SPI Slave, internally clocked
SID212_2	$t_{EN_HOLD_PRE}$	SPI Slave: from SCK falling edge before the first data bit, to SSEL invalid	20	–	–	ns	SPI Slave, internally clocked
SID213_2	$t_{EN_SETUP_CO}$	SPI Slave: from SSEL valid, to SCK falling edge in the first data bit	20	–	–	ns	SPI Slave, internally clocked
SID214_2	$t_{EN_HOLD_CO}$	SPI Slave: from SCK falling edge in the first data bit, to SSEL invalid	20	–	–	ns	SPI Slave, internally clocked
SID215_2	$t_{W_DIS_INT}$	SPI Slave Select inactive time	40	–	–	ns	SPI Slave, internally clocked
SID216_2	$t_{W_SCLKH_INT}$	SPI SCLK pulse width HIGH	36	–	–	ns	SPI Slave, internally clocked
SID217_2	$t_{W_SCLKL_INT}$	SPI SCLK pulse width LOW	36	–	–	ns	SPI Slave, internally clocked
SID218_2	t_{SIH_INT}	SPI MOSI hold from SCLK	20	–	–	ns	SPI Slave, internally clocked
SID219_2	C_{SPIS_INT}	SPI Capacitive Load	–	–	20	pF	SPI Slave, internally clocked

SPI Interface Slave (externally clocked, SMC I/O)

SID220_2	f_{SPI_EXT}	SPI operating frequency	–	–	12.5	MHz	SPI Slave, externally clocked: 12.5 Mbps
SID221_2	t_{DMI_EXT}	SPI Slave: MOSI Valid before Sclock capturing edge	8	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID222_2	t_{DSO_EXT}	SPI Slave: MISO Valid after Sclock driving edge, in the external-clocked mode	–	–	34	ns	SPI Slave, externally clocked: 12.5 Mbps
SID223_2	t_{HSO_EXT}	SPI Slave: Previous MISO data hold time	5	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID224_2	$t_{EN_SETUP_EXT}$	SPI Slave: SSEL valid to first SCK valid edge	20	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps

Note

65. In order to drive full bus load at 400 kHz, 6 mA I_{OL} is required at 0.6 V V_{OL} .
 66. In order to drive full bus load at 1 MHz, 20 mA I_{OL} is required at 0.4 V V_{OL} .

Table 26-10 SCB specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID225_2	t _{EN_HOLD_EXT}	SPI Slave Select active (LOW) from last SCLK hold	20	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID226_2	t _{W_DIS_EXT}	SPI Slave Select inactive time	20	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID227_2	t _{W_SCLKH_EXT}	SPI SCLK pulse width HIGH	36	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID228_2	t _{W_SCLKL_EXT}	SPI SCLK pulse width LOW	36	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID229_2	t _{SIH_EXT}	SPI MOSI hold from SCLK	5	–	–	ns	SPI Slave, externally clocked: 12.5 Mbps
SID230_2	C _{SPIS_EXT}	SPI Capacitive Load	–	–	20	pF	SPI Slave, externally clocked: 12.5 Mbps
SID231_2	t _{VSS_EXT}	SPI Slave: MISO valid after SSEL falling edge (CPHA = 0)	–	–	37	ns	SPI Slave, externally clocked: 12.5 Mbps

SPI Interface Slave (externally clocked, 20 MHz)

SID220A	f _{SPI_EXT}	SPI operating frequency	–	–	20	MHz	SPI Slave, externally clocked: 20 Mbps
SID221A	t _{DMI_EXT}	SPI Slave: MOSI Valid before Scklock capturing edge	5	–	–	ns	SPI Slave, externally clocked: 20 Mbps
SID222A	t _{DSO_EXT}	SPI Slave: MISO Valid after Scklock driving edge, in the external-clocked mode	–	–	18	ns	SPI Slave, externally clocked: 20 Mbps
SID223A	t _{HSO_EXT}	SPI Slave: Previous MISO data hold time	5	–	–	ns	SPI Slave, externally clocked: 20 Mbps
SID224A	t _{EN_SETUP_EXT}	SPI Slave: SSEL valid to first SCK valid edge	20	–	–	ns	SPI Slave, externally clocked: 20 Mbps
SID225A	t _{EN_HOLD_EXT}	SPI Slave Select active (LOW) from last SCLK hold	20	–	–	ns	SPI Slave, externally clocked: 20 Mbps
SID226A	t _{W_DIS_EXT}	SPI Slave Select inactive time	20	–	–	ns	SPI Slave, externally clocked: 20 Mbps
SID227A	t _{W_SCLKH_EXT}	SPI SCLK pulse width HIGH	20	–	–	ns	SPI Slave, externally clocked: 20 Mbps
SID228A	t _{W_SCLKL_EXT}	SPI SCLK pulse width LOW	20	–	–	ns	SPI Slave, externally clocked: 20 Mbps
SID229A	t _{SIH_EXT}	SPI MOSI hold from SCLK	5	–	–	ns	SPI Slave, externally clocked: 20 Mbps
SID230A	C _{SPIS_EXT}	SPI Capacitive Load	–	–	20	pF	SPI Slave, externally clocked: 20 Mbps
SID231A	t _{VSS_EXT}	SPI Slave: MISO valid after SSEL falling edge (CPHA = 0)	–	–	23	ns	SPI Slave, externally clocked: 20 Mbps

UART Interface
Note

65. In order to drive full bus load at 400 kHz, 6 mA I_{OL} is required at 0.6 V V_{OL}.

66. In order to drive full bus load at 1 MHz, 20 mA I_{OL} is required at 0.4 V V_{OL}.

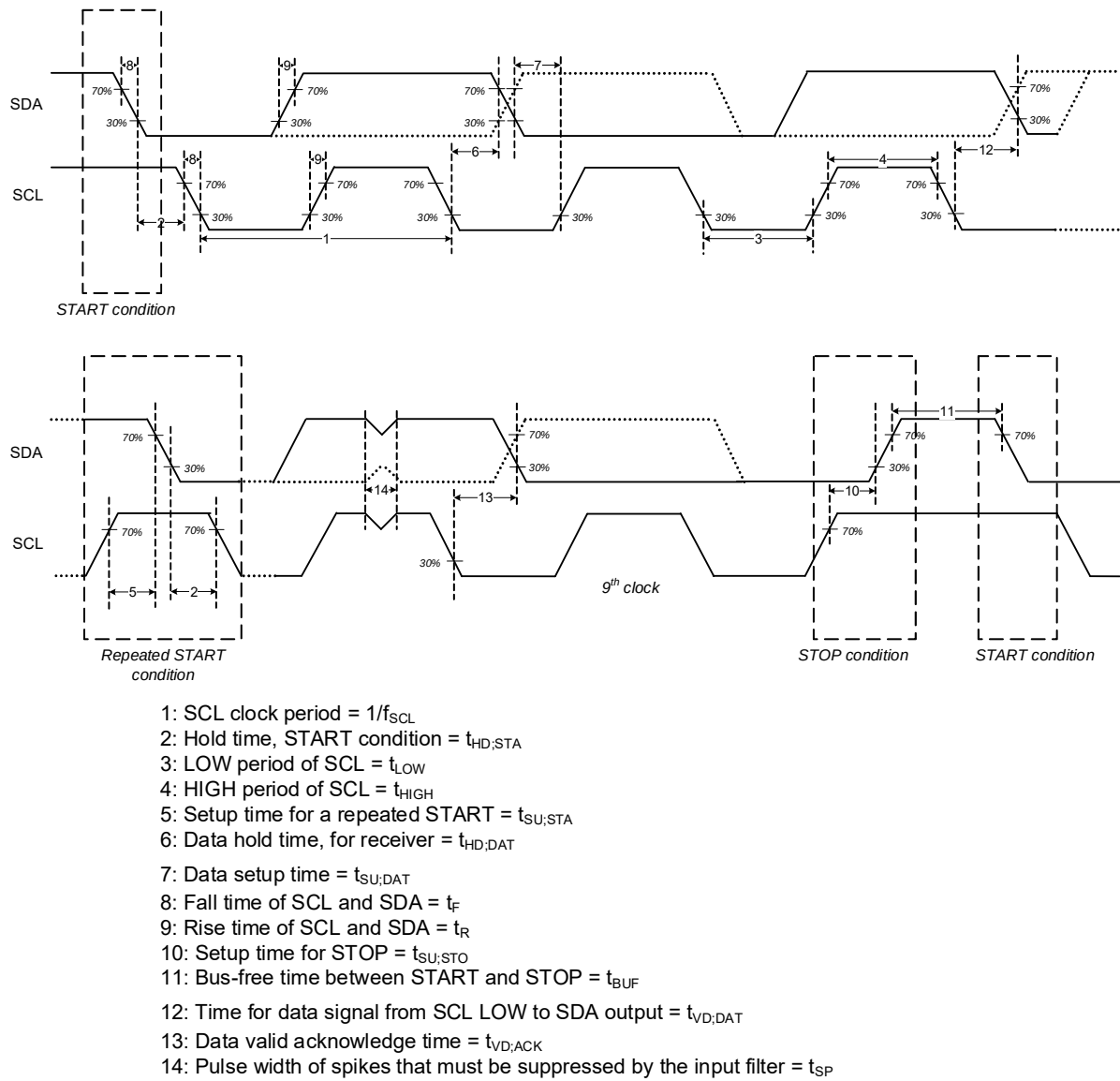
Table 26-10 SCB specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
Recommended I/O Configuration: GPIO_STD: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0>= 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0 GPIO_ENH: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0>= 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG_OUT/SLOW<0:0> = 0b0 GPIO_SMC: CFG_OUT/DRIVE_SEL<1:0> = 0b01, CFG_IN_AUTOLVL/VTRIP_SEL<0:0>= 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG_OUT/SLOW<0:0> = 0b0 HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b010, CFG_IN_AUTOLVL/VTRIP_SEL<0:0>= 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG_SLEW_EXT/SLEW<0:0> = 0b0							
SID240	f _{BPS}	Signaling rate	–	–	10	Mbps	
SID240A	f _{BPS_TX}	Signaling rate for TX on P16_0 for SCB#4 and P15_3 for SCB#3	–	–	25	Mbps	Valid only for TX at 20 pF load
SID241	f _{ACC}	Frequency accuracy of TX bit time on P16_0 for SCB#4 and P15_3 for SCB#3	–0.5	–	0.5	ns	With PLL 200 MHz ≤ f _{VCO} ≤ 400 MHz at 20 pF load
SID242	f _{JIT}	Jitter of TX on P16.0 for SCB#4 and P15.3 for SCB#3	–4.5	–	4.5	ns	at 20 pF load

Note

65. In order to drive full bus load at 400 kHz, 6 mA I_{OL} is required at 0.6 V V_{OL}.

66. In order to drive full bus load at 1 MHz, 20 mA I_{OL} is required at 0.4 V V_{OL}.


Figure 26-9 I²C timing diagrams

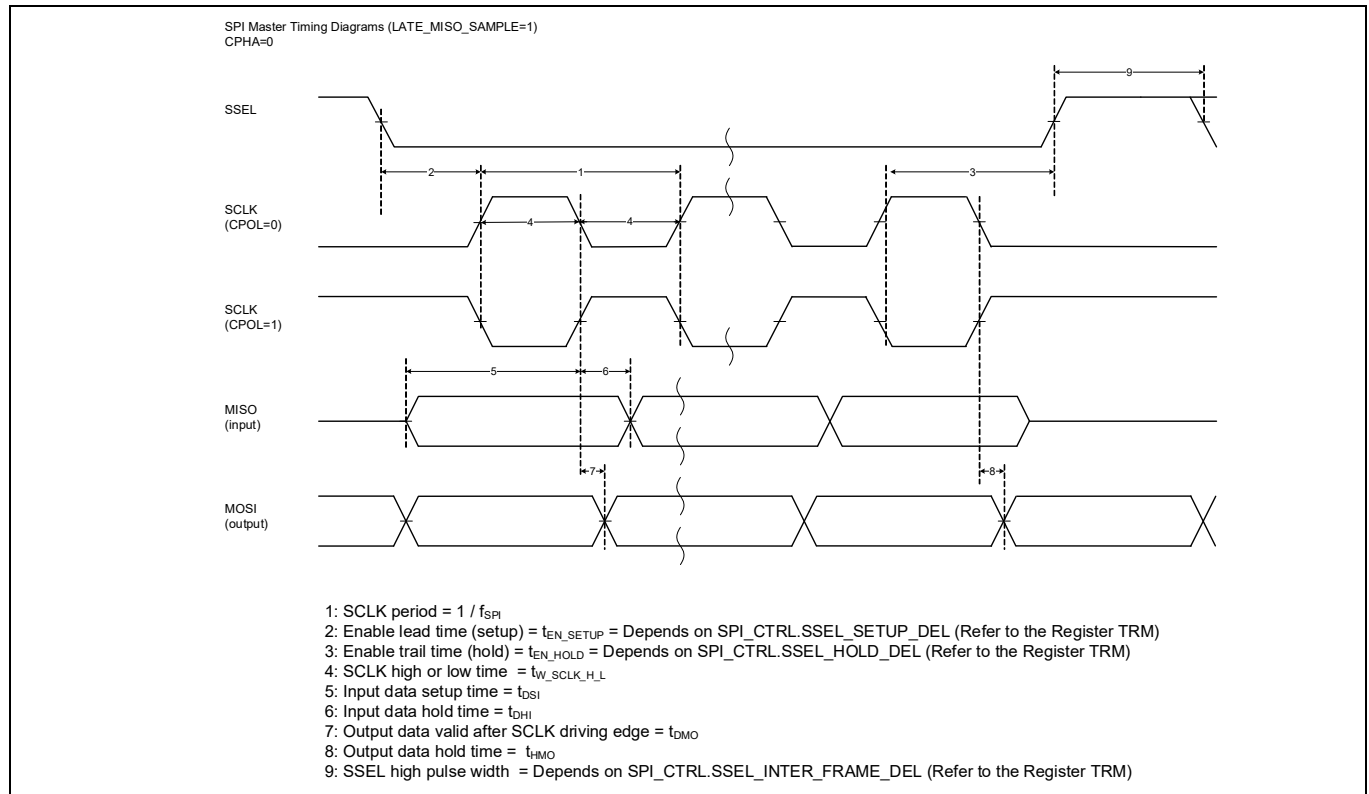


Figure 26-10 SPI master timing diagrams with LOW clock phase

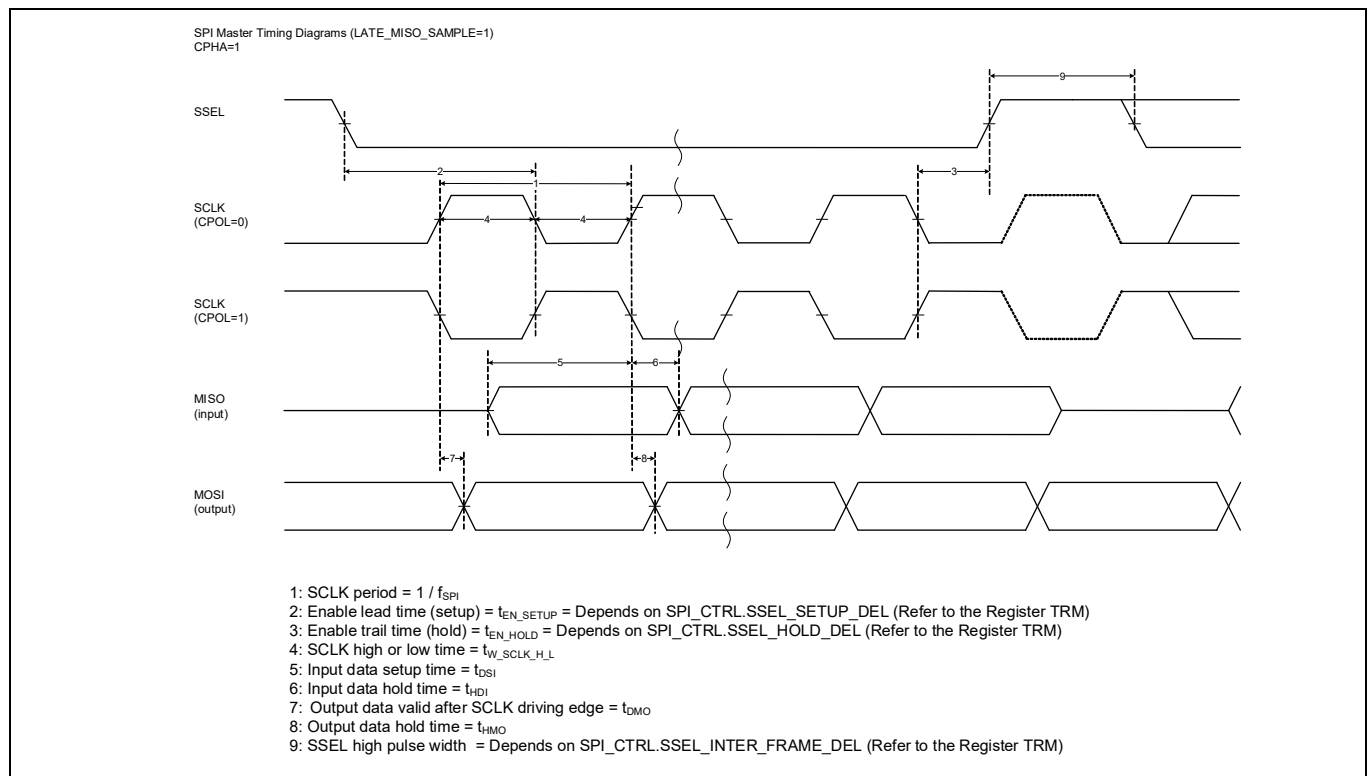


Figure 26-11 SPI master timing diagrams with HIGH clock phase

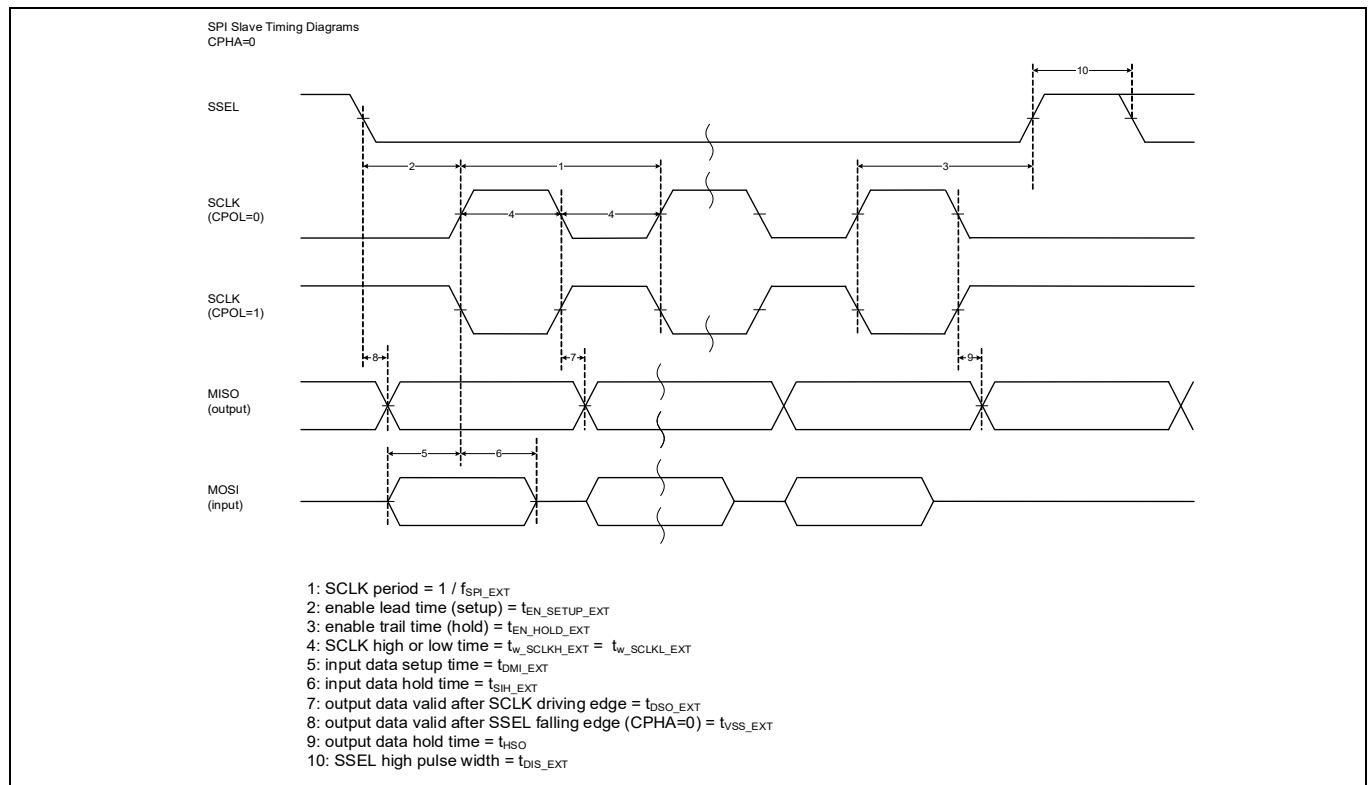


Figure 26-12 SPI slave timing diagrams with LOW clock phase

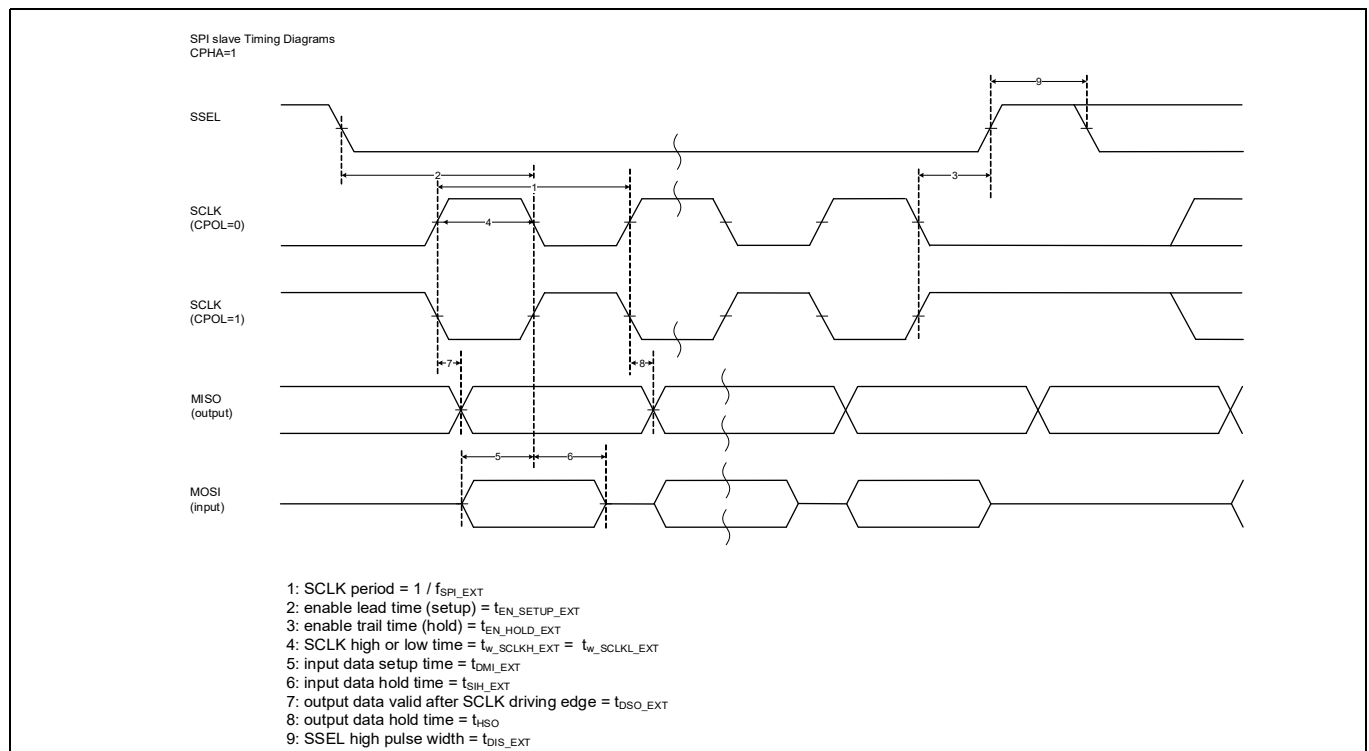


Figure 26-13 SPI slave timing diagrams with HIGH clock phase

Table 26-11 CAN FD specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID630	f_{HCLK}	System clock (HCLK) frequency	–	–	100	MHz	$f_{CCLK} \leq f_{HCLK}$, guaranteed by design
SID631	f_{CCLK}	CAN clock (CCLK) frequency	–	–	100	MHz	$f_{CCLK} \leq f_{HCLK}$, guaranteed by design

Table 26-12 LIN specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID249	f_{LIN}	Internal clock frequency to the LIN block	–	–	100	MHz	
SID250	BR_NOM	Bit rate on the LIN bus	1	–	20	kbps	Guaranteed by design
SID250A	BR_REF	Bit rate on the LIN bus (not in standard LIN specification) for re-flashing in LIN slave mode	1	–	115.2	kbps	Guaranteed by design

26.8 Memory

Table 26-13 Flash DC specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID257A	V_{PE}	Erase and program voltage	2.7	–	5.5	V	

Table 26-14 Flash AC specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID257	f_{FO}	Maximum operation frequency	–	–	100	MHz	Zero wait access to code-flash memory up to 100 MHz Zero wait access with cache hit up to 320 MHz
SID254	t_{ERS_SUS}	Maximum time from erase suspend command till erase is indeed suspend	–	–	37.5	μs	
SID255	$t_{ERS_RES_SUS}$	Minimum time allowed from erase resume to erase suspend	250	–	–	μs	Guaranteed by design
SID258	t_{BC_WF}	Blank Check time for Work Flash N-byte	–	–	$10 + 0.3 \times N$	μs	At 100 MHz, $N \geq 4$ and multiple of 4, excludes system overhead time
SID258A	$t_{AA_BC_ENTRY}$	Time to enter Blank Check mode	–	5	–	μs	
SID258B	$t_{AA_BC_EXIT}$	Time to exit Blank Check mode	–	5	–	μs	
SID259	$t_{SECTORERASE1}$	Sector erase time (code-flash: 32 KB)	–	45	90	ms	Includes internal preprogramming time
SID260	$t_{SECTORERASE2}$	Sector erase time (code-flash: 8 KB)	–	15	30	ms	Includes internal preprogramming time
SID261	$t_{SECTORERASE3}$	Sector erase time (work-flash, 2 KB)	–	80	160	ms	Includes internal preprogramming time
SID262	$t_{SECTORERASE4}$	Sector erase time (work-flash, 128 B)	–	5	15	ms	Includes internal preprogramming time

Table 26-14 Flash AC specifications *(continued)*

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID263	t _{WRITE1}	64-bit write time (code-flash)	–	30	60	μs	Excludes system overhead time
SID264	t _{WRITE2}	256-bit write time (code-flash)	–	40	70	μs	Excludes system overhead time
SID265	t _{WRITE3}	4096-bit write time (code-flash)	–	320	1200	μs	Excludes system overhead time
SID266	t _{WRITE4}	32-bit write time (work-flash)	–	30	60	μs	Excludes system overhead time
SID267	t _{FRET1}	Code-flash retention. 1000 program/erase cycles	20	–	–	years	Temperature at write/erase time. T _A ≤ +85°C average
SID182T1	t _{FRET2}	Code-flash retention. 100 program/erase cycles	50	–	–	years	Temperature at write/erase time. T _A ≤ +30°C average
SID268	t _{FRET3}	Work-flash retention. 125,000 program/erase cycles	20	–	–	years	Temperature at write/erase time. T _A ≤ +85°C average
SID269	t _{FRET4}	Work-flash retention. 250,000 program/erase cycles	10	–	–	years	Temperature at write/erase time. T _A ≤ +85°C average
SID182T2	t _{FRET5}	Work-flash retention. 1000 program/erase cycles	50	–	–	years	Temperature at write/erase time. T _A ≤ +30°C average
SID612	I _{CC_ACT2}	Program operating current (code or work-flash)	–	15	62	mA	V _{DDD} = 5 V, V _{CDD} = 1.1 V guaranteed by design
SID613	I _{CC_ACT3}	Erase operating current (code- or work-flash)	–	15	62	mA	V _{DDD} = 5 V, V _{CDD} = 1.1 V guaranteed by design

26.9 System resources

Table 26-15 System resources

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/ conditions
Power-on Reset Specifications							
SID270	V _{POR_R}	POR rising trip voltage	1.5	–	2.35	V	Guaranteed by design
SID276	V _{POR_F}	POR falling trip voltage	1.45	–	2.1	V	
SID271	V _{POR_H}	Level detection hysteresis	20	–	300	mV	
SID272	t _{DLY_POR}	Delay between V _{DDD} rising through 2.3 V and POR reset output rising through V _{DDD} / 2	–	–	3	μs	Guaranteed by design
SID273	t _{POFF}	Power off time	350	–	–	μs	V _{DDD} < 1.45 V Does not apply to SID274A and SID274B
SID274A	POR_RR1	V _{DDD} power ramp rate with robust BOD - XRES_L asserted (BOD operation is guaranteed)	–	–	100	mV/μs	Applies to ramp up and ramp down
SID274B	POR_RR1	V _{DDD} power ramp rate with robust BOD - XRES_L de-asserted (BOD operation is guaranteed)	1	–	100	mV/μs	Applies to ramp up and ramp down
SID275	POR_RR2	V _{DDD} power ramp rate without robust BOD	100	–	1000	mV/μs	This ramp does not support robust BOD t _{POFF} must be satisfied. Applies to ramp up and ramp down
High-voltage BOD (HV BOD) Specifications							
SID500	V _{TR_2P7_R}	HV BOD 2.7 V trimmed rising trip point for V _{DDD} and V _{DDA_ADC} (default)	2.474	2.55	2.627	V	
SID501	V _{TR_2P7_F}	HV BOD 2.7 V trimmed falling trip point for V _{DDD} and V _{DDA_ADC} (default)	2.449	2.525	2.601	V	
SID502	V _{TR_3P0_R}	HV BOD 3.0 V trimmed rising trip point for V _{DDD} and V _{DDA_ADC}	2.765	2.85	2.936	V	
SID503	V _{TR_3P0_F}	HV BOD 3.0 V trimmed falling trip point for V _{DDD} and V _{DDA_ADC}	2.74	2.825	2.91	V	
SID505	HVBOD_RR_A	Power ramp rate: V _{DDD} and V _{DDA_ADC} (Active)	–	–	100	mV/μs	
SID506	HVBOD_RR_DS	Power ramp rate: V _{DDD} and V _{DDA_ADC} (DeepSleep)	–	–	10	mV/μs	
SID507	t _{DLY_ACT_HVBOD}	Active mode delay between V _{DDD} falling/rising through V _{TR_2P7_F/R} or V _{TR_3P0_F/R} and an internal HV BOD output transitioning through V _{DDD} / 2	–	–	0.5	μs	Guaranteed by design
SID507A	t _{DLY_ACT_HVBOD_A}	Active mode delay between V _{DDA_ADC} falling/rising through V _{TR_2P7_F/R} or V _{TR_3P0_F/R} and internal HV BOD output transitioning through V _{DDD} / 2	–	–	1	μs	Guaranteed by design
SID507B	t _{DLY_DS_HVBOD}	DeepSleep mode delay between V _{DDD} /V _{DDA_ADC} falling/rising through V _{TR_2P7_F/R} or V _{TR_3P0_F/R} and an internal HV BOD output transitioning through V _{DDD} / 2	–	–	4	μs	Guaranteed by design

Table 26-15 System resources (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID508	t_{RES_HVBOD}	Response time of HV BOD, V_{DDD}/V_{DDA_ADC} supply. HV BOD guaranteed to generate pulse for V_{DDD}/V_{DDA_ADC} pulse width greater than this. (For falling-then-rising supply at max ramp rate; pulse width is time below $V_{TR_2P7_F}$ or $V_{TR_3P0_F}$)	100	–	–	ns	Guaranteed by design
Low-voltage BOD (LV BOD) Specifications							
SID510	$V_{TR_R_LVBOD}$	LV BOD trimmed rising trip point for V_{CCD}	0.917	0.945	0.973	V	
SID511	$V_{TR_F_LVBOD}$	LV BOD trimmed falling trip point for V_{CCD}	0.892	0.92	0.948	V	
SID515	$t_{DLY_ACT_LVBOD}$	Active delay between V_{CCD} falling/rising through V_{TR_R/F_LVBOD} and an internal LV BOD output transitioning through $V_{DDD} / 2$	–	–	1	μs	Guaranteed by design
SID515A	$t_{DLY_DS_LVBOD}$	DeepSleep mode delay between V_{CCD} falling/rising through V_{TR_R/F_LVBOD} and an internal LV BOD output transitioning through $V_{DDD} / 2$	–	–	12	μs	Guaranteed by design
SID516	t_{RES_LVBOD}	Response time of LV BOD. LV BOD guaranteed to generate pulse for V_{CCD} pulse width greater than this. (For falling-then-rising supply at max ramp rate; pulse width is time below $V_{TR_F_LVBOD}$)	100	–	–	ns	Guaranteed by design
Low-voltage Detector (LVD) DC Specifications							
SID520	$V_{TR_2P8_F}$	LVD 2.8 V trimmed falling trip point for V_{DDD}	Typ – 4%	2800	Typ + 4%	mV	
SID521	$V_{TR_2P9_F}$	LVD 2.9 V trimmed falling trip point for V_{DDD}	Typ – 4%	2900	Typ + 4%	mV	
SID522	$V_{TR_3P0_F}$	LVD 3.0 V trimmed falling trip point for V_{DDD}	Typ – 4%	3000	Typ + 4%	mV	
SID523	$V_{TR_3P1_F}$	LVD 3.1 V trimmed falling trip point for V_{DDD}	Typ – 4%	3100	Typ + 4%	mV	
SID524	$V_{TR_3P2_F}$	LVD 3.2 V trimmed falling trip point for V_{DDD}	Typ – 4%	3200	Typ + 4%	mV	
SID525	$V_{TR_3P3_F}$	LVD 3.3 V trimmed falling trip point for V_{DDD}	Typ – 4%	3300	Typ + 4%	mV	
SID526	$V_{TR_3P4_F}$	LVD 3.4 V trimmed falling trip point for V_{DDD}	Typ – 4%	3400	Typ + 4%	mV	
SID527	$V_{TR_3P5_F}$	LVD 3.5 V trimmed falling trip point for V_{DDD}	Typ – 4%	3500	Typ + 4%	mV	
SID528	$V_{TR_3P6_F}$	LVD 3.6 V trimmed falling trip point for V_{DDD}	Typ – 4%	3600	Typ + 4%	mV	
SID529	$V_{TR_3P7_F}$	LVD 3.7 V trimmed falling trip point for V_{DDD}	Typ – 4%	3700	Typ + 4%	mV	
SID530	$V_{TR_3P8_F}$	LVD 3.8 V trimmed falling trip point for V_{DDD}	Typ – 4%	3800	Typ + 4%	mV	
SID531	$V_{TR_3P9_F}$	LVD 3.9 V trimmed falling trip point for V_{DDD}	Typ – 4%	3900	Typ + 4%	mV	
SID532	$V_{TR_4P0_F}$	LVD 4.0 V trimmed falling trip point for V_{DDD}	Typ – 4%	4000	Typ + 4%	mV	

Electrical specifications

Table 26-15 System resources (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/ conditions
SID533	V _{TR_4P1_F}	LVD 4.1 V trimmed falling trip point for V _{DDD}	Typ – 4%	4100	Typ + 4%	mV	
SID534	V _{TR_4P2_F}	LVD 4.2 V trimmed falling trip point for V _{DDD}	Typ – 4%	4200	Typ + 4%	mV	
SID535	V _{TR_4P3_F}	LVD 4.3 V trimmed falling trip point for V _{DDD}	Typ – 4%	4300	Typ + 4%	mV	
SID536	V _{TR_4P4_F}	LVD 4.4 V trimmed falling trip point for V _{DDD}	Typ – 4%	4400	Typ + 4%	mV	
SID537	V _{TR_4P5_F}	LVD 4.5 V trimmed falling trip point for V _{DDD}	Typ – 4%	4500	Typ + 4%	mV	
SID538	V _{TR_4P6_F}	LVD 4.6 V trimmed falling trip point for V _{DDD}	Typ – 4%	4600	Typ + 4%	mV	
SID539	V _{TR_4P7_F}	LVD 4.7 V trimmed falling trip point for V _{DDD}	Typ – 4%	4700	Typ + 4%	mV	
SID540	V _{TR_4P8_F}	LVD 4.8 V trimmed falling trip point for V _{DDD}	Typ – 4%	4800	Typ + 4%	mV	
SID541	V _{TR_4P9_F}	LVD 4.9 V trimmed falling trip point for V _{DDD}	Typ – 4%	4900	Typ + 4%	mV	
SID542	V _{TR_5P0_F}	LVD 5.0 V trimmed falling trip point for V _{DDD}	Typ – 4%	5000	Typ + 4%	mV	
SID543	V _{TR_5P1_F}	LVD 5.1 V trimmed falling trip point for V _{DDD}	Typ – 4%	5100	Typ + 4%	mV	
SID544	V _{TR_5P2_F}	LVD 5.2 V trimmed falling trip point for V _{DDD}	Typ – 4%	5200	Typ + 4%	mV	
SID545	V _{TR_5P3_F}	LVD 5.3 V trimmed falling trip point for V _{DDD}	Typ – 4%	5300	Typ + 4%	mV	
SID546	V _{TR_2P8_R}	LVD 2.8 V trimmed rising trip point for V _{DDD}	Typ – 4%	2825	Typ + 4%	mV	Same as V _{TR_2P8_F} + 25 mV
SID547	V _{TR_2P9_R}	LVD 2.9 V trimmed rising trip point for V _{DDD}	Typ – 4%	2925	Typ + 4%	mV	Same as V _{TR_2P9_F} + 25 mV
SID548	V _{TR_3P0_R}	LVD 3.0 V trimmed rising trip point for V _{DDD}	Typ – 4%	3025	Typ + 4%	mV	Same as V _{TR_3P0_F} + 25 mV
SID549	V _{TR_3P1_R}	LVD 3.1 V trimmed rising trip point for V _{DDD}	Typ – 4%	3125	Typ + 4%	mV	Same as V _{TR_3P1_F} + 25 mV
SID550	V _{TR_3P2_R}	LVD 3.2 V trimmed rising trip point for V _{DDD}	Typ – 4%	3225	Typ + 4%	mV	Same as V _{TR_3P2_F} + 25 mV
SID551	V _{TR_3P3_R}	LVD 3.3 V trimmed rising trip point for V _{DDD}	Typ – 4%	3325	Typ + 4%	mV	Same as V _{TR_3P3_F} + 25 mV
SID552	V _{TR_3P4_R}	LVD 3.4 V trimmed rising trip point for V _{DDD}	Typ – 4%	3425	Typ + 4%	mV	Same as V _{TR_3P4_F} + 25 mV
SID553	V _{TR_3P5_R}	LVD 3.5 V trimmed rising trip point for V _{DDD}	Typ – 4%	3525	Typ + 4%	mV	Same as V _{TR_3P5_F} + 25 mV
SID554	V _{TR_3P6_R}	LVD 3.6 V trimmed rising trip point for V _{DDD}	Typ – 4%	3625	Typ + 4%	mV	Same as V _{TR_3P6_F} + 25 mV
SID555	V _{TR_3P7_R}	LVD 3.7 V trimmed rising trip point for V _{DDD}	Typ – 4%	3725	Typ + 4%	mV	Same as V _{TR_3P7_F} + 25 mV
SID556	V _{TR_3P8_R}	LVD 3.8 V trimmed rising trip point for V _{DDD}	Typ – 4%	3825	Typ + 4%	mV	Same as V _{TR_3P8_F} + 25 mV
SID557	V _{TR_3P9_R}	LVD 3.9 V trimmed rising trip point for V _{DDD}	Typ – 4%	3925	Typ + 4%	mV	Same as V _{TR_3P9_F} + 25 mV
SID558	V _{TR_4P0_R}	LVD 4.0 V trimmed rising trip point for V _{DDD}	Typ – 4%	4025	Typ + 4%	mV	Same as V _{TR_4P0_F} + 25 mV

Table 26-15 System resources (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/ conditions
SID559	V _{TR_4P1_R}	LVD 4.1 V trimmed rising trip point for V _{DDD}	Typ – 4%	4125	Typ + 4%	mV	Same as V _{TR_4P1_F} + 25 mV
SID560	V _{TR_4P2_R}	LVD 4.2 V trimmed rising trip point for V _{DDD}	Typ – 4%	4225	Typ + 4%	mV	Same as V _{TR_4P2_F} + 25 mV
SID561	V _{TR_4P3_R}	LVD 4.3 V trimmed rising trip point for V _{DDD}	Typ – 4%	4325	Typ + 4%	mV	Same as V _{TR_4P3_F} + 25 mV
SID562	V _{TR_4P4_R}	LVD 4.4 V trimmed rising trip point for V _{DDD}	Typ – 4%	4425	Typ + 4%	mV	Same as V _{TR_4P4_F} + 25 mV
SID563	V _{TR_4P5_R}	LVD 4.5 V trimmed rising trip point for V _{DDD}	Typ – 4%	4525	Typ + 4%	mV	Same as V _{TR_4P5_F} + 25 mV
SID564	V _{TR_4P6_R}	LVD 4.6 V trimmed rising trip point for V _{DDD}	Typ – 4%	4625	Typ + 4%	mV	Same as V _{TR_4P6_F} + 25 mV
SID565	V _{TR_4P7_R}	LVD 4.7 V trimmed rising trip point for V _{DDD}	Typ – 4%	4725	Typ + 4%	mV	Same as V _{TR_4P7_F} + 25 mV
SID566	V _{TR_4P8_R}	LVD 4.8 V trimmed rising trip point for V _{DDD}	Typ – 4%	4825	Typ + 4%	mV	Same as V _{TR_4P8_F} + 25 mV
SID567	V _{TR_4P9_R}	LVD 4.9 V trimmed rising trip point for V _{DDD}	Typ – 4%	4925	Typ + 4%	mV	Same as V _{TR_4P9_F} + 25 mV
SID568	V _{TR_5P0_R}	LVD 5.0 V trimmed rising trip point for V _{DDD}	Typ – 4%	5025	Typ + 4%	mV	Same as V _{TR_5P0_F} + 25 mV
SID569	V _{TR_5P1_R}	LVD 5.1 V trimmed rising trip point for V _{DDD}	Typ – 4%	5125	Typ + 4%	mV	Same as V _{TR_5P1_F} + 25 mV
SID570	V _{TR_5P2_R}	LVD 5.2 V trimmed rising trip point for V _{DDD}	Typ – 4%	5225	Typ + 4%	mV	Same as V _{TR_5P2_F} + 25 mV
SID571	V _{TR_5P3_R}	LVD 5.3 V trimmed rising trip point for V _{DDD}	Typ – 4%	5325	Typ + 4%	mV	Same as V _{TR_5P3_F} + 25 mV
SID573	LVD_RR_A	Power ramp rate: V _{DDD} (Active)	–	–	100	mV/μs	
SID574	LVD_RR_DS	Power ramp rate: V _{DDD} (DeepSleep)	–	–	10	mV/μs	
SID575	t _{DLY_ACT_LVD}	Active mode delay between V _{DDD} falling/rising through LVD rising/falling point and an internal LVD output transitioning through V _{DDD} / 2	–	–	1	μs	Guaranteed by design
SID575A	t _{DLY_DS_LVD}	DeepSleep mode delay between V _{DDD} falling/rising through LVD rising/falling point and an internal LVD output transitioning through V _{DDD} / 2	–	–	4	μs	Guaranteed by design
SID576	t _{RES_LVD}	Response time of LVD, V _{DDD} supply. LVD guaranteed to generate pulse for V _{DDD} pulse width greater than this. (For falling-then-rising supply at max ramp rate; pulse width is time below LVD falling trip point.)	100	–	–	ns	Guaranteed by design

High-voltage OVD Specifications

SID580	V _{TR_5P0_R}	High-voltage OVD 5.0-V trimmed rising trip point for V _{DDD} and V _{DDA_ADC}	5.049	5.205	5.361	V	
SID581	V _{TR_5P0_F}	High-voltage OVD 5.0-V trimmed falling trip point for V _{DDD} and V _{DDA_ADC}	5.025	5.18	5.335	V	
SID582	V _{TR_5P5_R}	High-voltage OVD 5.5-V trimmed rising trip point for V _{DDD} and V _{DDA_ADC} (default)	5.548	5.72	5.892	V	

Table 26-15 System resources (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID583	V _{TR_5P5_F}	High-voltage OVD 5.5-V trimmed falling trip point for V _{DDD} and V _{DDA_ADC} (default)	5.524	5.695	5.866	V	
SID585	HVOVD_RR_A	Power ramp rate: V _{DDD} and V _{DDA_ADC} (Active)	–	–	100	mV/μs	
SID586	HVOVD_RR_DS	Power ramp rate: V _{DDD} and V _{DDA_ADC} (DeepSleep)	–	–	10	mV/μs	
SID587	t _{DLY_ACT_HVOVD}	Active mode delay between V _{DDD} falling/rising through V _{TR_5P0_F/R} or V _{TR_5P5_F/R} and an internal HV OVD output transitioning through V _{DDD} / 2	–	–	1	μs	Guaranteed by design
SID587A	t _{DLY_ACT_HVOVD_A}	Active mode delay between V _{DDA_ADC} falling/rising through V _{TR_5P0_F/R} or V _{TR_5P5_F/R} and an internal HV OVD output transitioning through V _{DDD} / 2	–	–	1.5	μs	Guaranteed by design
SID587B	t _{DLY_DS_HVOVD}	DeepSleep mode delay between V _{DDD} /V _{DDA_ADC} falling/rising through V _{TR_5P0_F/R} or V _{TR_5P5_F/R} and an internal HV OVD output transitioning through V _{DDD} / 2	–	–	4	μs	Guaranteed by design
SID588	t _{RES_HVOVD}	Response time of HV OVD HV OVD guaranteed to generate pulse for V _{DDD} /V _{DDA_ADC} pulse width greater than this. (For rising-then-falling supply at max ramp rate; pulse width is time above V _{TR_5P0_R} or V _{TR_5P5_R})	100	–	–	ns	Guaranteed by design

Low-voltage OVD Specifications

SID590	V _{TR_R_LVOVD}	LV OVD trimmed rising trip point for V _{CCD}	Typ – 3%	1300	Typ + 3%	mV	
SID591	V _{TR_F_LVOVD}	LV OVD trimmed falling trip point for V _{CCD}	Typ – 3%	1275	Typ + 3%	mV	Same as V _{TR_R_LVOVD} – 25 mV
SID595	t _{DLY_ACT_LVOVD}	Active mode delay between V _{CCD} falling/rising through V _{TR_F/R_LVOVD} and an internal LV OVD output transitioning through V _{DDD} / 2	–	–	1	μs	Guaranteed by design
SID595A	t _{DLY_DS_LVOVD}	DeepSleep mode delay between V _{CCD} falling/rising through V _{TR_F/R_LVOVD} and an internal LV OVD output transitioning through V _{DDD} / 2	–	–	12	μs	Guaranteed by design
SID596	t _{RES_LVOVD}	Response time of LV OVD. LV OVD guaranteed to generate pulse for V _{CCD} pulse width greater than this. (For rising-then-falling supply at max ramp rate; pulse width is time above V _{TR_R_LVOVD})	100	–	–	ns	Guaranteed by design

Over current detection (OCD) Specifications

SID598	I _{OCD}	Over current detection range for internal Active regulator	312	–	630	mA	
SID599	I _{OCD_DPSLP}	Over current detection range for internal DeepSleep regulator	18	–	72	mA	

Electrical specifications

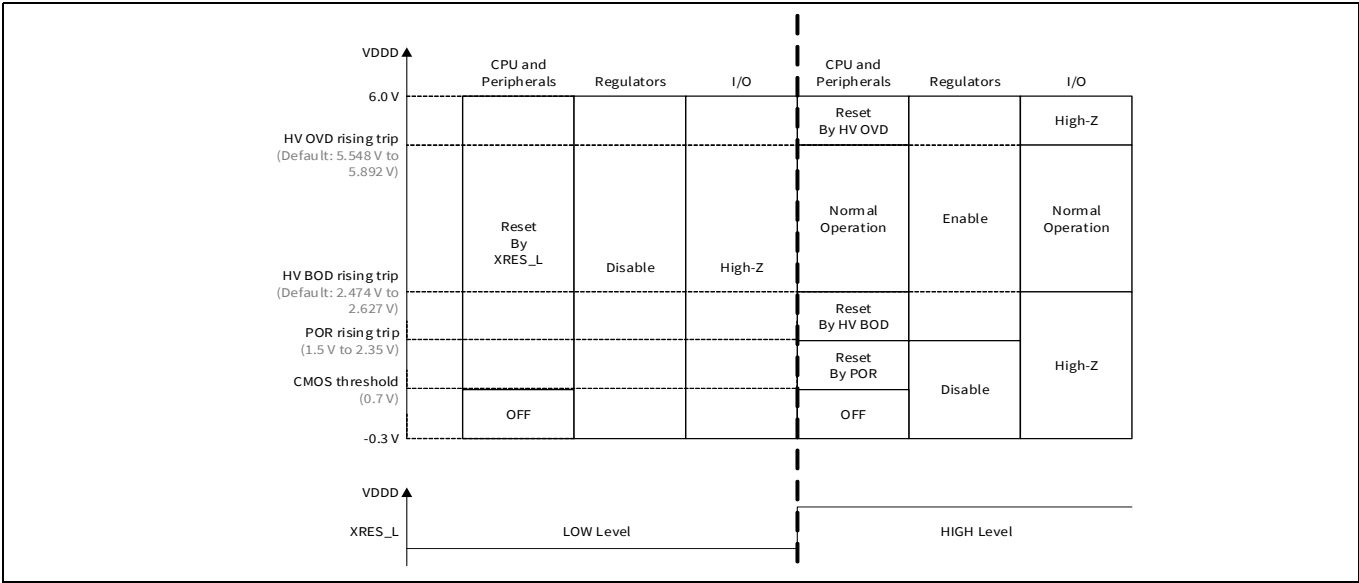


Figure 26-14 Device operations supply range

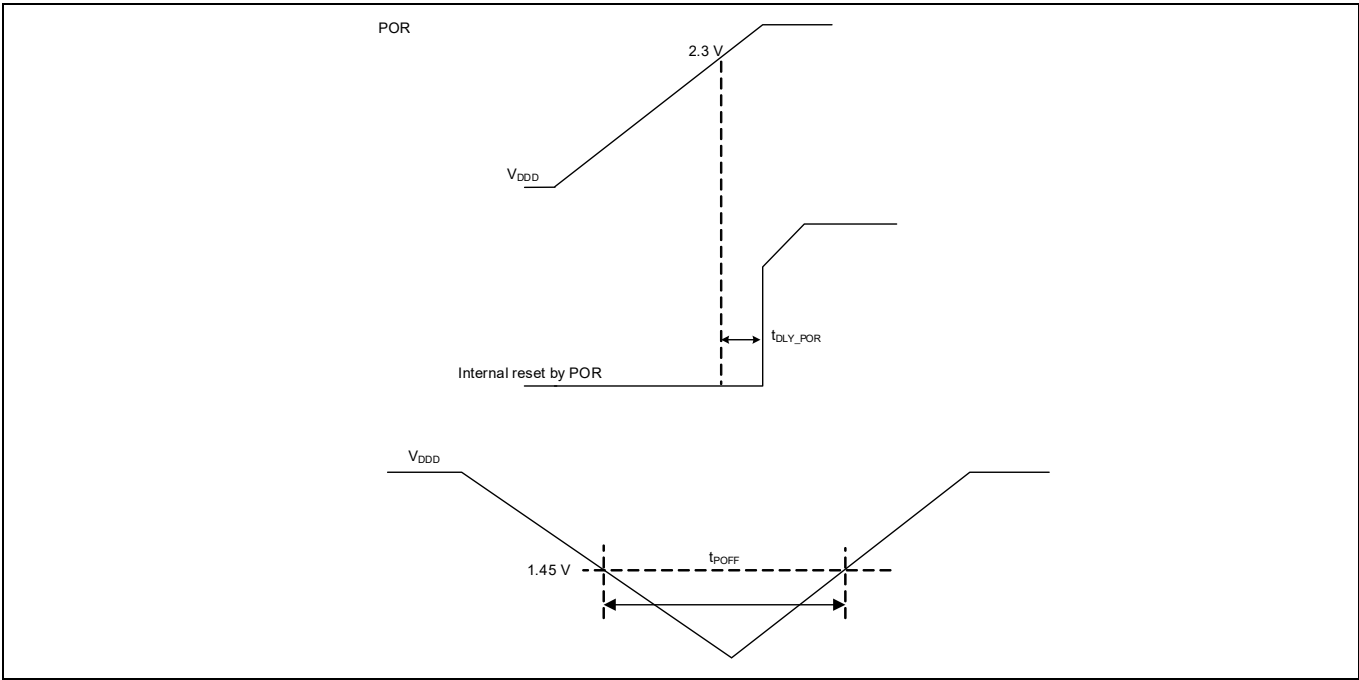


Figure 26-15 POR specifications

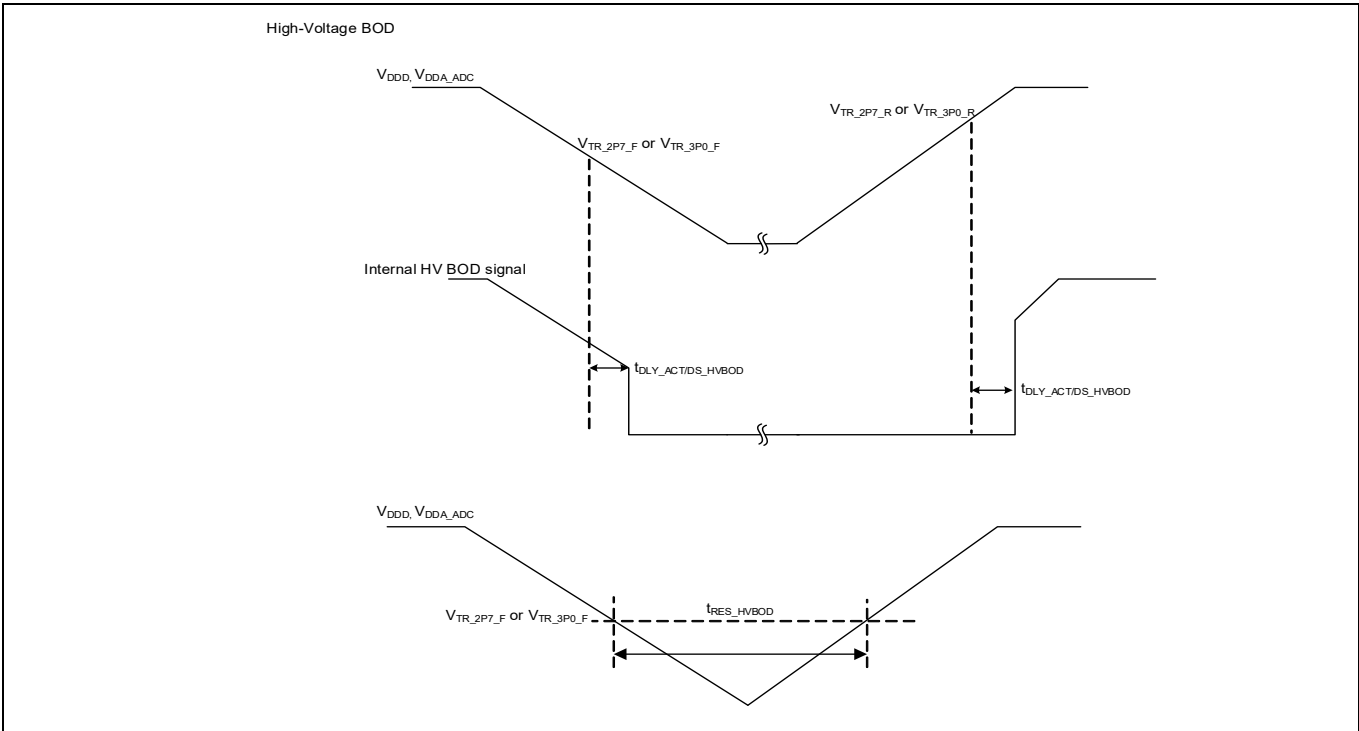


Figure 26-16 High-voltage BOD specifications

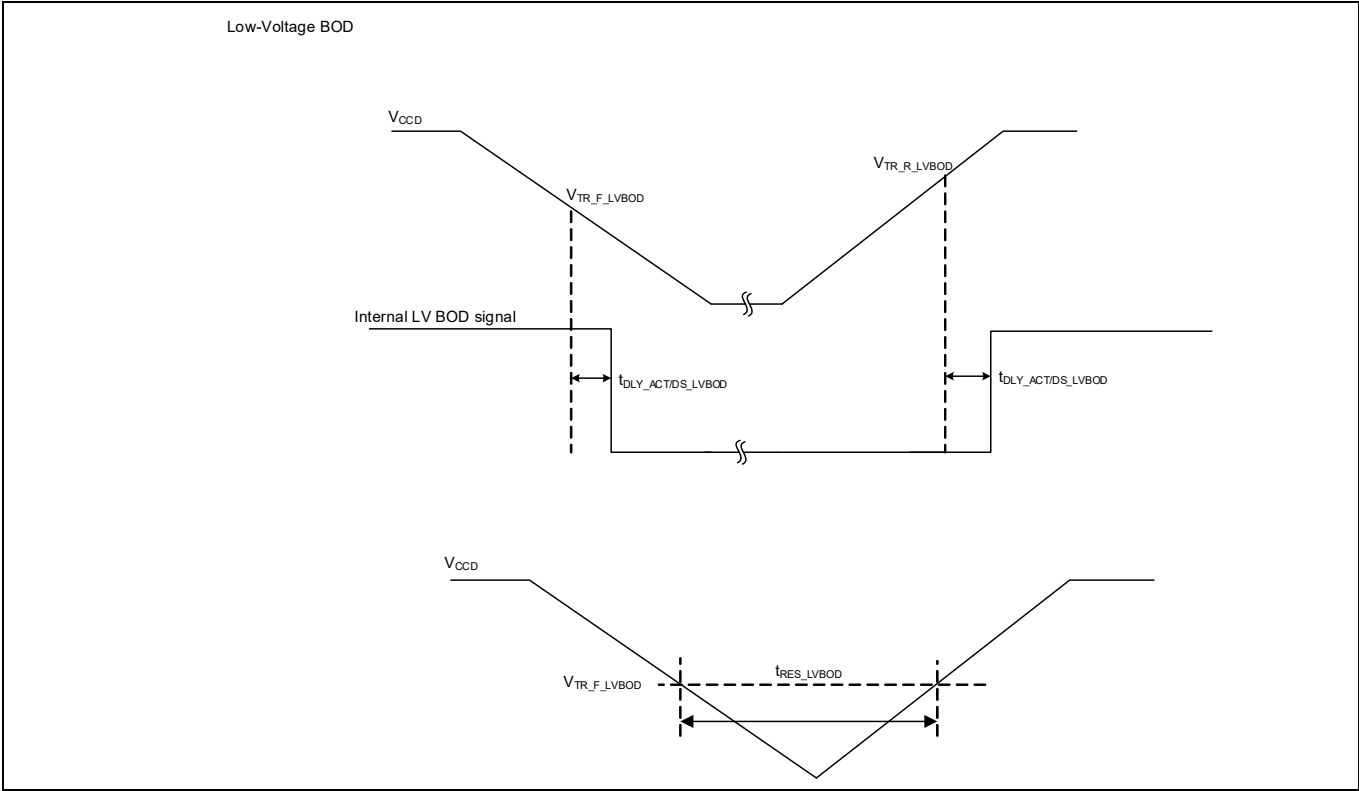


Figure 26-17 Low-voltage BOD specifications

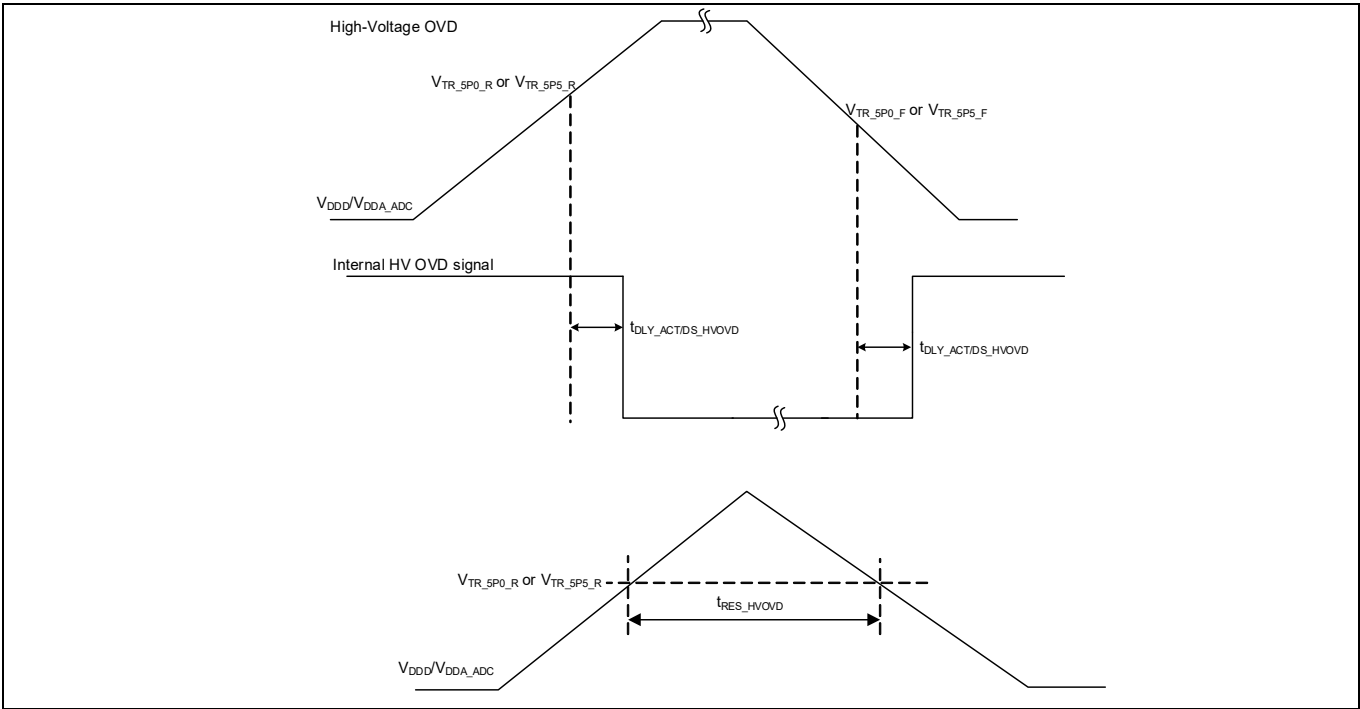


Figure 26-18 High-voltage OVD specifications

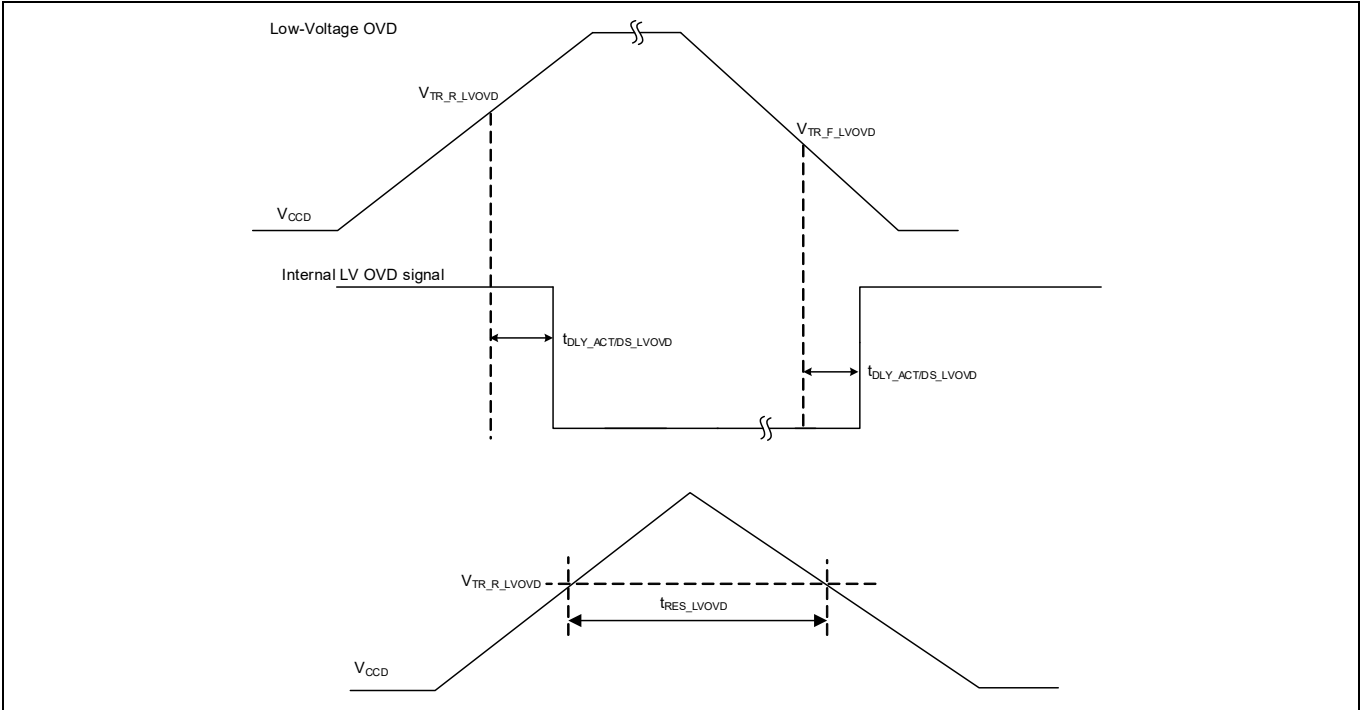
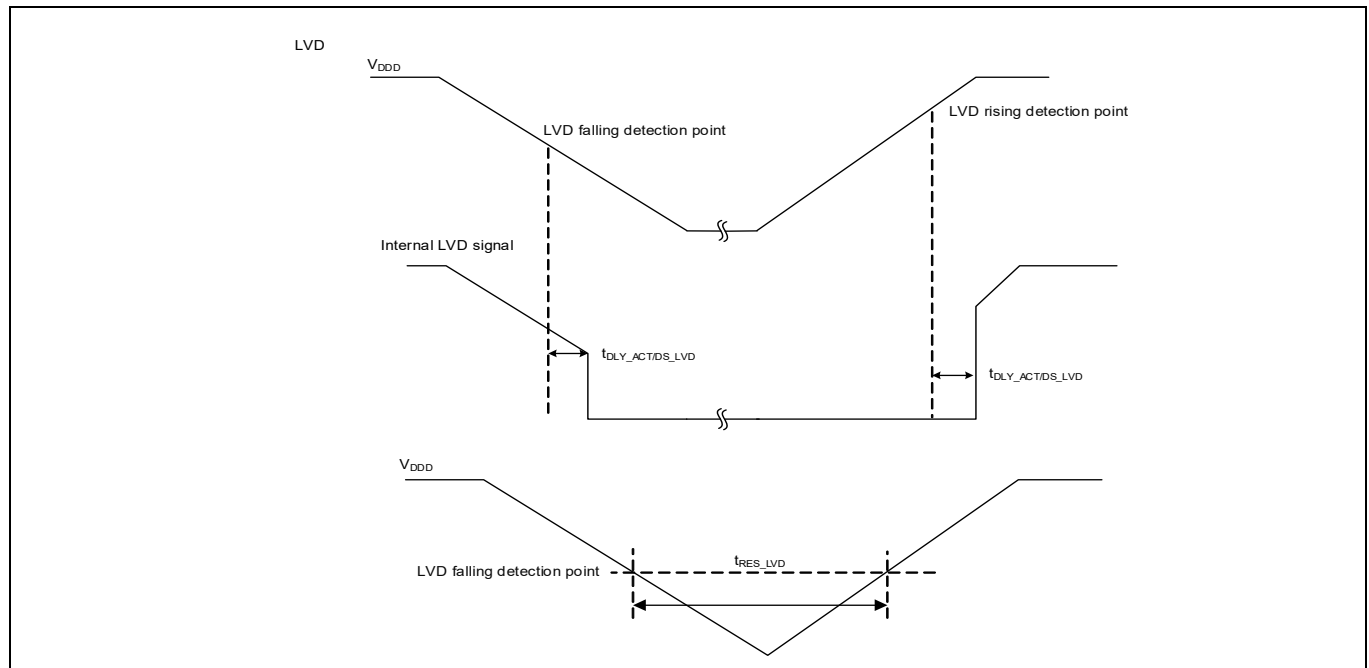


Figure 26-19 Low-voltage OVD specifications


Figure 26-20 LVD specifications

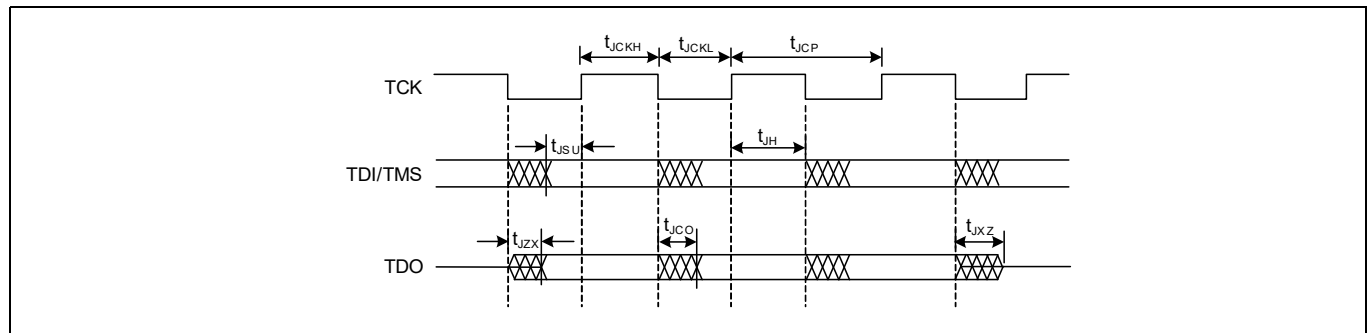
26.9.1 SWD, JTAG, and Trace specifications

Table 26-16 SWD interface specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
Recommended I/O Configuration: GPIO_STD: CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b1							
SID300	f _{SWDCLK}	SWD clock input frequency	–	–	10	MHz	2.7 V ≤ V _{DDIO_GPIO} ≤ 5.5 V
SID301	t _{SWDI_SETUP}	SWDI setup time	0.25 × T	–	–	ns	T = 1 / f _{SWDCLK}
SID302	t _{SWDI_HOLD}	SWDI hold time	0.25 × T	–	–	ns	T = 1 / f _{SWDCLK}
SID303	t _{SWDO_VALID}	SWDO valid time	–	–	0.5 × T	ns	T = 1 / f _{SWDCLK}
SID304	t _{SWDO_HOLD}	SWDO hold time	1	–	–	ns	T = 1 / f _{SWDCLK}

Table 26-17 JTAG AC specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
Recommended I/O Configuration: GPIO_STD: CFG_OUT/DRIVE_SEL<1:0> = 0b00, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b1							
SID620	t _{JCKH}	TCK HIGH time	25	–	–	ns	30-pF load on TDO
SID621	t _{JCKL}	TCK LOW time	25	–	–	ns	30-pF load on TDO
SID622	t _{JCP}	TCK clock period	62.5	–	–	ns	30-pF load on TDO
SID623	t _{JSU}	TDI/TMS setup time	6.25	–	–	ns	30-pF load on TDO
SID624	t _{JH}	TDI/TMS hold time	6.25	–	–	ns	30-pF load on TDO
SID625	t _{JZX}	TDO High-Z to active	–	–	25	ns	30-pF load on TDO
SID626	t _{JXZ}	TDO active to High-Z	–	–	25	ns	30-pF load on TDO
SID627	t _{JCO}	TDO clock to output	–	–	25	ns	30-pF load on TDO


Figure 26-21 JTAG specifications
Table 26-18 Trace Specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
Recommended I/O Configuration: HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b000, CFG_SLEW_EXT/SLEW<0:0> = 0b0							
SID1412A	C _{TRACE}	Trace capacitive load	–	–	30	pF	
SID1412	t _{TRACE_CYC}	Trace clock period	20	–	–	ns	Trace clock cycle time for 50 MHz
SID1413	t _{TRACE_CLKL}	Trace clock LOW pulse width	2	–	–	ns	Clock low pulse width
SID1414	t _{TRACE_CLKH}	Trace clock HIGH pulse width	2	–	–	ns	Clock high pulse width
SID1415	t _{TRACE_SETUP}	Trace data setup time	2	–	–	ns	Trace data setup time, CLK_PERI ≥ 75 MHz
SID1416	t _{TRACE_HOLD}	Trace data hold time	1	–	–	ns	Trace data hold time, CLK_PERI ≥ 75 MHz
SID1415A	t _{TRACE_SETUP}	Trace data setup time	3	–	–	ns	Trace data setup time, CLK_PERI < 75 MHz
SID1416A	t _{TRACE_HOLD}	Trace data hold time	2	–	–	ns	Trace data hold time, CLK_PERI < 75 MHz

26.10 Clock specifications

Table 26-19 Root and intermediate clocks^[67, 68]

Root Clock	Maximum permitted clock frequency (MHz) ^[69]	Source	Maximum permitted clock frequency (MHz) ^[69]						Description
			PLL/FLL Clock source: ECO/LPECO ^[70]			PLL/FLL Clock source: IMO ^[71, 72]			
			Integer	SSCG	Fractional	Integer	SSCG	Fractional	
CLK_HF0	160	PLL200#0	160	NA	NA	153	NA	NA	Root clock for CPUSS, PERI (CLK_MEM)
		FLL	100	NA	NA	100	NA	NA	
	100	PLL200#0	100	NA	NA	95	NA	NA	PERI (CLK_SLOW, CLK_PERI)
		FLL	100	NA	NA	97	NA	NA	
CLK_HF1	240	PLL400#0	240	235	237	229	225	227	CM7 CPU Core#0
		FLL	100	NA	NA	100	NA	NA	
CLK_HF2	100	PLL200#1	100	NA	NA	95	NA	NA	Peripheral clock root other than CLK_PERI (CAN FD, etc.)
		FLL	100	NA	NA	97	NA	NA	
CLK_HF3	100	PLL200#0	100	NA	NA	95	NA	NA	Event generator (CLK_REF), clock output on EXT_CLK pins (when used as output)
		FLL	100	NA	NA	97	NA	NA	
CLK_HF4	50	PLL200#1	50	NA	NA	47	NA	NA	ETH Channel#0. Internal clock 50 MHz for RMII, External PHY provides 25 MHz for MII
		FLL	50	NA	NA	48	NA	NA	
CLK_HF5	200	PLL400#1 / PLL400#2 / EXT_CLK	200	196	198	191	187	189	Sound Subsystem #0 root clock, ETH0 TSU clock (CLK_IF_SRSS0)
		FLL	100	NA	NA	100	NA	NA	
CLK_HF6	200	PLL400#1 / PLL400#2 / EXT_CLK	200	196	198	191	187	189	Sound Subsystem #1 root clock (CLK_IF_SRSS1)
		FLL	100	NA	NA	100	NA	NA	
CLK_HF7	200	PLL400#1 / PLL400#2 / EXT_CLK	200	196	198	191	187	189	Sound Subsystem #2 root clock (CLK_IF_SRSS2)
		FLL	100	NA	NA	100	NA	NA	
CLK_HF8	266	PLL400#1	200	NA	NA	191	NA	NA	SMIF#0 root clock
		PLL400#2	266	NA	NA	254	NA	NA	
		FLL	NA	NA	NA	NA	NA	NA	
CLK_HF9	266	PLL400#1	200	NA	NA	191	NA	NA	SMIF#1 root clock
		PLL400#2	266	NA	NA	254	NA	NA	
		FLL	NA	NA	NA	NA	NA	NA	

Notes

67. Intermediate clocks that are not listed have the same limitations as that of their parent clock.
68. Table indicates guaranteed mapping between a root clock (CLK_HFx) and the PLL.
69. Maximum clock frequency after the corresponding clock source (PLL/FLL + dividers). All internal tolerances and affects are covered by these frequencies.
70. For ECO, LPECO: up to ±150 ppm uncertainty of the external clock source are tolerated by design.
71. The IMO operation frequency tolerance is included.
72. ROM and flash boot execution with IMO/FLL at 100 MHz is guaranteed by design.

Table 26-19 Root and intermediate clocks^[67, 68] (continued)

Root Clock	Maximum permitted clock frequency (MHz) ^[69]	Source	Maximum permitted clock frequency (MHz) ^[69]						Description
			PLL/FLL Clock source: ECO/LPECO ^[70]			PLL/FLL Clock source: IMO ^[71, 72]			
			Integer	SSCG	Fractional	Integer	SSCG	Fractional	
CLK_HF10	203	PLL400#3	203	200	201	195	191	193	Video Subsystem root clock
		FLL	100	NA	NA	100	NA	NA	
CLK_HF11	224	PLL400#4	224	220	222	214	210	212	Display#0 root clock
		PLL200#2	200	NA	NA	191	NA	NA	
		FLL	100	NA	NA	100	NA	NA	
CLK_HF12	163	PLL400#4	163	160	161	156	153	154	Display#1 root clock
		PLL200#2	161	NA	NA	153	NA	NA	
		FLL	100	NA	NA	100	NA	NA	
CLK_HF13	ILO		NA						CSV Dedicated (< 1MHz)
CLK_FAST_0	240	CLK_HF1	240	235	237	229	226	228	CM7 CPU Core#0, intermediate clock
		FLL	100	NA	NA	100	NA	NA	
CLK_MEM	160	CLK_HF0	160	NA	NA	153	NA	NA	Intermediate clock for SMIF, Flash, Ethernet, VIDEOSS
		FLL	100	NA	NA	100	NA	NA	
CLK_SLOW	100	CLK_HF0	100	NA	NA	95	NA	NA	Generated by clock gating CLK_MEM, intermediate clock for CM0+, P-DMA, M-DMA, Crypto, SMIF, VIDEOSS
		FLL	100	NA	NA	97	NA	NA	
CLK_PERI	100	CLK_HF0	100	NA	NA	95	NA	NA	Generated by clock gating CLK_HF0, intermediate clock for IOSS, TCPWM0, CPU trace, SMIF, Sound Subsystem, Ethernet
		FLL	100	NA	NA	97	NA	NA	

Notes

67. Intermediate clocks that are not listed have the same limitations as that of their parent clock.
68. Table indicates guaranteed mapping between a root clock (CLK_HFx) and the PLL.
69. Maximum clock frequency after the corresponding clock source (PLL/FLL + dividers). All internal tolerances and affects are covered by these frequencies.
70. For ECO, LPECO: up to ±150 ppm uncertainty of the external clock source are tolerated by design.
71. The IMO operation frequency tolerance is included.
72. ROM and flash boot execution with IMO/FLL at 100 MHz is guaranteed by design.

Table 26-20 PLL400 operation modes

PLL400 operation mode	Spread spectrum clock generation (SSCG)	Fractional
Integer	OFF	OFF
SSCG	ON	OFF
Fractional	OFF	ON

Table 26-21 IMO AC specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID310	f_{IMO}	IMO operating frequency	7.632	8	8.368	MHz	Accuracy after factory trimming
SID311	$t_{STARTIMO}$	IMO startup time	–	–	7.5	μs	Startup time to 90% of final frequency
SID312	I_{IMO_ACT}	IMO current	–	13.5	22	μA	Guaranteed by design

Table 26-22 ILO AC specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID320	$f_{ILOTRIM}$	ILO operating frequency	30.965	32.768	34.57	kHz	5.5% accuracy after factory trimming
SID321	$t_{STARTILO}$	ILO startup time	–	8	12	μs	Startup time to 90% of final frequency
SID323	I_{ILO}	ILO current	–	500	2800	nA	Guaranteed by design

Table 26-23 LPECO specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID325	f_{LPECO}	LPECO operating frequency	3.99	–	8.01	MHz	Drive level protection DL ≥ 100 μW, ESR ≤ 200 Ω Crystal load capacitance (C_L) 5 pF to 25 pF
SID329	I_{LPECO_4M}	LPECO current at 4 MHz	–	93	110	μA	Shared with GPIO, Load: 10 pF BACKUP_LPECO_CTL/LPECO_AMP-DET_EN<0:0>=0b0
SID354	I_{LPECO_4M}	LPECO current at 4 MHz	–	97	125	μA	Shared with GPIO, Load: 15 pF BACKUP_LPECO_CTL/LPECO_AMP-DET_EN<0:0>=0b0
SID326	I_{LPECO_4M}	LPECO current at 4 MHz	–	106	145	μA	Shared with GPIO, Load: 20 pF BACKUP_LPECO_CTL/LPECO_AMP-DET_EN<0:0>=0b0
SID355	I_{LPECO_4M}	LPECO current at 4 MHz	–	115	155	μA	Shared with GPIO, Load: 25 pF BACKUP_LPECO_CTL/LPECO_AMP-DET_EN<0:0>=0b0
SID356	I_{LPECO_8M}	LPECO current at 8 MHz	–	140	165	μA	Shared with GPIO, Load: 10 pF BACKUP_LPECO_CTL/LPECO_AMP-DET_EN<0:0>=0b0
SID357	I_{LPECO_8M}	LPECO current at 8 MHz	–	149	175	μA	Shared with GPIO, Load: 15 pF BACKUP_LPECO_CTL/LPECO_AMP-DET_EN<0:0>=0b0
SID327	I_{LPECO_8M}	LPECO current at 8 MHz	–	165	190	μA	Shared with GPIO, Load: 20 pF BACKUP_LPECO_CTL/LPECO_AMP-DET_EN<0:0>=0b0

Note

73.Oscillator startup time is a performance parameter and mainly depending on the chosen external crystal and load capacitance.

Table 26-23 LPECO specifications *(continued)*

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID358	I _{LPECO_8M}	LPECO current at 8 MHz	–	183	220	μA	Shared with GPIO, Load: 25 pF BACKUP_LPECO_CTL/LPECO_AMP- DET_EN<0:0>=0b0
SID328	t _{START_LPECO}	LPECO startup time ^[73]	–	–	10	ms	Startup time to 90% of final frequency. Time from oscillator enable (BACKUP_LPECO_CTL.LPECO_EN<0:0> =0b1) to stable oscillation and sufficient amplitude (BACKUP_LPECO_STATUS.LPECO_REA DY<0:0>=0b1 and BACKUP_LPECO_STATUS.LPECO_AMP- DET_OK<0:0>=0b1).

Note

73.Oscillator startup time is a performance parameter and mainly depending on the chosen external crystal and load capacitance.

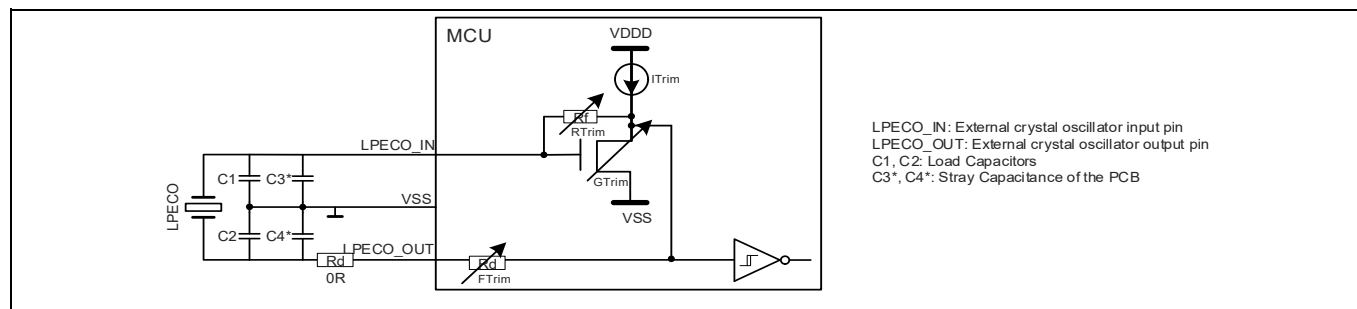


Figure 26-22 LPECO connection scheme^[74]

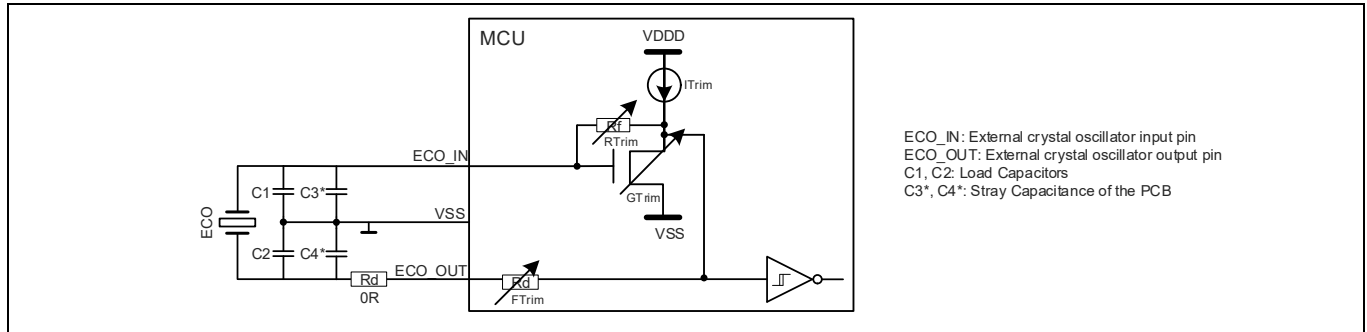
Table 26-24 ECO specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID330	f _{ECO}	Crystal frequency range	7.2	–	33.34	MHz	
SID332	R _{FDBK}	Feedback resistor value. Min: RTRIM = 3; Max: RTRIM = 0 with 100 kΩ step size on RTRIM	100	–	400	kΩ	Guaranteed by design
SID333	I _{ECO3}	ECO current at T _J = 150°C	–	1200	2000	μA	Maximum operation current with a 33-MHz crystal, max 18-pF load
SID334	t _{START_7.2M}	7.2-MHz ECO startup time ^[75]	–	–	10	ms	Startup time to 90% of final frequency. Time from oscillator enable (CLK_ECO_-CONFIG.ECO_EN<0:0>=0b1) to stable oscillation and sufficient amplitude (CLK_ECO_STATUS.ECO_OK<0:0>=0b1 and CLK_ECO_STATUS.ECO_READY<0:0>=0b1).
SID335	t _{START_33M}	33-MHz ECO startup time ^[75]	–	–	1	ms	Startup time to 90% of final frequency. Time from oscillator enable (CLK_ECO_-CONFIG.ECO_EN<0:0>=0b1) to stable oscillation and sufficient amplitude (CLK_ECO_STATUS.ECO_OK<0:0>=0b1 and CLK_ECO_STATUS.ECO_READY<0:0>=0b1).

Notes

74. Refer to the family-specific Architecture TRM for more information on crystal requirements (002-25800, TRAVEO™ T2G Automotive MCU cluster 2D architecture technical reference manual).

75. Oscillator startup time is a performance parameter and mainly depending on the chosen external crystal and load capacitance.


Figure 26-23 ECO connection scheme^[74]
Table 26-25 PLL specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
PLL Specifications for “PLL without SSCG and Fractional Operation” (PLL200)							
SID340	$t_{\text{PLL200_LOCK}}$	Time to achieve PLL lock	–	–	35	μs	Time from stable reference clock until PLL frequency is within 0.1% of final value and lock indicator is set
SID341	f_{OUT}	Output frequency from PLL block (PLL_OUT)	10.998	–	200.03	MHz	
SID346	f_{IN}	PLL input frequency (Reference Clock f_{REF})	3.988	–	33.34	MHz	
SID347	$I_{\text{PLL_200M}}$	PLL operating current	–	0.87	1.85	mA	$f_{\text{OUT}} = 200 \text{ MHz}$
SID348C	$f_{\text{PLL_VCO}}$	VCO frequency, clock output of 'Voltage Control Oscillator (VCO)'	169.97 45	–	400.06	MHz	
SID349C	$f_{\text{PLL_PFD}}$	Phase Detector Frequency, clock output of the Reference Divider (Q) and Feedback Divider (P)	3.988	–	8.0012	MHz	
SID342	PLL_LJIT1	Long term jitter	–0.25	–	0.25	ns	For 125 ns Guaranteed by design $f_{\text{PLL_VCO}}$: 320 MHz or 400 MHz $f_{\text{PLL_OUT}}$: 40 MHz to 200 MHz $f_{\text{PLL_PFD}}$: 8 MHz $f_{\text{PLL_IN}}$: ECO
SID343	PLL_LJIT2	Long term jitter	–0.5	–	0.5	ns	For 500 ns Guaranteed by design $f_{\text{PLL_VCO}}$: 320 MHz or 400 MHz $f_{\text{PLL_OUT}}$: 40 MHz to 200 MHz $f_{\text{PLL_PFD}}$: 8 MHz $f_{\text{PLL_IN}}$: ECO
SID344	PLL_LJIT3	Long term jitter	–0.5	–	0.5	ns	For 1000 ns Guaranteed by design $f_{\text{PLL_VCO}}$: 320 MHz or 400 MHz $f_{\text{PLL_OUT}}$: 40 MHz to 200 MHz $f_{\text{PLL_PFD}}$: 8 MHz $f_{\text{PLL_IN}}$: ECO

Electrical specifications

Table 26-25 PLL specifications (continued)

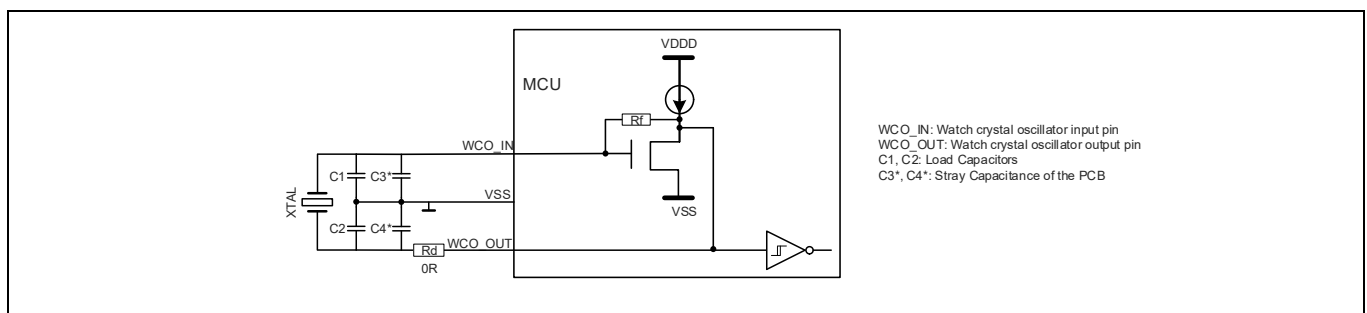
Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID345A1	PLL_LJIT5	Long term jitter	-0.75	-	0.75	ns	For 10000 ns Guaranteed by design f_{PLL_VCO} : 320 MHz or 400 MHz f_{PLL_OUT} : 40 MHz to 200 MHz f_{PLL_PFD} : 8 MHz f_{PLL_IN} : ECO
PLL Specifications for “PLL with SSCG and Fractional Operation” (PLL400)							
SID340A	t_{PLL400_LOCK}	Time to achieve PLL lock	-	-	50	µs	
SID341A	f_{OUT}	Output frequency from PLL block (PLL_OUT)	24.996	-	400.06	MHz	
SID343A	SPREAD_D	Spread spectrum modulation depth	0.5	-	3	%	Downspread only, triangle modulation
SID343B	f_{SPREAD_MR}	Spread spectrum modulation rate	-	-	32	kHz	Selected by modulation divider from f_{PFD}
SID346A	f_{IN}	PLL input frequency (Reference Clock f_{REF})	3.988	-	33.34	MHz	
SID347A	I_{PLL_400M}	PLL operating current	-	1.4	2.2	mA	$f_{OUT} = 400$ MHz
SID348A	f_{PFD_S}	Phase Detector Frequency, clock output of the Reference Divider (Q) and Feedback Divider (P)	3.988	-	20.003	MHz	Fractional operation OFF
SID349A	f_{PFD_F}	Phase Detector Frequency, clock output of the Reference Divider (Q) and Feedback Divider (P)	7.9988	-	20.003	MHz	Fractional operation ON
SID345A	f_{VCO}	VCO frequency, Clock output of 'Voltage Control Oscillator (VCO)'	399.94	-	800.12	MHz	
SID342D1	PLL400_LJIT1	Long term jitter	-0.25	-	0.25	ns	For 125 ns Guaranteed by Design f_{VCO} : 800 MHz (Integer mode) f_{IN} : ECO f_{PFD} : 4 MHz f_{OUT} : 100 MHz to 400 MHz
SID343D1	PLL400_LJIT2	Long term jitter	-0.5	-	0.5	ns	For 500 ns Guaranteed by Design f_{VCO} : 800 MHz (Integer mode) f_{IN} : ECO f_{PFD} : 4 MHz f_{OUT} : 100 MHz to 400 MHz
SID344D1	PLL400_LJIT3	Long term jitter	-1	-	1	ns	For 1000 ns Guaranteed by Design f_{VCO} : 800 MHz (Integer mode) f_{IN} : ECO f_{PFD} : 4 MHz f_{OUT} : 100 MHz to 400 MHz
SID345E1	PLL400_LJIT5	Long term jitter	-1.5	-	1.5	ns	For 10000 ns Guaranteed by Design f_{VCO} : 800 MHz (Integer mode) f_{IN} : ECO f_{PFD} : 4 MHz f_{OUT} : 100 MHz to 400 MHz

Table 26-26 FLL specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID350	t_{FLL_WAKE}	FLL wake up time	–	–	5	μs	Wakeup with < 10°C temperature change while in DeepSleep. $f_{FLL_IN} = 8$ MHz, $f_{FLL_OUT} = 100$ MHz, Time from stable reference clock until FLL frequency is within 5% of final value
SID351	f_{FLL_OUT}	Output frequency from FLL block	24	–	100	MHz	Output range of FLL divided-by-2 output
SID352	FLL_CJIT	FLL frequency accuracy	–1	–	1	%	This is added to the error of the source
SID353	f_{FLL_IN}	Input frequency	0.25	–	100	MHz	

Table 26-27 WCO specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID360	f_{WCO}	Watch crystal frequency	–	32.768	–	kHz	Tuning Fork Crystal with following parameters: DL (drive level) ≥ 0.5 μW, ESR ≤ 130 kΩ
SID361	WCO_DC	WCO duty cycle	10	–	90	%	
SID362	t_{START_WCO}	WCO start up time ^[76]	–	–	1000	ms	Time from oscillator enable (BACKUP_CTL.WCO_EN<0:0>=0b1) to stable oscillation and sufficient amplitude (BACKUP_STATUS.WCO_OK<0:0>=0b1)
SID363	I_{WCO}	WCO current	–	1.4	–	μA	AGC=OFF


Figure 26-24 WCO connection scheme^[77]
Notes

76. Oscillator startup time is a performance parameter and mainly depending on the chosen external crystal and load capacitance.

77. Refer to the family-specific Architecture TRM for more information on crystal requirements (002-25800, TRAVEO™ T2G Automotive MCU cluster 2D architecture technical reference manual).

Table 26-28 External clock input specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID366	f _{EXT}	External clock input frequency	0.25	–	100	MHz	For EXT_CLK pin (all input level settings: CMOS, TTL, Automotive)
SID367	EXT_DC	Duty cycle	45	–	55	%	

Table 26-29 MCWDT timeout specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID410	t _{MCWDT1}	Minimum MCWDT timeout	57.85	–	–	μs	When using the ILO (32 kHz + 5.5%) and 16-bit MCWDT counter Guaranteed by design
SID411	t _{MCWDT2}	Maximum MCWDT timeout	–	–	2.12	s	When using the ILO (32 kHz – 5.5%) and 16-bit MCWDT counter Guaranteed by design

Table 26-30 WDT timeout specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID412	t _{WDT1}	Minimum WDT timeout	57.85	–	–	μs	When using the ILO (32 kHz + 5.5%) and 32-bit WDT counter Guaranteed by design
SID413	t _{WDT2}	Maximum WDT timeout	–	–	38.53	h	When using the ILO (32 kHz – 5.5%) and 32-bit WDT counter Guaranteed by design
SID414	t _{WDT3}	Default WDT timeout	–	1000	–	ms	When using the ILO and 32-bit WDT counter at 0x8000 (default value), guaranteed by design

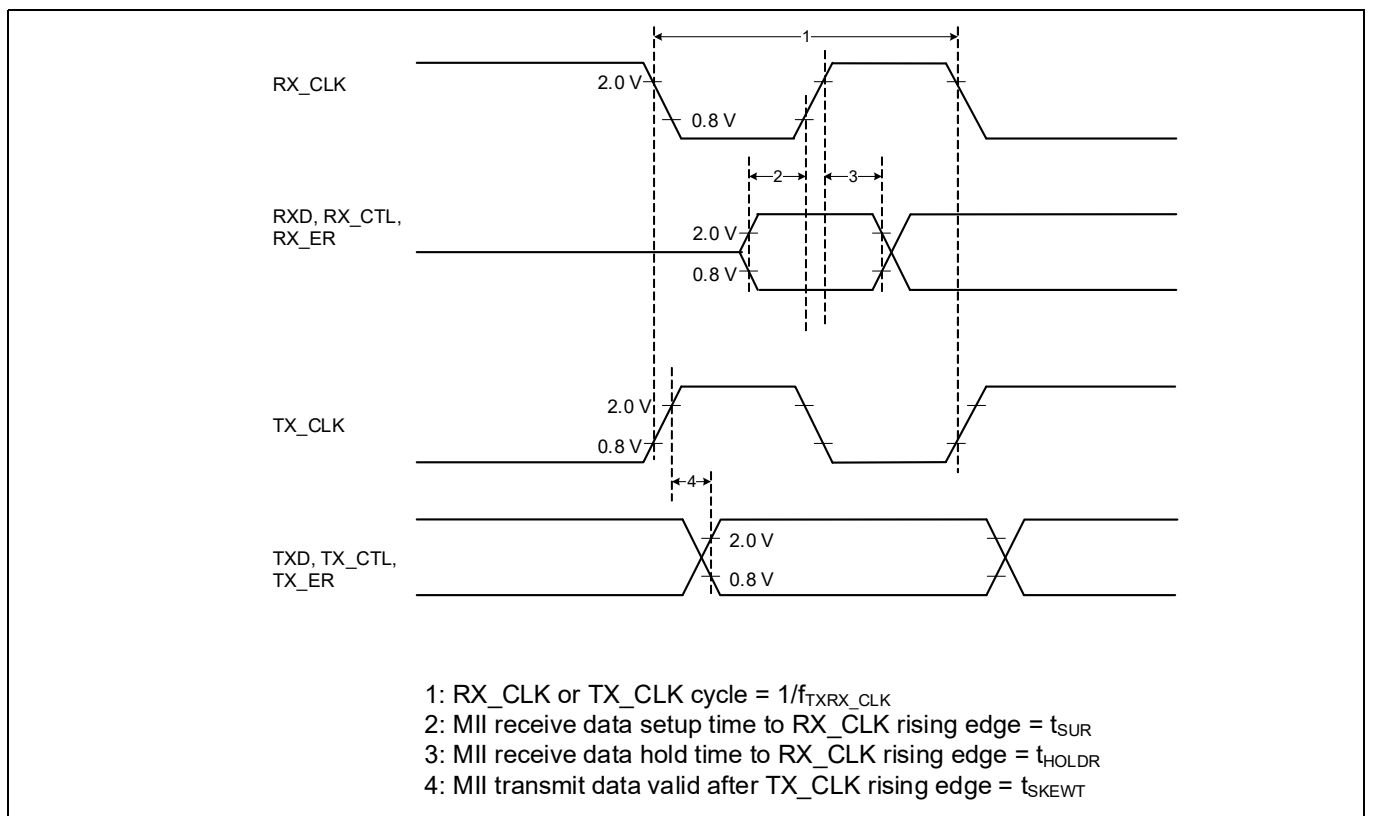
26.11 Ethernet specifications

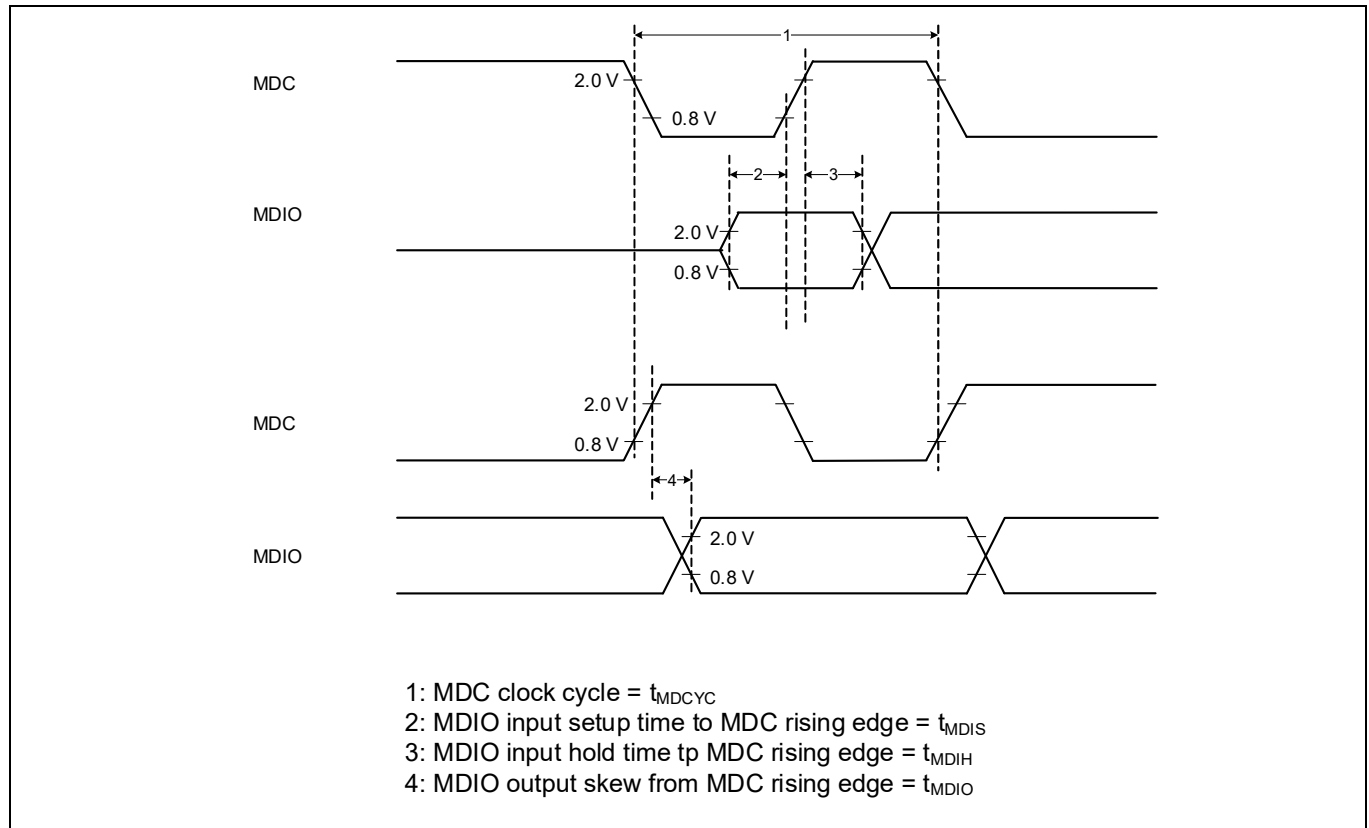
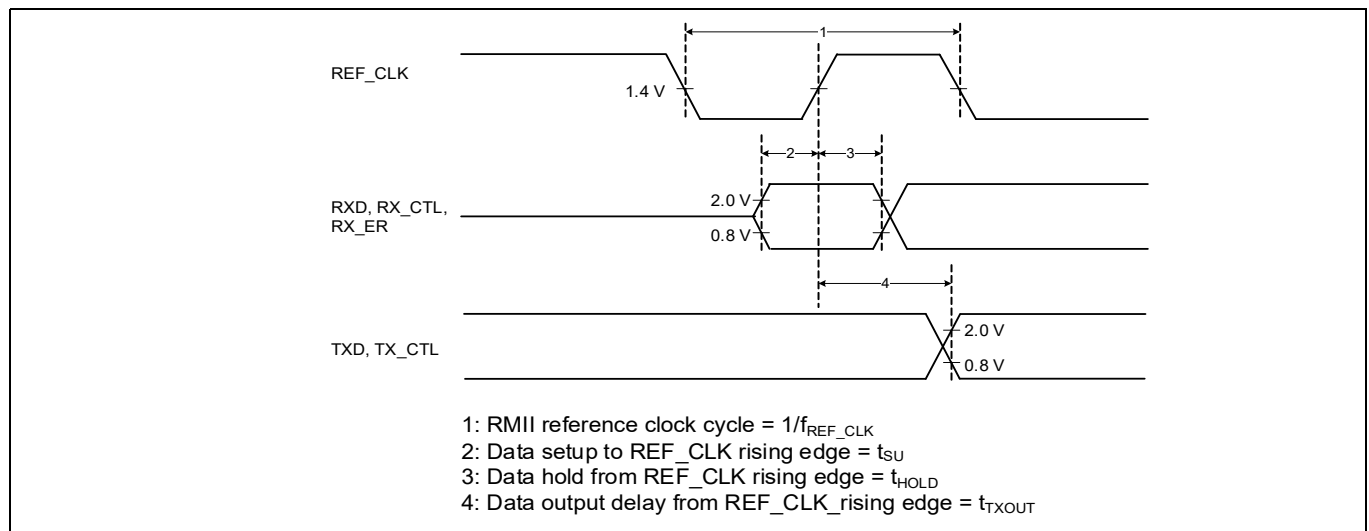
Table 26-31 Ethernet specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
Ethernet General Specifications							
SID364	C _L	Load capacitance	–	–	20	pF	for all between MAC and PHY for MII-IF, RMII-IF, MDC/MDIO-IF
SID368	f _{SYS}	System clock max frequency	–	–	100	MHz	Guaranteed by design
SID369	f _{AXI}	AXI clock max frequency	–	–	200	MHz	Guaranteed by design
Ethernet MII Specifications							
Recommended I/O configuration: HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b011, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b1, CFG_SLEW_EXT/SLEW<0:0> = 0b0							
SID370	t _{TXCYC}	MII tx_clk cycle	39.5	40	40.5	ns	
SID371	t _{RXCYC}	MII rx_clk cycle	39.5	40	40.5	ns	
SID372	t _{SKEWT}	MII Transmit data (txd,tx_en,tx_er) valid after tx_clk	0.5	–	25	ns	
SID373	t _{SUR}	MII Receive data setup to rx_clk rising edge	10	–	–	ns	
SID374	t _{HOLDR}	MII Receive data hold to rx_clk rising edge	10	–	–	ns	
SID375	f _{TXRX_CLK}	MII TX/RX_CLK Clock frequency	–50ppm	25	+50ppm	MHz	
SID376A	DUTY_REF	Duty cycle of reference clock	40	–	60	%	
SID365A	t _{RF}	Input rise / fall time	–	–	2	ns	20% to 80%
SID365E	t _{RFO}	Output rise / fall time	–	–	6.5	ns	20% to 80%
Ethernet RMII Specifications							
Recommended I/O configuration: HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b010, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b1, CFG_SLEW_EXT/SLEW<0:0> = 0b0							
SID375A	f _{REF_CLK}	RMII reference clock frequency	–50ppm	50	+50ppm	MHz	
SID376	DUTY_REF	Duty cycle of reference clock	40	–	60	%	
SID377	t _{SU}	RXD[1:0], CRS_DV, RX_ER Data Setup to REF_CLK rising edge.	4	–	–	ns	
SID378	t _{HOLD}	RXD[1:0], CRS_DV, RX_ER, Data hold from REF_CLK rising edge	2	–	–	ns	
SID379A	t _{TXOUTE}	External clock mode. TXD[1:0], TX_EN Data output delay from REF_CLK rising edge	2	–	14	ns	
SID379B	t _{TXOUTI}	Internal clock mode. TXD[1:0], TX_EN Data output delay from REF_CLK rising edge	2	–	16	ns	
SID365C	t _{RF}	Input rise / fall time	–	–	2	ns	20% to 80%

Table 26-31 Ethernet specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID365F	t_{RFO}	Output rise / fall time	–	–	6.5	ns	20% to 80%
Ethernet MDIO Specifications							
SID395	t_{MDCYC}	MDC clock cycle	400	–	–	ns	
SID395A	t_{HL_MDC}	MDIO Minimum high and low times for MDC	160	–	–	ns	
SID396	t_{MDIS}	MDIO input setup time to MDC rising edge	100	–	–	ns	
SID397	t_{MDIH}	MDIO input hold time to MDC rising edge	0	–	–	ns	
SID398	t_{MDIO}	MDIO output skew from MDC rising edge	10	–	390	ns	
SID365D	t_{RF}	Input rise / fall time	–	–	2	ns	20% to 80%
SID365G	t_{RFO}	Output MDIO rise / fall time	–	–	6.5	ns	20% to 80%


Figure 26-25 MII timing diagram


Figure 26-26 MDIO timing diagram

Figure 26-27 RMII timing diagram

26.11.1 Minimum bus frequency requirements

The following table details the required minimum operating frequencies for all possible Ethernet configurations and MAC speeds. Ethernet module uses **AXI** interface for DMA access.

Table 26-32 Minimum AXI frequency for MAC speeds

DMA bus width	MAC rate	Minimum AXI frequency
64	100 Mbps	10 MHz
64	10 Mbps	10 MHz

26.12 Sound subsystem specifications

Table 26-33 Sound Subsystem Specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
I²S I/O settings							
Recommended I/O configuration: HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b100, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b1, CFG_SLEW_EXT/SLEW<2:0> = 0b000							
I²S Serial Clock Frequency							
SID796	t _{SCLK}	Serial clock period	162	–	–	ns	Guaranteed by design No feature is used for low frequency I ² S operation: DUT RX Master: * RX_IF_CTL.LATE_SAMPLE = 0 * RX_IF_CTL.LATE_CAPTURE = 0b00 DUT TX Slave: No special configuration DUT RX Slave: * RX_IF_CTL.LATE_SAMPLE = 0
SID797	t _{HC}	Serial clock high time	0.35 × t _{SCLK}	–	–	ns	Guaranteed by design
SID798	t _{LC}	Serial clock low time	0.35 × t _{SCLK}	–	–	ns	Guaranteed by design
SID799	t _{MCLK}	Master clock period	20	–	–	ns	Guaranteed by design
I²S Transmitter Timing							
SID740	t _{DTR}	Delay from rising edge of TX_CLK to transition on TX_SD/TX_FSYNC (WS)	–	–	0.8 × t _{SCLK}	ns	Guaranteed by design
SID741	t _{HTR}	Hold from rising edge of TX_CLK to transition on TX_SD/TX_FSYNC (WS)	0	–	–	ns	Guaranteed by design
SID743	t _{HR_WS_POL_0}	TX Slave: Hold on TX_FSYNC (WS) after the 1st edge following the driving edge of TX_CLK (SCK_POLARITY = 0, half-cycle hold)	1.8	–	–	ns	
I²S Receiver Timing							
SID751	t _{SR}	Setup on RX_SD/RX_FSYNC (WS) before the rising edge to RX_CLK	0.2 × t _{SCLK}	–	–	ns	Guaranteed by Design Setup time is independent from RX_IF_CTL.LATE_SAMPLE, RX_IF_CTL.LATE_CAPTURE or SCK_POLARITY setting
SID752	t _{HR}	Hold on RX_SD/RX_FSYNC (WS) after the rising edge to RX_CLK	0	–	–	ns	Guaranteed by Design Sampling edge w.r.t driving edge of RX_SCLK: 1st edge (0.5 × t _{SCLK}) RX-Master: RX_IF_CTL.LATE_SAMPLE = 0, RX_IF_CTL.LATE_CAPTURE = 0b00 RX-Slave: SCK_POLARITY = 0
SID753	t _{SCLK_TRANS}	SCLK transition timing	1	–	8	ns	20% to 80%
SID754	t _{MCLK_TRANS}	MCLK transition timing	1	–	8	ns	20% to 80%
SID755	t _{DATA_TRANS}	DATA transition timing	1	–	8	ns	20% to 80%

Table 26-33 Sound Subsystem Specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
TDM I/O Settings							
Recommended I/O configuration: For serial clock above 25 MHz HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b011, CFG_IN_AUTOLVL/VTRIP_SEL<0:0>= 0b0, CFG_IN/VTRIP_SEL<0:0>= 0b1, CFG_SLEW_EXT/SLEW<0:0>= 0b0							
For serial clock up to 25 MHz HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b100, CFG_IN_AUTOLVL/VTRIP_SEL<0:0>= 0b0, CFG_IN/VTRIP_SEL<0:0>= 0b1, CFG_SLEW_EXT/SLEW<0:0>= 0b0							
TDM Serial Clock							
SID1000A	t _{SCLK}	Serial clock period, TDM[x] (x=0 through 3)	20	–	–	ns	Guaranteed by Design TX Master: TX_IF_CTL.SCK_POLARITY = 0 RX Master: not supported at 50 MHz TX Slave: not supported at 50 MHz RX Slave: not supported at 50 MHz
SID1000B	t _{SCLK}	Serial clock period, TDM[x] (x=0 through 3)	40	–	–	ns	Guaranteed by Design TX Master: TX_IF_CTL.SCK_POLARITY = 0 RX Master: RX_IF_CTL.LATE_SAMPLE = 1 RX_IF_CTL.LATE_CAPTURE = 0b00 TX Slave: Set TX_IF_CTL.SCK_POLARITY = 1 RX Slave: RX_IF_CTL.SCK_POLARITY = 0
SID1001	t _{HC}	Serial clock high time	0.35 × t _{SCLK}	–	–	ns	Guaranteed by design
SID1002	t _{LC}	Serial clock low time	0.35 × t _{SCLK}	–	–	ns	Guaranteed by design
SID1010	t _{MCLK}	Master clock input period	10	–	–	ns	MCLK must be SCLK*2; The maximum output frequency of the TDM depends on the used I/O type.
SID1002A	t _{MCLK}	Master clock output period	20	–	–	ns	
SID1002D	t _{MCLK_IH}	Master clock input high time	0.45 × t _{MCLK}	–	–	ns	
SID1002E	t _{MCLK_IL}	Master clock input low time	0.45 × t _{MCLK}	–	–	ns	
SID1002F	t _{MCLK_OH}	Master clock output high time	0.35 × t _{MCLK}	–	–	ns	
SID1002G	t _{MCLK_OL}	Master clock output low time	0.35 × t _{MCLK}	–	–	ns	
TDM Transmit Timing							
SID1003	t _{DTR}	Delay from rising edge of TX_CLK to transition on TX_SD/TX_FSYNC (WS)	–	–	0.8 × t _{SCLK}	ns	Guaranteed by design
SID1004	t _{HTR}	Hold from rising edge of TX_CLK to transition on TX_SD/TX_FSYNC (WS)	0	–	–	ns	Guaranteed by design
SID1011	t _{HR_WS_POL_0}	TX Slave: Hold on TX_FSYNC (WS) after the 1st edge following the driving edge of TX_CLK (SCK_POLARITY = 0, half-cycle hold)	1.8	–	–	ns	

Table 26-33 Sound Subsystem Specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID1012	$t_{HR_WS_POL_1}$	TX Slave: Hold on TX_FSYNC (WS) after the 2nd edge following the driving edge of TX_CLK (SCK_POLARITY = 1, zero-cycle hold)	1.8	–	–	ns	
TDM Receive Timing							
SID1005	t_{SR}	Setup on RX_SD/RX_FSYNC (WS) before the 1st edge following the driving edge of RX_CLK	$0.2 \times t_{SCLK}$	–	–	ns	Guaranteed by Design Setup time is independent from RX_IF_CTL.LATE_SAMPLE, RX_IF_CTL.LATE_CAPTURE and SCK_POLARITY setting
SID1006	t_{HR}	Hold on RX_SD/RX_FSYNC (WS) after the 1st edge following the driving edge of RX_CLK	0	–	–	ns	Guaranteed by Design Sampling edge w.r.t driving edge of RX_SCLK: 1st edge ($0.5 \times t_{SCLK}$) RX-Master: RX_IF_CTL.LATE_SAMPLE = 0, RX_IF_CTL.LATE_CAPTURE = 0b00 RX-Slave: SCK_POLARITY = 0
SID1006A	t_{HR}	Hold on RX_SD/RX_FSYNC (WS) after the 2nd edge following the driving edge of RX_CLK	0	–	–	ns	Guaranteed by Design Sampling edge w.r.t driving edge of RX_SCLK: 2nd edge ($1 \times t_{SCLK}$) RX-Master: RX_IF_CTL.LATE_SAMPLE = 1, RX_IF_CTL.LATE_CAPTURE = 0b00 RX-Slave: SCK_POLARITY = 1
SID1006B	t_{HR}	Hold on RX_SD/RX_FSYNC (WS) after the 3rd edge following the driving edge of RX_CLK	0	–	–	ns	Guaranteed by Design Sampling edge w.r.t driving edge of RX_SCLK: 3rd edge ($1.5 \times t_{SCLK}$) RX-Master: RX_IF_CTL.LATE_SAMPLE = 0, RX_IF_CTL.LATE_CAPTURE = 0b01 RX Slave: Not Applicable
TDM Transition Timing							
SID1007	t_{SCLK_TRANS}	SCLK input/output transition timing	–	–	$0.15 \times t_{SCLK}$	ns	Guaranteed by design
SID1008	t_{MCLK_TRANS}	MCLK input/output transition timing	–	–	$0.15 \times t_{SCLK}$	ns	Guaranteed by design
SID1009	t_{DATA_TRANS}	DATA input/output transition timing	–	–	$0.15 \times t_{SCLK}$	ns	Guaranteed by design
(PCM) PWM							
Recommended I/O configuration: HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b011, CFG_SLEW_EXT/SLEW<0:0> = 0b0							
SID1100_1	t_{PW_1}	Pulse width on CH1_P, CH1_N, CH2_P, CH2_N for HSIO_STDLN	8	–	–	ns	PWM clock ≤ 100 MHz, min pulse width nom. 10 ns – 20% max distortion Guaranteed by design
SID1101	f_{PWM}	PWM sample frequency	15	–	60	kHz	Guaranteed by design
SID1110	t_{MCLK}	Master clock input period	10	–	–	ns	Guaranteed by design
SID1111	t_{MCLKI_DUTY}	Master clock input duty cycle	40	–	50	%	Guaranteed by design
Sound Generator							
Recommended I/O configuration: GPIO_STD: CFG_OUT/DRIVE_SEL<1:0> = 0b01 GPIO_ENH: CFG_OUT/DRIVE_SEL<1:0> = 0b01 GPIO_SMC: CFG_OUT/DRIVE_SEL<1:0> = 0b01 HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b011, CFG_SLEW_EXT/SLEW<0:0> = 0b0							
SID1102	f_{PWM}	PWM sample frequency	15	–	60	kHz	Guaranteed by design
SID1103	t_{MCLK}	Master clock input period	10	–	–	ns	Guaranteed by design
SID1104	t_{MCLKI_DUTY}	Master clock input duty cycle	40	–	50	%	Guaranteed by design

Table 26-33 Sound Subsystem Specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
AudioDAC							
SID1300	f_{CLKDA0}	System clock frequency	2.048	–	18.432	MHz	All parameters specified $f_S = 44.1$ kHz, system clock $256 \times f_S$ and 16-bit data, $R_L = 20$ k Ω , $C_L = 100$ pF, unless otherwise noted
SID1301	f_S	Sampling clock	8	–	48	kHz	
SID1302	R_L	Analog output load resistance	20	–	–	k Ω	DAC_L, DAC_R
SID1303	C_L	Analog output load capacitance	–	–	100	pF	DAC_L, DAC_R
SID1304	C_{COM}	Com Capacitance	2.2	–	10	μ F	C_L, C_R
SID1305	V_{OUT_MAX}	Analog output single-end output range ($\pm$ full scale)	$0.655 \times V_{DDA_DAC}$	$0.673 \times V_{DDA_DAC}$	$0.690 \times V_{DDA_DAC}$	$V_{P,P}$	DAC_L, DAC_R, $R_L = 20$ k Ω , $C_L = 100$ pF
SID1306	V_{OUT_ZERO}	Analog output voltage (zero)	$0.49 \times V_{DDA_DAC}$	$0.5 \times V_{DDA_DAC}$	$0.51 \times V_{DDA_DAC}$	V	DAC_L, DAC_R
SID1307	THD + N	THD + N (Signal to Noise + Distortion ratio)	–	–82	–72	dB	These values do not include the noise caused by the analog power supply. Signal frequency: 1 kHz LPF (f_C : 20 kHz)
SID1308	SNR	Signal to Noise ratio	85	89	–	dB	These values do not include the noise caused by the analog power supply. Signal frequency: 1 kHz LPF (f_C : 20 kHz) A-weighting filter
SID1309	DR	Dynamic range	83	86	–	dB	These values do not include the noise caused by the analog power supply. Signal frequency: 1 kHz LPF (f_C : 20 kHz) A-weighting filter
SID1310	GAIN_MM	Gain mismatch between channels	–	–	0.4	dB	Signal frequency: 1 kHz
SID1312	CH_SEP	Channel Separation	–	80	–	dB	
SID1313	Z_{OUT}	Output impedance	150	200	250	Ω	
SID1314	PSRR_50	PSRR @ 50 Hz, digital input = 0	–	–35	–	dB	Digital input: zero noise 50 Hz
SID1315	PSRR_1K	PSRR @ 1 kHz, digital input = 0	–	–50	–	dB	Digital input: zero noise 1kHz
SID1316	PSRR_20K	PSRR @ 20 kHz, digital input = 0	–	–40	–	dB	Digital input: zero noise 20 kHz
SID1318	I_{DD}	Supply current normal operation	–	2.2	3.2	mA	
SID1319	I_{DD_OFF}	Supply current power-down	–	1	100	μ A	Typ: $T_A = 25^\circ\text{C}$, $V_{DDA_DAC} = 5.0$ V, process typ (TT) Max: $T_A = 105^\circ\text{C}$, $V_{DDA_DAC} = 5.5$ V, process worst (FF) For S-grade devices
SID1319_125	I_{DD_OFF}	Supply current power-down	–	1	100	μ A	Typ: $T_A = 25^\circ\text{C}$, $V_{DDA_DAC} = 5.0$ V, process typ (TT) Max: $T_A = 125^\circ\text{C}$, $V_{DDA_DAC} = 5.5$ V, process worst (FF) For E-grade devices
SID1320	t_{START}	Startup Time	–	–	70	ms	C_L and C_R should be 2.2 μ F

26.13 CXPI specifications

Table 26-34 CXPI specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/ conditions
SID1400	$f_{\text{CLK_AHB}}$	CLK_PERI clock frequency	–	–	100	MHz	Guaranteed by design, AHB Interface clock
SID1402	$t_{\text{BIT_CONT}}$	Width of clock disparity against the bit width $t_{\text{BIT_REF}}$ of nominal signaling rate	–0.5	–	+0.5	%	Guaranteed by design
SID1403	$t_{\text{RX_0_HI_CONT}}$	The time that should be detected the receiving node is HIGH level.	0.02	–	–	t_{BIT}	$t_{\text{BIT}} = 1 / f_{\text{BRC}}$, Guaranteed by design
SID1404	$t_{\text{TX_DIF_CONT}}$	Difference of width of LOW-level at the constant threshold that receiving node should discriminate logic '1' and logic '0'	0.05	–	–	t_{BIT}	$t_{\text{BIT}} = 1 / f_{\text{BRC}}$, Guaranteed by design $t_{\text{TX_DIF_CONT}} = t_{\text{TX_0_LO}} - t_{\text{TX_1_LO}}$
SID1405	$t_{\text{TX_0_PD_CONT}}^{[78]}$	At the time of logical value '0' outputs, time from the LOW level detection of the communication bus unit falling the voltage "TH_dom".	–	–	0.01	t_{BIT}	$t_{\text{BIT}} = 1 / f_{\text{BRC}}$, CTL0.FILTER_EN bit = '0', Guaranteed by design
SID1406	$t_{\text{TX_0_PD_CONT}}^{[78]}$	At the time of logical value '0' outputs, time from the LOW-level detection of the communication bus unit falling the voltage "TH_dom".	–	–	0.0125	t_{BIT}	$t_{\text{BIT}} = 1 / f_{\text{BRC}}$, CTL0.FILTER_EN bit = '1', Guaranteed by design
SID1407	$t_{\text{RX_0_FF_CONST}}$	Delay from external serial data input pin to a flop. This is a standard to satisfy AC.11.	–	–	20	ns	Guaranteed by design
SID1408	$t_{\text{TX_0_FF_CONST}}$	Delay from a flop to external serial data output pin. This is a standard to satisfy AC.11.	–	–	80	ns	Guaranteed by design
SID1409	BR	Bit rate	–	–	20	kbps	
SID1411	OS	Oversampling factor	–	–	400		

Note

78.The AC spec according to CXPI controller specification is maximum $0.01 t_{\text{BIT}}$. The AC spec, according to the CXPI system specification, including transceiver or driver/receiver is maximum $0.1 t_{\text{BIT}}$.

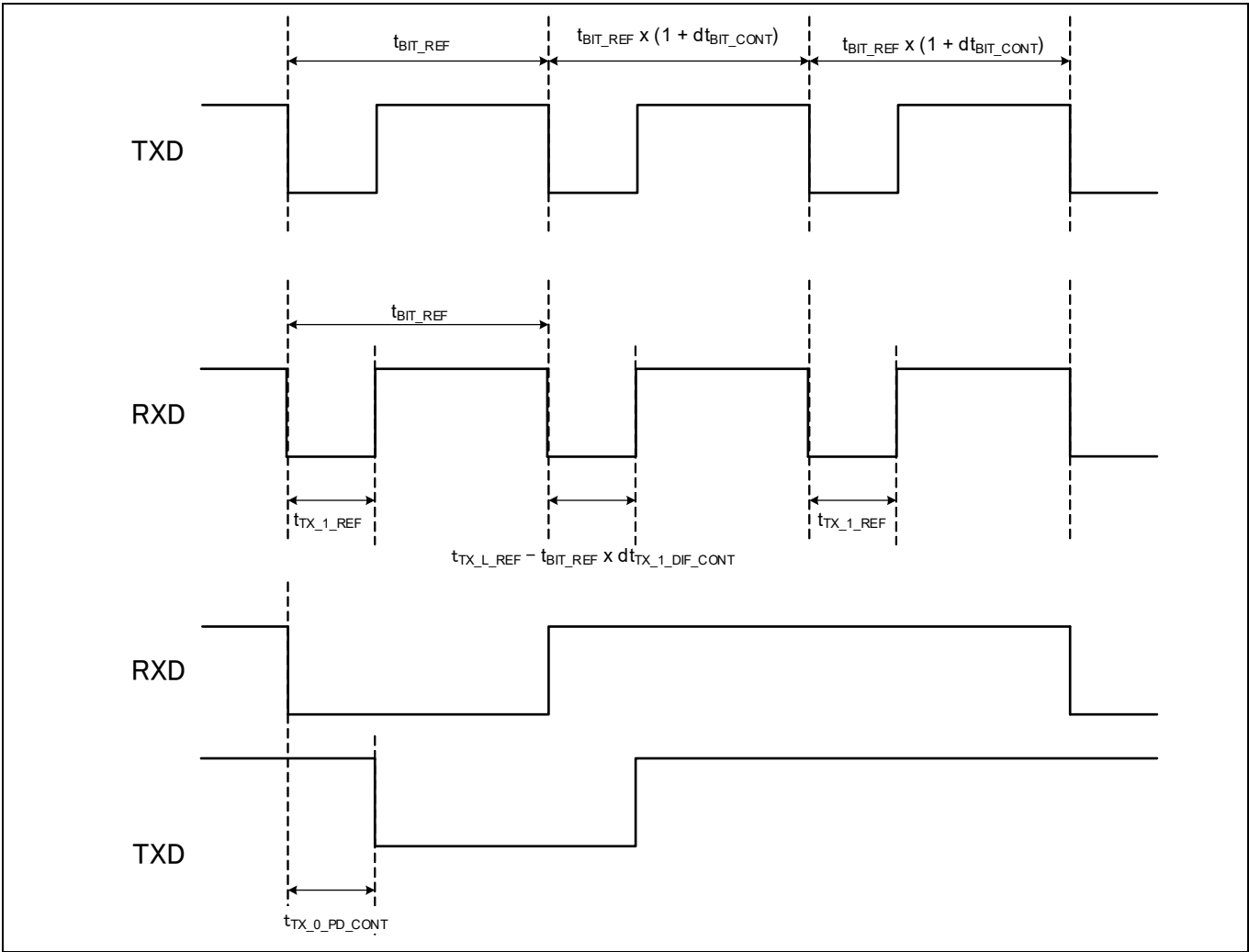


Figure 26-1 CXPI specifications

26.14 Serial memory interface specifications

Table 26-35 xSPI specifications

Spec ID	Parameter	Description	Min	Max	Min	Max	Units
xSPI (JEDEC JESD251)			xSPI266		xSPI200		
Recommended I/O configuration: xSPI266: HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b000, CFG_IN_AUTOLVL/VTRIP_SEL<0:0>= 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG_SLEW_EXT/SLEW<0:0> = 0b0 (single and dual slave [load ≤ 15 pF]) xSPI200: HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b001, CFG_IN_AUTOLVL/VTRIP_SEL<0:0>= 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG_SLEW_EXT/SLEW<0:0> = 0b0 (single and dual slave [load ≤ 15 pF])							
SID1500_2	t _{CK}	Interface clock period (JEDEC)	7.5	–	10	–	ns
SID1500_2CM	t _{CK}	Interface clock period (CMOS)	7.5	–	10	–	ns
SID1501_2	t _{CKDCD}	Allowable clock distortion ^[79]	–	0.05 × t _{CK}	–	0.05 × t _{CK}	ns
SID1502_2	t _{CKMPW}	Minimum clock pulse width (JEDEC)	3.375	–	4.5	–	ns
SID1502_2CM	t _{CKMPW}	Minimum clock pulse width (CMOS)	3.375	–	4.5	–	ns
SID1503_2HV	OUT_SR	Output slew rate with respect to V _{OH} /V _{OL}	1.37	–	1.03	–	V/ns
SID1504_2	t _{OSU}	Output setup time of DS and I/O[7:0] to CK	0.9	–	1.1	–	ns
SID1505_2	t _{OH}	Output hold time of DS and I/O[7:0] to CK	0.9	–	1.1	–	ns
SID1506_2HV	IN_SR	Input slew rate with respect to V _{IH} /V _{IL}	1.37	–	1.03	–	V/ns
SID1507_2	t _{DSMPW}	Input min pulse width of DS (JEDEC)	3.075	–	4.1	–	ns
SID1507_2CM	t _{DSMPW}	Input min pulse width of DS (CMOS)	3.075	–	4.1	–	ns
SID1508_2	t _{RQ}	Input DS to I/O[7:0] valid time (JEDEC)	–	0.675	–	0.9	ns
SID1508_2CM	t _{RQ}	Input DS to I/O[7:0] valid time (CMOS)	–	0.675	–	0.9	ns
SID1509_2	t _{RQH}	Input I/O[7:0] invalid to DS time (JEDEC)	–	0.675	–	0.9	ns
SID1509_2CM	t _{RQH}	Input I/O[7:0] invalid to DS time (CMOS)	–	0.675	–	0.9	ns
SID1511_2	t _{CKLCSL}	CK LOW to CS LOW	6	–	8	–	ns
SID1512_2	t _{CSLCKH}	CS LOW to CK HIGH	6	–	8	–	ns
SID1513_2	t _{CKLCSH}	CK LOW to CS HIGH	6	–	8	–	ns
SID1514_2	t _{CSHCKH}	CS HIGH to CK HIGH	6	–	8	–	ns
SID1515_2	t _{DSLCSH}	DS LOW to CS HIGH	6	–	8	–	ns
SID1516_2	t _{CSHDST}	CS HIGH to DS High-Z	–	7.5	–	10	ns
SID1517_2	t _{CSLDSL}	CS LOW to DS LOW	0	–	0	–	ns
SID1518_2	t _{DSTCSL}	DS High-Z to CS LOW	0	–	0	–	ns

Table 26-36 xSPI (JEDEC JESD251) Delay tap recommended configuration

Feature	xSPI266	xSPI200
	Rx	Rx
Delay Tap Selection (SMIF_DEVICE_DELAY_TAP_SEL/DELAY_TAPS_NR_LOG2<7:0>) for SMIF0	1	6
Delay Line Selection (SMIF_CTL/DELAY_LINE_SEL<2:0>) for SMIF0	0	0
Delay Tap Selection (SMIF_DEVICE_DELAY_TAP_SEL/DELAY_TAPS_NR_LOG2<7:0>) for SMIF1	1	6
Delay Line Selection (SMIF_CTL/DELAY_LINE_SEL<2:0>) for SMIF1	0	0

Note

79.PLL#400 with SSCG = 0, fractional divider = off.

Table 26-37 Input, output supported voltage reference levels

Signal	Supported modes for voltage reference levels	
	CMOS	JEDEC
<i>Clock</i>	$V_T = (50\% \times V_{DDIO_HSIO})$	
<i>RWDS (output)</i>	$V_T = (50\% \times V_{DDIO_HSIO})$	$V_{OH}/V_{OL} = 70\% / 30\% \times V_{DDIO_HSIO}$
<i>DQ[7:0] (output)</i>	$V_T = (50\% \times V_{DDIO_HSIO})$	$V_{OH}/V_{OL} = 70\% / 30\% \times V_{DDIO_HSIO}$
<i>RWDS (input)</i>	$V_T = (50\% \times V_{DDIO_HSIO})$	
<i>DQ[7:0] (input)</i>	$V_T = (50\% \times V_{DDIO_HSIO})$	$V_{IH}/V_{IL} = 70\% / 30\% \times V_{DDIO_HSIO}$

Notes:

- One of the modes (“CMOS”, “JEDEC”) needs to be selected depending on the requirements of the actual memory.
- Some parameters may be available and listed separately for the individual modes. The corresponding mode will be mentioned in the parameter description.
- Parameters without explicit mode description (e.g. t_{OSU}) are applicable for all modes but the voltage reference level as per the table still applies.

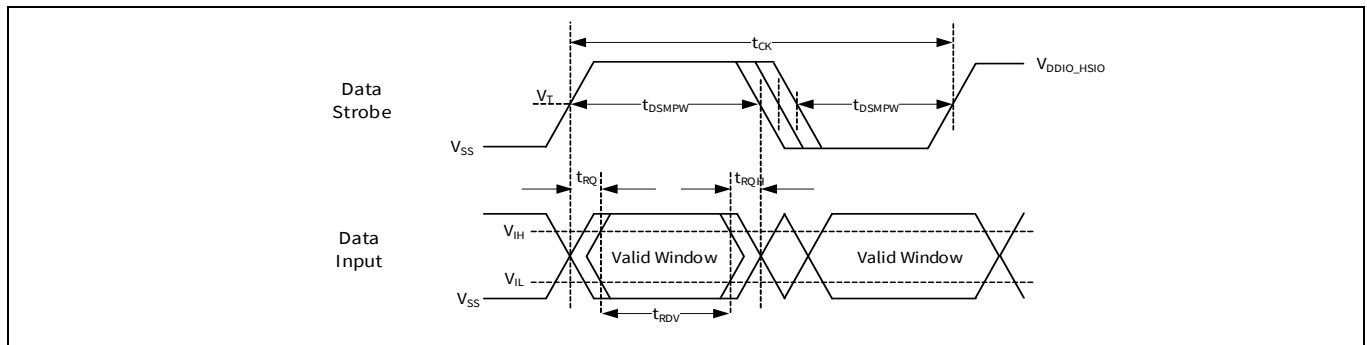


Figure 26-2 xSPI master data input timing reference level (JEDEC)

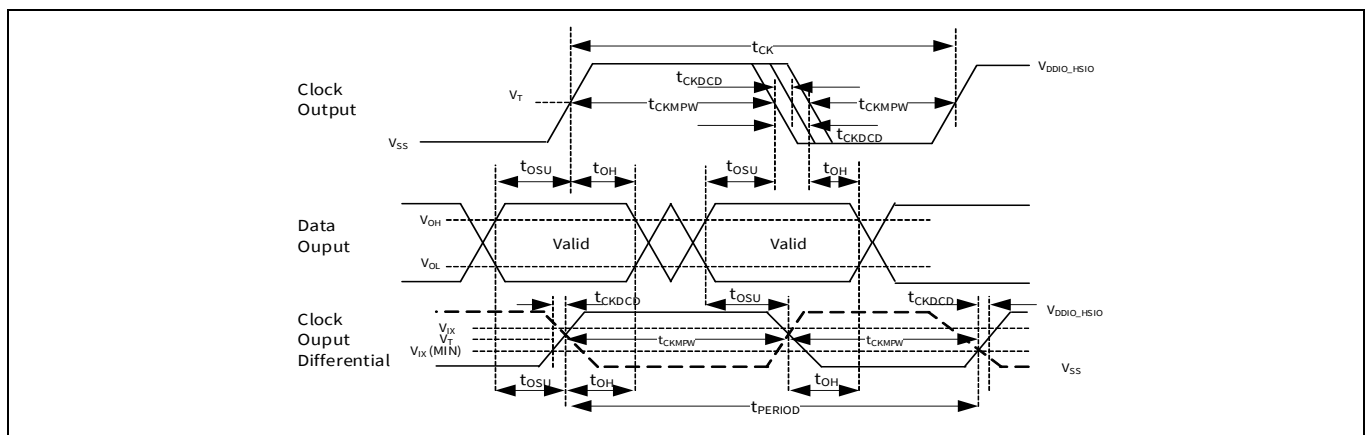


Figure 26-3 xSPI master data output timing reference level (JEDEC)

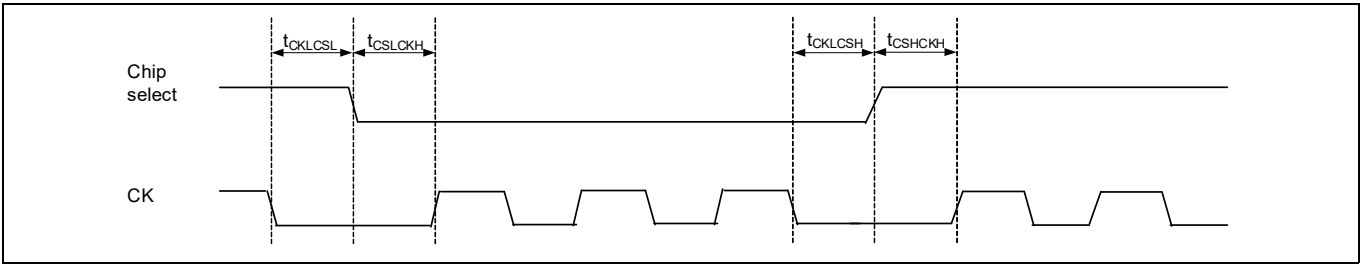


Figure 26-4 xSPI clock to chip select timing diagram

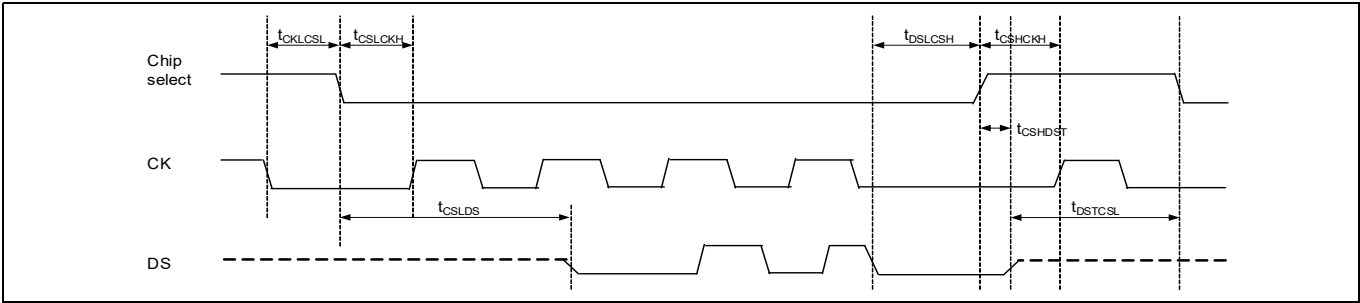


Figure 26-5 xSPI data strobe to chip select timing diagram

Electrical specifications

Table 26-38 Standard SPI specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
Standard SPI SDR							
Recommended I/O configuration:							
HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b001, CFG_IN_AUTOLVL/VTRIP_SEL<0:0>= 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG_SLEW_EXT/SLEW<0:0> = 0b0							
DLL Tap settings for RX:							
SMIF_CTL/DELAY_LINE_SEL<2:0> = 0, SMIF_DEVICE_DELAY_TAP_SEL/DELAY_TAPS_NR_LOG2<7:0> = 2							
All timings aligned with respect to $V_T = (50\% \times V_{DDIO_HSIO})$.							
SID1600_2 ^[80]	t_{CK}	Interface clock period	10	–	–	ns	15-pF output loads
SID1601	t_{CKPW}	Clock pulse width	$0.45 \times t_{CK}$	–	$0.55 \times t_{CK}$	ns	15-pF output loads
SID1602_HS	t_{CSS}	CS# active setup to CK ($f_{CK} > 50$ MHz)	4	–	–	ns	15-pF output loads, $f_{CK} > 50$ MHz Guaranteed by design
SID1602_LS	t_{CSS}	CS# active setup to CK ($f_{CK} \leq 50$ MHz)	5	–	–	ns	15-pF output loads, $f_{CK} \leq 50$ MHz Guaranteed by design
SID1603	t_{CSH0}	CS# active hold to CK (mode 0)	4	–	–	ns	15-pF output loads Guaranteed by design
SID1604	t_{CSH3}	CS# active hold to CK (mode 3)	6	–	–	ns	15-pF output loads Guaranteed by design
SID1605_2	t_{OSU}	Output setup time of DQ[7:0] to CK high ($f_{CK} = 100$ MHz)	2.1	–	–	ns	15-pF output loads For other frequencies: $t_{OSU} = t_{OSU_min} + 0.45 \times (t_{CK} - t_{CK_min})$ t_{OSU_min} = value at MIN of SID1605_2 t_{CK_min} = value at MIN of SID1600_2 t_{CK} = actual clock period
SID1606_2	t_{OH}	Output hold time of DQ[7:0] to CK high ($f_{CK} = 100$ MHz)	2.1	–	–	ns	15-pF output loads For other frequencies: $t_{OH} = t_{OH_min} + 0.45 \times (t_{CK} - t_{CK_min})$ t_{OH_min} = value at MIN of SID1606_2 t_{CK_min} = value at MIN of SID1600_2 t_{CK} = actual clock period
SID1607	t_{IN_V}	CK edge low to DQ[7:0] input valid time	1	–	6.7	ns	CTL/DELAY_TAP_ENABLE=1 (Delay line is enabled) Three options 1) CTL/CLOCK_IF_RX_SEL<2:0> = 0b011 2) CTL/CLOCK_IF_RX_SEL<2:0> = 0b100 or 0b101 CTL/INT_CLOCK_DL_ENABLED<0:0> = 0b0 CTL/INT_CLOCK_CAPTURE_CYCLE<1:0> = 0b01 3) CTL/CLOCK_IF_RX_SEL<2:0> = 0b100 or 0b101 CTL/INT_CLOCK_DL_ENABLED<0:0> = 0b1 CTL/INT_CLOCK_CAPTURE_CYCLE<1:0> needs to be adjusted based on INTR/DL_WARNING

Electrical specifications

Table 26-38 Standard SPI specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID1607A	t_{ISU}	DQ[7:0] input setup time	1.25	–	–	ns	CTL/DELAY_TAP_ENABLE=0 (Delay line is disabled/bypassed) CTL/CLOCK_IF_RX_SEL<2:0> = 0b011
SID1608	t_{IH}	DQ[7:0] input hold time	1.5	–	–	ns	CTL/DELAY_TAP_ENABLE=0 (Delay line is disabled/bypassed) CTL/CLOCK_IF_RX_SEL<2:0> = 0b011
SID1609	t_{RDV}	Input data valid time of DQ[7:0]	3.8	–	–	ns	CTL/DELAY_TAP_ENABLE=1 (Delay line is enabled) Three options 1) CTL/CLOCK_IF_RX_SEL<2:0> = 0b011 2) CTL/CLOCK_IF_RX_SEL<2:0> = 0b100 or 0b101 CTL/INT_CLOCK_DL_ENABLED<0:0> = 0b0 CTL/INT_CLOCK_CAPTURE_CYCLE<1:0> = 0b01 3) CTL/CLOCK_IF_RX_SEL<2:0> = 0b100 or 0b101 CTL/INT_CLOCK_DL_ENABLED<0:0> = 0b1 CTL/INT_CLOCK_CAPTURE_CYCLE<1:0> needs to be adjusted based on INTR/DL_WARNING
SID1610	t_{CS}	CS# HIGH time (Read)	10	–	–	ns	15-pF output loads Guaranteed by design
SID1610A	t_{CS}	CS# High time (Read when Reset feature and Quad mode are both enabled and aborted transaction)	20	–	–	ns	15-pF output loads Guaranteed by design
SID1610B	t_{CS}	CS# High time (Program / Erase)	50	–	–	ns	15-pF output loads Guaranteed by design
SID1611	t_{DIS}	CS# inactive to output disable time	–	–	8	ns	15-pF output loads Guaranteed by design
SID1613	IN_SR	Input slew rate with respect to V_{IH}/V_{IL}	0.7	–	–	V/ns	–

Standard SPI DDR
Recommended I/O configuration:

HSIO_STDLN: CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b001, CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0, CFG_SLEW_EXT/SLEW<2:0> = 0b000

DLL Tap settings for RX:

SMIF_CTL/DELAY_LINE_SEL<2:0> = 0, SMIF_DEVICE_DELAY_TAP_SEL/DELAY_TAPS_NR_LOG2<7:0> = 2

All timings aligned with respect to $V_T = (50\% \times V_{DDIO_HSIO})$.

SID1700_2 ^[80]	t_{CK}	Interface clock period	12.5	–	–	ns	15-pF output loads
SID1701	t_{CKPW}	Clock pulse width	$0.45 \times t_{CK}$	–	$0.55 \times t_{CK}$	ns	15-pF output loads
SID1702_HS	t_{CSS}	CS# active setup to CK ($f_{CK} > 50$ MHz)	4	–	–	ns	15-pF output loads, $f_{CK} > 50$ MHz Guaranteed by design
SID1702_LS	t_{CSS}	CS# active setup to CK ($f_{CK} \leq 50$ MHz)	5	–	–	ns	15-pF output loads, $f_{CK} \leq 50$ MHz Guaranteed by design
SID1703	t_{CSH0}	CS# active hold to CK (mode 0)	4	–	–	ns	15-pF output loads Guaranteed by design

Note

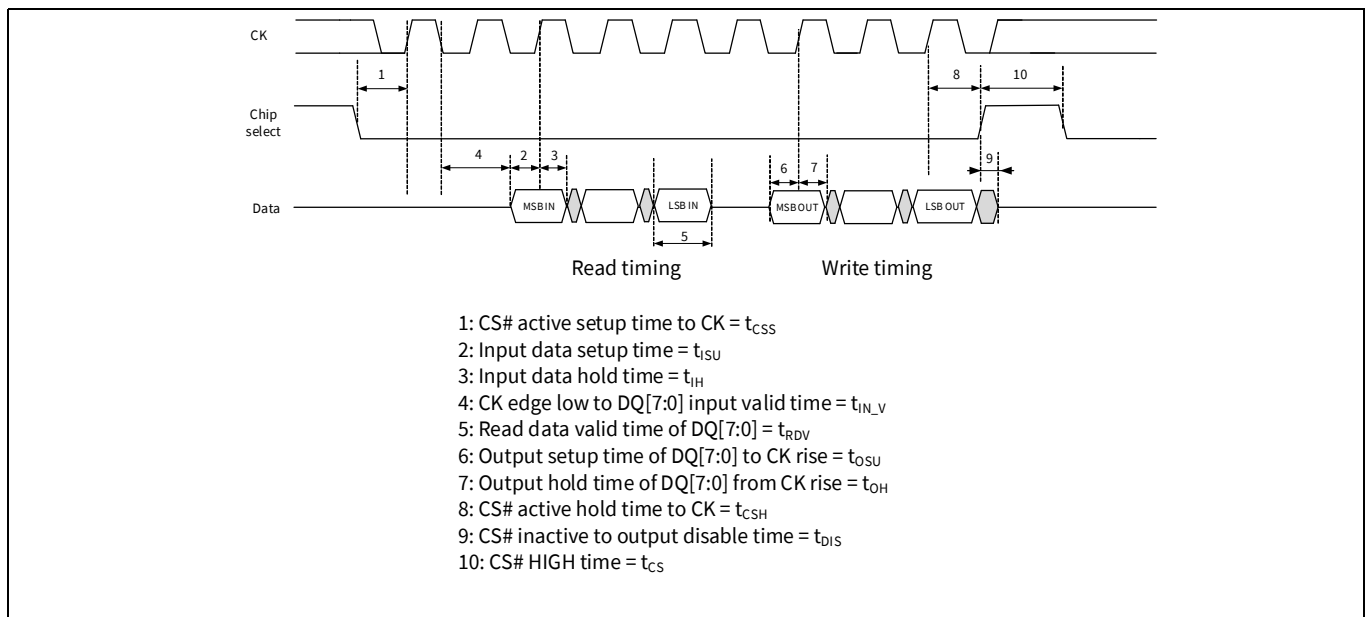
80.Ensure to explicitly configure PLL#400 in Integer mode with "SSCG = OFF", "Fractional = OFF".

Table 26-38 Standard SPI specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID1705_2	t_{OSU}	Output setup time of DQ[7:0] to CK edge ($f_{CK} = 80$ MHz)	2.1	–	–	ns	15-pF output loads For other frequencies: $t_{OSU} = t_{OSU_min} + 0.225 \times (t_{CK} - t_{CK_min})$ t_{OSU_min} = value at MIN of SID1705_2 t_{CK_min} = value at MIN of SID1700_2 t_{CK} = actual clock period
SID1706_2	t_{OH}	Output hold time of DQ[7:0] to CK edge ($f_{CK} = 80$ MHz)	1.6	–	–	ns	15-pF output loads For other frequencies: $t_{OH} = t_{OH_min} + 0.225 \times (t_{CK} - t_{CK_min})$ t_{OH_min} = value at MIN of SID1706_2 t_{CK_min} = value at MIN of SID1700_2 t_{CK} = actual clock period
SID1707	t_{IN_V}	CK edge low to DQ[7:0] input valid time	1	–	6.7	ns	CTL/DELAY_TAP_ENABL E=1 (Delay line is enabled) Three options 1) CTL/CLOCK_IF_RX_SEL<2:0> = 0b011 2) CTL/CLOCK_IF_RX_SEL<2:0> = 0b100 or 0b101 CTL/INT_CLOCK_DL_EN- ABLED<0:0> = 0b0 CTL/INT_CLOCK_CAP- TURE_CYCLE<1:0> = 0b01 3) CTL/CLOCK_IF_RX_SEL<2:0> = 0b100 or 0b101 CTL/INT_CLOCK_DL_EN- ABLED<0:0> = 0b1 CTL/INT_CLOCK_CAP- TURE_CYCLE<1:0> needs to be adjusted based on INTR/DL_WARNING
SID1707A	t_{ISU}	DQ[7:0] input setup time	1.25	–	–	ns	CTL/DELAY_TAP_ENABL E=0 (Delay line is disabled/bypassed) CTL/CLOCK_IF_RX_SEL<2:0> = 0b011
SID1708	t_{IH}	DQ[7:0] input hold time	1.5	–	–	ns	CTL/DELAY_TAP_ENABL E=0 (Delay line is disabled/bypassed) CTL/CLOCK_IF_RX_SEL<2:0> = 0b011

Table 26-38 Standard SPI specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID1709_2	t_{RDV}	Input data valid time of DQ[7:0] ($f_{CK} \leq 80$ MHz)	3.5	–	–	ns	CTL/DELAY_TAP_ENABL E=1 (Delay line is enabled) Three options 1) CTL/CLOCK_IF_RX_SEL< 2:0> = 0b011 2) CTL/CLOCK_IF_RX_SEL< 2:0> = 0b100 or 0b101 CTL/INT_CLOCK_DL_EN- ABLED<0:0> = 0b0 CTL/INT_CLOCK_CAP- TURE_CYCLE<1:0> = 0b01 3) CTL/CLOCK_IF_RX_SEL< 2:0> = 0b100 or 0b101 CTL/INT_CLOCK_DL_EN- ABLED<0:0> = 0b1 CTL/INT_CLOCK_CAP- TURE_CYCLE<1:0> needs to be adjusted based on INTR/DL_WARNING
SID1710	t_{CS}	CS# High time (Read)	10	–	–	ns	15-pF output loads Guaranteed by design
SID1710A	t_{CS}	CS# High time (Read when Reset feature and Quad mode are both enabled and aborted transaction)	20	–	–	ns	15-pF output loads Guaranteed by design
SID1710B	t_{CS}	CS# High time (Program / Erase)	50	–	–	ns	15-pF output loads Guaranteed by design
SID1711	t_{DIS}	CS# inactive to output disable time	–	–	8	ns	15-pF output loads Guaranteed by design
SID1713	IN_SR	Input slew rate with respect to V_{IH}/V_{IL}	0.7	–	–	V/ns	–


Figure 26-6 SDR write and read timing diagram

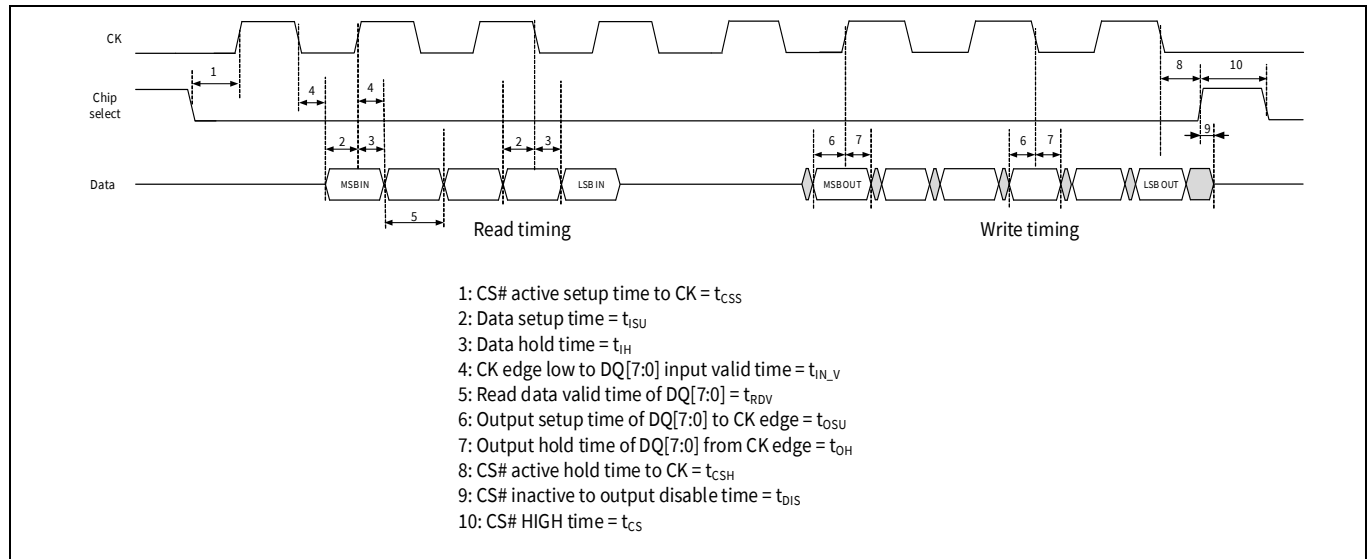


Figure 26-7 DDR write and read timing diagram

26.15 Graphics subsystem specifications

Table 26-39 Graphics specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
Display Output - TTL Mode							
Recommended I/O configuration: HSIO_STDLN (BGA package): CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b010, CFG_SLEW_EXT/SLEW<0:0> = 0b0 HSIO_STDLN (TEQFP package): CFG_DRIVE_EXT<1:0>/DRIVE_SEL_EXT<2:0> = 0b011, CFG_SLEW_EXT/SLEW<0:0> = 0b0 Note: Values are valid for FLL, PLL200 and PLL400 in operation mode Integer, SSCG and Fractional.							
SID866	t _{DC1CYC}	Clock cycle	25	–	–	ns	TTL_DSP1_CLOCK, C _L = 15 pF
SID873	t _{DC1CKPW}	Clock pulse width	0.40 × t _{DC1CYC}	–	0.60 × t _{DC1CYC}	ns	TTL_DSP1_CLOCK pulse width C _L = 15 pF
SID868	t _{DC1S}	Data/control output to TTL_D-SP1_CLOCK time	4	–	–	ns	TTL_DSP1_DATA_A0[11-0] TTL_DSP1_DATA_A1[11-0] TTL_DSP1_CONTROL[11-0] (TCON for FPDLink) C _L = 15 pF
SID869	t _{DC1H}	TTL_DSP1_CLOCK to Data/Control valid time	5	–	–	ns	TTL_DSP1_DATA_A0[11-0] TTL_DSP1_DATA_A1[11-0] TTL_DSP1_CONTROL[11-0] (TCON for FPDLink) C _L = 15 pF
SID890	t _{DSP0_CON-TROL_SKEW}	TTL_DSP0_CONTROL skew	–	–	4	ns	Skew between signals TTL_D-SP0_CONTROL[11-0] C _L = 15 pF
Display Capture							
Recommended I/O configuration: CFG_IN_AUTOLVL/VTRIP_SEL<0:0> = 0b0, CFG_IN/VTRIP_SEL<0:0> = 0b0							
SID875	t _{CAP0CYC}	Display capture Clock Cycle	12.5	–	–	ns	TTL_CAP0_CLK (HSIO)
SID876	t _{CAP0SU}	Display capture data setup time	1.9	–	–	ns	TTL_CAP0_DATA[35-0] (HSIO)
SID877	t _{CAP0HD}	Display capture data hold time	2.7	–	–	ns	TTL_CAP0_DATA[35-0] (HSIO)
FPD Link							
FPD-Link should be used with PLL200 or PLL400 in Integer mode. All values are given with PLL200 or PLL400 with SSCG = OFF, Fractional divider = OFF.							
SID880	I _{VDDA}	Total analog supply current in TX mode	–	–	30	mA	
SID881	I _{VDDPLL}	Total PLL supply current in TX mode	–	–	4	mA	
SID881B	I _{VDDHA}	Total I/O (LVDS driver) supply current in TX mode	–	–	91	mA	
SID884	I _{VDDA_PD}	Total analog supply current in Power-Down mode	–	4	300	μA	Typ: T _A = 25°C, V _{DDA_FPD} = 1.15 V, process typ (TT) Max: T _A = 105°C, V _{DDA_FPD} = 1.21 V, process worst (FF) For S-grade devices
SID884_125	I _{VDDA_PD}	Total analog supply current in Power-Down mode	–	4	300	μA	Typ: T _A = 25°C, V _{DDA_FPD} = 1.15 V, process typ (TT) Max: T _A = 125°C, V _{DDA_FPD} = 1.21 V, process worst (FF) For E-grade devices
SID884_1	I _{VDDA_PD_1}	Total analog supply current in Power-Down mode (room temp)	–	–	5	μA	Max: T _A = 25°C, V _{DDA_FPD} = 1.15 V (max VREG), process worst (FF)
SID884_2	I _{VDDA_PD_2}	Total analog supply current in Power-Down mode	–	–	40	μA	Max: T _A = 85°C, V _{DDA_FPD} = 1.15 V (max VREG), process worst (FF)
SID885	I _{VDDPLL_PD}	Total PLL supply current in Power-Down mode	–	3	200	μA	Typ: T _A = 25°C, V _{DDPLL_FPD} = 1.15 V, process typ (TT) Max: T _A = 105°C, V _{DDPLL_FPD} = 1.21 V, process worst (FF); For S-grade devices

Electrical specifications

Table 26-39 Graphics specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID885_125	I_{VDDPLL_PD}	Total PLL supply current in Power-Down mode	–	3	200	μA	Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDPLL_FPD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 125^{\circ}\text{C}$, $V_{DDPLL_FPD} = 1.21\text{ V}$, process worst (FF); For E-grade devices
SID885_1	$I_{VDDPLL_PD_1}$	Total PLL supply current in Power-Down mode (room temp)	–	–	4	μA	Max: $T_A = 25^{\circ}\text{C}$, $V_{DDPLL_FPD} = 1.15\text{ V}$ (max VREG), process worst (FF)
SID885_2	$I_{VDDPLL_PD_2}$	Total PLL supply current in Power-Down mode	–	–	25	μA	Max: $T_A = 85^{\circ}\text{C}$, $V_{DDPLL_FPD} = 1.15\text{ V}$ (max VREG), process worst (FF)
SID885B	I_{VDDHA_PD}	Total I/O (LVDS driver) supply current in Power-Down mode	–	0.5	50	μA	Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDHA_FPD} = 3.3\text{ V}$, process typ (TT) Max: $T_A = 105^{\circ}\text{C}$, $V_{DDHA_FPD} = 3.6\text{ V}$, process worst (FF); For S-grade devices
SID885B_125	I_{VDDHA_PD}	Total I/O (LVDS driver) supply current in Power-Down mode	–	0.5	50	μA	Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDHA_FPD} = 3.3\text{ V}$, process typ (TT) Max: $T_A = 125^{\circ}\text{C}$, $V_{DDHA_FPD} = 3.6\text{ V}$, process worst (FF); For E-grade devices
SID885B_1	$I_{VDDHA_PD_1}$	Total I/O (LVDS driver) supply current in Power-Down mode (room temp)	–	–	1	μA	Max: $T_A = 25^{\circ}\text{C}$, $V_{DDHA_FPD} = 3.6\text{ V}$ (max VREG), process worst (FF)
SID885B_2	$I_{VDDHA_PD_2}$	Total I/O (LVDS driver) supply current in Power-Down mode	–	–	12	μA	Max: $T_A = 85^{\circ}\text{C}$, $V_{DDHA_FPD} = 3.6\text{ V}$ (max VREG), process worst (FF)
SID895	V_{OD}	Steady-state magnitude of the differential output voltage	247	350	454	mV	
SID896	$V_{\Delta VOD_M}$	Variation of signal swing voltage between drivers	–	–	25	mV	
SID897	V_{CM}	Output Common-mode voltage	1.125	1.25	1.375	V	
SID898	$V_{\Delta VCM_M}$	Delta in Common-mode voltage between drivers	–	–	25	mV	
SID899A	I_{SA}	Magnitude of current flowing through output terminal P when the output terminals are short-circuited to ground.	–	–	24	mA	See Figure 6 of “TIA/EIA-644-A” specifications.
SID899B	I_{SB}	Magnitude of current flowing through output terminal M when the output terminals are short-circuited to ground.	–	–	24	mA	See Figure 6 of “TIA/EIA-644-A” specifications.
SID899C	I_{OS}	Magnitude of current flowing through the output terminals when they are short-circuited to each other.	–	–	12	mA	See Figure 7 of “TIA/EIA-644-A” specifications.
SID900	t_{WAKE}	Wakeup time	–	–	1.2	ms	
SID901	t_{PDD}	Power down delay time	–	–	100	μs	Guaranteed by design
SID902	f_{PX}	Configured pixel clock frequency	7	–	110	MHz	BGA package Guaranteed by design
SID902_3	f_{PX}	Configured pixel clock frequency	7	–	80	MHz	TEQFP package Characterization only
SID903	f_{PX110}	Output clock frequency (110 MHz)	103.7	110	116.3	MHz	BGA only; When transmitting an alternating 0/1 bit pattern
SID904	f_{PX55}	Output clock frequency (55 MHz)	52.35	55	57.65	MHz	When transmitting an alternating 0/1 bit pattern

Electrical specifications

Table 26-39 Graphics specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID905	f _{PX28}	Output clock frequency (28 MHz)	26.66	28	29.34	MHz	When transmitting an alternating 0/1 bit pattern
SID906	f _{PX14}	Output clock frequency (14 MHz)	13.28	14	14.72	MHz	When transmitting an alternating 0/1 bit pattern
SID907	f _{PX7}	Output clock frequency (7 MHz)	6.59	7	7.41	MHz	When transmitting an alternating 0/1 bit pattern
SID908	GAIN_JIT_LVDS	Gain region max long-term total jitter	–	–	0.32	UI2 p-p	
SID909	ATTEN_JIT_LVDS	Attenuation region long-term total jitter	–	–	0.34	UI2 p-p	
SID910	C2C_JIT	Cycle-to-cycle jitter	–	–	0.11	UI	
SID911	t _{CSK}	Channel-to-channel skew of driver outputs	–	–	100	ps	BGA package
SID911_2	t _{CSK}	Channel-to-channel skew of driver outputs	–	–	200	ps	TEQFP package
SID913	TPPos0	Transmit Pulse Position Offset 0	–0.168	0	0.168	ns	
SID914	TPPos1	Transmit Pulse Position Offset 1	T / 7 – TPPos0	T / 7	T / 7 + TPPos0	ns	
SID915	TPPos2	Transmit Pulse Position Offset 2	2T / 7 – TPPos0	2T / 7	T / 7 + TPPos0	ns	
SID916	TPPos3	Transmit Pulse Position Offset 3	3T / 7 – TPPos0	3T / 7	3T / 7 + TPPos0	ns	
SID917	TPPos4	Transmit Pulse Position Offset 4	4T / 7 – TPPos0	4T / 7	4T / 7 + TPPos0	ns	
SID918	TPPos5	Transmit Pulse Position Offset 5	5T / 7 – TPPos0	5T / 7	5T / 7 + TPPos0	ns	
SID919	TPPos6	Transmit Pulse Position Offset 6	6T / 7 – TPPos0	6T / 7	6T / 7 + TPPos0	ns	
SID920	t _{LLHT}	Differential driver rise time	–	–	390	ps	BGA package
SID920_2	t _{LLHT}	Differential driver rise time	–	–	500	ps	TEQFP package
SID921	t _{LHLT}	Differential driver fall time	–	–	390	ps	BGA package
SID921_2	t _{LHLT}	Differential driver fall time	–	–	500	ps	TEQFP package
SID922	t _{RF_MATCH}	Lane-to-lane rise/fall delta	–	–	40	ps	
SID923	f _{PLL}	Input clock frequency of FPD-Link PLL	110	–	220	MHz	–

MIPI/DPHY

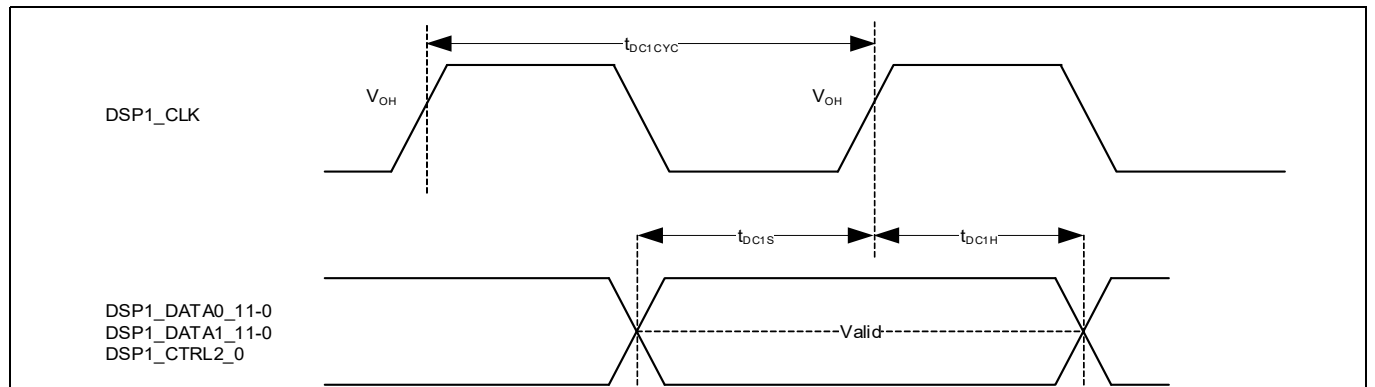
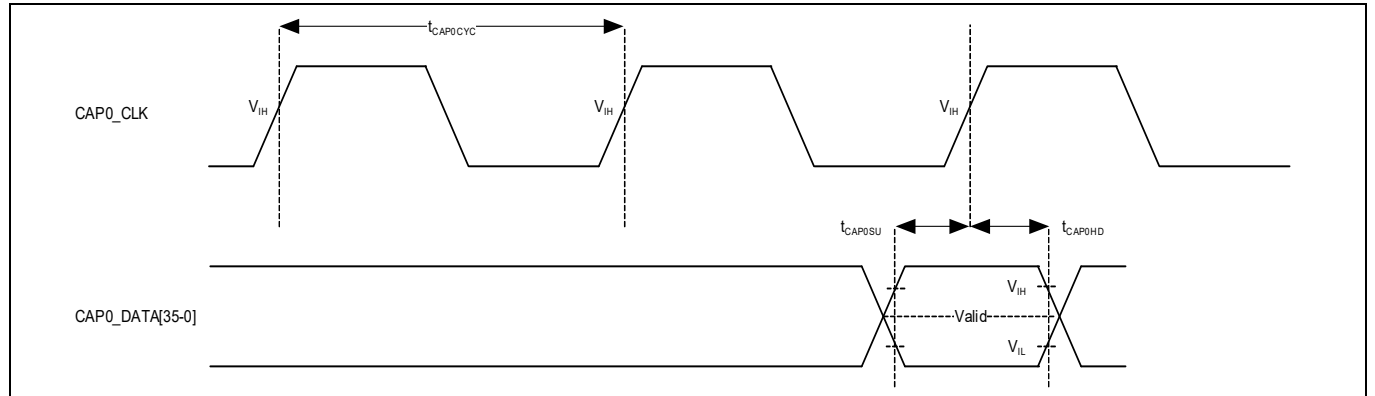
SID1447	f _{PX_QFP}	Pixel clock frequency	–	–	80	MHz	TEQFP package
SID1448	f _{PX_BGA}	Pixel clock frequency	–	–	110	MHz	BGA package
SID1417	V _{CMRX}	Common-mode voltage HS receive mode	70	–	330	mV	
SID1418	V _{IDTH}	Differential input HIGH threshold	70	–	–	mV	
SID1419	V _{IDTL}	Differential Input LOW threshold	–	–	–70	mV	
SID1420	V _{IHHS}	Single-ended input HIGH voltage	–	–	460	mV	
SID1421	V _{ILHS}	Single-ended Input LOW voltage	–40	–	–	mV	
SID1422	Z _{ID}	Differential Input Impedance	80	–	125	Ω	
SID1423	V _{IH_LS}	Logic 1 input voltage LS	–	–	880	mV	
SID1424	V _{IL_LS}	Logic 0 Input voltage LS	550	–	–	mV	

Table 26-39 Graphics specifications (continued)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID1425	V _{HYST}	Input hysteresis	25	–	–	mV	
SID1426	I _{LEAK}	Pin leakage current DPx, DNx, CLKP/N in LP mode	–100	–	100	μA	T _A = 85°C
SID1427	I _{VDDA_LP}	Current in LP	–	–	3	mA	
SID1428	I _{VDDA_PD}	Current when D-PHY powered down	–	8	800	μA	Typ: T _A = 25°C, V _{DDA_MIP1} = 1.15 V, process typ (TT) Max: T _A = 105 °C, V _{DDA_MIP1} = 1.21 V, process worst (FF)
SID1428_1	I _{VDDA_PD_1}	Current when D-PHY powered down (room temp)	–	–	20	μA	Max: T _A = 25°C, V _{DDA_MIP1} = 1.15 V (max VREG), process worst (FF)
SID1428_2	I _{VDDA_PD_2}	Current when D-PHY powered down	–	–	150	μA	Max: T _A = 85°C, V _{DDA_MIP1} = 1.15 V (max VREG), process worst (FF)
SID1429	I _{VDDA_ULP}	Current in ULP	–	–	2	mA	
SID1430	I _{VDDA_HS}	current in HS	–	–	35	mA	
SID1431	t _{CLK_TERM_EN}	Time for the Clock Lane receiver to enable the HS line termination, starting from the time point when Dn crosses VIL,MAX	–	–	38	ns	
SID1432	t _{D_TERM_EN}	Time for the Data Lane receiver to enable the HS line termination, starting from the time point when Dn crosses, VIL,MAX	–	–	38	ns	
SID1433	t _{CLK_SETTLE}	Time interval during which HS receiver should ignore any Clock Lane HS transitions, starting from the beginning of TCLK-PREPARE	95	–	300	ns	
SID1434	t _{HS_SETTLE}	Time interval during which the HS receiver shall ignore any DATA Lane HS transitions, starting from the beginning of THSPREPARE. The HS receiver shall ignore any Data Lane transitions before minimum value, and the HS receiver shall respond to any Data Lane transitions after maximum value	85 + 6 × UI	–	145 + 10 × UI	ns	
SID1435	t _{HS-SKIP}	Time interval during which the HS-RX should ignore any transitions on the Data Lane, following a HS burst. The end point of the interval is defined as the beginning of the LP-11 state following the HS burst.	40	–	55 + 4 × UI	ns	
SID1436	V _{ΔVCMRX_HF}	Common-mode interference	–	–	100	mV	Beyond 450 MHz
SID1437	V _{ΔVCMRX_LF}	Common-mode interference	–	–	50	mV	50 to 450 MHz
SID1438	C _{CM}	Common-mode termination	–	–	60	pF	
SID1439	t _{E_SPIKE}	Input pulse rejection	–	–	300	ps	
SID1440	t _{MIN_RX}	Minimum pulse width response	–	–	20	ns	
SID1441	t _{SETUP_QFP}	Data to clock setup time	0.15	–	–	UI	Valid for TEQFP package
SID1442	t _{HOLD_QFP}	Clock to data hold time	0.15	–	–	UI	Valid for TEQFP package

Table 26-39 Graphics specifications *(continued)*

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/conditions
SID1443	$t_{\text{SETUP_BGA}}$	Data to clock setup time	0.2	–	–	UI	Valid for BGA package
SID1444	$t_{\text{HOLD_BGA}}$	Clock to data hold time	0.2	–	–	UI	Valid for BGA package
SID1445	$I_{\text{VDDA_1P4GB-PS_HS}}$	Current in high speed max frequency	–	–	35	mA	
SID1446	$I_{\text{VDDA_10M_LP}}$	Current in LP mode max frequency	–	–	2	mA	


Figure 26-8 TTL display out timing

Figure 26-9 Video capture timing

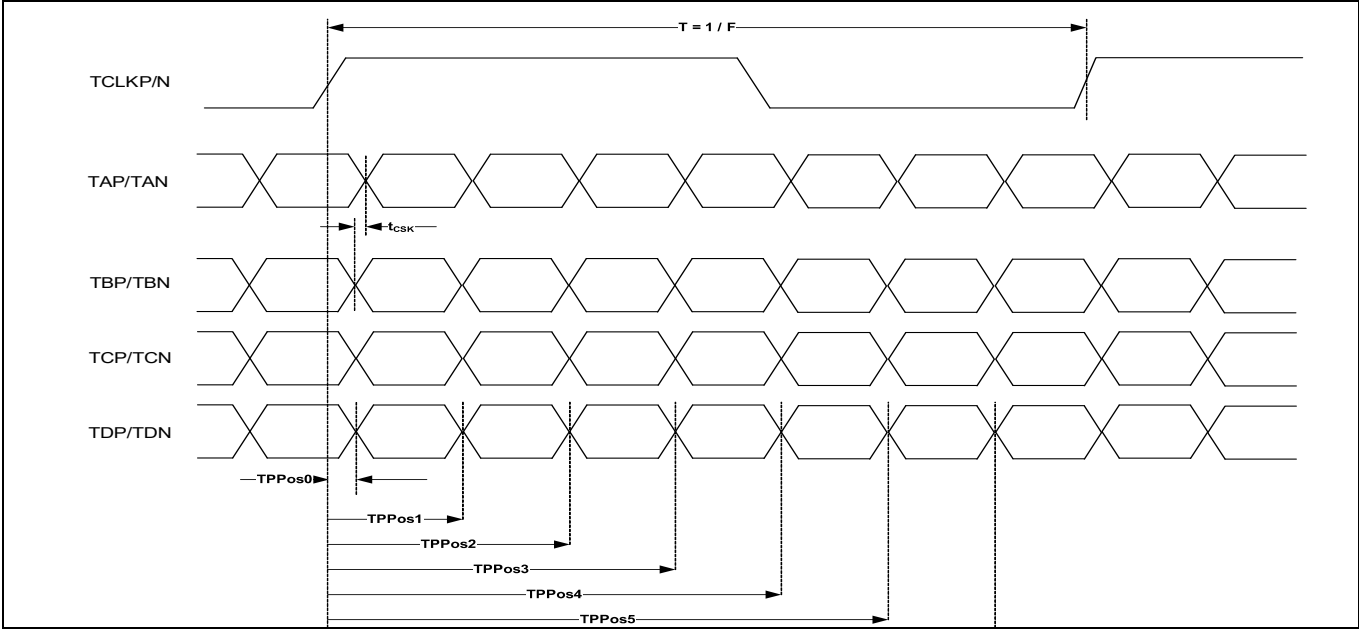


Figure 26-10 FPD-link output pulse position error and channel-to-channel skew

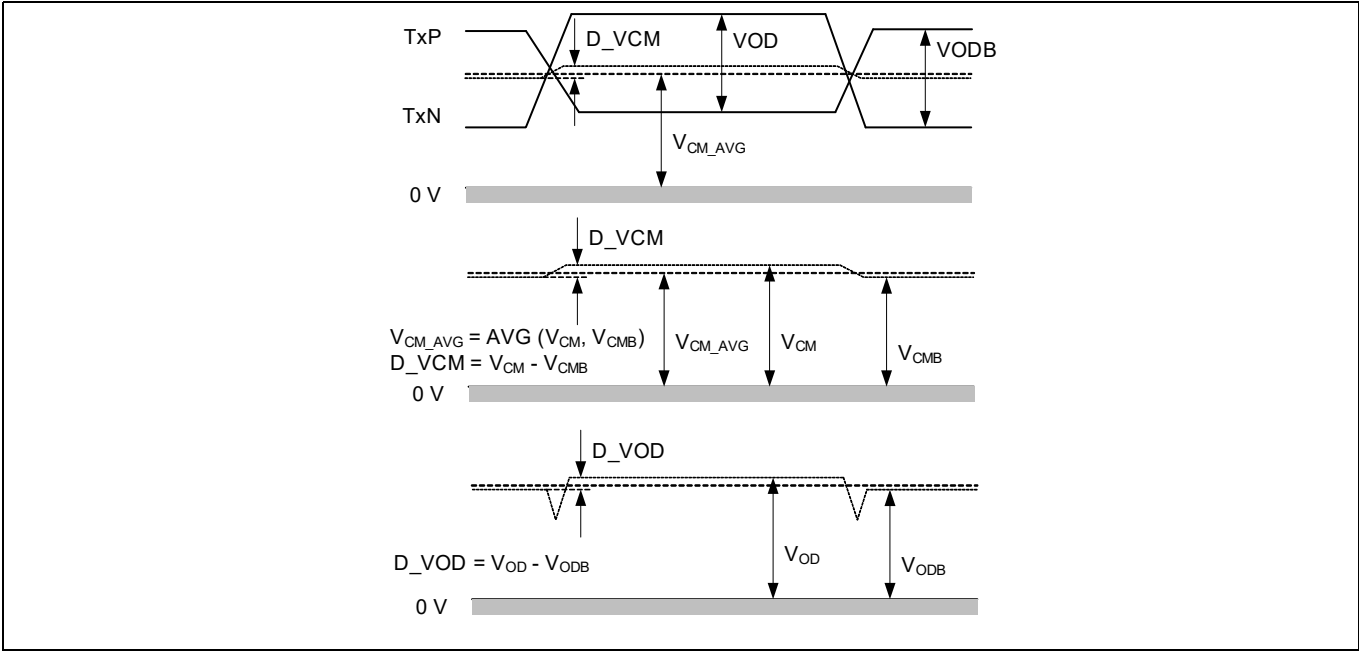


Figure 26-11 Skew between TxP and TxN, and steady-state differential amplitude and common-mode voltages

26.15.1 VIDEOSS capture timing groups

The [Table 26-40](#) lists the capture signals and clocks. AC timing is guaranteed between all clocks and capture signals.

Table 26-40 Capture timing groups

Pin	ACT#6	ACT#11
P13.2	TTL_CAP0_DATA[23]	
P13.3	TTL_CAP0_DATA[22]	TTL_CAP0_DATA[26]
P13.4	TTL_CAP0_DATA[21]	TTL_CAP0_DATA[25]
P13.5	TTL_CAP0_DATA[20]	TTL_CAP0_DATA[24]
P13.6	TTL_CAP0_DATA[19]	TTL_CAP0_DATA[0]
P13.7	TTL_CAP0_DATA[18]	TTL_CAP0_DATA[1]
P14.0	TTL_CAP0_DATA[17]	TTL_CAP0_DATA[2]
P14.1	TTL_CAP0_DATA[16]	TTL_CAP0_DATA[3]
P14.2	TTL_CAP0_DATA[15]	TTL_CAP0_DATA[4]
P14.3	TTL_CAP0_DATA[14]	TTL_CAP0_DATA[5]
P14.4	TTL_CAP0_DATA[13]	TTL_CAP0_DATA[6]
P14.5	TTL_CAP0_DATA[12]	TTL_CAP0_DATA[7]
P14.6	TTL_CAP0_DATA[11]	TTL_CAP0_DATA[8]
P14.7	TTL_CAP0_DATA[10]	TTL_CAP0_DATA[9]
P15.0	TTL_CAP0_CLK	
P15.1	TTL_CAP0_DATA[10]	TTL_CAP0_DATA[9]
P15.2	TTL_CAP0_DATA[11]	TTL_CAP0_DATA[8]
P15.3	TTL_CAP0_DATA[12]	TTL_CAP0_DATA[7]
P15.4	TTL_CAP0_DATA[13]	TTL_CAP0_DATA[6]
P15.5	TTL_CAP0_DATA[14]	TTL_CAP0_DATA[5]
P15.6	TTL_CAP0_DATA[15]	TTL_CAP0_DATA[4]
P15.7	TTL_CAP0_DATA[16]	TTL_CAP0_DATA[3]
P16.0	TTL_CAP0_DATA[17]	TTL_CAP0_DATA[2]
P16.1	TTL_CAP0_DATA[18]	TTL_CAP0_DATA[1]
P16.2	TTL_CAP0_DATA[19]	TTL_CAP0_DATA[0]
P16.3	TTL_CAP0_DATA[20]	TTL_CAP0_DATA[24]
P16.4	TTL_CAP0_DATA[21]	TTL_CAP0_DATA[25]
P16.5	TTL_CAP0_DATA[22]	TTL_CAP0_DATA[26]
P16.6	TTL_CAP0_DATA[23]	

Table 26-41 Capture timing group clocks

Group	Clock	EROS Parameter
Group 0	P15.0	SID875

27 Ordering information

The CYT3DL microcontroller part numbers and features are listed in [Table 27-1](#).

Table 27-1 CYT3DL ordering information^[81]

Base device code	Product	Package	CM7 Cores	Code-flash (KB)	Work-flash (KB)	RAM (KB)	ADC channels	SCB	CAN FD	LIN	CXPI	Ethernet channels	SMIF	Audio DAC	MIPI	Free graphics software ^[86]	Qt bundle ^[89]	Autosar package	Temperature grade	JTAG ID code
CYT3DLBBAS	CYT3DLBBABQ1BZSGS	272-BGA	1	4160 ^[83]	128 ^[85]	384	48	12	4	2	2	1	2	0	0	No	No	No	S ^[86]	0x1E841069 ^[87]
CYT3DLBBBS	CYT3DLBBBQ1BZSGS	272-BGA	1	4160	128	384	48	12	4	2	2	1	2	0	0	No	No	No	S	0x1E842069
CYT3DLBBCS	CYT3DLBBCBQ1BZSGS	272-BGA	1	4160	128	384	48	12	4	2	2	1	2	0	1	No	No	No	S	0x1E843069
CYT3DLBBDS	CYT3DLBBDBQ1BZSGS	272-BGA	1	4160	128	384	48	12	4	2	2	1	2	0	1	No	No	No	S	0x1E844069
CYT3DLBBES	CYT3DLBBEBQ1BZSGS	272-BGA	1	4160	128	384	48	12	4	2	2	1	2	1	0	No	No	No	S	0x1E845069
CYT3DLBBFS	CYT3DLBBFBQ1BZSGS	272-BGA	1	4160	128	384	48	12	4	2	2	1	2	1	0	No	No	No	S	0x1E846069
CYT3DLBBGS	CYT3DLBBGBQ1BZSGS	272-BGA	1	4160	128	384	48	12	4	2	2	1	2	1	1	No	No	No	S	0x1E847069
CYT3DLBBHS ^[82]	CYT3DLBBHBQ1BZSGS	272-BGA	1	4160	128	384	48	12	4	2	2	1	2	1	1	No	No	No	S	0x1E848069
CYT3DLBBSS	CYT3DLBBSBQ1BZSGS	272-BGA	1	4160	128	384	48	12	4	2	2	1	2	1	1	Yes	Yes	No	S	0x1E870069
CYT3DLBBZS	CYT3DLBBZBQ1BZSGS	272-BGA	1	4160	128	384	48	12	4	2	2	1	2	1	1	Yes	No	No	S	0x1E87E069
CYT3DLBBVS	CYT3DLBBVBQ1BZSGS	272-BGA	1	4160	128	384	48	12	4	2	2	1	2	1	1	Yes	Yes	Yes	S	0x1E872069
CYT3DLBBYS	CYT3DLBBYBQ1BZSGS	272-BGA	1	4160	128	384	48	12	4	2	2	1	2	1	1	Yes	No	Yes	S	0x1E873069
CYT3DLABAS	CYT3DLABABQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	0	0	No	No	No	S	0x1E849069
CYT3DLABBS	CYT3DLABBBQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	0	0	No	No	No	S	0x1E84A069
CYT3DLABCS	CYT3DLABCBQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	0	1	No	No	No	S	0x1E84B069
CYT3DLABDS	CYT3DLABDBQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	0	1	No	No	No	S	0x1E84C069
CYT3DLABES	CYT3DLABEBQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	1	0	No	No	No	S	0x1E84D069
CYT3DLABFS	CYT3DLABFBQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	1	0	No	No	No	S	0x1E84E069
CYT3DLABGS	CYT3DLABGBQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	1	1	No	No	No	S	0x1E84F069

Notes

81. Supported shipment types are “Tray” (default) and “Tape and Reel”. Add the character ‘T’ at the end to get the ordering code for “Tape and Reel” shipment type.

82. This part is available as an engineering sample.

83. Code-flash size 4160 KB = 32 KB × 126 (Large Sectors) + 8 KB × 16 (Small Sectors).

84. S-grade temperature (–40°C to 105°C) and E-grade temperature (–40°C to 125°C).

85. Work-flash size 128 KB = 2 KB × 48 (Large Sectors) + 128 B × 256 (Small Sectors).

86. S-grade Temperature (–40°C to 105°C).

87. JTAG ID CODE bits 12 through 27, represents the Silicon ID of the device.

88. [Graphics software](#).

89. Distribution License model by the Qt Company Oy. [About Qt Group](#).



Ordering information

Table 27-1 **CYT3DL ordering information**^[81] *(continued)*

Base device code	Product	Package	CM7 Cores	Code-flash (KB)	Work-flash (KB)	RAM (KB)	ADC channels	SCB	CAN FD	LIN	CXPI	Ethernet channels	SMIF	Audio DAC	MIPI	Free graphics software ^[88]	Qt bundle ^[89]	Autosar package	Temperature grade	JTAG ID code
CYT3DLABHS ^[82]	CYT3DLABHBQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	1	1	No	No	No	S	0x1E850069
CYT3DLABSS	CYT3DLABSBQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	1	1	Yes	Yes	No	S	0x1E871069
CYT3DLABVS	CYT3DLABVBQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	1	1	Yes	Yes	Yes	S	0x1E874069
CYT3DLABYS	CYT3DLABYBQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	1	1	Yes	No	Yes	S	0x1E875069
CYT3DLABZS	CYT3DLABZBQ1AESGS	216-TEQFP	1	4160	128	384	48	12	4	2	2	1	2	1	1	Yes	No	No	S	0x1E87F069

27.1 Part number nomenclature

Table 27-2 Device code nomenclature

Field	Description	Value	Meaning					
CY	Cypress (an Infineon company) prefix	CY						
T	Category	T	TRAVEO™					
F	Family name	3	TRAVEO™ T2G (Core M7 Single)					
A	Application	D	Cluster with 2D Graphics					
D	Code-flash/Work-flash/SRAM quantity	L	4160 KB / 128 KB / 384 KB					
P	Packages	B	272-BGA					
		A	216-TEQFP					
H	Hardware option	B	Security on (HSM), RSA - 3K					
I	Marketing option		Audio DAC	MIPI	2 x Video Out ^[92]	Free graphics software	Qt bundle	Autosar package
		A	No	No	No	No	No	No
		B	No	No	Yes	No	No	No
		C	No	Yes	No	No	No	No
		D	No	Yes	Yes	No	No	No
		E	Yes	No	No	No	No	No
		F	Yes	No	Yes	No	No	No
		G	Yes	Yes	No	No	No	No
		H	Yes	Yes	Yes	No	No	No
		S	Yes	Yes	Yes	Yes ^[90]	Yes	No
		V	Yes	Yes	Yes	Yes	Yes	Yes
		Y	Yes	Yes	Yes	Yes	No	Yes
		Z	Yes	Yes	Yes	Yes ^[91]	No	No
C	Temperature grade	S	S-grade (–40°C to 105°C) and E-grade (–40°C to 125°C)					

Notes

90.Qt runtime, Infineon graphics package (2D Graphics Driver, Safety Signature Driver, Dynamic Warping Library).

91.Infineon graphics package (2D Graphics Driver, Safety Signature Driver, Dynamic Warping Library).

92.A "No" signifies the presence of either FPD-link or RGB video out, and a "Yes" signifies the availability of both FPD-link and RGB video outs.

Table 27-3 Ordering code nomenclature

Field	Description	Value	Meaning
CY	Cypress (an Infineon company) prefix	CY	
T	Category	T	TRAVEO™
F	Family name	3	TRAVEO™ T2G (Core M7 Single)
A	Application	D	Cluster with 2D Graphics
D	Code-flash/Work-flash/SRAM quantity	L	4160 KB / 128 KB / 384 KB
P	Packages	B	272-BGA
		A	216-TEQFP

Notes

93.Qt runtime, Infineon graphics package (2D Graphics Driver, Safety Signature Driver, Dynamic Warping Library).

94.Infineon graphics package (2D Graphics Driver, Safety Signature Driver, Dynamic Warping Library).

95.A "No" signifies that 1x video, either RGB video out or FPD-link is guaranteed, and a "Yes" signifies that 2x video out, that is both RGB video out and FPD-link are guaranteed.

Table 27-3 Ordering code nomenclature (continued)

Field	Description	Value	Meaning					
H	Hardware option	B	Security on (HSM), RSA - 3K					
I	Marketing option		Audio DAC	MIPI	2 x Video Out^[95]	Free graphics software	Qt bundle	Autosar package
		A	No	No	No	No	No	No
		B	No	No	Yes	No	No	No
		C	No	Yes	No	No	No	No
		D	No	Yes	Yes	No	No	No
		E	Yes	No	No	No	No	No
		F	Yes	No	Yes	No	No	No
		G	Yes	Yes	No	No	No	No
		H	Yes	Yes	Yes	No	No	No
		S	Yes	Yes	Yes	Yes ^[93]	Yes	No
		V	Yes	Yes	Yes	Yes	Yes	Yes
		Y	Yes	Yes	Yes	Yes	No	Yes
		Z	Yes	Yes	Yes	Yes ^[94]	No	No
R	Revision	B	First revision (0x13)					
F	Fab location	Q	UMC (Fab 12i) Singapore					
X	Reserved	1	Reserved					
K	Package code	AE	TEQFP					
		BZ	BGA					
C	Temperature grade	S	S-grade (–40°C to 105°C) and E-grade (–40°C to 125°C)					
Q	Quality grade	ES	Engineering samples					
		GS	Standard grade of automotive					
S	Shipment type	Blank	Tray shipment					
		T	Tape and Reel shipment					

Notes

93.Qt runtime, Infineon graphics package (2D Graphics Driver, Safety Signature Driver, Dynamic Warping Library).

94.Infineon graphics package (2D Graphics Driver, Safety Signature Driver, Dynamic Warping Library).

95.A "No" signifies that 1x video, either RGB video out or FPD-link is guaranteed, and a "Yes" signifies that 2x video out, that is both RGB video out and FPD-link are guaranteed.

28 Packaging

CYT3DL microcontroller is offered in the packages listed in the [Table 28-1](#).

Table 28-1 Package information

Package	Dimensions ^[96]	Contact/Lead Pitch	Coefficient of Thermal Expansion	I/O Pins
216-TEQFP	24 × 24 × 1.6 mm (max)	0.4-mm	a1 ^[97] = 8.4 ppm/°C, a2 ^[98] = 29.4 ppm/°C	108
272-BGA	16 × 16 × 1.7 mm (max)	0.8-mm	a1 ^[97] = 11.9 ppm/°C, a2 ^[98] = 34.3 ppm/°C	135

Table 28-2 Package characteristics^[99]

Parameter	Description	Conditions	Min	Typ	Max	Units
T _A	Operating ambient temperature	S-grade	-40	-	105	°C
		E-grade			125	
T _J	Operating junction temperature	216-TEQFP	-	-	145.5	°C
		272-BGA			145	
R _{θJA}	Package thermal resistance, junction to ambient θ _{JA} ^[100]	216-TEQFP	-	-	16.2	°C/Watt
		272-BGA	-	-	17.7	°C/Watt
R _{θJB}	Package thermal resistance, junction to board θ _{JB}	216-TEQFP	-	-	11.9	°C/Watt
		272-BGA	-	-	12.6	°C/Watt
R _{θJC}	Package thermal resistance, junction to case θ _{JC}	216-TEQFP	-	-	2.4	°C/Watt
		272-BGA	-	-	3.0	°C/Watt

Table 28-3 Solder reflow peak temperature, package moisture sensitivity level (MSL), IPC/JEDEC J-STD-2

Package	Maximum Peak Temperature (°C)	Maximum Time at Peak Temperature (seconds)	MSL
216-TEQFP	260	30	3
272-BGA	260	30	3

Notes

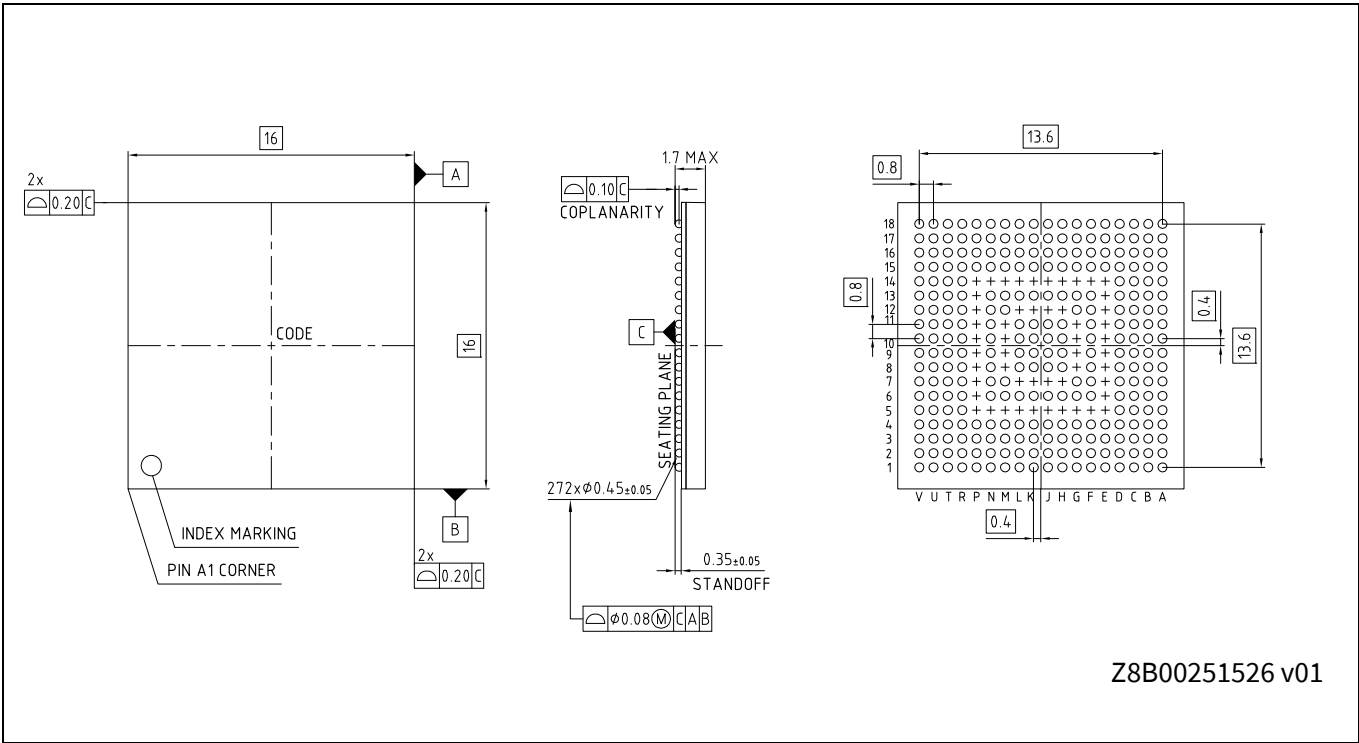
96.The dimensions (column 2) are valid for room temperature.

97.a1 = CTE (Coefficient of Thermal Expansion) value below T_g (ppm/°C) (T_g is glass transition temperature which is 131°C).

98.a2 = CTE value above T_g (ppm/°C).

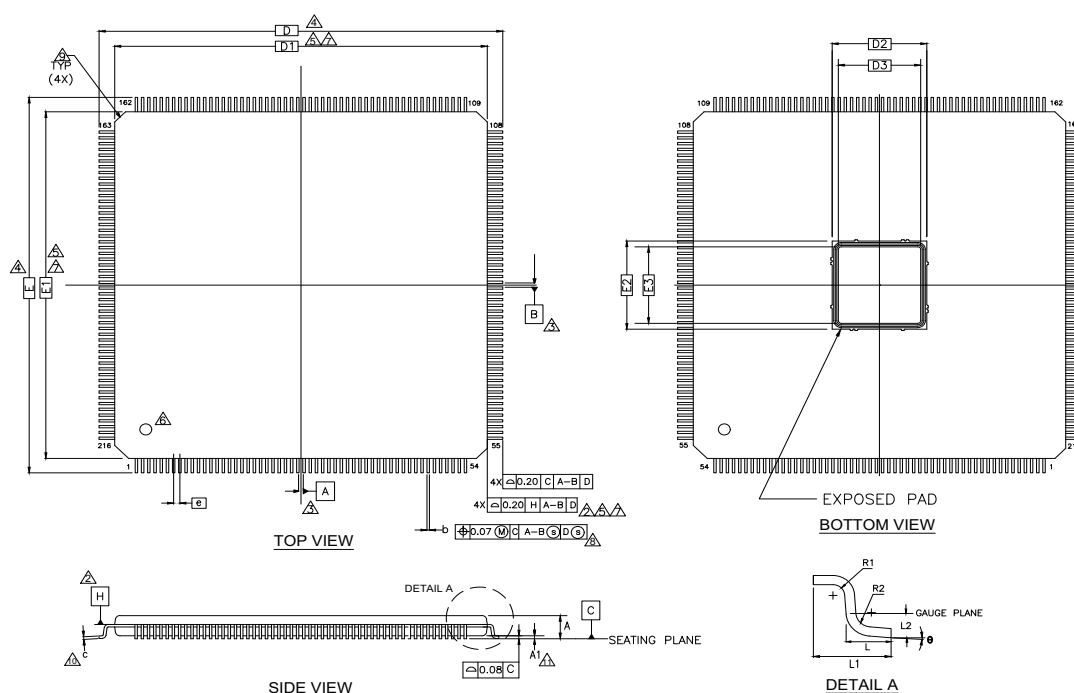
99.Board condition complies to JESD51-7(4 Layers).

100.The T_A and T_J values for the packages will be provided in a later revision of the datasheet.



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Figure 28-1 272-ball FBGA package outline (PG-LFBGA-272)



SYMBOL	DIMENSION		
	MIN.	NOM.	MAX.
A	—	—	1.60
A1	0.05	—	0.15
D	26.00 BSC		
D1	24.00 BSC		
D2	7.40 REF		
D3	6.60 REF		
E	26.00 BSC		
E 1	24.00 BSC		
E 2	7.40 REF		
E 3	6.60 REF		
R 1	0.08	—	—
R 2	0.08	—	0.20
θ	0°	3.5°	7°
c	0.09	0.127	0.20
b	0.13	0.16	0.23
L	0.45	0.60	0.75
L 1	1.00 REF		
L 2	0.25 REF		
e	0.40 BSC		

NOTES

1. ALL DIMENSIONS ARE IN MILLIMETERS.

1. ALL DIMENSIONS ARE IN MILLIMETERS.

△ DATUM PLANE H IS LOCATED AT THE BOTTOM OF THE MOLD PARTING LINE COINCIDENT WITH WHERE THE LEAD EXITS THE BODY.

3 DATUMS A-B AND D TO BE DETERMINED AT DATUM PLANE H.

4. TO BE DETERMINED AT SEATING PLANE C.

5 DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION.

ALLOWABLE PROTRUSION IS 0.25mm PRE SIDE.
DIMENSIONS D1 AND E1 INCLUDE MOLD MISMATCH AND ARE DETERMINED
AT DATUM PLANE H.

⑥ DETAILS OF PIN 1 IDENTIFIER ARE OPTIONAL BUT MUST BE LOCATED WITHIN THE ZONE INDICATED.

REGARDLESS OF THE RELATIVE SIZE OF THE UPPER AND LOWER BODY SECTIONS, DIMENSIONS D1 AND E1 ARE DETERMINED AT THE LARGEST FEATURE OF THE BODY EXCLUSIVE OF MOLD FLASH AND GATE BURRS, BUT INCLUDING ANY MISMATCH BETWEEN THE UPPER AND LOWER SECTIONS OF THE MOLDER BODY.

⚠️ DIMENSION b DOES NOT INCLUDE DAMBER PROTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED b MAXIMUM BY MORE THAN 0.08mm. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE LEAD FOOT.

9. EXACT SHAPE AND SIZE OF THIS FEATURE IS OPTIONAL.

△ THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10mm AND 0.25mm FROM THE LEAD TIP.

11. A1 IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.

002-30407 **

Figure 28-2 216-TEQFP package outline (PG-TQFP-216)

29 Appendix

29.1 External IP revisions

Table 29-1 IP revisions

Module	IP	Revision	Vendor
CANFD	mxttcanfd	M_TTCAN IP revision: Rev.3.2.3	Bosch
Arm® Cortex®-M0+	armcm0p	Cortex-M0+-r0p1	Arm®
Arm® Cortex®-M7	armcm7	Cortex-M7-r1p2	Arm®
Arm® Coresight	armcoresighttk	CoreSight-SoC-TM100-r3p2	Arm®
Ethernet	mxeth	GEM_GXL r1p09	Cadence

29.2 Internal IP revisions

Table 29-2 Internal IP revisions

Module	Revision
SMIF	SMIF version 3.0 (Variant v3.1)

29.3 MIPI formats supported^[101]

Table 29-3 MIPI formats supported

MIPI Format	ID	Remarks
YUV422 8-bit	0x1E	Full processing supported
YUV422 10-bit	0x1F	
RGB888	0x24	
RGB666	0x23	
RGB565	0x22	
RGB555	0x21	
RGB444	0x20	
RAW8	0x2A	Data can be written to VRAM as is, no color processing or format conversion supported.
RAW10	0x2B	
RAW12	0x2C	
RAW14	0x2D	
RAW16	0x2E	
RAW20	0x2F	
Generic 8-bit Long Packet Data Types	0x10	Supported
	0x11	Data can be written to VRAM as is, no color processing or format conversion supported.
User Defined Byte-based Data	0x30 - 0x37	Data can be written to VRAM as is, no color processing or format conversion supported.

Note

101.CYT3DL devices do not support MIPI data ID type 0x12.

30 Acronyms

Table 30-1 Acronyms used in the document

Acronym	Description
A/D	Analog to Digital
ABS	Absolute
ADC	Analog to Digital converter
AES	Advanced encryption standard
AHB	AMBA (advanced microcontroller bus architecture) high-performance bus, Arm® data transfer bus
Arm®	Advanced RISC machine, a CPU architecture
ASIL	Automotive safety integrity level
BOD	Brown-out detection
CAN FD	Controller Area Network with Flexible Data rate
CMOS	Complementary metal-oxide-semiconductor
CPU	Central Processing Unit
CRC	Cyclic redundancy check, an error-checking protocol
CSV	Clock supervisor
DES	Data encryption standard
DW	Dataview same as P-DMA
ECC	Error correcting code
ECO	External crystal oscillator
ETM	Embedded Trace Macrocell
FLL	Frequency Locked Loop
FPU	Floating point unit
GHS	Green hills tool chain with IDE
GPIO	General purpose input/output
HSM	Hardware security module
I/O	Input/output
I ² C	Inter-Integrated Circuit, a communications protocol
ILO	Internal low-speed oscillator
IMO	Internal main oscillator
IPC	Inter-processor communication
IrDA	Infrared interface
IRQ	Interrupt request
JTAG	Joint test action group
LIN	Local Interconnect Network, a communications protocol
LVD	Low voltage detection
OTA	Over-the-air programming
OTP	One-time programmable
OVD	Over voltage detection
P-DMA	Peripheral-Direct Memory Access
PASS	Programmable Analog Subsystem
PLL	Phase Locked Loop

Acronyms

Table 30-1 **Acronyms used in the document** *(continued)*

Acronym	Description
POR	Power-on reset
PPU	Peripheral protection unit
PRNG	Pseudorandom number generator
PSOC™	Programmable system on chip
PWM	Pulse-width modulation
MCU	Microcontroller Unit
MCWDT	Multi-counter watchdog timer
M-DMA	Memory-Direct Memory Access
MISO	Master-in slave-out
MMIO	Memory mapped I/O
MOSI	Master-out slave-in
MPU	Memory protection unit
NVIC	Nested vectored interrupt controller
RAM	Random access memory
RISC	Reduced-instruction-set computing
ROM	Read only memory
RTC	Real-time clock
SAR	Successive approximation register
SCB	Serial communication block
SCL	I ² C serial clock
SDA	I ² C serial data
SHA	Secure hash algorithm
SHE	Secure hardware extension
SMPU	Shared memory protection unit
SPI	Serial peripheral interface, a communications protocol
SRAM	Static random access memory
SWD	Single wire debug
TCM	Tightly Coupled Memory
TCPWM	Timer/Counter Pulse-width modulator
TTL	Transistor-transistor logic
TRNG	True random number generator
UART	Universal Asynchronous Transmitter Receiver, a communications protocol
WCO	Watch crystal oscillator
WDT	Watchdog timer reset
XIP	eXecute In Place
XTAL	Crystal

Revision history

Document revision	Date	Description of changes
**	2020-03-02	New datasheet
*A	2020-06-04	Updated Blocks and functionality . Updated Peripheral I/O map . Updated Pin assignment . Updated Package pin list and alternate functions Updated Power pin assignments Updated Alternate function pin assignments Removed PMIC_VADJ reference throughout. Updated Electrical specifications . Updated VIDEOSS capture timing groups and Table 27-2 . Updated Packaging .
*B	2020-09-14	Updated Features and Features list Updated Timer/Counter/PWM block (TCPWM) . Updated I/Os . Updated Peripheral I/O map . Updated Alternate function pin assignments and Pin function description . Updated Peripheral clocks . Updated Electrical specifications . Updated VIDEOSS capture timing groups . Added Appendix .
*C	12/07/2020	Updated Features list . Updated Peripheral instance list . Updated Electrical specifications . Updated Clock specifications . Updated Packaging .
*D	2021-05-13	Updated Features list . Updated Clock system , Power modes , and I/Os . Added footnote in Pin assignment . Updated Faults . Updated Electrical specifications . Updated VIDEOSS capture timing groups . Updated Appendix .
*E	2021-09-17	Reamed Traveo II to TRAVEO™ T2G. Updated Features list . Corrected links in Functional description . Updated Power pin assignments Updated Alternate function pin assignments Updated Peripheral protection unit fixed structure pairs Updated Electrical specifications . Updated Clock specifications Added Table 26-36 Added Table 26-40 , and Table 26-41 Updated Ordering information Updated Packaging
*F	2022-05-13	Minor change to correct the page layout from pages 166-169.
*G	2022-06-23	Migrated to IFX template Updated Electrical specifications . Updated Clock specifications Updated Ordering information Updated Packaging

Document revision	Date	Description of changes
*H	2023-03-03	Updated Features, Features list, and Peripheral instance list. Updated Peripherals and I/Os. Updated Peripheral I/O map, Pin assignment, and Package pin list and alternate functions. Updated Trigger multiplexer and Triggers one-to-one. Updated Electrical specifications. Updated Part number nomenclature and Packaging.
*I	2024-03-05	Updated Ethernet MAC. Changed description of SID902 and SID902_3 to "Configured Pixel Clock Frequency" Removed text "BGA only;" from the comments of SID904. Changed SID1613 min value from 1.37 to 0.7 V/ns. Added SID1613 and SID1713 in Table 26-38. Added content under FDP-LINK in Table 26-39. Updated IMO connections in Figure 7-1. Updated content for HSIO_STDLN under I2C Interface-Standard-mode, I2C Interface-Fast-mode, and I2C Interface-Fast-Plus mode in Table 26-10. Removed SID68 in Figure 26-3. Updated Errata.
*J	2025-06-24	Updated the code-flash, maximum ambient temperature, and GPIO_STD in Table 1-1. Updated Ethernet MAC. Added +B input in Table 11-1. Updated the following in Table 26-1: - Updated details/conditions for: SID33B, SID26B, SID34, SID34_2 - Added Spec ID: SID33I, SID26B_125, SID33B_125, SID34_125, SID34_2_125, SID36_125 Updated the following in Table 26-3: - Included support for E-grade devices - Updated min and max values for SID606 and SID606A - Updated details/conditions for: SID51C, SID52C, SID50B - Added Spec ID: SID51C_125, SID52C_125, SID50B_125 Updated the following in Table 26-4: - Updated details/conditions for: SID73, SID82, SID83, SID84, SID85 - Added Spec ID: SID73_125, SID82_125, SID83_125, SID84_125, SID85_125 Updated the legends in Figure 26-6. Updated the following in Table 26-5: - Updated details/conditions for: SID670, SID670A, SID670C, SID653B, SID657B, SID676H - Added Spec ID: SID670_125, SID670A_125, SID670C_125, SID653B_125, SID657B_125, SID676H_125 Updated the following in Table 26-7: - Updated details/conditions for: SID104, SID105, SID109, SID109A, SID110, SID111, SID112, SID115, SID115B, SID115D, SID115A, SID115C, SID115E - Added Spec ID: SID104_125, SID105_125, SID109_125, SID109A_125, SID110_125, SID111_125, SID112_125, SID115_125, SID115B_125, SID115D_125, SID115A_125, SID115C_125, SID115E_125

Revision history

Document revision	Date	Description of changes
*J	2025-06-24	Updated the following in Table 26-10: - Added SID129_3 and SID129_4 - Updated the description for SID129_2 Updated the following in Table 26-33: - Updated details/conditions for: SID1319, SID1004, SID1007, SID1008, SID1009 - Added Spec ID: SID1319_125, SID52C_125, SID50B_125, SID Added note and updated the following in Table 26-39: - Updated details/conditions for: SID884, SID885, SID885B - Added Spec ID: SID923, SID884_125, SID885_125, SID885B_125 Updated Table 26-40. Updated the following in Table 27-1: - Added products CYT3DLBBSS, CYT3DLBBVS, CYT3DLBBYS, CYT3DLBBZS, CYT3DLABSS, CYT3DLABVS, CYT3DLABYS, and CYT3DLABZS - Added note [84] to support E-grade devices Added Free graphics software, Qt bundle, and Autosar package columns and marketing option for S, V, Y, and Z values in Table 27-2, and Table 27-3. Update note [93] in Table 27-3. Updated Figure 28-1. Updated the following in Table 28-2: - Updated conditions and max value for T_A, T_J - Updated max values for $R_{\theta JA}$, $R_{\theta JB}$, and $R_{\theta JC}$ Added Revision history change log. Removed Errata.

Revision history change log

Rev. *J Section updates

Section	Change description	Current spec	New spec	Reason for change
1 Features list	Table 1-1 CYT3DL feature list Updated Code-flash	Code-flash 4160 KB (4031 KB + 128 KB)	Code-flash 4160 KB (4032 KB + 128 KB)	Correction
1 Features list	Table 1-1 CYT3DL feature list Updated SMIF (Single SPI / Dual SPI/ Quad SPI / Octal SPI / xSPI)	2 ch (HSIO_STDLN at 133 MHz)	Added as 2 columns : 2 ch (HSIO_STDLN at 100 MHz), 2 ch (HSIO_STDLN at 133 MHz)	Correction
1 Features list	Table 1-1 CYT3DL feature list Updated maximum ambient temperature	105°C for S-grade	105°C for S-grade, 125°C for E-grade	Correction
3.2.4 Clock System	3.2.4.3 PLL and FLL	A PLL (three 200 MHz and five 400 MHz) or FLL may be used to generate high-speed clocks from the IMO, ECO, or an EXT_CLK. The FLL provides a much faster lock than the PLL (5 µs instead of 35 µs) in exchange for a small amount (±2%) of frequency error[9] and a lower max output frequency (100 MHz instead of up to 400 MHz). The 400-MHz PLL supports spread spectrum clock generation (SSCG) with down spreading.	A PLL (three 200 MHz and five 400 MHz) or FLL may be used to generate high-speed clocks from the IMO, ECO, or an EXT_CLK. The FLL provides a much faster lock than the PLL (5 µs instead of 35 µs) in exchange for a small amount (±1%) of frequency error[9] and a lower max output frequency (100 MHz instead of up to 400 MHz). The 400-MHz PLL supports spread spectrum clock generation (SSCG) with down spreading.	Correction
3.3 Peripherals	3.3.9 Ethernet MAC Updated description	CYT3DL supports one Ethernet channel with transfer rates of 10, or 100 Mbps. The input/output frames and flow control are compliant with the Ethernet/IEEE 802.3bw standard and also IEEE-1588 precision-time protocol (PTP). CYT3DL supports full-duplex data transport using external PHY devices. The MAC supports glue-free connection to PHYs through IEEE standard MII, and RMII interfaces. The device also supports Audio-Video Bridging (AVB). The MAC supports standard 6-byte programmable addresses. Module uses AXI interface for DMA access.	CYT3DL supports one Ethernet channel with transfer rates of 10, or 100 Mbps. It is compatible with IEEE 802.3 standard. It supports IEEE 802AS and 1588 precision clock synchronization protocol. It supports MII and RMII PHY interfaces. It supports full-duplex data transport using external PHY devices. It supports half-duplex data transport in RMII mode only using external PHY devices. The device also supports Audio-Video Bridging (AVB). The MAC supports standard 6-byte programmable addresses. Module uses AXI interface for DMA access.	Correction
26 Electrical specifications	Corrected branch section name and table name	26.2 Device-level specifications Table 26-2 Recommended operating conditions	26.2 Recommended operating conditions Table 26-2 Device-level specifications	Correction
26.14 Serial memory interface specifications	Table 26-35 xSPI specifications Updated symbol in Recommended I/O configuration	load ≤ 15 pF	load ≤ 15 pF	Correction
26.15 Graphics subsystem specifications	Added note	None	Added: Note: Values are valid for PLL400 in operation mode Integer, SSCG and Fractional	Addition
27 Ordering information	Table 27-1 Added eight new device codes and a column 'Autosar package'	None	Added eight new device codes CYT3DLBBS, CYT3DLBBZS, CYT3DLABSS, CYT3DLABZS, CYT3DLBBVS, CYT3DLBBYS, CYT3DLABVS, and CYT3DLABYS	Addition
27.1 Part number nomenclature	Table 27-2 and Table 27-3 Updated marketing option, temperature grade, and added notes	Marketing option not specified for S, V, Y, and Z values. Software bundle and Autosar package requirement not specified.	Added marketing option for S, V, Y, and Z values. Added software bundle requirements and Autosar package columns and added 'Notes, *xx: Qt runtime, Infineon Graphics package (2D Graphics Driver, Safety Signature Driver, JPEG Decoder Driver, Dynamic Warping Library) *yy: Infineon Graphics package (2D Graphics Driver, Safety Signature Driver, JPEG Decoder Driver, Dynamic Warping Library) S-grade (-40°C to 105°C) and E-grade (-40°C to 125°C)	Updated
28 Packaging	Table 28-2 Updated conditions and max value	None	Added T _J conditions for 216-TEQFP and 272-BGA, Updated max values for T _J , R _{θJA} (216-TEQFP), R _{θJB} (216-TEQFP), and R _{θJC} (216-TEQFP and 272-BGA)	Updated
31 Errata	17. Greater change of Low voltage detection (LVD) level can issue an Over voltage detection (OVD) reset	None	Added "[17] Greater change of Low voltage detection (LVD) level can issue an Over voltage detection (OVD) reset"	Added errata
31 Errata	19. SCB transition times in SPI mode clarified	Transition time in SPI mode not specified	Added Transition timing and new spec ID	Updated

Revision history change log

Rev. *J Electrical spec updates

Spec ID	Description	Changed item	Current spec	New spec	Reason for change
SID33B	HIGH-level total output current for SMC[51]	Details/conditions	25°C < T _A ≤ 105°C	Added: For S-grade devices	Updated spec
SID33B_125	HIGH-level total output current for SMC[51]	Added as new spec ID	-	SID33B_125 ΣIOH_SMC_ABS HIGH-level total output current for SMC [51] - - 300 mA 25 °C < T _A ≤ 125 °C For E-Grade devices	New spec
SID33I	HIGH-level total output current for SMC	Added as new spec ID	-	SID33I ΣIOH_SMC_ABS HIGH-level total output current for SMC - - -450 mA -40°C ≤ T _A ≤ 25°C	New spec
SID34_2	Power dissipation	Added details/conditions	-	25°C < T _A ≤ 105°C For S-grade devices	Updated spec
SID34_2_125	Power dissipation	Added as new spec	-	SID34_2_125 PD Power dissipation - - 1400 mW 25 °C < T _A ≤ 125 °C For E-Grade devices, BGA-272: 1400 mW; TEQFP-216: 1600 mW based on R _{th}	New spec
SID36_125	Operating ambient temperature	Added as new spec	-	SID36_125 T _A Operating ambient temperature -40 - 125 °C For E-Grade devices	New spec
SID51C	V _{CCD} current in external PMIC mode	Details/conditions	Typ: T _A = 25°C, V _{CCD} = 1.15 V, process typ (TT) Max: T _A = 105°C, T _J = 150°C, V _{CCD} = 1.21 V, process worst (FF) (Maximum expected V _{CCD} when T _J = 150°C is reached due to self-heating)	Added: For S-grade devices	Updated spec
SID51C_125	V _{CCD} current in external PMIC mode	Added as new spec	-	SID51C_125 ICC1 V _{CCD} current in external PMIC mode - - 450 950 mA Typ: T _A = 25°C, V _{CCD} = 1.15 V, process typ (TT) Max: T _A = 125°C, T _J = 150°C, V _{CCD} = 1.21 V, process worst (FF) (Maximum expected V _{CCD} when T _J = 150°C is reached due to self-heating) For E-grade devices	New spec
SID52C	V _{DD} current in external PMIC mode, Use case with VIDEOSS (V _{DD} current for SID51C use case)	Details/conditions	Cortex®-M7 at 240 MHz generated by PLL with ECO reference, executing Dhrystone from flash with cache enabled. Cortex®-M0+ is sleeping at 100 MHz. Graphics Engine at 200 MHz, operating 2D rendering, drawing, capture, output on 2 displays. All other peripherals, peripheral clocks, interrupts, CSV, DMA, ECO are enabled. No I/O toggling. Typ: T _A = 25°C, V _{CCD} = 1.15 V, process typ (TT) Max: T _A = 105°C, V _{CCD} = 1.21 V, process worst (FF);	Added: For S-grade devices	Updated spec
SID52C_125	V _{DD} current in external PMIC mode, Use case with VIDEOSS (V _{DD} current for SID51C use case)	Added as new spec	-	Cortex®-M7 at 240 MHz generated by PLL with ECO reference, executing Dhrystone from flash with cache enabled. Cortex®-M0+ is sleeping at 100 MHz. Graphics Engine at 200 MHz, operating 2D rendering, drawing, capture, output on 2 displays. All other peripherals, peripheral clocks, interrupts, CSV, DMA, ECO are enabled. No I/O toggling. Typ: T _A = 25°C, V _{CCD} = 1.15 V, process typ (TT) Max: T _A = 125°C, V _{CCD} = 1.21 V, process worst (FF); For E-grade devices	New spec
SID50B	V _{CCD} current in external PMIC mode. Cortex®-M7/M0+ CPUs in Sleep mode. VIDEOSS in sleep mode (clocks off)	Details/conditions	Clocks running at max frequency, All CPUs in Sleep mode. VIDEOSS in sleep mode All other peripherals, peripheral clocks, interrupts, CSV, DMA, ECO are disabled. No IO toggling. Typ: T _A = 25°C, V _{DD} = 5.0 V, V _{CCD} = 1.15 V, process typ (TT) Max: T _A = 105°C, V _{DD} = 5.5 V, V _{CCD} = 1.21 V, process worst (FF);	Added For S-grade devices	Updated spec

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SID50B_125	V_{CCD} current in external PMIC mode. Cortex®-M7/M0+ CPUs in Sleep mode. VIDEOSS in sleep mode (clocks off)	Added as new spec	-	SID50B_125 I_{CC1} V_{CCD} current in external PMIC mode. Cortex®-M7/M0+ CPUs in Sleep mode. VIDEOSS in sleep mode (clocks off) Clocks running at max frequency, All CPUs in Sleep mode. VIDEOSS in sleep mode. All other peripherals, peripheral clocks, interrupts, CSV, DMA, ECO are disabled. No IO toggling. Typ: $T_A = 25^\circ\text{C}$, $V_{DD} = 5.0\text{ V}$, $V_{CCD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 125^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, $V_{CCD} = 1.21\text{ V}$, process worst (FF); For E-grade devices	New spec
SID73	I_{DD} when XRES_L asserted	Details/conditions	Max: $T_A = 105^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, process worst (FF)	Added: For S-grade devices	Updated spec
SID73_125	I_{DD} when XRES_L asserted	Added as new spec ID	-	SID73_125 I_{DD_XRES} I_{DD} when XRES_L asserted - 1.7 mA Max: $T_A = 125^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, process worst (FF); For E-grade devices	New spec
SID82	I_{DDIO_HSIO} when XRES_L is asserted	Details/conditions	Typ: $T_A = 25^\circ\text{C}$, $V_{DDIO_HSIO} = 3.3\text{ V}$, process typ (TT) Max: $T_A = 105^\circ\text{C}$, $V_{DDIO_HSIO} = 3.6\text{ V}$, process worst (FF);	Added: For S-grade devices	Updated spec
SID82_125	I_{DDIO_HSIO} when XRES_L is asserted	Added as new spec ID	-	SID82_125 I_{DDIO_HSIO} I_{DDIO_HSIO} when XRES_L is asserted - 1.5 300 μA Typ: $T_A = 25^\circ\text{C}$, $V_{DDIO_HSIO} = 3.3\text{ V}$, process typ (TT) Max: $T_A = 105^\circ\text{C}$, $V_{DDIO_HSIO} = 3.6\text{ V}$, process worst (FF); For E-grade devices	New spec
SID83	I_{DDIO_SMC} when XRES_L is asserted	Details/conditions	Typ: $T_A = 25^\circ\text{C}$, $V_{DDIO_SMC} = 5.0\text{ V}$, process typ (TT) Max: $T_A = 105^\circ\text{C}$, $V_{DDIO_SMC} = 5.5\text{ V}$, process worst (FF)	Added: For S-grade devices	Updated spec
SID83_125	I_{DDIO_SMC} when XRES_L is asserted	Added as new spec ID	-	SID83_125 I_{DDIO_SMC} I_{DDIO_SMC} when XRES_L is asserted - 0.06 90 μA Typ: $T_A = 25^\circ\text{C}$, $V_{DDIO_SMC} = 5.0\text{ V}$, process typ (TT) Max: $T_A = 125^\circ\text{C}$, $V_{DDIO_SMC} = 5.5\text{ V}$, process worst (FF); For E-grade devices	New spec
SID84	$I_{DDIO_GPIO_1}$ when XRES_L is asserted	Details/conditions	Typ: $T_A = 25^\circ\text{C}$, $V_{DDIO_GPIO_1} = 5.0\text{ V}$, process typ (TT) Max: $T_A = 105^\circ\text{C}$, $V_{DDIO_GPIO_1} = 5.5\text{ V}$, process worst (FF)	Added: For S-grade devices	Updated spec
SID84_125	$I_{DDIO_GPIO_1}$ when XRES_L is asserted	Added as new spec ID	-	SID84_125 $I_{DDIO_GPIO_1}$ $I_{DDIO_GPIO_1}$ when XRES_L is asserted - 0.05 40 μA Typ: $T_A = 25^\circ\text{C}$, $V_{DDIO_GPIO_1} = 5.0\text{ V}$, process typ (TT) Max: $T_A = 105^\circ\text{C}$, $V_{DDIO_GPIO_1} = 5.5\text{ V}$, process worst (FF); For E-grade devices	New spec
SID85	$I_{DDIO_GPIO_2}$ when XRES_L is asserted	Details/conditions	Typ: $T_A = 25^\circ\text{C}$, $V_{DDIO_GPIO_2} = 5.0\text{ V}$, process typ (TT) Max: $T_A = 105^\circ\text{C}$, $V_{DDIO_GPIO_2} = 5.5\text{ V}$, process worst (FF)	Added: For S-grade devices	Updated spec
SID85_125	$I_{DDIO_GPIO_2}$ when XRES_L is asserted	Added as new spec ID	-	SID85_125 $I_{DDIO_GPIO_2}$ $I_{DDIO_GPIO_2}$ when XRES_L is asserted - 0.05 50 μA Typ: $T_A = 25^\circ\text{C}$, $V_{DDIO_GPIO_2} = 5.0\text{ V}$, process typ (TT) Max: $T_A = 105^\circ\text{C}$, $V_{DDIO_GPIO_2} = 5.5\text{ V}$, process worst (FF); For E-grade devices	New spec
SID670	Input leakage current	Details/conditions	$V_{DDIO_GPIO_x} = V_{DD} = V_{DDA_ADC} = 5.5\text{ V}$, $V_{SS} < V_I < V_{DDIO_GPIO_x}$, $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$ This is valid for the pin which do not have ADC input functionality	Added: For S-grade devices	Updated spec
SID670_125	Input leakage current	Added as new spec ID	-	SID670_125 I_{IL} Input leakage current - 1 1 μA $V_{DDIO_GPIO_x} = V_{DD} = V_{DDA_ADC} = 5.5\text{ V}$, $V_{SS} < V_I < V_{DDIO_GPIO_x}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ This is valid for the pin which do not have ADC input functionality; For E-grade devices.	New spec

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SID653B	Output voltage LOW level	Details/ conditions	$I_{OL} = 30 \text{ mA}$ $CFG_OUT/DRIVE_SEL<1:0> = 0b00$ $CFG_OUT/SLOW<0:0> = 0b1$ $25^{\circ}\text{C} < T_A \leq 105^{\circ}\text{C}$ $V_{DDIO_SMC} \geq 4.5 \text{ V}$	Added: For S-grade devices	Updated spec
SID653B_125	Output voltage LOW level	Added as new spec ID	-	SID653B_125B V_{OL5} Output voltage LOW level - - $0.5 V I_{OL} = 30 \text{ mA}$ $CFG_OUT/DRIVE_SEL<1:0> = 0b00$ $CFG_OUT/SLOW<0:0> = 0b1$ $25^{\circ}\text{C} < T_A \leq 125^{\circ}\text{C}$ $V_{DDIO_SMC} \geq 4.5 \text{ V}$ For E-grade devices	New spec
SID657B	Output voltage HIGH level	Details/ conditions	$I_{OL} = -30 \text{ mA}$ $CFG_OUT/DRIVE_SEL<1:0> = 0b00$ $CFG_OUT/SLOW<0:0> = 0b1$ $25^{\circ}\text{C} < T_A \leq 105^{\circ}\text{C}$ $V_{DDIO_SMC} \geq 4.5 \text{ V}$	Added: For S-grade devices	Updated spec
SID657B_125	Output voltage HIGH level	Added as new spec ID	-	SID657B_125 V_{OH5} Output voltage HIGH level $V_{DDIO_SMC} - 0.5 - - V I_{OL} = -30 \text{ mA}$ $CFG_OUT/DRIVE_SEL<1:0> = 0b00$ $CFG_OUT/SLOW<0:0> = 0b1$ $25^{\circ}\text{C} < T_A \leq 125^{\circ}\text{C}$ $V_{DDIO_SMC} \geq 4.5 \text{ V}$ For E-grade devices	New spec
SID670A	Input leakage current	Details/ conditions	$V_{DDIO_SMC} = V_{DD} = 5.5 \text{ V}$, $V_{SS} < V_I < V_{DDIO_SMC}$ $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ This is valid for the pin which do not have ADC input functionality	Added: For S-grade devices	Updated spec
SID670A_125	Input leakage current	Added as new spec ID	-	SID670A_125 I_L Input leakage current $-2 - 2 \mu\text{A} V_{DDIO_SMC} = V_{DD} = 5.5 \text{ V}$, $V_{SS} < V_I < V_{DDIO_SMC}$ $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ This is valid for the pin which do not have ADC input functionality; For E-grade devices	New spec
SID670C	Input leakage current	Details/ conditions	$V_{DDIO_GPIO} = V_{DD} = 5.5 \text{ V}$, $V_{SS} < V_I < V_{DDIO_GPIO}$ $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$	Added: For S-grade devices	Updated spec
SID670C_125	Input leakage current	Added as new spec ID	-	SID670C_125 I_L Input leakage current $-1 - 1 \mu\text{A} V_{DDIO_GPIO} = V_{DD} = 5.5 \text{ V}$, $V_{SS} < V_I < V_{DDIO_GPIO}$ $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$; For E-grade devices	New spec
SID26B	LOW-level total output current for SMC[51]	Details/ conditions	$25^{\circ}\text{C} < T_A \leq 105^{\circ}\text{C}$	$25^{\circ}\text{C} < T_A \leq 105^{\circ}\text{C}$ For S-grade devices	Updated spec
SID26B_125	LOW-level total output current for SMC[51]	Added as new spec ID	-	SID26B_125 $\Sigma I_{OL_SMC_ABS}$ LOW-level total output current for SMC [51] - - $300 \text{mA} 25^{\circ}\text{C} < T_A \leq 125^{\circ}\text{C}$ For E-Grade devices	New spec
SID129_2	SCB transition in SPI mode	Description	SCB transition in SPI mode	SCB input transition in SPI mode	Updated spec
SID129_3	SCB output transition in SPI mode	Added as new spec ID	-	SID129_3 t_{SPI_TRANS} SCB output transition in SPI mode - - $10 \text{ns} \text{Valid for HSIO_STDN}$	New spec
SID129_4	SCB output transition in SPI mode	Added as new spec ID	-	SID129_4 t_{SPI_TRANS} SCB output transition in SPI mode - - $20 \text{ns} \text{Valid for GPIO_STD, GPIO_ENH, GPIO_SMC}$	New spec
SID741	Delay from rising edge of TX_CLK to transition on TX_SD/TX_FSYNC (WS)	Description	Delay from rising edge of TX_CLK to transition on TX_SD/TX_FSYNC (WS)	Hold from rising edge of TX_CLK to transition on TX_SD/TX_FSYNC (WS)	Updated spec
SID73	IDD when XRES_L asserted	Details/ conditions	Typ: $T_A = 25^{\circ}\text{C}$, $V_{DD} = 5 \text{ V}$, process typ (TT), Max: $T_A = 105^{\circ}\text{C}$, $V_{DD} = 5.5 \text{ V}$, process worst (FF)	Max: $T_A = 105^{\circ}\text{C}$, $V_{DD} = 5.5 \text{ V}$, process worst (FF)	Updated spec
SID606	PMIC digital input LOW voltage (%VDD)	Min and max values	Min value ' $0.3 \times V_{DD}$ ' and max value '-'	Min value '-' and max value ' $0.3 \times V_{DD}$ '	Updated spec
SID606A	PMIC digital input HIGH voltage (%VDD)	Min and max values	Min value '-' and max value ' $0.7 \times V_{DD}$ '	Min value ' $0.7 \times V_{DD}$ ' and max value '-'	Updated spec
SID676H	Input leakage current	Details/ conditions	$V_{DDIO_HSIO} = 3.6 \text{ V}$, $V_{SS} < V_I < V_{DDIO_HSIO}$ $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$	Added: For S-grade devices	Updated spec
SID676H_125	Input leakage current	Added as new spec ID	-	SID676H_125 I_{L12} Input leakage current $-1 - 1 \mu\text{A} V_{DDIO_HSIO} = 3.6 \text{ V}$, $V_{SS} < V_I < V_{DDIO_HSIO}$ $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$; For E-grade devices	New spec
SID104	Zero transition voltage	Details/ conditions	$V_{DDA_ADC} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ before offset adjustment	Added: For S-grade devices	Updated spec

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SID104_125	Zero transition voltage	Added as new spec ID	-	SID104_125 V_{ZT} Zero transition voltage -20 - 20 mV $V_{DDA_ADC} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ before offset adjustment; For E-grade devices	New spec
SID105	Full-scale transition voltage	Details/conditions	$V_{DDA_ADC} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$ before offset adjustment	Added: For S-grade devices	Updated spec
SID105_125	Full-scale transition voltage	Added as new spec ID	-	SID105 V_{FST} Full-scale transition voltage -20 - 20 mV $V_{DDA_ADC} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ before offset adjustment; For E-grade devices	New spec
SID110	Integral nonlinearity	Details/conditions	$V_{DDA_ADC} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$	Added: For S-grade devices	Updated spec
SID110_125	Integral nonlinearity	Added as new spec ID	-	SID110_125 A_{INL} Integral nonlinearity -2.5 - 2.5 LSB $V_{DDA_ADC} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$; For E-grade devices	New spec
SID111	Differential nonlinearity	Details/conditions	$V_{DDA_ADC} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$	Added: For S-grade devices	Updated spec
SID111_125	Differential nonlinearity	Added as new spec ID	-	SID111_125 A_{DNL} Differential nonlinearity -0.99 - 1.9 LSB $V_{DDA_ADC} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$; For E-grade devices	New spec
SID112	Measure the ADC output with input switching through all input channels of one ADC	Details/conditions	$V_{DDA_ADC} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$	Added: For S-grade devices	Updated spec
SID112_125	Measure the ADC output with input switching through all input channels of one ADC	Added as new spec ID	-	SID112_125 A_{GE} Measure the ADC output with input switching through all input channels of one ADC -7 - 7 LSB $V_{DDA_ADC} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$; For E-grade devices	New spec
SID115	Analog input leakage current (GPIO_STD)	Details/conditions	When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$	Added: For S-grade devices	Updated spec
SID115_125	Analog input leakage current (GPIO_STD)	Added as new spec ID	-	SID115_125 I_{AIC} Analog input leakage current (GPIO_STD) -350 - 350 nA When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$; For E-grade devices	New spec
SID115B	Analog input leakage current (GPIO_ENH)	Details/conditions	When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$	Added: For S-grade devices	Updated spec
SID115B_125	Analog input leakage current (GPIO_ENH)	Added as new spec ID	-	SID115B_125 I_{AIC} Analog input leakage current (GPIO_ENH) -700 - 700 nA When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$; For E-grade devices	New spec
SID115D	Analog input leakage current (GPIO_SMC)	Details/conditions	When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$	Added: For S-grade devices	Updated spec
SID115D_125	Analog input leakage current (GPIO_SMC)	Added as new spec ID	-	SID115D_125 I_{AIC} Analog input leakage current (GPIO_SMC) -1075 - 1075 nA When input pad is selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$; For E-grade devices	New spec
SID115A	Analog input leakage current (GPIO_STD)	Details/conditions	When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$	Added: For S-grade devices	Updated spec
SID115A_125	Analog input leakage current (GPIO_STD)	Added as new spec ID	-	SID115A_125 I_{AIC2} Analog input leakage current (GPIO_STD) -165 - 165 nA When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$; For E-grade devices	New spec
SID115C	Analog input leakage current (GPIO_ENH)	Details/conditions	When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$	Added: For S-grade devices	Updated spec
SID115C_125	Analog input leakage current (GPIO_ENH)	Added as new spec ID	-	SID115C_125 I_{AIC2} Analog input leakage current (GPIO_ENH) -515 - 515 nA When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7 \text{ V to } 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$; For E-grade devices	New spec

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SID115E	Analog input leakage current (GPIO_SMC)	Details/conditions	When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$	Added: For S-grade devices	Updated spec
SID115E_125	Analog input leakage current (GPIO_SMC)	Added as new spec ID	-	SID115E_125 I_{AIC2} Analog input leakage current (GPIO_SMC) - - 1015 nA When input pad is not selected for conversion, $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$; For E-grade devices	New spec
SID1319	Supply current power-down	Details/conditions	Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDA_DAC} = 5.0\text{ V}$, process typ (TT) Max: $T_A = 105^{\circ}\text{C}$, $V_{DDA_DAC} = 5.5\text{ V}$, process worst (FF)	Added: For S-grade devices	Updated spec
SID1319_125	Supply current power-down	Added as new spec ID	-	SID1319_125 I_{DD_OFF} Supply current power-down - 1 100 μA Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDA_DAC} = 5.0\text{ V}$, process typ (TT) Max: $T_A = 125^{\circ}\text{C}$, $V_{DDA_DAC} = 5.5\text{ V}$, process worst (FF); For E-grade devices	New spec
SID884	Total analog supply current in Power-Down mode	Details/conditions	Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDA_FPD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 105^{\circ}\text{C}$, $V_{DDA_FPD} = 1.21\text{ V}$, process worst (FF)	Added: For S-grade devices	Updated spec
SID884_125	Total analog supply current in Power-Down mode	Added as new spec ID	-	SID884_125 I_{VDDA_PD} Total analog supply current in Power-Down mode - 4 300 μA Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDA_FPD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 125^{\circ}\text{C}$, $V_{DDA_FPD} = 1.21\text{ V}$, process worst (FF); For E-grade devices	New spec
SID885	Total PLL supply current in Power-Down mode	Details/conditions	Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDPLL_FPD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 105^{\circ}\text{C}$, $V_{DDPLL_FPD} = 1.21\text{ V}$, process worst (FF)	Added: For S-grade devices	Updated spec
SID885_125	Total PLL supply current in Power-Down mode	Added as new spec ID	-	SID885_125 I_{VDDPLL_PD} Total PLL supply current in Power-Down mode - 3 200 μA Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDPLL_FPD} = 1.15\text{ V}$, process typ (TT) Max: $T_A = 125^{\circ}\text{C}$, $V_{DDPLL_FPD} = 1.21\text{ V}$, process worst (FF); For E-grade devices	New spec
SID885B	Total I/O (LVDS driver) supply current in Power-Down mode	Details/conditions	Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDHA_FPD} = 3.3\text{ V}$, process typ (TT) Max: $T_A = 105^{\circ}\text{C}$, $V_{DDHA_FPD} = 3.6\text{ V}$, process worst (FF)	Added: For S-grade devices	Updated spec
SID885B_125	Total I/O (LVDS driver) supply current in Power-Down mode	Added as new spec ID	-	SID885B_125 I_{VDDHA_PD} Total I/O (LVDS driver) supply current in Power-Down mode - 0.5 50 μA Typ: $T_A = 25^{\circ}\text{C}$, $V_{DDHA_FPD} = 3.3\text{ V}$, process typ (TT) Max: $T_A = 105^{\circ}\text{C}$, $V_{DDHA_FPD} = 3.6\text{ V}$, process worst (FF); For E-grade devices	New spec
SID109	Total error	Details/conditions	$V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $V_{REFL} = V_{SSA_ADC}$, $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ Total error after offset and gain adjustment at 12-bit resolution mode	Added: For S-grade devices	Updated spec
SID109_125	Total error	Added as new spec ID	-	SID109_125 A_{TE} Total error -5 - 5 LSb $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $V_{REFL} = V_{SSA_ADC}$, $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$; For E-grade devices	New spec
SID109A	Total error	Details/conditions	$V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $V_{REFL} = V_{SSA_ADC}$, $-40^{\circ}\text{C} \leq T_A \leq 105^{\circ}\text{C}$ Total error after offset and gain adjustment at 12-bit resolution mode	Added: For S-grade devices	Updated spec
SID109A_125	Total error	Added as new spec ID	-	SID109A_125 A_{TEB} Total error -12 - 12 LSb $V_{DDA_ADC} = V_{REFH} = 2.7\text{ V}$ to 5.5 V , $V_{REFL} = V_{SSA_ADC}$, $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$; For E-grade devices	New spec
SID1004	Delay from rising edge of TX_CLK to transition on TX_SD/TX_FSYNC (WS)	Description	Delay from rising edge of TX_CLK to transition on TX_SD/TX_FSYNC (WS)	Hold from rising edge of TX_CLK to transition on TX_SD/TX_FSYNC (WS)	Updated spec
SID1007	SCLK input transition timing	Description	SCLK transition timing	SCLK input/output transition timing	Updated spec
SID1008	MCLK transition timing	Description	MCLK transition timing	MCLK input/output transition timing	Updated spec
SID1009	DATA input transition timing	Description	DATA transition timing	DATA input/output transition timing	Updated spec

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